# IS25LP128F IS25WP128F

## 128Mb

## SERIAL FLASH MEMORY WITH 166MHZ MULTI I/O SPI & QUAD I/O QPI DTR INTERFACE

**DATA SHEET**

# 128Mb

**SERIAL FLASH MEMORY WITH 166MHZ MULTI I/O SPI &
QUAD I/O QPI DTR INTERFACE**

## FEATURES

- **Industry Standard Serial Interface**
  - IS25LP128F: 128Mbit/16Mbyte
  - IS25WP128F: 128Mbit/16Mbyte
  - 3 or 4 Byte Addressing Mode
  - Supports Standard SPI, Fast, Dual, Dual I/O, Quad, Quad I/O, SPI DTR, Dual I/O DTR, Quad I/O DTR, and QPI
  - Software & Hardware Reset
  - Supports Serial Flash Discoverable Parameters (SFDP)

- **High Performance Serial Flash (SPI)**
  - 80MHz Normal Read
  - Up to166Mhz Fast Read
  - Up to 80MHz DTR (Dual Transfer Rate)
  - Equivalent Throughput of 664 Mb/s
  - Selectable Dummy Cycles
  - Configurable Drive Strength
  - Supports SPI Modes 0 and 3
  - More than 100,000 Erase/Program Cycles
  - More than 20-year Data Retention

- **Flexible & Efficient Memory Architecture**
  - Chip Erase with Uniform Sector/Block Erase (4/32/64 Kbyte)
  - Program 1 to 256 Byte per Page
  - Program/Erase Suspend & Resume

- **Efficient Read and Program modes**
  - Low Instruction Overhead Operations
  - Continuous Read 8/16/32/64 Byte Burst Wrap
  - Selectable Burst Length
  - QPI for Reduced Instruction Overhead
  - AutoBoot Operation

- **Low Power with Wide Temp. Ranges**
  - Single Voltage Supply
    IS25LP: 2.30V to 3.60V
    IS25WP: 1.65V to 1.95V
  - 10 mA Active Read Current
  - 8 µA Standby Current
  - 1 µA Deep Power Down
  - Temp Grades:
    Extended: -40°C to +105°C
    Auto Grade (A3) : -40°C to +125°C

- **Advanced Security Protection**
  - Software and Hardware Write Protection
  - Advanced Sector/Block Protection
  - Top/Bottom Block Protection
  - Power Supply Lock Protection
  - 4x256 Byte Dedicated Security Area with OTP User-lockable Bits
  - 128 bit Unique ID for Each Device (Call Factory)

- **Industry Standard Pin-out & Packages**
  - M =16-pin SOIC 300mil
  - B = 8-pin SOIC 208mil
  - K = 8-contact WSON 6x5mm
  - L = 8-contact WSON 8x6mm
  - G = 24-ball TFBGA (4x6 ball array)
  - H = 24-ball TFBGA (5x5 ball array)
  - KGD (Call Factory)

## GENERAL DESCRIPTION

The IS25LP128F and IS25WP128F Serial Flash memory offers a versatile storage solution with high flexibility and performance in a simplified pin count package. ISSI's "Industry Standard Serial Interface" Flash is for systems that require limited space, a low pin count, and low power consumption. The device is accessed through a 4-wire SPI Interface consisting of a Serial Data Input (SI), Serial Data Output (SO), Serial Clock (SCK), and Chip Enable (CE#) pins, which can also be configured to serve as multi-I/O (see pin descriptions).

The device supports Dual and Quad I/O as well as standard, Dual Output, and Quad Output SPI. Clock frequencies of up to 166MHz allow for equivalent clock rates of up to 664MHz (166MHz x 4) which equates to 83Mbytes/s of data throughput. The IS25xP series of Flash adds support for DTR (Double Transfer Rate) commands that transfer addresses and read data on both edges of the clock. These transfer rates can outperform 16-bit Parallel Flash memories allowing for efficient memory access to support XIP (execute in place) operation.

Initial state of the memory array is erased (all bits are set to 1) when shipped from the factory.

QPI (Quad Peripheral Interface) supports 2-cycle instruction further reducing instruction times. Pages can be erased in groups of 4Kbyte sectors, 32Kbyte blocks, 64Kbyte blocks, and/or the entire chip. The uniform sector and block architecture allows for a high degree of flexibility so that the device can be utilized for a broad variety of applications requiring solid data retention.

### Supply Voltage & Temperature Range vs. Maximum Speed

| | Voltage & Temp. | Speed |
|---|---|---|
| IS25LP (3.0V typ.) | 2.30~3.6V, 125°C | 133MHz |
| | 2.70~3.6V, 125°C | 166MHz |
| IS25WP (1.8V typ.) | 1.65~1.95V, 125°C | 133MHz |
| | 1.70~1.95V, 105°C | 166MHz(1) |

Note:
1. Values are guaranteed by characterization and not 100% tested in production.

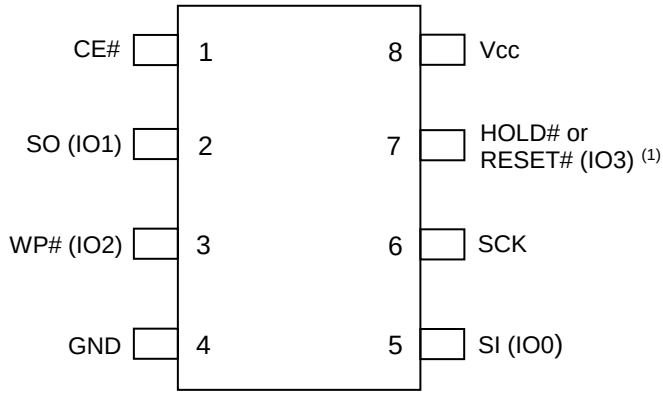
**TABLE OF CONTENTS**

FEATURES ..... 2
GENERAL DESCRIPTION ..... 3
TABLE OF CONTENTS ..... 4
1. PIN CONFIGURATION ..... 7
2. PIN DESCRIPTIONS ..... 9
3. BLOCK DIAGRAM ..... 11
4. SPI MODES DESCRIPTION ..... 12
5. SYSTEM CONFIGURATION ..... 14
5.1 BLOCK/SECTOR ADDRESSES ..... 14
5.2 Serial Flash Discoverable Parameters ..... 15
6. REGISTERS ..... 20
6.1 STATUS REGISTER ..... 20
6.2 FUNCTION REGISTER ..... 25
6.3 READ REGISTER AND EXTENDED REGISTER ..... 26
6.3.1 READ REGISTER ..... 26
6.3.2 EXTENDED READ REGISTER ..... 28
6.4 AUTOBOOT REGISTER ..... 30
6.5 BANK ADDRESS REGISTER ..... 31
6.6 ADVANCED SECTOR/BLOCK PROTECTION (ASP) RELATED REGISTER ..... 32
6.6.1 ADVANCED SECTOR/BLOCK PROTECTION REGISTER (ASPR) ..... 32
6.6.2 PASSWORD REGISTER ..... 33
6.6.3 PPB LOCK REGISTER ..... 33
6.6.4 PPB REGISTER ..... 34
6.6.5 DYB REGISTER ..... 34
7. PROTECTION MODE ..... 35
7.1 HARDWARE WRITE PROTECTION ..... 35
7.2 SOFTWARE WRITE PROTECTION ..... 35
7.2.1 BLOCK PROTECTION BITS ..... 35
7.2.2 ADVANCED SECTOR/BLOCK PROTECTION (ASP) ..... 36
8. DEVICE OPERATION ..... 43
8.1 COMMAND OVERVIEW ..... 43
8.2 COMMAND SET SUMMARY ..... 44
8.3 NORMAL READ OPERATION (NORD, 03h or 4NORD, 13h) ..... 52
8.4 FAST READ OPERATION (FRD, 0Bh or 4FRD, 0Ch) ..... 55
8.5 HOLD OPERATION ..... 59
8.6 FAST READ DUAL I/O OPERATION (FRDIO, BBh or 4FRDIO, BCh) ..... 60
8.7 FAST READ DUAL OUTPUT OPERATION (FRDO, 3Bh or 4FRDO, 3Ch) ..... 64
8.8 FAST READ QUAD OUTPUT OPERATION (FRQO, 6Bh or 4FRQO 6Ch) ..... 67

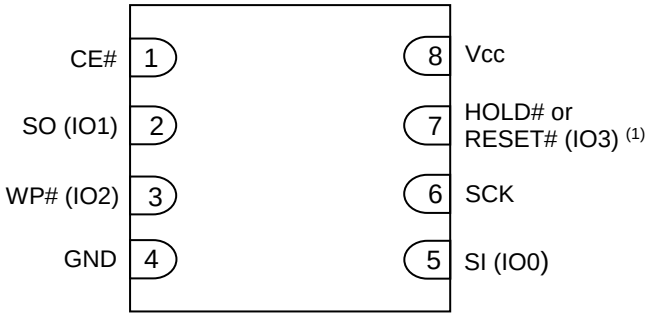
8.9 FAST READ QUAD I/O OPERATION (FRQIO, EBh or 4FRQIO, ECh) ..... 70
8.10 PAGE PROGRAM OPERATION (PP, 02h or 4PP, 12h) ..... 77
8.11 QUAD INPUT PAGE PROGRAM OPERATION (PPQ, 32h/38h or 4PPQ, 34h/3Eh) ..... 80
8.12 ERASE OPERATION ..... 81
8.13 SECTOR ERASE OPERATION (SER, D7h/20h or 4SER, 21h) ..... 82
8.14 BLOCK ERASE OPERATION (BER32K:52h or 4BER32K:5Ch, BER64K:D8h or 4BER64K:DCh) ..... 84
8.15 CHIP ERASE OPERATION (CER, C7h/60h) ..... 87
8.16 WRITE ENABLE OPERATION (WREN, 06h) ..... 88
8.17 WRITE DISABLE OPERATION (WRDI, 04h) ..... 89
8.18 READ STATUS REGISTER OPERATION (RDSR, 05h) ..... 90
8.19 WRITE STATUS REGISTER OPERATION (WRSR, 01h) ..... 91
8.20 READ FUNCTION REGISTER OPERATION (RDFR, 48h) ..... 92
8.21 WRITE FUNCTION REGISTER OPERATION (WRFR, 42h) ..... 93
8.22 ENTER QUAD PERIPHERAL INTERFACE (QPI) MODE OPERATION (QPIEN, 35h; QPIDI,F5h) ..... 94
8.23 PROGRAM/ERASE SUSPEND & RESUME ..... 95
8.24 ENTER DEEP POWER DOWN (DP, B9h) ..... 98
8.25 RELEASE DEEP POWER DOWN (RDPD, ABh) ..... 99
8.26 SET READ PARAMETERS OPERATION (SRPNV: 65h, SRPV: C0h/63h) ..... 100
8.27 SET EXTENDED READ PARAMETERS OPERATION (SERPNV: 85h, SERPV: 83h) ..... 102
8.28 READ READ PARAMETERS OPERATION (RDRP, 61h) ..... 103
8.29 READ EXTENDED READ PARAMETERS OPERATION (RDERP, 81h) ..... 104
8.30 CLEAR EXTENDED READ REGISTER OPERATION (CLERP, 82h) ..... 105
8.31 READ PRODUCT IDENTIFICATION (RDID, ABh) ..... 106
8.32 READ PRODUCT IDENTIFICATION BY JEDEC ID OPERATION (RDJDID, 9Fh; RDJDIDQ, AFh) 108
8.33 READ DEVICE MANUFACTURER AND DEVICE ID OPERATION (RDMDID, 90h) ..... 109
8.34 READ UNIQUE ID NUMBER (RDUID, 4Bh) ..... 110
8.35 READ SFDP OPERATION (RDSFDP, 5Ah) ..... 111
8.36 NO OPERATION (NOP, 00h) ..... 111
8.37 SOFTWARE RESET (RESET-ENABLE (RSTEN, 66h) AND RESET (RST, 99h)) AND HARDWARE RESET ..... 112
8.38 SECURITY INFORMATION ROW ..... 113
8.39 INFORMATION ROW ERASE OPERATION (IRER, 64h) ..... 114
8.40 INFORMATION ROW PROGRAM OPERATION (IRP, 62h) ..... 115
8.41 INFORMATION ROW READ OPERATION (IRRD, 68h) ..... 116
8.42 FAST READ DTR MODE OPERATION (FRDTR, 0Dh or 4FRDTR, 0Eh) ..... 117
8.43 FAST READ DUAL IO DTR MODE OPERATION (FRDDTR, BDh or 4FRDDTR, BEh) ..... 122
8.44 FAST READ QUAD IO DTR MODE OPERATION IN SPI MODE (FRQDTR, EDh or 4FRQDTR, EEh) ..... 126
8.45 SECTOR LOCK/UNLOCK FUNCTIONS ..... 134
8.46 AUTOBOOT ..... 137

8.47 READ BANK ADDRESS REGISTER OPERATION (RDBR: 16h/C8h) ..... 141
8.48 WRITE BANK ADDRESS REGISTER OPERATION (WRBRNV: 18h, WRBRV: 17h/C5h) ..... 142
8.49 ENTER 4-BYTE ADDRESS MODE OPERATION (EN4B, B7h) ..... 143
8.50 EXIT 4-BYTE ADDRESS MODE OPERATION (EX4B, 29h) ..... 144
8.51 READ DYB OPERATION (RDDYB, FAh or 4RDDYB, E0h) ..... 145
8.52 WRITE DYB OPERATION (WRDYB, FBh or 4WRDYB, E1h) ..... 147
8.53 READ PPB OPERATION (RDPPB, FCh or 4RDPPB, E2h) ..... 149
8.54 PROGRAM PPB OPERATION (PGPPB, FDh or 4PGPPB, E3h) ..... 150
8.55 ERASE PPB OPERATION (ERPPB, E4h) ..... 152
8.56 READ ASP OPERATION (RDASP, 2Bh) ..... 153
8.57 PROGRAM ASP OPERATION (PGASP, 2Fh) ..... 154
8.58 READ PPB LOCK BIT OPERATION (RDPLB, A7h) ..... 155
8.59 WRITE PPB LOCK BIT OPERATION (WRPLB, A6h) ..... 156
8.60 SET FREEZE BIT OPERATION (SFRZ, 91h) ..... 157
8.61 READ PASSWORD OPERATION (RDPWD, E7h) ..... 158
8.62 PROGRAM PASSWORD OPERATION (PGPWD, E8h) ..... 159
8.63 UNLOCK PASSWORD OPERATION (UNPWD, E9h) ..... 160
8.64 GANG SECTOR/BLOCK LOCK OPERATION (GBLK, 7Eh) ..... 161
8.65 GANG SECTOR/BLOCK UNLOCK OPERATION (GBUN, 98h) ..... 162
9. ELECTRICAL CHARACTERISTICS ..... 163
9.1 ABSOLUTE MAXIMUM RATINGS (1) ..... 163
9.2 OPERATING RANGE ..... 163
9.3 DC CHARACTERISTICS ..... 164
9.4 AC MEASUREMENT CONDITIONS ..... 165
9.5 PIN CAPACITANCE ..... 165
9.6 AC CHARACTERISTICS ..... 166
9.7 SERIAL INPUT/OUTPUT TIMING ..... 168
9.8 POWER-UP AND POWER-DOWN ..... 170
9.9 PROGRAM/ERASE PERFORMANCE ..... 171
9.10 RELIABILITY CHARACTERISTICS ..... 171
10. PACKAGE TYPE INFORMATION ..... 172
10.1 8-CONTACT ULTRA-THIN SMALL OUTLINE NO-LEAD (WSON) PACKAGE 8x6mm (L) ..... 172
10.2 16-LEAD PLASTIC SMALL OUTLINE PACKAGE (300 MILS BODY WIDTH) (M) ..... 173
10.3 24-BALL THIN PROFILE FINE PITCH BGA 6x8mm 4x6 BALL ARRAY (G) ..... 174
10.4 24-BALL THIN PROFILE FINE PITCH BGA 6x8mm 5x5 BALL ARRAY (H) ..... 175
10.5 8-Pin JEDEC 208mil Broad Small Outline Integrated Circuit (SOIC) PACKAGE (B) ..... 176
10.6 8 Contact Ultra-Thin Small Outline No-Lead (WSON) PACKAGE 6X5MM (K) ..... 177
11. ORDERING INFORMATION – Valid Part Numbers ..... 178

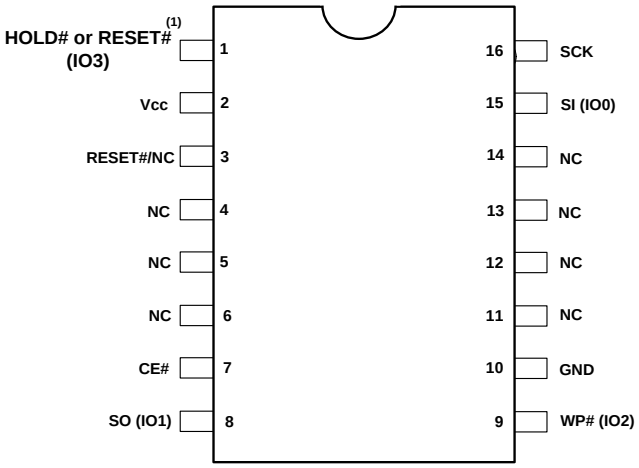
# 1. PIN CONFIGURATION




**8-pin SOIC 208mil**

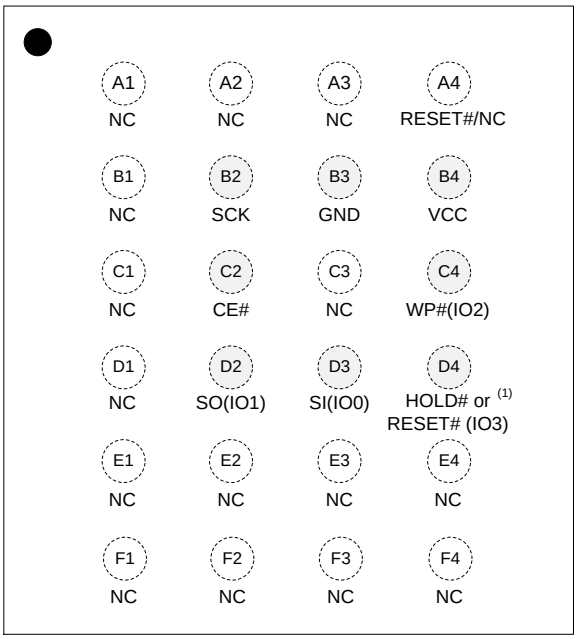



**8-contact WSON 6x5mm**
**8-contact WSON 8x6mm**



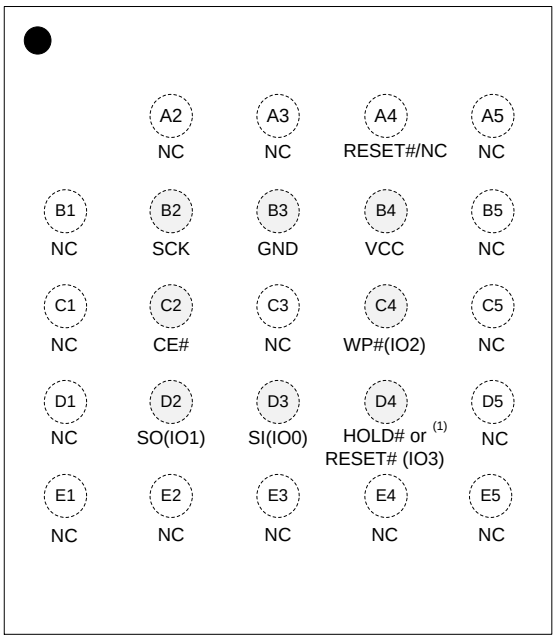

**16-pin SOIC 300mil (Package: M)**

Top View, Balls Facing Down




**24-ball TFBGA 6x8mm (4x6 ball array)**
**(Package: G)**

Top View, Balls Facing Down




**24-ball TFBGA 6x8mm (5x5 ball array)**
**(Package: H)**

**Note:**

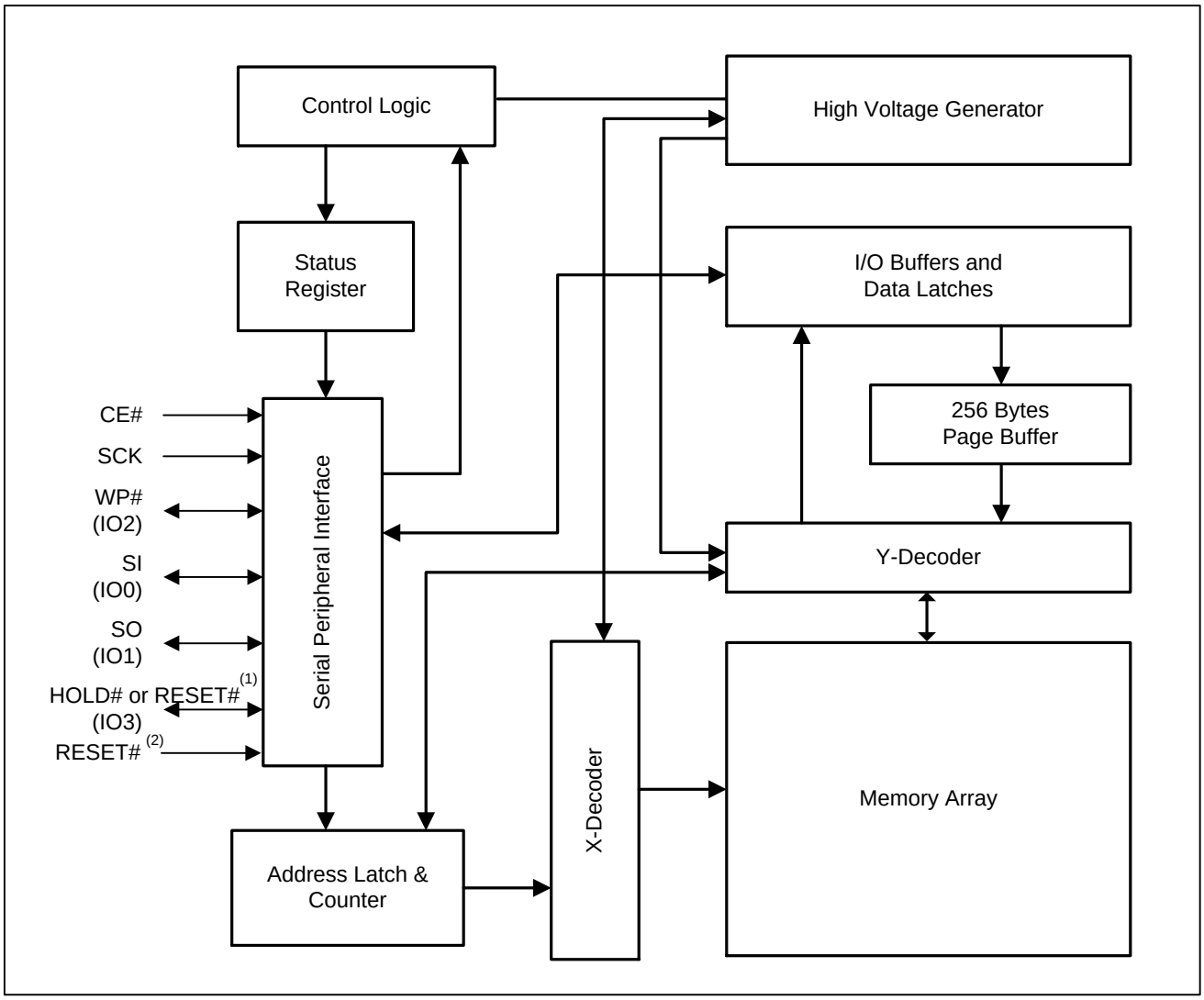
1. **The pin can be configured as Hold# or Reset# by setting P7 bit of the Read Register. Pin default is Hold# (IO3).**

## 2. PIN DESCRIPTIONS

| SYMBOL | TYPE | DESCRIPTION |
|---|---|---|
| CE# | INPUT | **Chip Enable:** The Chip Enable (CE#) pin enables and disables the devices operation. When CE# is high the device is deselected and output pins are in a high impedance state. When deselected the devices non-critical internal circuitry power down to allow minimal levels of power consumption while in a standby state.<br>When CE# is pulled low the device will be selected and brought out of standby mode. The device is considered active and instructions can be written to, data read, and written to the device. After power-up, CE# must transition from high to low before a new instruction will be accepted.<br>Keeping CE# in a high state deselects the device and switches it into its low power state. Data will not be accepted when CE# is high. |
| SI (IO0),<br>SO (IO1) | INPUT/OUTPUT | **Serial Data Input, Serial Output, and IOs (SI, SO, IO0, and IO1):**<br>This device supports standard SPI, Dual SPI, and Quad SPI operation. Standard SPI instructions use the unidirectional SI (Serial Input) pin to write instructions, addresses, or data to the device on the rising edge of the Serial Clock (SCK). Standard SPI also uses the unidirectional SO (Serial Output) to read data or status from the device on the falling edge of the serial clock (SCK).<br>In Dual and Quad SPI mode, SI and SO become bidirectional IO pins to write instructions, addresses or data to the device on the rising edge of the Serial Clock (SCK) and read data or status from the device on the falling edge of SCK. Quad SPI instructions use the WP# and HOLD# pins as IO2 and IO3 respectively. |
| WP# (IO2) | INPUT/OUTPUT | **Write Protect/Serial Data IO (IO2):** The WP# pin protects the Status Register from being written in conjunction with the SRWD bit. When the SRWD is set to “1” and the WP# is pulled low, the Status Register bits (SRWD, QE, BP3, BP2, BP1, BP0) are write-protected and vice-versa for WP**#** high. When the SRWD is set to “0”, the Status Register is not write-protected regardless of WP# state.<br>When the QE bit is set to “1”, the WP**#** pin (Write Protect) function is not available since this pin is used for IO2. |
| HOLD# (IO3)<br>or<br>RESET# (IO3) | INPUT/OUTPUT | **HOLD# or RESET#/Serial Data IO (IO3):** When the QE bit of Status Register is set to “1”, HOLD**#** pin or RESET**#** is not available since it becomes IO3.<br>**Most packages except for 16-pin SOIC and 24-ball BGA:**<br>When QE=0, the pin acts as HOLD# or RESET# and either one can be selected by the P7 bit setting in Read Register. HOLD# will be selected if P7=0 (Default) and RESET# will be selected if P7=1.<br>**16-pin SOIC and 24-ball BGA packages :**<br>- When QE=0 and Dedicated RESET# is Enabled (Default), the pin acts as HOLD# regardless of the P7 bit setting in Read Register.<br>- When QE=0 and Dedicated RESET# is Disabled, the pin acts as HOLD# or RESET# and either one can be selected by the P7 bit setting in Read Register. HOLD# will be selected if P7=0 (Default) and RESET# will be selected if P7=1.<br>The HOLD# pin allows the device to be paused while it is selected. It pauses serial communication by the master device without resetting the serial sequence. The HOLD# pin is active low. When HOLD# is in a low state and CE# is low, the SO pin will be at high impedance. Device operation can resume when HOLD# pin is brought to a high state. |

| SYMBOL | TYPE | DESCRIPTION |
|---|---|---|
| RESET# | INPUT/OUTPUT | **RESET#:** This dedicated RESET# is available in 16-pin SOIC and 24-ball BGA packages.<br>The RESET# pin is a hardware RESET signal. When RESET# is driven HIGH, the memory is in the normal operating mode. When RESET# is driven LOW, the memory enters reset mode and output is High-Z. If RESET# is driven LOW while an internal WRITE, PROGRAM, or ERASE operation is in progress, data may be lost.<br>Dedicated RESET# function can be Disabled when bit 0 of Function Register = 1.<br>It has an internal pull-up resistor and may be left floating if not used. |
| SCK | INPUT | **Serial Data Clock:** Synchronized Clock for input and output timing operations. |
| Vcc | POWER | **Power:** Device Core Power Supply |
| GND | GROUND | **Ground:** Connect to ground when referenced to Vcc |
| NC | Unused | **NC:** Pins labeled “NC” stand for “No Connect” and should be left uncommitted. |

## 3. BLOCK DIAGRAM




**Note:**

**1: In case of 16-pin SOIC or 24-ball TFBFA, when QE=0 and Dedicated RESET# is Disabled, the pin acts as HOLD# or RESET# and either one can be selected by the P7 bit setting in Read Register. HOLD# will be selected if P7=0 (Default) and RESET# will be selected if P7=1.**

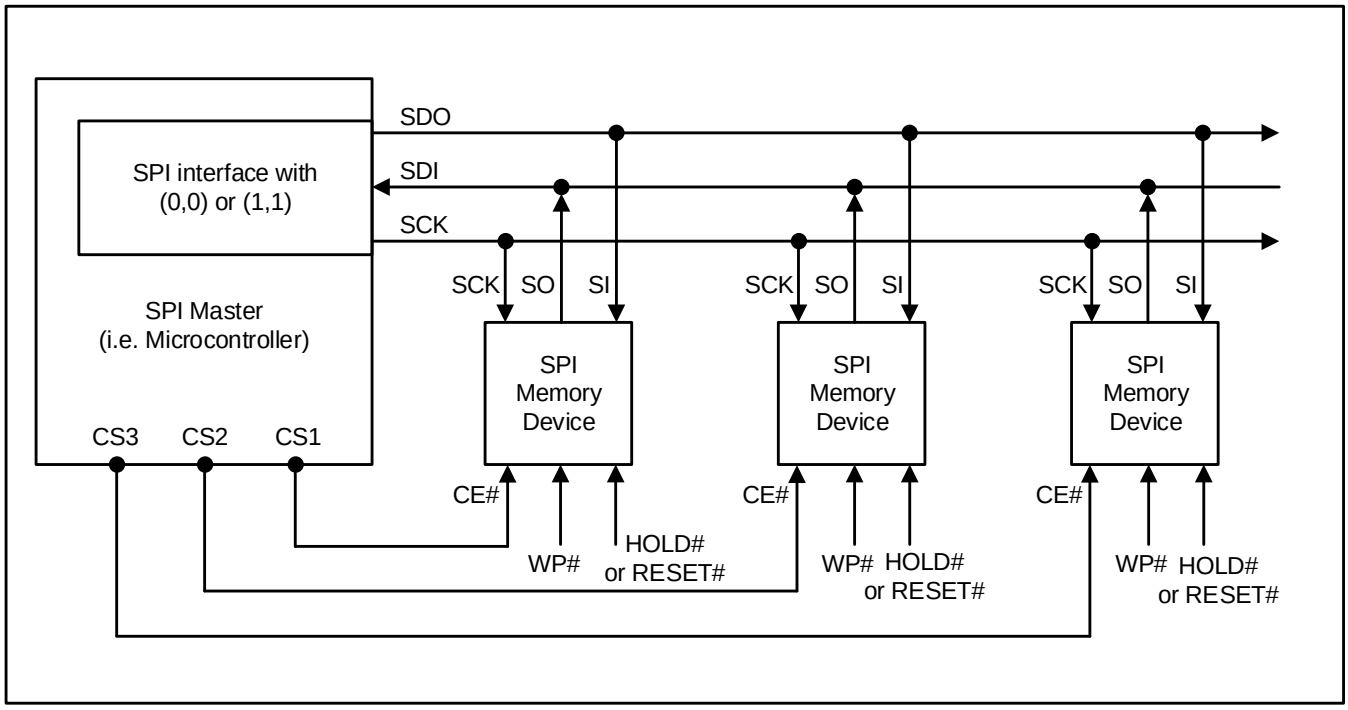
## 4. SPI MODES DESCRIPTION

Multiple IS25LP128F devices or multiple IS25WP128F devices can be connected on the SPI serial bus and controlled by a SPI Master, i.e. microcontroller, as shown in Figure 4.1. The devices support either of two SPI modes:

Mode 0 (0, 0)
Mode 3 (1, 1)

The difference between these two modes is the clock polarity. When the SPI master is in stand-by mode, the serial clock remains at "0" (SCK = 0) for Mode 0 and the clock remains at "1" (SCK = 1) for Mode 3. Please refer to Figure 4.2 and Figure 4.3 for SPI and QPI mode. In both modes, the input data is latched on the rising edge of Serial Clock (SCK), and the output data is available from the falling edge of SCK.

**Figure 4.1 Connection Diagram among SPI Master and SPI Slaves (Memory Devices)**




**Notes:**
**1. In case of 16-pin SOIC and 24-ball TFBGA, dedicated RESET# is supported.**
**2. SI and SO pins become bidirectional IO0 and IO1 respectively during Dual I/O mode and SI, SO, WP#, and HOLD# pins become bidirectional IO0, IO1, IO2, and IO3 respectively during Quad I/O or QPI mode.**

**Figure 4.2 SPI Mode Support**

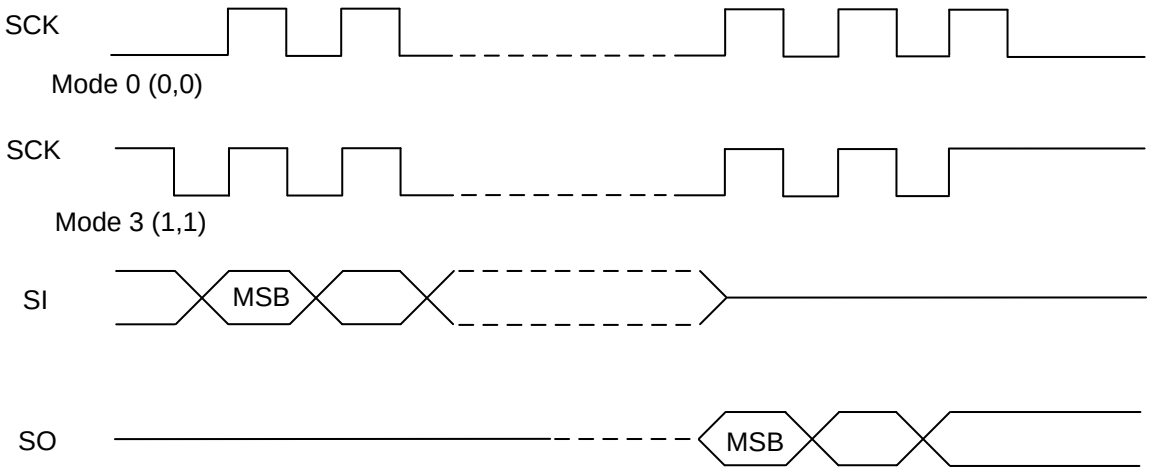
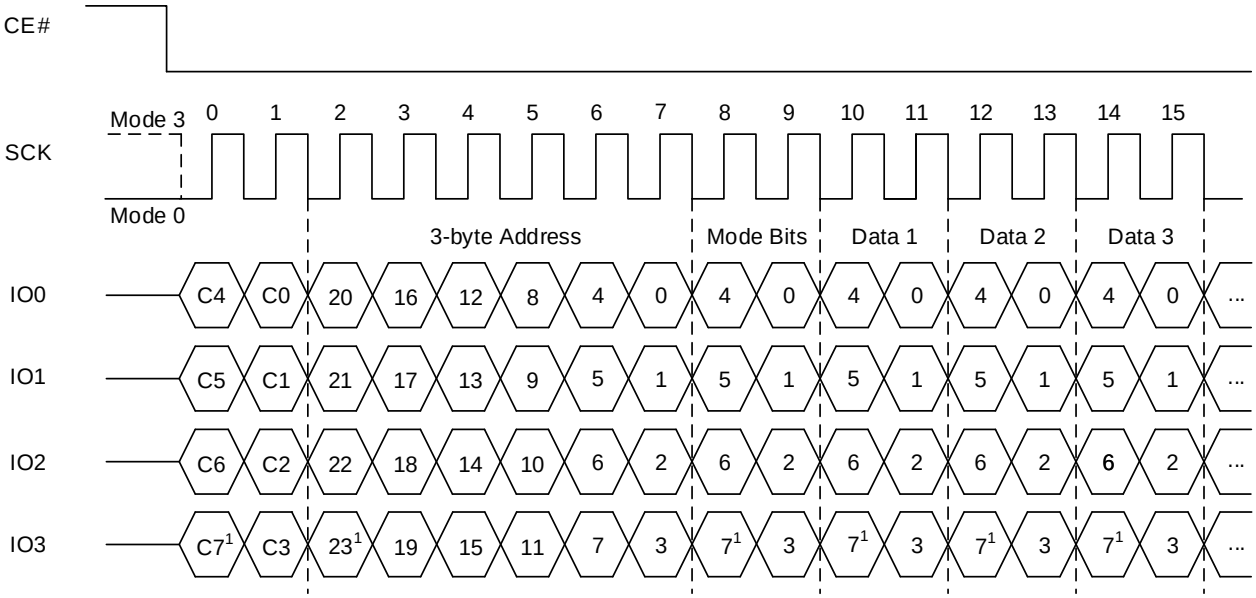



**Figure 4.3 QPI Mode Support**




**Note1: MSB (Most Significant Bit)**

# 5. SYSTEM CONFIGURATION

The memory array is divided into uniform 4 Kbyte sectors or uniform 32/64 Kbyte blocks (a block consists of eight/sixteen adjacent sectors respectively).

Table 5.1 illustrates the memory map of the device. The Status Register controls how the memory is protected.

## 5.1 BLOCK/SECTOR ADDRESSES

**Table 5.1 Block/Sector Addresses**

| Memory Density | Block No. (64Kbyte) | Block No. (32Kbyte) | Sector No. | Sector Size (Kbyte) | Address Range |
|---|---|---|---|---|---|
| 128Mb | Block 0 | Block 0 | Sector 0 | 4 | 000000h – 000FFFh |
| | | | : | : | : |
| | | Block 1 | : | : | : |
| | | | Sector 15 | 4 | 00F000h - 00FFFFh |
| | Block 1 | Block 2 | Sector 16 | 4 | 010000h – 010FFFh |
| | | | : | : | : |
| | | Block 3 | : | : | : |
| | | | Sector 31 | 4 | 01F000h - 01FFFFh |
| | Block 2 | Block 4 | Sector 32 | 4 | 020000h – 020FFFh |
| | | | : | : | : |
| | | Block 5 | : | : | : |
| | | | Sector 47 | 4 | 02F000h – 02FFFFh |
| | : | : | : | : | : |
| | Block 63 | Block 126 | Sector 1008 | 4 | 3F0000h – 3F0FFFh |
| | | | : | : | : |
| | | Block 127 | : | : | : |
| | | | Sector 1023 | 4 | 3FF000h – 3FFFFFh |
| | : | : | : | : | : |
| | Block 127 | Block 254 | Sector 2032 | 4 | 7F0000h – 7F0FFFh |
| | | | : | : | : |
| | | Block 255 | : | : | : |
| | | | Sector 2047 | 4 | 7FF000h – 7FFFFFh |
| | : | : | : | : | : |
| | Block 254 | Block 508 | Sector 4064 | 4 | FE0000h – FE0FFFh |
| | | | : | : | : |
| | | Block 509 | : | : | : |
| | | | Sector 4079 | 4 | FEF000h – FEFFFFh |
| | Block 255 | Block 510 | Sector 4080 | 4 | FF0000h – FF0FFFh |
| | | | : | : | : |
| | | Block 511 | : | : | : |
| | | | Sector 4095 | 4 | FFF000h – FFFFFFh |

## 5.2 SERIAL FLASH DISCOVERABLE PARAMETERS

The Serial Flash Discoverable Parameters (SFDP) standard defines the structure of the SFDP database within the memory device. SFDP is the standard of JEDEC JESD216.
The JEDEC-defined header with Parameter ID FF00h and related Basic Parameter Table is mandatory. Additional parameter headers and tables are optional.

**Table 5.2 Signature and Parameter Identification Data Values**

| Description | | Address (Byte) | Address (Bit) | Data |
|---|---|---|---|---|
| SFDP Signature | | 00h | 7:0 | 53h |
| | | 01h | 15:8 | 46h |
| | | 02h | 23:16 | 44h |
| | | 03h | 31:24 | 50h |
| SFDP Revision | Minor | 04h | 7:0 | 06h |
| | Major | 05h | 15:8 | 01h |
| Number of Parameter Headers (NPH) | | 06h | 23:16 | **00h** |
| Unused | | 07h | 31:24 | FFh |
| Parameter ID LSB | | 08h | 7:0 | 00h |
| Parameter Minor Revision | | 09h | 15:8 | 06h |
| Parameter Major Revision | | 0Ah | 23:16 | 01h |
| Parameter Table Length (in DWPRDs) | | 0Bh | 31:24 | 10h |
| Basic Flash Parameter Table Pointer (PTP) | | 0Ch | 7:0 | 30h |
| | | 0Dh | 15:8 | 00h |
| | | 0Eh | 23:16 | 00h |
| Parameter ID MSB | | 0Fh | 31:24 | FFh |

**Table 5.3 JEDEC Basic Flash Parameter Table**

| Description | Address (Byte) | Address (Bit) | Data |
|---|---|---|---|
| Minimum Sector Erase Sizes | 30h | 1:0 | 01b |
| Write Granularity | | 2 | 1b |
| Volatile Status Register Block Protect bits | | 3 | 0b |
| Write Enable Instruction Select for writing to Volatile Status Register | | 4 | 0b |
| Unused | | 7:5 | 111b |
| 4KB Erase Instruction | 31h | 15:8 | 20h |
| Supports (1-1-2) Fast Read | 32h | 16 | 1b |
| Address Bytes | | 18:17 | 01b |
| Supports Double Transfer Rate (DTR) Clocking | | 19 | 1b |
| Supports (1-2-2) Fast Read | | 20 | 1b |
| Supports (1-4-4) Fast Read | | 21 | 1b |
| Supports (1-1-4) Fast Read | | 22 | 1b |
| Unused | | 23 | 1b |
| Reserved | 33h | 31:24 | FFh |
| Flash memory Density (bits) | 34h | 7:0 | FFh |
| | 35h | 15:8 | FFh |
| | 36h | 23:16 | FFh |
| | 37h | 31:24 | 07h |
| 1-4-4 Fast Read Wait Cycle Count | 38h | 4:0 | 00100b |
| 1-4-4 Fast Read Mode bit Cycle Count | | 7:5 | 010b |
| 1-4-4 Fast Read Instruction | 39h | 15:8 | EBh |
| 1-1-4 Fast Read Wait Cycle Count | 3Ah | 20:16 | 01000b |
| 1-1-4 Fast Read Mode bit Cycle Count | | 23:21 | 000b |
| 1-1-4 Fast Read Instruction | 3Bh | 31:24 | 6Bh |
| 1-1-2 Fast Read Wait Cycle Count | 3Ch | 4:0 | 01000b |
| 1-1-2 Fast Read Mode bit Cycle Count | | 7:5 | 000b |
| 1-1-2 Fast Read Instruction | 3Dh | 15:8 | 3Bh |
| 1-2-2 Fast Read Wait Cycle Count | 3Eh | 20:16 | 00000b |
| 1-2-2 Fast Read Mode bit Cycle Count | | 23:21 | 100b |
| 1-2-2 Fast Read Instruction | 3Fh | 31:24 | BBh |

**Table 5.3 JEDEC Basic Flash Parameter Table (Continued)**

| Description | Address (Byte) | Address (Bit) | Data |
|---|---|---|---|
| Supports (2-2-2) Fast Read | 40h | 0 | 0 |
| Reserved | | 3:1 | 111b |
| Supports (4-4-4) Fast Read | | 4 | 1 |
| Reserved | | 7:5 | 111b |
| Reserved | 43:41h | 31:8 | FFFFFFh |
| Reserved | 45:44h | 15:0 | FFFFh |
| 2-2-2 Fast Read Wait Cycle Count | 46h | 20:16 | 00000b |
| 2-2-2 Fast Read Mode bit Cycle Count | | 23:21 | 000b |
| 2-2-2 Fast Read Instruction | 47h | 31:24 | FFh |
| Reserved | 49:48h | 15:0 | FFFFh |
| 4-4-4 Fast Read Wait Cycle Count | 4Ah | 20:16 | 00100b |
| 4-4-4 Fast Read Mode bit Cycle Count | | 23:21 | 010b |
| 4-4-4 Fast Read Instruction | 4Bh | 31:24 | EBh |
| Erase Type 1 Size (4KB) | 4Ch | 7:0 | 0Ch |
| Erase Type 1 Instruction | 4Dh | 15:8 | 20h |
| Erase Type 2 Size (32KB) | 4Eh | 23:16 | 0Fh |
| Erase Type 2 Instruction | 4Fh | 31:24 | 52h |
| Erase Type 3 Size (64KB) | 50h | 7:0 | 10h |
| Erase Type 3 Instruction | 51h | 15:8 | D8h |
| Erase Type 4 Size (256KB) | 52h | 23:16 | 00h |
| Erase Type 4 Instruction | 53h | 31:24 | FFh |
| Multiplier from typical erase time to maximum erase time | 57:54h | 3:0 | 0010b |
| Sector Type 1 ERASE time (typ) | | 8:4 | 00110b |
| | | 10:9 | 01b |
| Sector Type 2 ERASE time (typ) | | 15:11 | 01000b |
| | | 17:16 | 01b |
| Sector Type 3 ERASE time (typ) | | 22:18 | 01010b |
| | | 24:23 | 01b |
| Sector Type 4 ERASE time (typ) | | 29:25 | 00000b |
| | | 31:30 | 00b |

**Table 5.3 JEDEC Basic Flash Parameter Table (Continued)**

| Description | Address (Byte) | Address (Bit) | Data |
|---|---|---|---|
| Multiplier from typical time to maximum time for page or byte PROGRAM | 58h | 3:0 | 0010b |
| Page size | | 7:4 | 1000b |
| Page Program Typical time | 5Ah:59h | 12:8 | 11000b |
| | | 13 | 0b |
| Byte Program Typical time, first byte | | 17:14 | 0111b |
| | | 18 | 0b |
| Byte Program Typical time, additional byte | | 22:19 | 0000b |
| | | 23 | 0b |
| Chip Erase, Typical time | 5Bh | 28:24 | 01000b |
| Units | | 30:29 | 10b |
| Reserved | | 31 | 1b |
| Prohibited Operations During Program Suspend | 5Ch | 3:0 | 1100b |
| Prohibited Operations During Erase Suspend | | 7:4 | 1110b |
| Reserved | 5Eh:5Dh | 8 | 1b |
| Program Resume to Suspend Interval | | 12:9 | 0110b |
| Suspend in-progress program max latency | | 17:13 | 01100b |
| | | 19:18 | 10b |
| Erase Resume to Suspend Interval | | 23:20 | 0110b |
| Suspend in-progress erase max latency | 5Fh | 28:24 | 01100b |
| | | 30:29 | 10b |
| Suspend /Resume supported | | 31 | 0b |
| Program Resume Instruction | 60h | 7:0 | 7Ah |
| Program Suspend Instruction | 61h | 15:8 | 75h |
| Resume Instruction | 62h | 23:16 | 7Ah |
| Suspend Instruction | 63h | 31:24 | 75h |
| Reserved | 64h | 1:0 | 11b |
| Status Register Polling Device Busy | | 7:2 | 111101b |

**Table 5.3 JEDEC Basic Flash Parameter Table (Continued)**

| Description | | Address (Byte) | Address (Bit) | Data |
|---|---|---|---|---|
| Exit Deep Power-down to next operation delay | 3V | 67h:65h | 12:8 | 00010b |
| | 1.8V | | | 00100b |
| Exit Deep Power-down to next operation delay Units | | | 14:13 | 01b |
| Exit Deep Power-down Instruction | | | 22:15 | ABh |
| Enter Deep Power-down Instruction | | | 30:23 | B9h |
| Deep Power-down Supported | | | 31 | 0b |
| 4-4-4 mode disable sequences (QPIDI) | | 69h:68h | 3:0 | 1010b |
| 4-4-4 mode enable sequences (QPIEN) | | | 8:4 | 00100b |
| 0-4-4 Mode Supported | | | 9 | 1b |
| 0-4-4 Mode Exit Method | | | 15:10 | 110000b |
| 0-4-4 Mode Entry Method: | | 6Ah | 19:16 | 1100b |
| Quad Enable Requirements (QER) | | | 22:20 | 010b |
| Hold or RESET Disable | | | 23 | 0b |
| Reserved | | 6Bh | 31:24 | FFh |
| Volatile or Non-Volatile Register and Write Enable (WREN) Instruction for Status Register 1 | | 6Ch | 6:0 | 1101000b |
| Reserved | | | 7 | 1b |
| Soft Reset and Rescue Sequence Support | | 6Eh:6Dh | 13:8 | 110000b |
| Exit 4-Byte Addressing | | | 23:14 | 1111101000b |
| Enter 4-Byte Addressing | | 6Fh | 31:24 | 10101001b |

# 6. REGISTERS

The device has various sets of Registers: Status, Function, Read, Extended Read and Autoboot.
When the register is read continuously, the same data is output repeatedly until CE# goes HIGH.

## 6.1 STATUS REGISTER

Status Register Format and Status Register Bit Definitions are described in Tables 6.1 & 6.2.
During power up sequence, volatile register will be loaded with the value of non-volatile value.

**Table 6.1 Status Register Format**

| | Bit 7 | Bit 6 | Bit 5 | Bit 4 | Bit 3 | Bit 2 | Bit 1 | Bit 0 |
|---|---|---|---|---|---|---|---|---|
| | SRWD | QE | BP3 | BP2 | BP1 | BP0 | WEL | WIP |
| Default | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |

**Table 6.2 Status Register Bit Definition**

| Bit | Name | Definition | Read-/Write | Type |
|---|---|---|---|---|
| Bit 0 | WIP | Write In Progress Bit:<br>"0" indicates the device is ready (default)<br>"1" indicates a write cycle is in progress and the device is busy | R | Volatile |
| Bit 1 | WEL | Write Enable Latch:<br>"0" indicates the device is not write enabled (default)<br>"1" indicates the device is write enabled | R/W[1] | Volatile |
| Bit 2 | BP0 | Block Protection Bit: (See Tables 6.4 for details)<br>"0" indicates the specific blocks are not write-protected (default)<br>"1" indicates the specific blocks are write-protected | R/W | Non-Volatile |
| Bit 3 | BP1 | | | |
| Bit 4 | BP2 | | | |
| Bit 5 | BP3 | | | |
| Bit 6 | QE | Quad Enable bit:<br>“0” indicates the Quad output function disable (default)<br>“1” indicates the Quad output function enable | R/W | Non-Volatile |
| Bit 7 | SRWD | Status Register Write Disable: (See Table 7.1 for details)<br>"0" indicates the Status Register is not write-protected (default)<br>"1" indicates the Status Register is write-protected | R/W | Non-Volatile |

**Note: WEL bit can be written by WREN and WRDI commands, but cannot by WRSR and VSRWE command.**

The BP0, BP1, BP2, BP3, QE, and SRWD are non-volatile and volatile memory cells that can be written by a Write Status Register (WRSR) instruction. The default value of the BP0, BP1, BP2, BP3, QE, and SRWD bits were set to “0” at factory.

The function of Status Register bits are described as follows:

**WIP bit**: Write In Progress (WIP) is read-only, and can be used to detect the progress or completion of a Program, Erase, Write/Set Non-Volatile/OTP Register, or Gang Sector/Block Lock/Unlock operation. WIP is set to “1” (busy state) when the device is executing the operation. During this time the device will ignore further instructions except for Read Status/Function/Extended Read Register and Software/Hardware Reset instructions. In addition to the instructions, an Erase/Program Suspend instruction also can be executed during a Program or Erase operation. When an operation has completed, WIP is cleared to “0” (ready state) whether the operation is successful or not and the device is ready for further instructions.

**WEL bit**: Write Enable Latch (WEL) bit indicates the status of the internal write enable latch. When WEL bit is “0”, the internal write enable latch is disabled and the Write operations described in Table 6.3 are inhibited. When WEL bit is “1”, the Write operations are allowed. WEL bit is set by a Write Enable (WREN, 06h) instruction. Most of Write Non-Volatile/Volatile Register, Program and Erase instruction must be preceded by a WREN instruction.

WEL bit can be reset by a Write Disable (WRDI) instruction. It will automatically reset after the completion of any Write Non-Volatile Register, Program and Erase operation.

**Table 6.3 Instructions requiring WREN instruction ahead**

| Instructions must be preceded by the WREN instruction | | |
|---|---|---|
| **Name** | **Hex Code** | **Operation** |
| PP | 02h | Serial Input Page Program (3-byte or 4-byte Address) |
| 4PP | 12h | Serial Input Page Program (4-byte Address) |
| PPQ | 32h/38h | Quad Input Page Program (3-byte or 4-byte Address) |
| 4PPQ | 34h/3Eh | Quad Input Page Program (4-byte Address) |
| SER | D7h/20h | Sector Erase 4KB (3-byte or 4-byte Address) |
| 4SER | 21h | Sector Erase 4KB (4-byte Address) |
| BER32 (32KB) | 52h | Block Erase 32KB (3-byte or 4-byte Address) |
| 4BER32 (32KB) | 5Ch | Block Erase 32KB (4-byte Address) |
| BER64 (64KB) | D8h | Block Erase 64KB (3-byte or 4-byte Address) |
| 4BER64 (64KB) | DCh | Block Erase 64KB (4-byte Address) |
| CER | C7h/60h | Chip Erase |
| **WRSR** | 01h | Write Status Register |
| WRFR | 42h | Write Function Register |
| SRPNV | 65h | Set Read Parameters (Non-Volatile) |
| **SRPV**(1) | 63h | Set Read Parameters (Volatile) |
| SERPNV | 85h | Set Extended Read Parameters (Non-Volatile) |
| SERPV | 83h | Set Extended Read Parameters (Volatile) |
| IRER | 64h | Erase Information Row |
| IRP | 62h | Program Information Row |
| WRABR | 15h | Write AutoBoot Register |
| WRBRNV | 18h | Write Non-Volatile Bank Address Register |
| **WRBRV**(1) | C5h | Write Volatile Bank Address Register |
| WRDYB | FBh | Write DYB Register (4-byte Address) |
| 4WRDYB | E1h | Write DYB Register (3-byte or 4-byte Address) |
| PGPPB | FDh | Write PPB (3-byte or 4-byte Address) |
| 4PGPPB | E3h | Write PPB (4-byte Address) |
| ERPPB | E4h | Erase PPB |
| PGASP | 2Fh | Program ASP |
| WRPLB | A6h | Write PPB Lock Bit |
| SFRZ | 91h | Set FREEZE bit |
| GBLK | 7Eh | GANG Sector/Block Lock |
| GBUN | 98h | GANG Sector/Block Unlock |
| PGPWD | E8h | Program Password |

**Note:**
**1. C0h command for SRPV operation and 17h command for WRBRV operation do not require WREN command ahead.**

**BP3, BP2, BP1, BP0 bits**: The Block Protection (BP3, BP2, BP1 and BP0) bits are used to define the portion of the memory area to be protected. Refer to Table 6.4 for the Block Write Protection (BP) bit settings. When a defined combination of BP3, BP2, BP1 and BP0 bits are set, the corresponding memory area is protected. Any program or erase operation to that area will be inhibited.

**Note: A Chip Erase (CER) instruction will be ignored unless all the Block Protection Bits are "0"s.**

**SRWD bit**: The Status Register Write Disable (SRWD) bit operates in conjunction with the Write Protection (WP#) signal to provide a Hardware Protection Mode. When the SRWD is set to "0", the Status Register is not write-protected. When the SRWD is set to "1" and the WP# is pulled low ($V_{IL}$), the bits of Status Register (SRWD, QE, BP3, BP2, BP1, BP0) become read-only, and a WRSR instruction will be ignored. If the SRWD is set to "1" and WP# is pulled high ($V_{IH}$), the Status Register can be changed by a WRSR instruction.

**QE bit**: The Quad Enable (QE) that allows quad operation. When the QE bit is set to "0", the pin WP# and HOLD#/RESET# are enabled. When the QE bit is set to "1", the IO2 and IO3 pins are enabled.

**WARNING: The QE bit must be set to "0" if WP# or HOLD#/RESET# pin (or ball) is tied directly to the power supply.**

**Table 6.4 Block (64Kbyte) assignment by Block Write Protect (BP) Bits**

| Status Register Bits | | | | Protected Memory Area (128Mb, 256Blocks) | |
|---|---|---|---|---|---|
| BP3 | BP2 | BP1 | BP0 | TBS(T/B selection) = 0, Top area | TBS(T/B selection) = 1, Bottom area |
| 0 | 0 | 0 | 0 | 0 (None) | 0 (None) |
| 0 | 0 | 0 | 1 | 1 (1 block : 255th) | 1 (1 block : 0th) |
| 0 | 0 | 1 | 0 | 2 (2 blocks : 254th and 255th) | 2( 2 blocks : 0th and 1st) |
| 0 | 0 | 1 | 1 | 3 (4 blocks : 252nd to 255th) | 3 (4 blocks : 0th to 3rd) |
| 0 | 1 | 0 | 0 | 4 (8 blocks : 248th to 255th) | 4 (8 blocks : 0th to 7th) |
| 0 | 1 | 0 | 1 | 5 (16 blocks : 240th to 255th) | 5 (16 blocks : 0th to 15th) |
| 0 | 1 | 1 | 0 | 6 (32 blocks : 224th to 255th) | 6 (32 blocks : 0th to 31st) |
| 0 | 1 | 1 | 1 | 7 (64 blocks : 192nd to 255th) | 7 (64 blocks : 0th to 63rd) |
| 1 | 0 | 0 | 0 | 8 (128 blocks : 128th to 255th) | 8 (128 blocks : 0th to 127th) |
| 1 | 0 | 0 | 1 | 9 (256 blocks : 0th to 255th) All blocks | 9 (256 blocks : 0th to 255th) All blocks |
| 1 | 0 | 1 | X(1) | 10-11 (256 blocks : 0th to 255th) All blocks | 10-11 (256 blocks : 0th to 255th) All blocks |
| 1 | 1 | x(1) | x(1) | 12-15 (256 blocks : 0th to 255th) All blocks | 12-15 (256 blocks : 0th to 255th) All blocks |

| Status Register Bits | | | | Protected Memory Area (Optional BP Table (2), 128Mb, 256Blocks) | |
|---|---|---|---|---|---|
| BP3 | BP2 | BP1 | BP0 | TBS = 0, Top area | TBS = 1, Bottom area |
| 0 | 0 | 0 | 0 | 0 ( None) | 0 ( None) |
| 0 | 0 | 0 | 1 | 1 (1 block : 255$^{th}$) | 1 (1 block : 0$^{th}$) |
| 0 | 0 | 1 | 0 | 2 (2 blocks : 254$^{th}$ and 255$^{th}$) | 2 (2 blocks : 0$^{th}$ and 1$^{st}$) |
| 0 | 0 | 1 | 1 | 3 (4 blocks : 252$^{nd}$ to 255$^{th}$) | 3 (4 blocks : 0$^{th}$ to 3$^{rd}$) |
| 0 | 1 | 0 | 0 | 4 (8 blocks : 248$^{th}$ to 255$^{th}$) | 4 (8 blocks : 0$^{th}$ to 7$^{th}$) |
| 0 | 1 | 0 | 1 | 5 (16 blocks : 240$^{th}$ to 255$^{th}$) | 5 (16 blocks : 0$^{th}$ to 15$^{th}$) |
| 0 | 1 | 1 | 0 | 6 (32 blocks : 224$^{th}$ to 255$^{th}$) | 6 (32 blocks : 0$^{th}$ to 31$^{st}$) |
| 0 | 1 | 1 | 1 | 7 (64 blocks : 192$^{nd}$ to 255$^{th}$) | 7 (64 blocks : 0$^{th}$ to 63$^{rd}$) |
| 1 | 0 | 0 | 0 | 8 (128 blocks : 128$^{th}$ to 255$^{th}$) | 8 (128 blocks : 0$^{th}$ to 127$^{th}$) |
| 1 | 0 | 0 | 1 | 9 (192 blocks : 64$^{th}$ to 255$^{th}$) | 9 (192 blocks : 0$^{th}$ to 191$^{st}$) |
| 1 | 0 | 1 | 0 | 10 (224 blocks : 32$^{nd}$ to 255$^{th}$) | 10 (224 blocks : 0$^{th}$ to 223$^{rd}$) |
| 1 | 0 | 1 | 1 | 11 (240 blocks : 16$^{th}$ to 255$^{th}$) | 11 (240 blocks : 0$^{th}$ to 239$^{th}$) |
| 1 | 1 | 0 | 0 | 12 (248 blocks : 8$^{th}$ to 255$^{th}$) | 12 (248 blocks : 0$^{th}$ to 247$^{th}$) |
| 1 | 1 | 0 | 1 | 13 (252 blocks : 4$^{th}$ to 255$^{th}$) | 13 (252 blocks : 0$^{th}$ to 251$^{st}$) |
| 1 | 1 | 1 | 0 | 14 (254 blocks : 2$^{nd}$ to 255$^{th}$) | 14 (254 blocks : 0$^{th}$ to 253$^{rd}$) |
| 1 | 1 | 1 | 1 | 15 (256 blocks : 0$^{th}$ to 255$^{th}$) | 15 (256 blocks : 0$^{th}$ to 255$^{th}$) |

**Notes:**
**1. x is don't care**
**2. For Optional BP Table, see the Ordering Information (Option "B")**

### 6.2 FUNCTION REGISTER

Function Register Format and Bit definition are described in Table 6.5 and Table 6.6.

**Table 6.5 Function Register Format**

| | Bit 7 | Bit 6 | Bit 5 | Bit 4 | Bit 3 | Bit 2 | Bit 1 | Bit 0 |
|---|---|---|---|---|---|---|---|---|
| | IRL3 | IRL2 | IRL1 | IRL0 | ESUS | PSUS | TBS | Dedicated RESET# Disable |
| Default | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 or 1 |

**Table 6.6 Function Register Bit Definition**

| Bit | Name | Definition | Read /Write | Type |
|---|---|---|---|---|
| Bit 0 | Dedicated RESET# Disable | Dedicated RESET# Disable bit<br>“0” indicates Dedicated RESET# was enabled<br>“1” indicates Dedicated RESET# was disabled | R/W for 0<br>R for 1 | OTP |
| Bit 1 | TBS | Top/Bottom Selection. (See Table 6.4 for details)<br>“0” indicates Top area.<br>“1” indicates Bottom area. | R/W | OTP |
| Bit 2 | PSUS | Program suspend bit:<br>“0” indicates program is not suspend<br>“1” indicates program is suspend | R | Volatile |
| Bit 3 | ESUS | Erase suspend bit:<br>"0" indicates Erase is not suspend<br>"1" indicates Erase is suspend | R | Volatile |
| Bit 4 | IR Lock 0 | Lock the Information Row 0:<br>“0” indicates the Information Row can be programmed<br>“1” indicates the Information Row cannot be programmed | R/W | OTP |
| Bit 5 | IR Lock 1 | Lock the Information Row 1:<br>“0” indicates the Information Row can be programmed<br>“1” indicates the Information Row cannot be programmed | R/W | OTP |
| Bit 6 | IR Lock 2 | Lock the Information Row 2:<br>“0” indicates the Information Row can be programmed<br>“1” indicates the Information Row cannot be programmed | R/W | OTP |
| Bit 7 | IR Lock 3 | Lock the Information Row 3:<br>“0” indicates the Information Row can be programmed<br>“1” indicates the Information Row cannot be programmed | R/W | OTP |

**Note: Once OTP bits of Function Register are written to “1”, it cannot be modified to “0” any more.**

**Dedicated RESET# Disable bit**: The default status of the bit is dependent on package type. The device with dedicated RESET# (16-pin SOIC and 24-ball BGA) can be programmed to “1” to disable dedicated RESET# function to move RESET# function to Hold#/RESET# pin (or ball). So the device with dedicated RESET# can be used for dedicated RESET# application and HOLD#/RESET# application.

**TBS bit**: BP0~3 area assignment can be changed from Top (default) to Bottom by setting TBS bit to “1”. However, once Bottom is selected, it cannot be changed back to Top since TBS bit is OTP. See Table 6.4 for details.

**PSUS bit**: The Program Suspend Status bit indicates when a Program operation has been suspended. The PSUS changes to “1” after a suspend command is issued during the program operation. Once the suspended Program resumes, the PSUS bit is reset to “0”.

**ESUS bit**: The Erase Suspend Status bit indicates when an Erase operation has been suspended. The ESUS bit is “1” after a suspend command is issued during an Erase operation. Once the suspended Erase resumes, the ESUS bit is reset to “0”.

**IR Lock bit 0 ~ 3**: The default is “0” so that the Information Row can be programmed. If the bit is set to “1”, it cannot be changed back to “0” again since IR Lock bits are OTP.

### 6.3 READ REGISTER AND EXTENDED REGISTER

Read Register format and bit definitions are described below. Read Register and Extended Read Register consist of a pair of rewritable non-volatile register and volatile register, respectively. During power up sequence, volatile register will be loaded with the value of non-volatile value.

#### 6.3.1 READ REGISTER

Table 6.7 and Table 6.8 define all bits that control features in SPI/QPI modes. HOLD#/RESET# pin selection (P7) bit is used to select HOLD# pin or RESET# pin in SPI mode when QE="0" for the device with HOLD#/RESET#. When QE=1 or in QPI mode, P7 bit setting will be ignored since the pin becomes IO3.
For 16-pin SOIC or 24-ball TFBGA with dedicated RESET# device (Dedicated RESET# Disable bit in Functional Register is "0"), HOLD# will be selected regardless of P7 bit setting when QE="0" in SPI mode.

The SET READ PARAMETERS Operations (SRPNV: 65h, SRPV: C0h or 63h) are used to set all the Read Register bits, and can thereby define HOLD#/RESET# pin (or ball) selection, dummy cycles, and burst length with wrap around. SRPNV is used to set the non-volatile register and SRPV is used to set the volatile register.

**Table 6.7 Read Register Parameter Bit Table**

| | P7 | P6 | P5 | P4 | P3 | P2 | P1 | P0 |
|---|---|---|---|---|---|---|---|---|
| | HOLD#/ RESET# | Dummy Cycles | Dummy Cycles | Dummy Cycles | Dummy Cycles | Wrap Enable | Burst Length | Burst Length |
| Default | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |

**Table 6.8 Read Register Bit Definition**

| Bit | Name | Definition | Read-/Write | Type |
|---|---|---|---|---|
| P0 | Burst Length | Burst Length | R/W | Non-Volatile and Volatile |
| P1 | Burst Length | Burst Length | R/W | Non-Volatile and Volatile |
| P2 | Burst Length Set Enable | Burst Length Set Enable Bit:<br>"0" indicates disable (default)<br>"1" indicates enable | R/W | Non-Volatile and Volatile |
| P3 | Dummy Cycles | Number of Dummy Cycles:<br>Bits1 to Bit4 can be toggled to select the number of dummy cycles (1 to 15 cycles) | R/W | Non-Volatile and Volatile |
| P4 | Dummy Cycles | | R/W | Non-Volatile and Volatile |
| P5 | Dummy Cycles | | R/W | Non-Volatile and Volatile |
| P6 | Dummy Cycles | | R/W | Non-Volatile and Volatile |
| P7 | HOLD#/ RESET# | HOLD#/RESET# function selection Bit:<br>"0" indicates the HOLD# function is selected (default)<br>"1" indicates the RESET# function is selected | R/W | Non-Volatile and Volatile |

**Table 6.9 Burst Length Data**

| | P1 | P0 |
|---|---|---|
| 8 bytes | 0 | 0 |
| 16 bytes | 0 | 1 |
| 32 bytes | 1 | 0 |
| 64 bytes | 1 | 1 |

**Table 6.10 Wrap Function**

| Wrap around boundary | **P2** |
|---|---|
| Whole array regardless of P1 and P0 value | 0 |
| Burst Length set by P1 and P0 | 1 |

**Table 6.11 Read Dummy Cycles vs Max Frequency**

| P[6:3] | Dummy Cycles[2,3] | Fast Read[5] 0Bh/0Ch | | Fast Read Dual Output 3Bh/3Ch | Fast Read Dual IO BBh/BCh | Fast Read Quad Output 6Bh/6Ch | Fast Read Quad IO EBh/ECh | FRDTR 0Dh/0Eh | FRDDTR BDh/BEh | FRQDTR EDh/EEh |
|---|---|---|---|---|---|---|---|---|---|---|
| | | SPI | QPI | SPI | SPI | SPI | SPI, QPI | SPI/QPI | SPI[4] | SPI, QPI |
| 0 | Default[1] | **166MHz** | **81MHz** | **166MHz** | **104MHz** | **145MHz** | **81MHz** | **80/69MHz** | **60MHz** | **69MHz** |
| 1 | 1 | 98MHz | 23MHz | 75MHz | 55MHz | 63MHz | 23MHz | 50/11MHz | 30MHz | 11MHz |
| 2 | 2 | 110MHz | 34MHz | 84MHz | 80MHz | 75MHz | 34MHz | 63/23MHz | 40MHz | 23MHz |
| 3 | 3 | 122MHz | 46MHz | 98MHz | 95MHz | 87MHz | 46MHz | 75/34MHz | 50MHz | 34MHz |
| 4 | 4 | 133MHz | 58MHz | 133MHz | **104MHz** | 98MHz | 58MHz | 80/46MHz | **60MHz** | 46MHz |
| 5 | 5 | 145MHz | 69MHz | 140MHz | 120MHz | 110MHz | 69MHz | 80/58MHz | 70MHz | 58MHz |
| 6 | 6 | 156MHz | **81MHz** | 150MHz | 133MHz | 122MHz | **81MHz** | 80/**69**MHz | 80MHz | 69MHz |
| 7 | 7 | 166MHz | 93MHz | 166MHz | 140MHz | 133MHz | 93MHz | 80/80MHz | 80MHz | 80MHz |
| 8 | 8 | **166MHz** | 104MHz | **166MHz** | 150MHz | **145MHz** | 104MHz | **80**/80MHz | 80MHz | 80MHz |
| 9 | 9 | 166MHz | 122MHz | 166MHz | 166MHz | 156MHz | 122MHz | 80/80MHz | 80MHz | 80MHz |
| 10 | 10 | 166MHz | 127MHz | 166MHz | 166MHz | 166MHz | 127MHz | 80/80MHz | 80MHz | 80MHz |
| 11 | 11 | 166MHz | 139MHz | 166MHz | 166MHz | 166MHz | 139MHz | 80/80MHz | 80MHz | 80MHz |
| 12 | 12 | 166MHz | 151MHz | 166MHz | 166MHz | 166MHz | 151MHz | 80/80MHz | 80MHz | 80MHz |
| 13 | 13 | 166MHz | 162MHz | 166MHz | 166MHz | 166MHz | 162MHz | 80/80MHz | 80MHz | 80MHz |
| 14 | 14 | 166MHz | 166MHz | 166MHz | 166MHz | 166MHz | 166MHz | 80/80MHz | 80MHz | 80MHz |
| 15 | 15 | 166MHz | 166MHz | 166MHz | 166MHz | 166MHz | 166MHz | 80/80MHz | 80MHz | 80MHz |

**Notes:**

**1. Default dummy cycles are as follows.**

| Operation | Command | | Dummy Cycles | | Comment |
|---|---|---|---|---|---|
| | Normal mode | DTR mode | Normal mode | DTR mode | |
| Fast Read SPI | 0Bh/0Ch | 0Dh/0Eh | 8 | 8 | RDUID, IRRD instructions are also applied. |
| Fast Read QPI | 0Bh/0Ch | 0Dh/0Eh | 6 | 6 | |
| Fast Read Dual Output | 3Bh/3Ch | - | 8 | - | |
| Fast Read Dual IO SPI | BBh/BCh | BDh/BEh | 4 | 4 | |
| Fast Read Quad Output | 6Bh/6Ch | - | 8 | - | |
| Fast Read Quad IO SPI, QPI | EBh/ECh | EDh/EEh | 6 | 6 | |

**2. Enough number of dummy cycles must be applied to execute properly the AX read operation.**

**3. Must satisfy bus I/O contention. For instance, if the number of dummy cycles and AX bits cycles are same, then X must be Hi-Z.**

**4. QPI mode is not available for FRDDTR command.**

**5. RDUID, IRRD instructions are also applied.**

### 6.3.2 EXTENDED READ REGISTER

Table 6.12 and Table 6.13 define all bits that control features in SPI/QPI modes. The ODS2, ODS1, ODS0 (EB7, EB6, EB5) bits provide a method to set and control driver strength. The four bits (EB3, EB2, EB1, EB0) are read-only bits and may be checked to know what the WIP status is or whether there is an error during an Erase, Program, or Write/Set Register operation. These bits are not affected by SERPNV or SERPV commands. EB4 bit remains reserved for future use.

The SET EXTENDED READ PARAMETERS Operations (SERPNV: 85h, SERPV: 83h) are used to set all the Extended Read Register bits, and can thereby define the output driver strength used during READ modes. SRPNV is used to set the non-volatile register and SRPV is used to set the volatile register.

**Table 6.12 Extended Read Register Bit Table**

| | EB7 | EB6 | EB5 | EB4 | EB3 | EB2 | EB1 | EB0 |
|---|---|---|---|---|---|---|---|---|
| | ODS2 | ODS1 | ODS0 | Reserved | E_ERR | P_ERR | PROT_E | WIP |
| Default | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 |

**Table 6.13 Extended Read Register Bit Definition**

| Bit | Name | Definition | Read-/Write | Type |
|---|---|---|---|---|
| EB0 | WIP | Write In Progress Bit:<br>Has exactly same function as the bit0 (WIP) of Status Register<br>“0”: Ready, “1”: Busy | R | Volatile |
| EB1 | PROT_E | Protection Error Bit:<br>"0" indicates no error<br>"1" indicates protection error in an Erase or a Program operation | R | Volatile |
| EB2 | P_ERR | Program Error Bit:<br>"0" indicates no error<br>"1" indicates a Program operation failure or protection error | R | Volatile |
| EB3 | E_ERR | Erase Error Bit:<br>"0" indicates no error<br>"1" indicates an Erase operation failure or protection error | R | Volatile |
| EB4 | Reserved | Reserved | R | Reserved |
| EB5 | ODS0 | Output Driver Strength:<br>Output Drive Strength can be selected according to Table 6.14 | R/W | Non-Volatile and Volatile |
| EB6 | ODS1 | | R/W | Non-Volatile and Volatile |
| EB7 | ODS2 | | R/W | Non-Volatile and Volatile |

**Table 6.14 Driver Strength Table**

| ODS2 | ODS1 | ODS0 | Description | Remark |
|---|---|---|---|---|
| 0 | 0 | 0 | Reserved | |
| 0 | 0 | 1 | 12.50% | |
| 0 | 1 | 0 | 25% | |
| 0 | 1 | 1 | 37.50% | |
| 1 | 0 | 0 | Reserved | |
| 1 | 0 | 1 | 75% | |
| 1 | 1 | 0 | 100% | |
| 1 | 1 | 1 | 50% | Default |

**WIP bit**: The definition of the WIP bit is exactly same as the one of Status Register.

**PROT_E bit**: The Protection Error bit indicates whether an Erase or Program operation has attempted to modify a protected array sector or block, or to access a locked Information Row region. When the bit is set to "1" it indicates that there was an error or errors in previous Erase or Program operations. See Table 6.15 for details.

**P_ERR bit**: The Program Error bit indicates whether a Program operation has succeeded or failed, or whether a Program operation has attempted to program a protected array sector/block or a locked Information Row region. When the bit is set to "1" it indicates that there was an error or errors in previous Program or Write/Set Non-Volatile Register operations. See Table 6.15 for details.

**E_ERR bit**: The Erase Error bit indicates whether an Erase operation has succeeded or failed, or whether an Erase operation has attempted to erase a protected array sector/block or a locked Information Row region. When the bit is set to "1" it indicates that there was an error or errors in previous Erase or Write/Set Non-Volatile Register operations. See Table 6.15 for details.

**Table 6.15 Instructions to set PROT_E, P_ERR, or E_ERR bit**

| Instructions | Description |
|---|---|
| PP/4PP/PPQ/4PPQ/PGPPB/ 4PGPPB/PGPWD | The commands will set the P_ERR if there is a failure in the operation. Attempting to program within the protected array sector/block or within an erase suspended sector/block will result in a programming error with P_ERR and PROT_E set to "1". |
| IRP | The command will set the P_ERR if there is a failure in the operation. In attempting to program within a locked Information Row region, the operation will fail with P_ERR and PROT_E set to 1. |
| PGASP | The command will set the P_ERR if there is a failure in the operation. Attempting to program ASPR[2:1] after the Protection Mode is selected or attempting to program ASPR[2:1] = 00b will result in a programming error with P_ERR and PROT_E set to "1". |
| UNPWD | If the UNPWD command supplied password does not match the hidden internal password, the UNPWD operation fails in the same manner as a programming operation on a protected sector/block and sets the P_ERR and PROT_E to "1". |
| WRSR/WRABR/SRPNV/ SERPNV/WRBRNV | The update process for the non-volatile register bits involves an erase and a program operation on the non-volatile register bits. If either the erase or program portion of the update fails, the related error bit (P_ERR or E_ERR) will be set to "1".<br>Only for WRSR command, when Status Register is write-protected by SRWD bit and WP# pin, attempting to write the register will set PROT_E and E_ERR to "1". |
| WRFR | The commands will set the P_ERR if there is a failure in the operation. |
| SER/4SER/BER32K/ 4BER32K/BER64K/ 4BER64K/CER/IRER/ERPPB | The commands will set the E_ERR if there is a failure in the operation. E_ERR and PROT_E will be set to "1" when the user attempts to erase a protected main memory sector/block or a locked Information Row region. Chip Erase (CER) command will set E_ERR and PROT_E if any blocks are protected by Block Protection bits (BP3~BP0). But Chip Erase (CER) command will not set E_ERR and PROT_E if sectors/blocks are protected by ASP (DYB bits or PPB bits) only. |

**Notes**:
1. **OTP bits in the Function Register and TBPARM (OTP bit) in the ASP Register may only be programmed to "1". Writing of the bits back to "0" is ignored and no error is set.**
2. **Read only bits and partially protected bits by FREEZE bit in registers are never modified by a command so that the corresponding bits in the Write/Set Register command data byte are ignored without setting any error indication.**
3. **Once the PROT_E, P_ERR, and E_ERR error bits are set to "1", they remains set to "1" until they are cleared to "0" with a Clear Extended Read Register (CLERP) command. This means that those error bits must be cleared through the CLERP command. Alternatively, Hardware Reset, or Software Reset may be used to clear the bits.**
4. **Any further command will be executed even though the error bits are set to "1".**

### 6.4 AUTOBOOT REGISTER

AutoBoot Register Bit (32 bits) definitions are described in Table 6.16.

**Table 6.16 AutoBoot Register Parameter Bit Table**

| Bits | Symbols | Function | Type | Default Value | Description |
|---|---|---|---|---|---|
| AB[31:5] | ABSA | AutoBoot Start Address | Non-Volatile | 0000000h | 32 byte boundary address for the start of boot code access |
| AB[4:1] | ABSD | AutoBoot Start Delay | Non-Volatile | 0h | Number of initial delay cycles between CE# going low and the first bit of boot code being transferred, and it is the same as dummy cycles of FRD (QE=0) or FRQIO (QE=1).<br>Example: The number of initial delay cycles is 8 (QE=0) or 6 (QE=1) when AB[4:1]=0h (Default setting). |
| AB0 | ABE | AutoBoot Enable | Non-Volatile | 0 | 1 = AutoBoot is enabled<br>0 = AutoBoot is not enabled |

### 6.5 BANK ADDRESS REGISTER

Related Commands: Read Volatile Bank Address Register (RDBR 16h/C8h), Write Volatile Bank Address Register (WRBRV 17h/C5h), Write Non-Volatile Bank Address Register (WRBRNV 18h), Enter 4-byte Address Mode (EN4B B7h), and Exit 4-byte Address Mode (EX4B 29h).

Bank Address Register Bit (8 bits) definitions are described in Table 6.17 and Table 6.18.

**Table 6.17 Bank Address Register Bit Table**

| | BA7 | BA6 | BA5 | BA4 | BA3 | BA2 | BA1 | BA0 |
|---|---|---|---|---|---|---|---|---|
| | EXTADD | Reserved | Reserved | Reserved | Reserved | Reserved | Reserved | Reserved |
| Default | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |

**Table 6.18 Bank Address Register Bit Definition**

| Bit | Name | Definition | Read-/Write | Type |
|---|---|---|---|---|
| BA0 | Reserved | Reserved | R | Reserved |
| BA1 | Reserved | Reserved | R | Reserved |
| BA2 | Reserved | Reserved | R | Reserved |
| BA3 | Reserved | Reserved | R | Reserved |
| BA4 | Reserved | Reserved | R | Reserved |
| BA5 | Reserved | Reserved | R | Reserved |
| BA6 | Reserved | Reserved | R | Reserved |
| BA7 | EXTADD | 3-byte or 4-byte addressing selection Bit:<br>"0" indicates 3-byte addressing.<br>"1" indicates 4-byte addressing. | R/W | Non-Volatile and Volatile |

**EXTADD**: Extended Address (EXTADD) controls the address field size for legacy SPI commands. When shipped from factory, it is cleared to “0” for 3 bytes (24 bits) of address. When set to “1”, the legacy commands will require 4 bytes (32 bits) for the address field.

## 6.6 ADVANCED SECTOR/BLOCK PROTECTION (ASP) RELATED REGISTER

### 6.6.1 ADVANCED SECTOR/BLOCK PROTECTION REGISTER (ASPR)

Related Commands: Read ASP (RDASP 2Bh) and Program ASP (PGASP 2Fh).

Advanced Sector/Block Protection (ASP) Register Bit (16 bits) definitions are described in Tables 6.19 and 6.20.

**Table 6.19 Advanced Sector/Block Protection Register (ASPR) Bit Table**

| | 15 | 7 to 14 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|---|---|---|---|
| | TBPARM | Reserved | Reserved | Reserved | Reserved | Reserved | PWDMLB | PSTMLB | Reserved |
| Default | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 |

**Table 6.20 Advanced Sector/Block Protection Register (ASPR) Bit Definition**

| Bit | Name | Definition | Read-/Write | Type |
|---|---|---|---|---|
| 0 | Reserved | Reserved | R | Reserved |
| 1 | PSTMLB | Persistent Protection Mode Lock Bit<br>“0” = Persistent Protection Mode permanently enabled.<br>“1” = Persistent Protection Mode not permanently enabled. | R/W | OTP |
| 2 | PWDMLB | Password Protection Mode Lock Bit<br>“0” = Password Protection Mode permanently enabled.<br>“1” = Password Protection Mode not permanently enabled. | R/W | OTP |
| 14:3 | Reserved | Reserved | R | Reserved |
| 15 | TBPARM | Configures Parameter Sectors location<br>“0” = 4KB physical sectors at top, (high address)<br>“1” = 4KB physical sectors at bottom (Low address) | R/W | OTP |

The Advanced Sector/Block Protection Register (ASPR) is used to permanently configure the behavior of Advanced Sector/Block Protection (ASP) features and parameter sectors location.

**PWDMLB (ASPR[2]) and PSTMLB (ASPR[1]) bits**: When shipped from the factory, all devices default ASP to the Persistent Protection Mode, with all sectors unprotected, when power is applied. The device programmer or host system must then choose which sector/block protection method to use. Programming either of the Protection Mode Lock Bits locks the part permanently in the selected mode:

- ASPR[2:1] = 11 = No ASP mode selected, Persistent Protection Mode is the default.
- ASPR[2:1] = 10 = Persistent Protection Mode permanently selected.
- ASPR[2:1] = 01 = Password Protection Mode permanently selected.
- ASPR[2:1] = 00 = Illegal condition, attempting to program both bits to zero results in a programming failure and the program operation will abort. It will result in a programming error with P_ERR set to 1.

As a result, PWDMLB and PSTMLB are mutually exclusive, only one may be programmed to zero.

ASPR programming rules:

- If the Password Protection Mode is chosen, the password must be programmed prior to setting the corresponding bit.
- Once the Protection Mode is selected, the ASPR[2:1] bits are permanently protected from programming and no further change to the ASPR[2:1] is allowed. Attempting to program ASPR[2:1] after selected will result in a programming error with P_ERR set to 1. The programming time of the ASPR is the same as the typical page programming time. The system can determine the status of the ASPR programming operation by reading the WIP bit in the Status Register or Extended Read Register.
- TBPARM bit can be programmed even after ASPR[2:1] bits are programmed while the FREEZE bit in the PPB Lock Register is “0”.

**TBPARM bit**: TBPARM defines the logical location of the parameter block. The parameter block consists of thirty-two 4KB sectors, which replace two 64KB blocks. When TBPARM is default state (“1”), the parameter block is at the Bottom of the array. When TBPARM is programmed to “0”, the parameter block is in the top of the memory array address space. TBPARM is OTP and default state “1” when it ships from Factory. If TBPARM is programmed to “0”, an attempt to change it back to “1” will fail and ignore the Program.

The desired state of TBPARM must be selected during the initial configuration of the device during system manufacture; before the first program or erase operation on the main flash array. TBPARM must not be programmed after programming or erasing is done in the main flash array.

TBS bit in the Function Register can be programmed independent of TBPARM. Therefore, the user can select to store parameter information from the bottom of the array and protect boot code starting at the top of the array, and vice versa. Or the user can select to store and protect the parameter information starting from the top or bottom together.

### 6.6.2 PASSWORD REGISTER

Related Commands: Read Password (RDPWD E7h), Program Password (PGPWD E8h), and Unlock Password (UNPWD, E9h).

**Table 6.21 Password Register Bit Definition**

| Bit | Name | Definition | Default | Read-/Write | Type |
|---|---|---|---|---|---|
| 63:0 | PSWD | 64 bit hidden password:<br>The password is no longer readable after the password protection mode is selected by programming ASPR bit 2 to zero. | FFFFFFFF-FFFFFFFFh | R/W | OTP |

### 6.6.3 PPB LOCK REGISTER

Related Commands: Read PPB Lock Bit (RDPLB A7h), Write PPB Lock Bit (WRPLB A6h), UNPWD (E9h) and Set FREEZE Bit (SFRZ 91h).

**Table 6.22 PPB Lock Register Bit Definition**

| Bit | Name | Definition | Default | Read-/Write | Type |
|---|---|---|---|---|---|
| 0 | PPBLK | PPB Lock bit: Protect PPB Array<br>“0” = PPB array protected until next power cycle or Hardware Reset<br>“1” = PPB array may be programmed or erased. | Persistent: 1<br>Password: 0 | R/W | Volatile |
| 6:1 | Reserved | Reserved | Reserved | R | Reserved |
| 7 | FREEZE | Lock current state of BP3-0 bits in Status Register, TBS in Function Register and TBPARM in ASPR, and Information Row (IR) regions.<br>“1” = Locked<br>“0” = Un-locked | 0 | R/W | Volatile |

**PPBLK bit**: The PPB Lock bit is a volatile bit for protecting all PPB bits. When cleared to 0, it locks all PPBs, when set to “1”, it allows the PPBs to be changed. The WRPLB command is used to clear the PPB Lock bit to “0”. The PPB Lock bit must be cleared to 0 only after all the PPBs are configured to the desired settings.

In Persistent Protection mode, the PPB Lock bit is set to “1” during POR or Hardware Reset. The PPB Lock bit can only be cleared to “0” by the Write PPB Lock Bit (WRPLB A6h) command only. When cleared to “0”, no software command sequence can set the PPB Lock bit back to “1”, only another Hardware Reset or power-up can set the PPB Lock bit.

In the Password Protection mode, the PPB Lock bit is cleared to 0 during POR or Hardware Reset. The PPB Lock bit can only be set to 1 by the Unlock Password command only. When set to “1”, no software command sequence can clear the PPB Lock bit back to “0”, only another Hardware Reset or power-up can clear the PPB Lock bit.

**FREEZE bit**: FREEZE bit, when set to “1”, locks the current state of BP3-0 in Status Register, TBS in the Function Register, TBPARM in the Advanced Sector/Block Protection Register, and the Information Row. This prevents writing, programming, or erasing these areas. As long as FREEZE remains cleared to logic “0”, BP3-0 in Status Register, TBS in the Function Register, and TBPARM in the Advanced Sector/Block Protection Register are writable and the Information Row is programmable. Once FREEZE has been written to a logic “1” it can only be cleared to a logic “0” by a power-on cycle or a Hardware Reset. Software Reset will not affect the state of FREEZE. The FREEZE is volatile and the default state of FREEZE after power-on is “0”. The FREEZE can be set to “1” by a SFRZ command only.

### 6.6.4 PPB REGISTER

Related Commands: Read PPB (RDPPB FCh or 4RDPPB E2h)), Program PPB (PGPPB FDh or 4PGPPB E3h), and Erase PPB (ERPPB E4h).

**Table 6.23 PPB Register Bit Definition**

| Bit | Name | Definition | Default | Read-/Write | Type |
|---|---|---|---|---|---|
| 7:0 | PPB | Read or Program per sector/block PPB:<br>00h = PPB for the sector/block addressed by the RDPPB or PGPPB command is programmed to “0”, protecting that sector/block from program or erase operations.<br>FFh = PPB for the sector/block addressed by the RDPPB or PGPPB command is erased to “1”, not protecting that sector/block from program or erase operations. | FFh | R/W | Non-Volatile |

### 6.6.5 DYB REGISTER

Related Commands: Read DYB (RDDYB FAh or 4RDDYB E0h) and Write DYB (WRDYB FBh or 4WRDYB E1h).

**Table 6.24 DYB Register Bit Definition**

| Bit | Name | Definition | Default | Read-/Write | Type |
|---|---|---|---|---|---|
| 7:0 | DYB | Read or Write per sector/block DYB:<br>00h = DYB for the sector/block addressed by the RDDYB or WRDYB command is cleared to “0”, protecting that sector/block from program or erase operations.<br>FFh = DYB for the sector/block addressed by the RDDYB or WRDYB command is set to “1”, not protecting that sector/block from program or erase operations. | FFh | R/W | Volatile |

# 7. PROTECTION MODE

The device supports hardware and software write-protection mechanisms.

## 7.1 HARDWARE WRITE PROTECTION

The Write Protection (WP#) pin provides a hardware write protection method for BP3, BP2, BP1, BP0, SRWD, and QE in the Status Register. Refer to the section 6.1 STATUS REGISTER.

Write inhibit voltage ($V_{WI}$) is specified in the section 9.7 POWER-UP AND POWER-DOWN. All write sequence will be ignored when Vcc drops to $V_{WI}$.

**Table 7.1 Hardware Write Protection on Status Register**

| SRWD | WP# | Status Register |
|---|---|---|
| 0 | Low | Writable |
| 1 | Low | Protected |
| 0 | High | Writable |
| 1 | High | Writable |

**Note: Before the execution of any program, erase or Write Status/Function Register instruction, the Write Enable Latch (WEL) bit must be enabled by executing a Write Enable (WREN) instruction. If the WEL bit is not enabled, the program, erase or write register instruction will be ignored.**

## 7.2 SOFTWARE WRITE PROTECTION

The device also provides two kinds of software write protection feature. One is Block Protection by Block Protection bits (BP3, BP2, BP1, BP0) and another is Advanced Sector/Block Protection (ASP). When Block Protection is enabled (i.e., any BP3-0 are set to “1”), Advanced Sector/Block Protection (ASP) can still be used to protect sectors/blocks not protected by the Block Protection scheme. In the case that both ASP and Block Protection are used on the same sector/block the logical OR of ASP and Block Protection related to the sector/block is used.

### 7.2.1 BLOCK PROTECTION BITS

The device provides a software write protection feature. The Block Protection bits (BP3, BP2, BP1, BP0) allow part or the whole memory area to be write-protected. For details, see 6.1 Status Register.

### 7.2.2 ADVANCED SECTOR/BLOCK PROTECTION (ASP)

There are two ways to implement software Advanced Sector/Block Protection on this device: Password Protection method or Persistent Protection methods. Through these two protection methods, user can disable or enable the programming or erasing operation to any or all blocks including 32 top 4K sectors or 32 bottom 4K sectors. The Figure 7.1 shows an overview of these methods.

Every main flash array block/top sector/bottom sector has a non-volatile (PPB) and a volatile (DYB) protection bit associated with it. When either bit is 0, the sector is protected from program and erase operations.

The PPB bits are protected from program and erase when the PPB Lock bit is “0”. The PPB bits are erased so that all main flash array sectors are unprotected when shipped from factory.

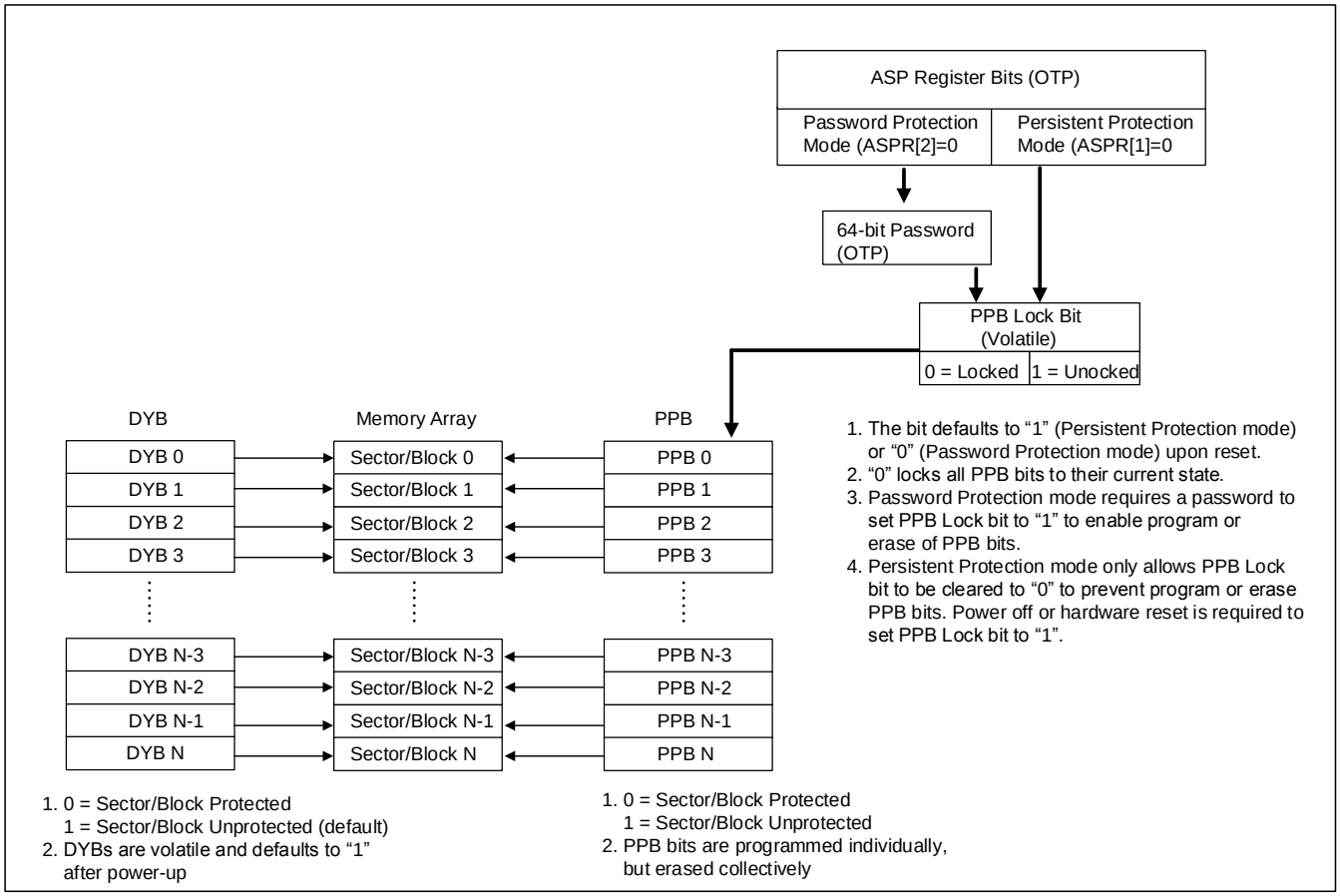
There are two methods for managing the state of the PPB Lock bit, Persistent Protection and Password Protection.

The Persistent Protection Mode sets the PPB Lock bit to “1” during power up or Hardware Reset so that the PPB bits are unprotected. There is a WRPLB command to clear the PPB Lock bit to “0” to protect the PPB bits. There is no command in the Persistent Protection method to set the PPB Lock bit therefore the PPB Lock bit will remain at “0” until the next power up or Hardware Reset. The Persistent Protection method allows boot code the option of changing sector protection by programming or erasing the PPB, then protecting the PPB from further change for the remainder of normal system operation by clearing the PPB Lock bit. This is sometimes called Boot-code controlled sector protection.

The Password Protection Mode requires use of a password to control PPB protection. In the Password Protection Mode, the PPB Lock bit is cleared to “0” during power up or Hardware Reset to protect the PPB bits. A 64-bit password may be permanently programmed and hidden for the Password Protection Mode. The UNPWD command can be used to provide a password for comparison with the hidden password. If the password matches the PPB Lock bit is set to “1” to unprotect the PPB. The WRPLB command can be used to clear the PPB Lock bit to “0”. After clearing the PPB Lock bit to “0”, the UNPWD command can be used again to unprotect the PPB.

The selection of the PPB Lock bit management method is made by programming OTP bits in the ASP Register so as to permanently select the method used.

**Figure 7.1 Advanced Sector/Block Protection**




**Note: 128M: N = 285 = 32 (32xTop 4K sectors or 32xBottom 4K sectors) + 254 (254x64K blocks) - 1**

**Table 7.2 PPB/DYB and Sector/Block mapping (TBPARM = 1)**

| Memory Density | PPB Group | DYB Group | Block No. (64Kbyte) | Sector No. | Sector Size (Kbyte) | Address Range |
|---|---|---|---|---|---|---|
| 128Mb | PPB 0 | DYB 0 | Block 0 | Sector 0 | 4 | 000000h - 000FFFh |
| | : | : | | : | : | : |
| | : | : | | : | : | : |
| | PPB 15 | DYB 15 | | Sector 15 | 4 | 00F000h - 00FFFFh |
| | PPB 16 | DYB 16 | Block 1 | Sector 16 | 4 | 010000h - 010FFFh |
| | : | : | | : | : | : |
| | : | : | | : | : | : |
| | PPB 31 | DYB 31 | | Sector 31 | 4 | 01F000h - 01FFFFh |
| | PPB 32 | DYB 32 | Block 2 | Sector 32 | 4 | 020000h - 020FFFh |
| | | | | : | : | : |
| | | | | : | : | : |
| | | | | Sector 47 | 4 | 02F000h - 02FFFFh |
| | : | : | : | : | : | : |
| | PPB 284 | DYB 284 | Block 254 | Sector 4064 | 4 | FE0000h – FE0FFFh |
| | | | | : | : | : |
| | | | | : | : | : |
| | | | | Sector 4079 | 4 | FEF000h – FEFFFFh |
| | PPB 285 | DYB 285 | Block 255 | Sector 4080 | 4 | FF0000h – FF0FFFh |
| | | | | : | : | : |
| | | | | : | : | : |
| | | | | Sector 4095 | 4 | FFF000h – FFFFFFh |

**Table 7.3 PPB/DYB and Sector/Block mapping (TBPARM = 0)**

| Memory Density | PPB Group | DYB Group | Block No. (64Kbyte) | Sector No. | Sector Size (Kbyte) | Address Range |
|---|---|---|---|---|---|---|
| **128Mb** | PPB 0 | DYB 0 | Block 0 | Sector 0 | 4 | 000000h - 000FFFh |
| | | | | : | : | : |
| | | | | : | : | : |
| | | | | Sector 15 | 4 | 00F000h - 00FFFFh |
| | PPB 1 | DYB 1 | Block 1 | Sector 16 | 4 | 010000h - 010FFFh |
| | | | | : | : | : |
| | | | | : | : | : |
| | | | | Sector 31 | 4 | 01F000h - 01FFFFh |
| | PPB 2 | DYB 2 | Block 2 | Sector 32 | 4 | 020000h - 020FFFh |
| | | | | : | : | : |
| | | | | : | : | : |
| | | | | Sector 47 | 4 | 02F000h - 02FFFFh |
| | : | : | : | : | : | : |
| | PPB 126 | DYB 126 | Block 126 | Sector 2016 | 4 | 7E0000h – 7E0FFFh |
| | | | | : | : | : |
| | | | | : | : | : |
| | | | | Sector 2031 | 4 | 7EF000h – 7EFFFFh |
| | PPB 127 | DYB 127 | Block 127 | Sector 2032 | 4 | 7F0000h – 7F0FFFh |
| | | | | : | : | : |
| | | | | : | : | : |
| | | | | Sector 2047 | 4 | 7FF000h – 7FFFFFh |
| | : | : | : | : | : | : |
| | PPB 254 | DYB 254 | Block 254 | Sector 4064 | 4 | FE0000h – FE0FFFh |
| | : | : | | : | : | : |
| | : | : | | : | : | : |
| | PPB 269 | DYB 269 | | Sector 4079 | 4 | FEF000h – FEFFFFh |
| | PPB 270 | DYB 270 | Block 255 | Sector 4080 | 4 | FF0000h – FF0FFFh |
| | : | : | | : | : | : |
| | : | : | | : | : | : |
| | PPB 285 | DYB 285 | | Sector 4095 | 4 | FFF000h – FFFFFFh |

## Persistent Protection Bits (PPBs)

The Persistent Protection Bits (PPBs) are unique for each sector/block and non-volatile (refer to Figure 7.1, Table 7.2, and Table 7.3). It is programmed individually but must be erased as a group, similar to the way individual words may be programmed in the main array but an entire sector/block must be erased at the same time. The PPBs have the same endurances as the Flash memory. Preprogramming and verification prior to erasure are handled by the device, and therefore do not require system monitoring. Programming a PPB bit requires the typical page programming time. Erasing all the PPBs requires typical sector erase time. During PPB bit programming and PPB bit erasing, status is available by reading the Status Register or Extended Read Register. Reading of a PPB bit requires the initial access time of the device.

**Notes:**
1. Each PPB is individually programmed to “0” and all are erased to “1” in parallel.
2. The PPB Lock bit must be cleared first before changing the status of a PPB.
3. While programming PPB, array data cannot be read from any sectors/blocks.
4. When reading the PPB of the desired sector/block the address should be location zero within the sector/block. The high order address bits not used must be zero.
5. There are no means for individually erasing a specific PPB and no specific sector/block address is required for this operation.
6. The state of the PPB for a given sector/block can be verified by using a PPB Read command.
7. When the parts are first shipped, the PPBs are cleared (erased to “1”).

## Dynamic Protection Bits (DYBs)

Dynamic Protection Bits (DYBs) are volatile and unique for each sector/block and can be individually modified. DYBs only control the protection for unprotected sectors/blocks that have their PPBs cleared (erased to “1”). By issuing the Write DYB command, the DYBs are cleared to “0” or set to “1”, thus placing each sector/block in the protected or unprotected state respectively. This feature allows software to easily protect sectors/blocks against inadvertent changes, yet does not prevent the easy removal of protection when changes are needed. The DYBs can be set or cleared as often as needed as they are volatile bits.

## Persistent Protection Bit (PPB) Lock Bit

The PPB Lock bit is a volatile bit for protecting all PPB bits. When cleared to “0”, it locks all PPBs and when set to “1”, it allows the PPBs to be changed. . If the PPB Lock bit is “0”, the PPB Program or Erase command does not execute and fails without programming or erasing the PPB.

In Persistent Protection mode, the PPB Lock bit is set to “1” during power up or Hardware Reset. When cleared to “0”, no software command sequence can set the PPB Lock bit to “1”, only another Hardware Reset or power-up can set the PPB Lock bit.

In the Password Protection mode, the PPB Lock bit is cleared to “0” during power up or a Hardware Reset during power up or a Hardware Reset during power up or a Hardware Reset. The PPB Lock bit can only be set to “1” by the Password Unlock command.

The PPB Lock bit must be cleared to “0” only after all PPBs are configured to the desired settings.

**Sector/Block Protection States Summary**

Each sector in specific blocks and each of all other blocks except for the specific blocks can be in one of the following protection states:

- Unlocked – The sector/block is unprotected and protection can be changed by a simple command. The protection state defaults to unprotected after a power cycle, software reset, or hardware reset.
- Dynamically Locked – A sector/block is protected and protection can be changed by a simple command. The protection state is not saved across a power cycle.
- Persistently Locked – A sector/block is protected and protection can only be changed if the PPB Lock bit is set to "1". The protection state is non-volatile and saved across a power cycle or reset. Changing the protection state requires programming and or erase of the PPB bits**.**

Table 7.4 contains all possible combinations of the DYB, PPB, and PPB Lock bit relating to the status of the sector/block. In summary, if the PPB Lock bit is locked (cleared to "0"), no changes to the PPBs are allowed. The PPB Lock bit can only be unlocked (set to "1") through a Hardware Reset or power cycle.

**Table 7.4 Sector/Block Protection States**

| | | Protection Bit values | | Assigned Sector/Block State |
|---|---|---|---|---|
| | | **PPB** | **DYB** | |
| "0" = Locked or Protected<br>"1" = Unlocked or Unprotected | | 1 | 1 | Unprotected |
| | | 1 | 0 | Protected |
| | | 0 | 1 | Protected |
| | | 0 | 0 | Protected |
| **PPB Lock Bit** | 1 | Changeable | Changeable | |
| | 0 | NOT changeable | Changeable | |

## Persistent Protection Mode

The Persistent Protection Mode sets the PPB Lock bit to "1" during power up or Hardware Reset so that the PPB bits are unprotected by a device Hardware Reset. Software Reset does not affect the PPB Lock bit. The WRPLB command can clear the PPB Lock bit to "0" to protect the PPB. There is no command to set the PPB Lock bit therefore the PPB Lock bit will remain at "0" until the next power up or Hardware Reset.

## Password Protection Mode

The Password Protection Mode allows an even higher level of security than the Persistent Protection Mode by requiring a 64-bit password for unlocking the device PPB Lock bit. In addition to this password requirement, after power up or Hardware Reset, the PPB Lock bit is cleared to "0" to maintain the password mode of operation. Successful execution of the Unlock Password command by entering the entire password sets the PPB Lock bit to "1", allowing for sector/block PPBs modifications.

**Notes:**

1. The password is all "1"s when shipped from Factory. It is located in its own memory space and is accessible through the use of the Program Password and Read Password commands.
2. Once the Password is programmed and verified, the Password Protection Mode Lock Bit (ASPR[2]=0) in ASP Register must be programmed in order to prevent reading or modifying the password. After the Password Protection Mode Lock Bit is programmed, all further Program and Read commands to the password region are disabled and these commands are ignored so that there is no means to verify what the password is. Password verification is only allowed before selecting the Password Protection Mode.
3. The Program Password Command is only capable of programming "0"s. Programming a "1" after a cell is programmed as a "0" results in the cell left as a "0" with no programming error.
4. All 64-bit password combinations are valid as a password.
5. The Protection Mode Lock Bits in ASP Register are not erasable because they are OTP.
6. The exact password must be entered in order for the unlocking function to occur. If the password provided by Unlock Password command does not match the hidden internal password, the unlock operation fails in the same manner as a programming operation on a protected sector/block. The P_ERR and PROT_E are set to 1 and the PPB Lock bit remains cleared to 0. In this case it is a failure to change the state of the PPB Lock bit because it is still protected by the lack of a valid password.
7. The Unlock Password command cannot be accepted any faster than once every 100µs ± 20µs. This makes it take an unreasonably long time (58 million years) for a hacker to run through all the 64-bit combinations in an attempt to correctly match a password. The Read Status Register command or the Read Extended Read Register may be used to read the WIP bit to determine when the device has completed the Unlock Password command or is ready to accept a new password command. When a valid password is provided the Unlock Password command does not insert the 100µs delay before returning the WIP bit to zero.
8. If the password is lost after selecting the Password Protection Mode, there is no way to set the PPB Lock bit.

# 8. DEVICE OPERATION

## 8.1 COMMAND OVERVIEW

The device utilizes an 8-bit instruction register. Refer to Table 8.3. Instruction Set for details on instructions and instruction codes. All instructions, addresses, and data are shifted in with the most significant bit (MSB) first on Serial Data Input (SI) or Serial Data IOs (IO0, IO1, IO2, IO3). The input data on SI or IOs is latched on the rising edge of Serial Clock (SCK) for normal mode and both of rising and falling edges for DTR mode after Chip Enable (CE#) is driven low ($V_{IL}$). Every instruction sequence starts with a one-byte instruction code and is followed by address bytes and/or dummy cycles (configurable) and/or data bytes, depending on the type of instruction. CE# must be driven high ($V_{IH}$) after the last bit of the instruction sequence has been shifted in to end the operation.

Commands are structured as follows:

- Each command begins with a byte (eight bits) instruction.
- The instruction may be stand alone or may be followed by address bits to select a location within one of several address spaces in the device. The address may be either a 24-bit or 32-bit byte boundary address.
- The SPI interface with Multiple IO provides the option for each transfer of address and data information to be done one, two, or four bits in parallel. This enables a tradeoff between the number of signal connections (IO bus width) and the speed of information transfer. If the host system can support a two or four bit wide IO bus the memory performance can be increased by using the instructions that provide parallel two bit (dual) or parallel four bit (quad) transfers.
- The width of all transfers following the instruction are determined by the instruction sent.
- All single bit or parallel bit groups are transferred in most to least significant bit order.
- Some instructions send Mode Bits following the address to indicate that the next command will be of the same type with an implied, rather than an explicit, instruction. The next command thus does not provide an instruction byte, only a new address and mode bits. This reduces the time needed to send each command when the same command type is repeated in a sequence of commands.
- The address or Mode Bits may be followed by Dummy Cycles before read data is returned to the host.
- Dummy Cycles may be zero to several SCK cycles. In fact, Mode Bits will be counted as a part of Dummy Cycles.
- All instruction, address, Mode, and data information is transferred in byte granularity. Addresses are shifted into the device with the Most Significant Byte first. All data is transferred with the lowest address byte sent first. Following bytes of data are sent in lowest to highest byte address order i.e. the byte address increments.
- All attempts to read the flash memory array during a program, erase, or a write cycle (embedded operations) are ignored. The embedded operation will continue to execute without any affect. A very limited set of commands are accepted during an embedded operation. These are discussed in the individual command descriptions. While a program, erase, or write operation is in progress, it is recommended to check that the Write In Progress (WIP) bit is “0” before issuing most commands to the device, to ensure the new command can be accepted.
- Depending on the command, the time for execution varies. A command to read status information from an executing command is available to determine when the command completes execution and whether the command was successful.
- Following are some general signal relationship descriptions to keep in mind.
  - The host always controls the Chip Enable (CE#), Serial Clock (SCK), and Serial Input (SI) - SI for single bit wide transfers. The memory drives Serial Output (SO) for single bit read transfers. The host and memory alternately drive the IO0-IO3 signals during Dual and Quad transfers.
  - All commands begin with the host selecting the memory by driving CE# low before the first rising edge of SCK. CE# is kept low throughout a command and when CE# is returned high the command ends.

  Generally, CE# remains low for 8-bit transfer multiples to transfer byte granularity information. All commands will not be accepted if CE# is returned high not at an 8-bit boundary.

## 8.2 COMMAND SET SUMMARY

### Extended Addressing

To accommodate addressing above 128Mb (24-bit), there are three options:

1. New instructions with 4-byte (32-bit) address. See Table 8.1.
2. 4-byte addressing with the 3-byte address instructions:
   For backward compatibility to the 3-byte address instructions, the standard instructions can be used in conjunction with the EXTADD Bit in the Bank Address Register (BAR [7]) or Enter 4-byte Address Mode to switch from 3 bytes to 4 bytes of address field. When EXTADD bit is set to 1 or Enter 4-byte Address Mode command is issued, the instructions are changed to require 4-byte (32-bit) for the address field. See Table 8.2.
3. 3-byte addressing with the 3-byte address instructions:
   For backward compatibility to the 3-byte addressing, the standard instructions can be used in conjunction with the Bank Address Register. When EXTADD bit is set to 0 or Exit 4-byte Address Mode command is issued after 4-byte Address Mode operation, the instructions are changed to require 3-byte (24-bit) for the address field See Table 8.2.

**Table 8.1 New Instruction Set with 4-byte address**

| Instruction Name | Operation | Code | Address Mode |
|---|---|---|---|
| 4NORD | 4-byte Address Normal Read Mode | 13h | 4-byte Address |
| 4FRD | 4-byte Address Fast Read Mode | 0Ch | 4-byte Address |
| 4FRDIO | 4-byte Address Fast Read Dual I/O | BCh | 4-byte Address |
| 4FRDO | 4-byte Address Fast Read Dual Output | 3Ch | 4-byte Address |
| 4FRQIO | 4-byte Address Fast Read Quad I/O | ECh | 4-byte Address |
| 4FRQO | 4-byte Address Fast Read Quad Output | 6Ch | 4-byte Address |
| 4FRDTR | 4-byte Address Fast Read DTR Mode | 0Eh | 4-byte Address |
| 4FRDDTR | 4-byte Address Fast Read Dual I/O DTR | BEh | 4-byte Address |
| 4FRQDTR | 4-byte Address Fast Read Quad I/O DTR | EEh | 4-byte Address |
| 4PP | 4-byte Address Serial Input Page Program | 12h | 4-byte Address |
| 4PPQ | 4-byte Address Quad Input Page Program | 34h/3Eh | 4-byte Address |
| 4SER | 4-byte Address Sector Erase | 21h | 4-byte Address |
| 4BER32 (32KB) | 4-byte Address Block Erase 32KB | 5Ch | 4-byte Address |
| 4BER64 (64KB) | 4-byte Address Block Erase 64KB | DCh | 4-byte Address |
| 4SECUNLOCK | 4-byte Address Sector Unlock | 25h | 4-byte Address |
| 4RDDYB | 4-byte Address Read DYB | E0 | 4-byte Address |
| 4WRDYB | 4-byte Address Write DYB | E1 | 4-byte Address |
| 4RDPPB | 4-byte Address Read PPB | E2 | 4-byte Address |
| 4PGPPB | 4-byte Address Program PPB | E3 | 4-byte Address |

**Table 8.2 Instruction Set with 3-byte or 4-byte address according to EXTADD Bit setting**

| Instruction Name | Operation | Code | Address Mode | |
|---|---|---|---|---|
| | | | EXTADD (BAR[7] = 1 | EXTADD (BAR[7]) = 0 |
| NORD | Normal Read Mode | 03h | 4-byte Address | 3-byte Address |
| FRD | Fast Read Mode | 0Bh | 4-byte Address | 3-byte Address |
| FRDIO | Fast Read Dual I/O | BBh | 4-byte Address | 3-byte Address |
| FRDO | Fast Read Dual Output | 3Bh | 4-byte Address | 3-byte Address |
| FRQIO | Fast Read Quad I/O | EBh | 4-byte Address | 3-byte Address |
| FRQO | Fast Read Quad Output | 6Bh | 4-byte Address | 3-byte Address |
| FRDTR | Fast Read DTR Mode | 0Dh | 4-byte Address | 3-byte Address |
| FRDDTR | Fast Read Dual I/O DTR | BDh | 4-byte Address | 3-byte Address |
| FRQDTR | Fast Read Quad I/O DTR | EDh | 4-byte Address | 3-byte Address |
| PP | Serial Input Page Program | 02h | 4-byte Address | 3-byte Address |
| PPQ | Quad Input Page Program | 32h/38h | 4-byte Address | 3-byte Address |
| SER | Sector Erase | D7h/20h | 4-byte Address | 3-byte Address |
| BER32 (32KB) | Block Erase 32KB | 52h | 4-byte Address | 3-byte Address |
| BER64 (64KB) | Block Erase 64KB | D8h | 4-byte Address | 3-byte Address |
| SECUNLOCK | Sector Unlock | 26h | 4-byte Address | 3-byte Address |
| RDDYB | Read DYB | FA | 4-byte Address | 3-byte Address |
| WRDYB | Write DYB | FB | 4-byte Address | 3-byte Address |
| RDPPB | Read PPB | FC | 4-byte Address | 3-byte Address |
| PGPPB | Program PPB | FD | 4-byte Address | 3-byte Address |

**Table 8.3 All Instruction Set**

| Instruction Name | Operation | Mode | Byte0 | Byte1 | Byte2 | Byte3 | Byte4 | Byte5 | Byte6 |
|---|---|---|---|---|---|---|---|---|---|
| NORD | Normal Read Mode (3-byte Address) | SPI | 03h | A <23:16> | A <15:8> | A <7:0> | Data out | | |
| NORD | Normal Read Mode (4-byte Address) | SPI | 03h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Data out | |
| 4NORD | 4-byte Address Normal Read Mode | SPI | 13h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Data out | |
| FRD | Fast Read Mode (3-byte Address) | SPI QPI | 0Bh | A <23:16> | A <15:8> | A <7:0> | Dummy(1) Byte | Data out | |
| FRD | Fast Read Mode (4-byte Address) | SPI QPI | 0Bh | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Dummy(1) Byte | Data out |
| 4FRD | 4-byte Address Fast Read Mode | SPI QPI | 0Ch | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Dummy(1) Byte | Data out |
| FRDIO | Fast Read Dual I/O (3-byte Address) | SPI | BBh | A <23:16> Dual | A <15:8> Dual | A <7:0> Dual | AXh(1),(2) Dual | Dual Data out | |
| FRDIO | Fast Read Dual I/O (4-byte Address) | SPI | BBh | A <31::24> | A <23:16> Dual | A <15:8> Dual | A <7:0> Dual | AXh(1),(2) Dual | Dual Data out |
| 4FRDIO | 4-byte Address Fast Read Dual I/O | SPI | BCh | A <31::24> | A <23:16> Dual | A <15:8> Dual | A <7:0> Dual | AXh(1),(2) Dual | Dual Data out |
| FRDO | Fast Read Dual Output (3-byte Address) | SPI | 3Bh | A <23:16> | A <15:8> | A <7:0> | Dummy(1) Byte | Dual Data out | |
| FRDO | Fast Read Dual Output (4-byte Address) | SPI | 3Bh | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Dummy(1) Byte | Dual Data out |
| 4FRDO | 4-byte Address Fast Read Dual Output | SPI | 3Ch | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Dummy(1) Byte | Dual Data out |
| FRQIO | Fast Read Quad I/O (3-byte Address) | SPI QPI | EBh | A <23:16> Quad | A <15:8> Quad | A <7:0> Quad | AXh(1), (2) Quad | Quad Data out | |
| FRQIO | Fast Read Quad I/O (4-byte Address) | SPI QPI | EBh | A <31::24> Quad | A <23:16> Quad | A <15:8> Quad | A <7:0> Quad | AXh(1), (2) Quad | Quad Data out |
| 4FRQIO | 4-byte Address Fast Read Quad I/O | SPI QPI | ECh | A <31::24> Quad | A <23:16> Quad | A <15:8> Quad | A <7:0> Quad | AXh(1), (2) Quad | Quad Data out |
| FRQO | Fast Read Quad Output (3-byte Address) | SPI | 6Bh | A <23:16> | A <15:8> | A <7:0> | Dummy(1) Byte | Quad Data out | |
| FRQO | Fast Read Quad Output (4-byte Address) | SPI | 6Bh | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Dummy(1) Byte | Quad Data out |
| 4FRQO | 4-byte Address Fast Read Quad Output | SPI | 6Ch | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Dummy(1) Byte | Quad Data out |

| Instruction Name | Operation | Mode | Byte0 | Byte1 | Byte2 | Byte3 | Byte4 | Byte5 | Byte6 |
|---|---|---|---|---|---|---|---|---|---|
| FRDTR | Fast Read DTR Mode (3-byte Address) | SPI QPI | 0Dh | A <23:16> | A <15:8> | A <7:0> | Dummy(1) Byte | Dual Data out | |
| FRDTR | Fast Read DTR Mode (4-byte Address) | SPI QPI | 0Dh | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Dummy(1) Byte | Dual Data out |
| 4FRDTR | 4-byte Address Fast Read DTR Mode | SPI QPI | 0Eh | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Dummy(1) Byte | Dual Data out |
| FRDDTR | Fast Read Dual I/O DTR (3-byte Address) | SPI | BDh | A <23:16> Dual | A <15:8> Dual | A <7:0> Dual | AXh(1), (2) Dual | Dual Data out | |
| FRDDTR | Fast Read Dual I/O DTR (4-byte Address) | SPI | BDh | A <31::24> | A <23:16> Dual | A <15:8> Dual | A <7:0> Dual | AXh(1), (2) Dual | Dual Data out |
| 4FRDDTR | 4-byte Address Fast Read Dual I/O DTR | SPI | BEh | A <31::24> | A <23:16> Dual | A <15:8> Dual | A <7:0> Dual | AXh(1), (2) Dual | Dual Data out |
| FRQDTR | Fast Read Quad I/O DTR (3-byte Address) | SPI QPI | EDh | A <23:16> | A <15:8> | A <7:0> | AXh(1), (2) Quad | Quad Data out | |
| FRQDTR | Fast Read Quad I/O DTR (4-byte Address) | SPI QPI | EDh | A <31::24> | A <23:16> | A <15:8> | A <7:0> | AXh(1), (2) Quad | Quad Data out |
| 4FRQDTR | 4-byte Address Fast Read Quad I/O DTR | SPI QPI | EEh | A <31::24> | A <23:16> | A <15:8> | A <7:0> | AXh(1), (2) Quad | Quad Data out |
| PP | Input Page Program (3-byte Address) | SPI QPI | 02h | A <23:16> | A <15:8> | A <7:0> | PD (256byte) | | |
| PP | Input Page Program (4-byte Address) | SPI QPI | 02h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | PD (256byte) | |
| 4PP | 4-byte Address Input Page Program | SPI QPI | 12h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | PD (256byte) | |
| PPQ | Quad Input Page Program (3-byte Address) | SPI | 32h/38h | A <23:16> | A <15:8> | A <7:0> | Quad PD (256byte) | | |
| PPQ | Quad Input Page Program (4-byte Address) | SPI | 32h/38h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Quad PD (256byte) | |
| 4PPQ | 4-byte Address Quad Input Page Program | SPI | 34h/3Eh | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Quad PD (256byte) | |
| SER | Sector Erase (3-byte Address) | SPI QPI | D7h/20h | A <23:16> | A <15:8> | A <7:0> | | | |
| SER | Sector Erase (4-byte Address) | SPI QPI | D7h/20h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | | |
| 4SER | 4-byte Address Sector Erase | SPI QPI | 21h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | | |

| Instruction Name | Operation | Mode | Byte0 | Byte1 | Byte2 | Byte3 | Byte4 | Byte5 | Byte6 |
|---|---|---|---|---|---|---|---|---|---|
| BER32 (32KB) | Block Erase 32Kbyte (3-byte Address) | SPI QPI | 52h | A <23:16> | A <15:8> | A <7:0> | | | |
| BER32 (32KB) | Block Erase 32Kbyte (4-byte Address) | SPI QPI | 52h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | | |
| 4BER32 (32KB) | 4-byte Address Block Erase 32Kbyte | SPI QPI | 5Ch | A <31::24> | A <23:16> | A <15:8> | A <7:0> | | |
| BER64 (64KB) | Block Erase 64Kbyte (3-byte Address) | SPI QPI | D8h | A <23:16> | A <15:8> | A <7:0> | | | |
| BER64 (64KB) | Block Erase 64Kbyte (4-byte Address) | SPI QPI | D8h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | | |
| 4BER64 (64KB) | 4-byte Address Block Erase 64Kbyte | SPI QPI | DCh | A <31::24> | A <23:16> | A <15:8> | A <7:0> | | |
| CER | Chip Erase | SPI QPI | C7h/60h | | | | | | |
| WREN | Write Enable | SPI QPI | 06h | | | | | | |
| WRDI | Write Disable | SPI QPI | 04h | | | | | | |
| RDSR | Read Status Register | SPI QPI | 05h | Data out | | | | | |
| WRSR | Write Status Register | SPI QPI | 01h | Data in | | | | | |
| RDFR | Read Function Register | SPI QPI | 48h | Data out | | | | | |
| WRFR | Write Function Register | SPI QPI | 42h | Data in | | | | | |
| QPIEN | Enter QPI mode | SPI | 35h | | | | | | |
| QPIDI | Exit QPI mode | QPI | F5h | | | | | | |
| PERSUS | Suspend during program/erase | SPI QPI | 75h/B0h | | | | | | |
| PERRSM | Resume program/erase | SPI QPI | 7Ah/30h | | | | | | |
| DP | Deep Power Down | SPI QPI | B9h | | | | | | |
| RDID, RDPD | Read ID / Release Power Down | SPI QPI | ABh | XXh(3) | XXh(3) | XXh(3) | ID7-ID0 | | |
| SRPNV | Set Read Parameters (Non-Volatile) | SPI QPI | 65h | Data in | | | | | |
| SRPV | Set Read Parameters (Volatile) | SPI QPI | C0h/63h | Data in | | | | | |
| SERPNV | Set Extended Read Parameters (Non-Volatile) | SPI QPI | 85h | Data in | | | | | |

| Instruction Name | Operation | Mode | Byte0 | Byte1 | Byte2 | Byte3 | Byte4 | Byte5 | Byte6 |
|---|---|---|---|---|---|---|---|---|---|
| SERPV | Set Extended Read Parameters (Volatile) | SPI QPI | 83h | Data in | | | | | |
| RDRP | Read Read Parameters (Volatile) | SPI QPI | 61h | Data out | | | | | |
| RDERP | Read Extended Read Parameters (Volatile) | SPI QPI | 81h | Data out | | | | | |
| CLERP | Clear Extended Read Register | SPI QPI | 82h | | | | | | |
| RDJDID | Read JEDEC ID Command | SPI | 9Fh | MF7-MF0 | ID15-ID8 | ID7-ID0 | | | |
| RDMDID | Read Manufacturer & Device ID | SPI QPI | 90h | XXh(3) | XXh(3) | 00h | MF7-MF0 | ID7-ID0 | |
| | | | | | | 01h | ID7-ID0 | MF7-MF0 | |
| RDJDIDQ | Read JEDEC ID QPI mode | QPI | AFh | MF7-MF0 | ID15-ID8 | ID7-ID0 | | | |
| RDUID | Read Unique ID | SPI QPI | 4Bh | A(4) <23:16> | A(4) <15:8> | A(4) <7:0> | Dummy Byte | Data out | |
| RDSFDP | SFDP Read | SPI | 5Ah | A <23:16> | A <15:8> | A <7:0> | Dummy Byte | Data out | |
| NOP | No Operation | SPI QPI | 00h | | | | | | |
| RSTEN | Software Reset Enable | SPI QPI | 66h | | | | | | |
| RST | Software Reset | SPI QPI | 99h | | | | | | |
| IRER | Erase Information Row | SPI QPI | 64h | A <23:16> | A <15:8> | A <7:0> | | | |
| IRP | Program Information Row | SPI QPI | 62h | A <23:16> | A <15:8> | A <7:0> | PD (256byte) | | |
| IRRD | Read Information Row | SPI QPI | 68h | A <23:16> | A <15:8> | A <7:0> | Dummy Byte | Data out | |
| SECUNLOCK | Sector Unlock (3-byte Address) | SPI QPI | 26h | A <23:16> | A <15:8> | A <7:0> | | | |
| SECUNLOCK | Sector Unlock (4-byte Address) | SPI QPI | 26h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | | |
| 4SECUNLOCK | 4-byte Address Sector Unlock | SPI QPI | 25h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | | |
| SECLOCK | Sector Lock | SPI QPI | 24h | | | | | | |
| RDABR | Read AutoBoot Register | SPI | 14h | Data out 1 | Data out 2 | Data out 3 | Data out 4 | | |
| WRABR | Write AutoBoot Register | SPI QPI | 15h | Data in 1 | Data in 2 | Data in 3 | Data in 4 | | |

| Instruction Name | Operation | Mode | Byte0 | Byte1 | Byte2 | Byte3 | Byte4 | Byte5 | Byte6 |
|---|---|---|---|---|---|---|---|---|---|
| RDBR | Read Bank Address Register (Volatile) | SPI QPI | 16h/C8h | Data out | | | | | |
| WRBRV | Write Bank Address Register (Volatile) | SPI QPI | 17h/C5h | Data in | | | | | |
| WRBRNV | Write Bank Address Register (Non-Volatile) | SPI QPI | 18h | Data in | | | | | |
| EN4B | Enter 4-byte Address Mode | SPI QPI | B7h | | | | | | |
| EX4B | Exit 4-byte Address Mode | SPI QPI | 29h | | | | | | |
| RDDYB | Read DYB (3-byte Address) | SPI QPI | FAh | A <23:16> | A <15:8> | A <7:0> | Data out | | |
| RDDYB | Read DYB (4-byte Address) | SPI QPI | FAh | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Data out | |
| 4RDDYB | 4-byte Address Read DYB | SPI QPI | E0h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Data out | |
| WRDYB | Write DYB (3-byte Address) | SPI QPI | FBh | A <23:16> | A <15:8> | A <7:0> | Data in | | |
| WRDYB | Write DYB (4-byte Address) | SPI QPI | FBh | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Data in | |
| 4WRDYB | 4-byte Address Write DYB | SPI QPI | E1h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Data in | |
| RDPPB | Read PPB (3-byte Address) | SPI | FCh | A <23:16> | A <15:8> | A <7:0> | Data out | | |
| RDPPB | Read PPB (4-byte Address) | SPI | FCh | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Data out | |
| 4RDPPB | 4-byte Address Read PPB | SPI | E2h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | Data out | |
| PGPPB | Program PPB (Individually) (3-byte Address) | SPI QPI | FDh | A <23:16> | A <15:8> | A <7:0> | | | |
| PGPPB | Program PPB (Individually) (4-byte Address) | SPI QPI | FDh | A <31::24> | A <23:16> | A <15:8> | A <7:0> | | |
| 4PGPPB | 4-byte Address Program PPB (Individually) | SPI QPI | E3h | A <31::24> | A <23:16> | A <15:8> | A <7:0> | | |
| ERPPB | Erase PPB (as a group) | SPI QPI | E4h | | | | | | |
| RDASP | Read ASP | SPI QPI | 2Bh | Data out (2 byte) | | | | | |
| PGASP | Program ASP | SPI QPI | 2Fh | PD (2 byte) | | | | | |
| RDPLB | Read PPB Lock Bit | SPI | A7h | Data out | | | | | |
| WRPLB | Write PPB Lock Bit | SPI QPI | A6h | | | | | | |
| SFRZ | Set FREEZE bit | SPI QPI | 91h | | | | | | |

| Instruction Name | Operation | Mode | Byte0 | Byte1 | Byte2 | Byte3 | Byte4 | Byte5 | Byte6 |
|---|---|---|---|---|---|---|---|---|---|
| RDPWD | Read Password | SPI | E7h | Data out (8 byte) | | | | | |
| PGPWD | Program Password | SPI QPI | E8h | PD (8 byte) | | | | | |
| UNPWD | Unlock Password | SPI QPI | E9h | Data in (8 byte) | | | | | |
| GBLK | Set all DYB bits (Gang Sector/ Block Lock) | SPI QPI | 7Eh | | | | | | |
| GBUN | Clear all DYB bits (Gang Sector/ Block Unlock) | SPI QPI | 98h | | | | | | |

**Notes:**
1. **The number of dummy cycles depends on the value setting in the Table 6.11 Read Dummy Cycles.**
2. **AXh has to be counted as a part of dummy cycles. X means "don't care".**
3. **XX means "don't care".**
4. **A<23:9> are "don't care" and A<8:4> are always "0".**

### 8.3 NORMAL READ OPERATION (NORD, 03h or 4NORD, 13h)

The Normal Read (NORD) instruction is used to read memory contents at a maximum frequency of 80MHz.

- 03h (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- 03h (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- 13h is followed by a 4-byte address (A31-A0)

The Normal Read instruction code is transmitted via the SI line, followed by three (A23 - A0) or four (A31 – A0) address bytes of the first memory location to be read as above. A total of 24 or 32 address bits are shifted in, but only $A_{VMSB}$ (Valid Most Significant Bit) - $A_0$ are decoded. The remaining bits (A31 – $A_{VMSB+1}$) are ignored. The first byte addressed can be at any memory location. Upon completion, any data on the SI will be ignored. Refer to Table 8.4 for the related Address Key.

The first byte data (D7 - D0) is shifted out on the SO line, MSB first. A single byte of data, or up to the whole memory array, can be read out in one Normal Read instruction. The address is automatically incremented by one after each byte of data is shifted out. The read operation can be terminated at any time by driving CE# high (VIH) after the data comes out. When the highest address of the device is reached, the address counter will roll over to the 000000h address, allowing the entire memory to be read in one continuous Read instruction.

If the Normal Read instruction is issued while an Erase, Program or Write operation is in process (WIP=1) the instruction is ignored and will not have any effects on the current operation.

**Table 8.4 Address Key**

| Mode | **Valid Address** | **128Mb** |
|---|---|---|
| 3 byte address | $A_{VMSB}$(2)–$A_0$ | A23-A0 |
| 4 byte address | | A23-A0 (A31-A24=X)(2) |

**Notes:**

1. **X=Don't Care**
2. **$A_{VMSB}$ is a Valid MSB. In 4 byte address for 128Mb, A31 is an MSB, and A23 is a Valid MSB.**

**Figure 8.1 Normal Read Sequence (03h [EXTADD=0], 3-byte address)**

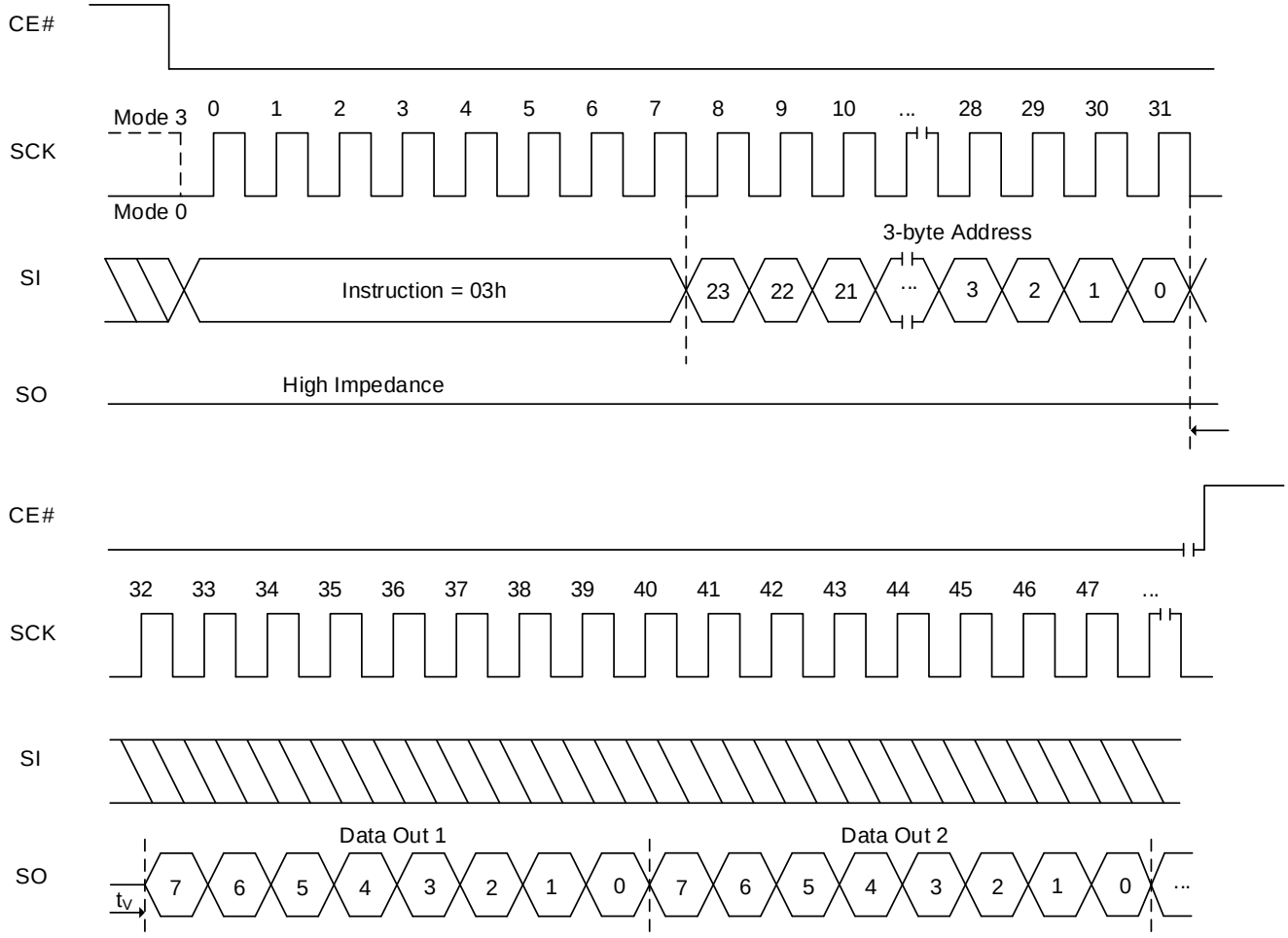
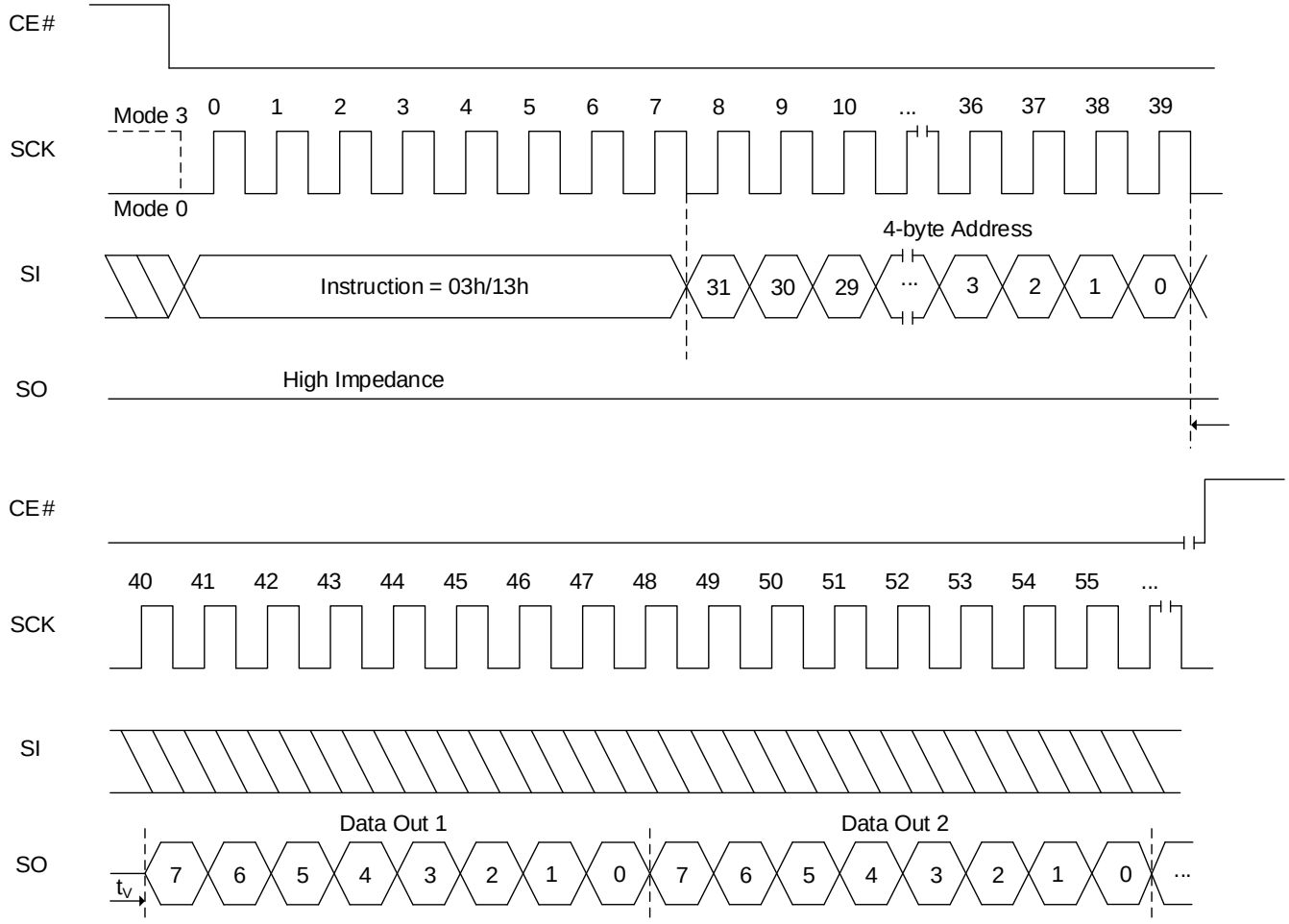


**Figure 8.2 Normal Read Sequence (03h [EXTADD=1] or 13h, 4-byte address)**



### 8.4 FAST READ OPERATION (FRD, 0Bh or 4FRD, 0Ch)

The Fast Read (FRD, 4FRD) instruction is used to read memory data at up to a 166MHz clock.

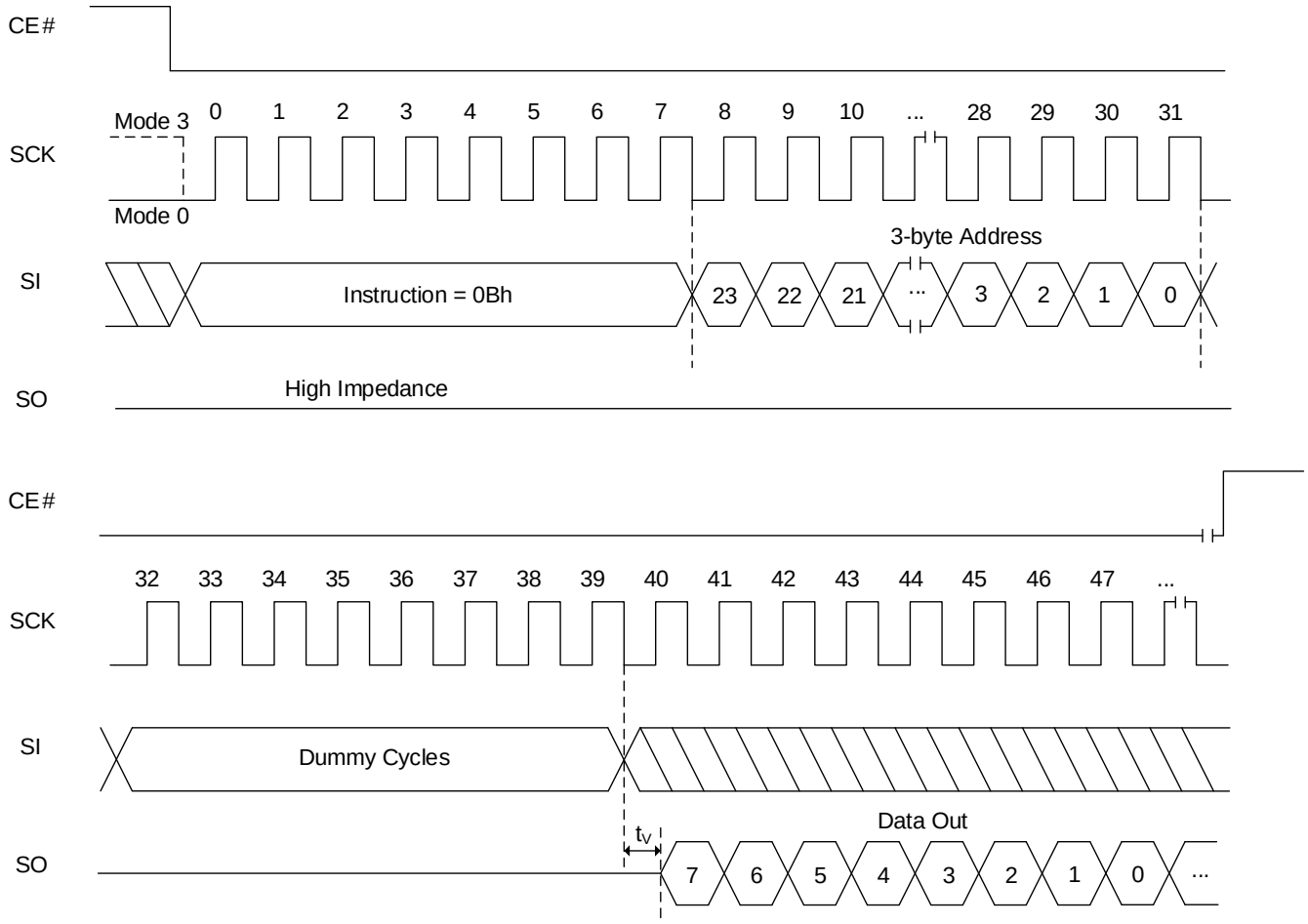
- 0Bh (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- 0Bh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- 0Ch is followed by a 4-byte address (A31-A0)

The Fast Read instruction code is followed by three or four address bytes as above and dummy cycles (configurable, default is 8 clocks), transmitted via the SI line, with each bit latched-in during the rising edge of SCK. Then the first data byte from the address is shifted out on the SO line, with each bit shifted out at a maximum frequency $f_{CT}$, during the falling edge of SCK.

The first byte addressed can be at any memory location. The address is automatically incremented by one after each byte of data is shifted out. When the highest address is reached, the address counter will roll over to the 000000h address, allowing the entire memory to be read with a single Fast Read instruction. The Fast Read instruction is terminated by driving CE# high (VIH).

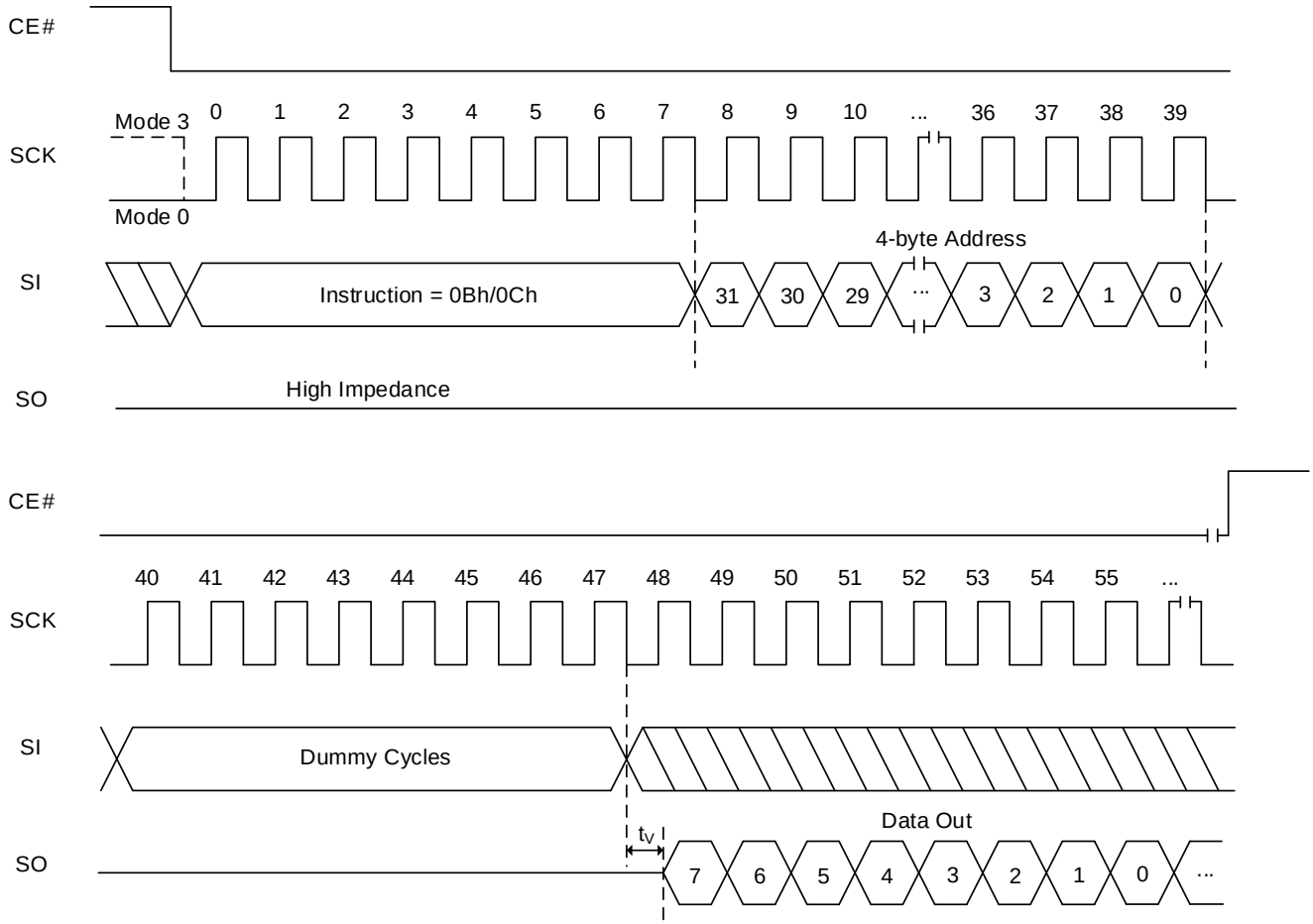
If the Fast Read instruction is issued while an Erase, Program or Write cycle is in process (WIP=1) the instruction is ignored without affecting the current cycle.

**Figure 8.3 Fast Read Sequence (0Bh [EXTADD=0], 3-byte address)**




**Note: Dummy cycles depends on Read Parameter setting. Detailed information in Table 6.11 Read Dummy Cycles.**

**Figure 8.4 Fast Read Sequence (0Bh [EXTADD=1] or 0Ch, 4-byte address)**




**Note: Dummy cycles depends on Read Parameter setting. Detailed information in Table 6.11 Read Dummy Cycles.**

**FAST READ OPERATION IN QPI MODE (FRD, 0Bh or 4FRD, 0Ch)**

The Fast Read (FRD) instruction in QPI mode is used to read memory data at up to a 166MHz clock.

- 0Bh (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- 0Bh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- 0Ch is followed by a 4-byte address (A31-A0)

The Fast Read instruction code (2 clocks) is followed by three (6 clocks) or four (8 clocks) address bytes as above and 6 dummy cycles (configurable, default is 6 clocks), transmitted via the IO3, IO2, IO1 and IO0 lines, with each bit latched-in during the rising edge of SCK. Then the first data byte addressed is shifted out on the IO3, IO2, IO1 and IO0 lines, with each bit shifted out at a maximum frequency $f_{CT}$, during the falling edge of SCK.

The first byte addressed can be at any memory location. The address is automatically incremented by one after each byte of data is shifted out. When the highest address is reached, the address counter will roll over to the 000000h address, allowing the entire memory to be read with a single Fast Read QPI instruction. The Fast Read QPI instruction is terminated by driving CE# high (VIH).

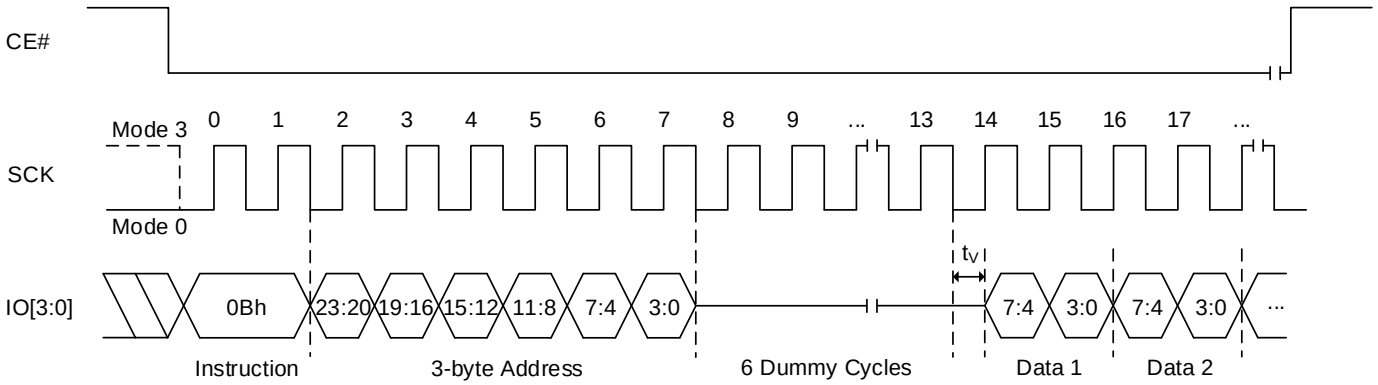
If the Fast Read instruction in QPI mode is issued while an Erase, Program or Write cycle is in process (WIP=1) the instruction is ignored without affecting the current cycle.

The Fast Read sequence in QPI mode is also applied to the commands in the following table 8.5. However, only 3-byte address mode QPI sequence is applied for RDUID, and IRRD commands.

**Table 8.5 Instructions that Fast Read sequence in QPI Mode is applied to**

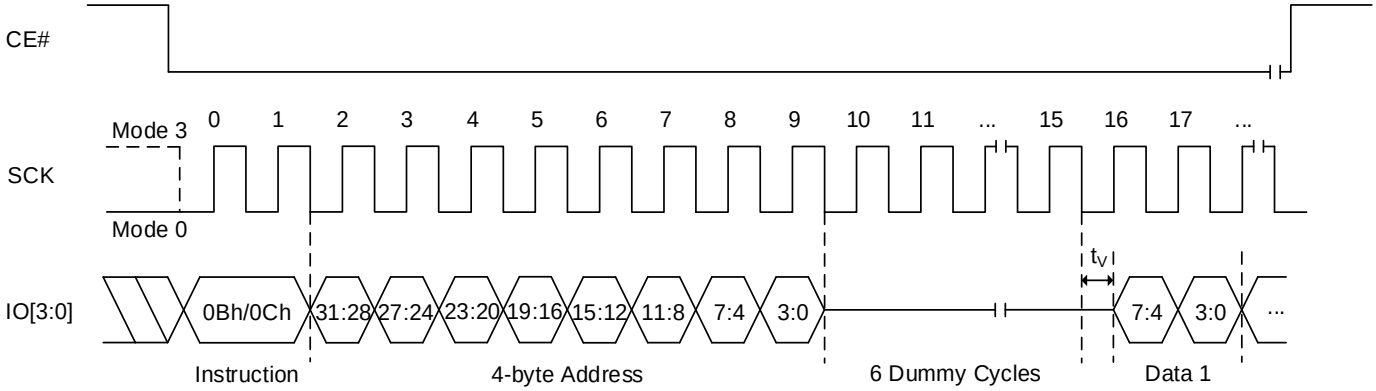
| Instruction Name | Operation | Hex Code |
|---|---|---|
| FRQIO | Fast Read Quad I/O | EBh |
| RDUID | Read Unique ID | 4Bh |
| IRRD | Read Information Row | 68h |

**Figure 8.5 Fast Read QPI Sequence (0Bh [EXTADD=0], 3-byte address)**




**Note: Number of dummy cycles depends on Read Parameter setting. Detailed information in Table 6.11 Read Dummy Cycles.**

**Figure 8.6 Fast Read Sequence In QPI Mode (0Bh [EXTADD=1] or 0Ch, 4-byte address)**




**Note: Number of dummy cycles depends on Read Parameter setting. Detailed information in Table 6.11 Read Dummy Cycles.**

## 8.5 HOLD OPERATION

HOLD# is used in conjunction with CE# to select the device. When the device is selected and a serial sequence is underway, HOLD# can be used to pause the serial communication with the master device without resetting the serial sequence. To pause, HOLD# is brought low while the SCK signal is low. To resume serial communication, HOLD# is brought high while the SCK signal is low (SCK may still toggle during HOLD). Inputs to SI will be ignored while SO is in the high impedance state, during HOLD.

**Note: HOLD is not supported in DTR mode or with QE=1 or when RESET# is selected for the HOLD# or RESET# pin.**

Timing graph can be referenced in AC Parameters Figure 9.4.

### 8.6 FAST READ DUAL I/O OPERATION (FRDIO, BBh or 4FRDIO, BCh)

The Fast Read Dual I/O (FRDIO, 4FRDIO) instruction allows the address bits to be input two bits at a time. This may allow for code to be executed directly from the SPI in some applications.

- BBh (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- BBh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- BCh is followed by a 4-byte address (A31-A0)

The FRDIO/4FRDIO instruction code is followed by three or four address bytes as above and dummy cycles (configurable, default is 4 clocks), transmitted via the IO1 and IO0 lines, with each pair of bits latched-in during the rising edge of SCK. The address MSB is input on IO1, the next bit on IO0, and this shift pattern continues to alternate between the two lines. Depending on the usage of AX read operation mode, a mode byte may be located after address input.

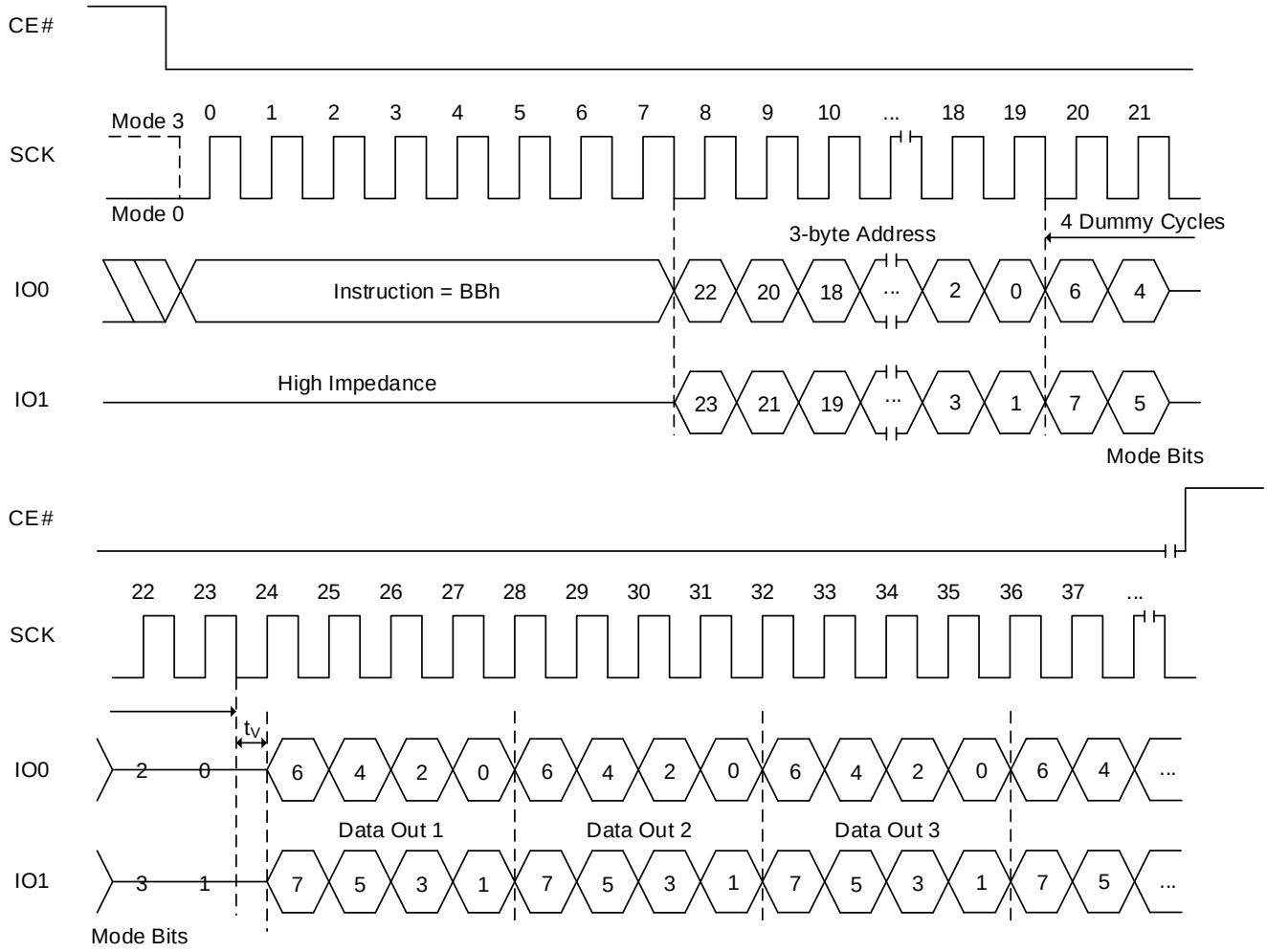
The first data byte addressed is shifted out on the IO1 and IO0 lines, with each pair of bits shifted out at a maximum frequency $f_{CT}$, during the falling edge of SCK. The first bit (MSB) is output on IO1, while simultaneously the second bit is output on IO0. Figures 8.7 and 8.8 illustrates the timing sequence.

The first byte addressed can be at any memory location. The address is automatically incremented by one after each byte of data is shifted out. When the highest address is reached, the address counter will roll over to the 000000h address, allowing the entire memory to be read with a single FRDIO/4FRDIO instruction. The FRDIO/4FRDIO instruction is terminated by driving CE# high ($V_{IH}$).

The device supports the AX read operation by applying mode bits during dummy period. Mode bits consist of 8 bits, such as M7 to M0. Four cycles after address input are reserved for Mode bits in FRDIO/4FRDIO execution. M7 to M4 are important for enabling this mode. M3 to M0 become don't care for future use. When M[7:4]=1010(Ah), it enables the AX read operation and subsequent FRDIO/4FRDIO execution skips command code. It saves cycles as described in Figures 8.9 and 8.10. When the code is different from AXh (where X is don't care), the device exits the AX read operation. After finishing the read operation, device becomes ready to receive a new command. SPI or QPI mode configuration retains the prior setting. Mode bit must be applied during dummy cycles. Number of dummy cycles in Table 6.11 includes number of mode bit cycles. If dummy cycles are configured as 4 cycles, data output will start right after mode bit is applied.

If the FRDIO/4FRDIO instruction is issued while an Erase, Program or Write cycle is in process (WIP=1) the instruction is ignored and will not affect the current cycle.

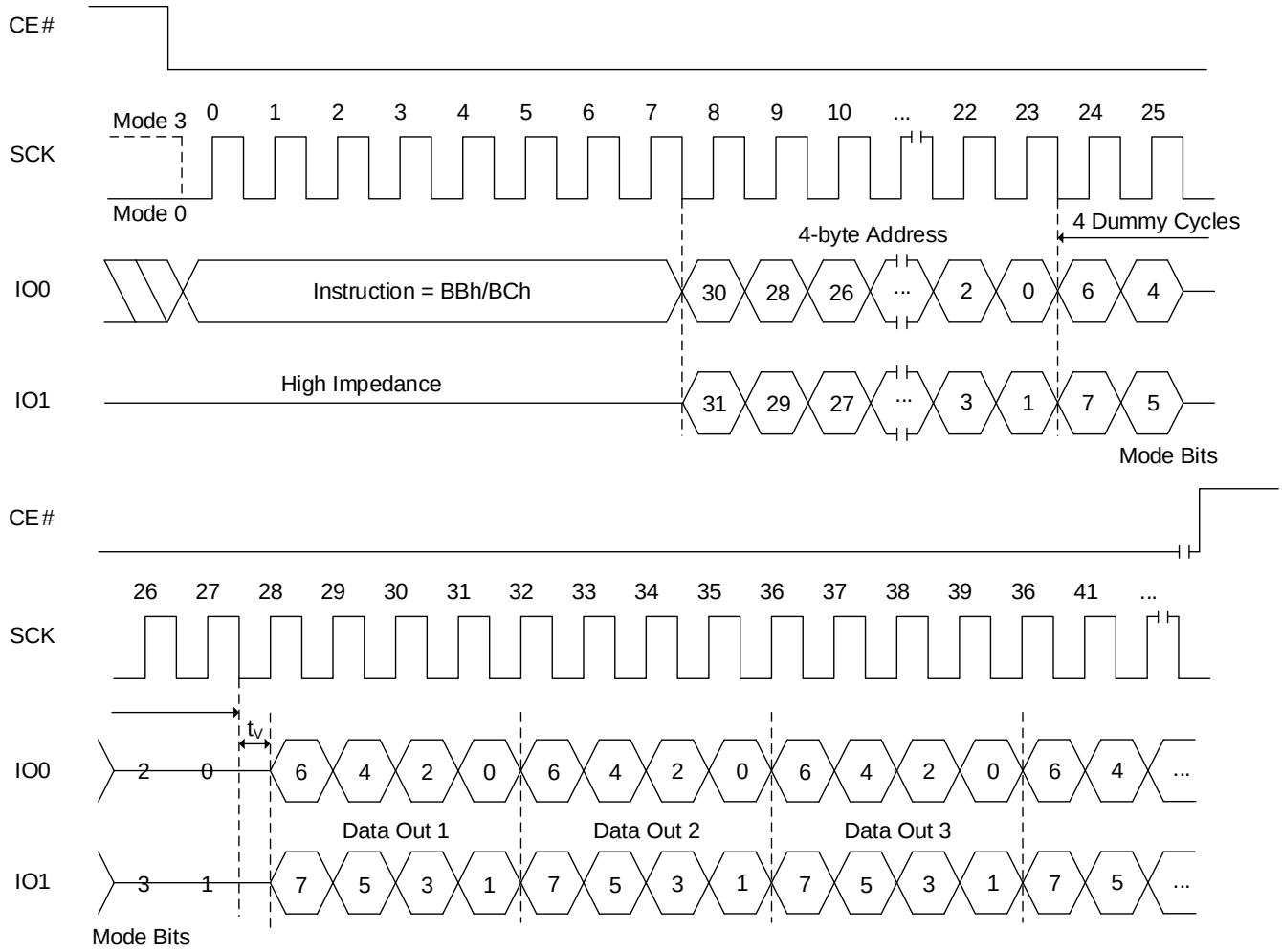
**Figure 8.7 Fast Read Dual I/O Sequence (BBh [EXTADD=0], 3-byte address)**




**Notes:**

1. **If the mode bits=AXh (where X is don't care), it can execute the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

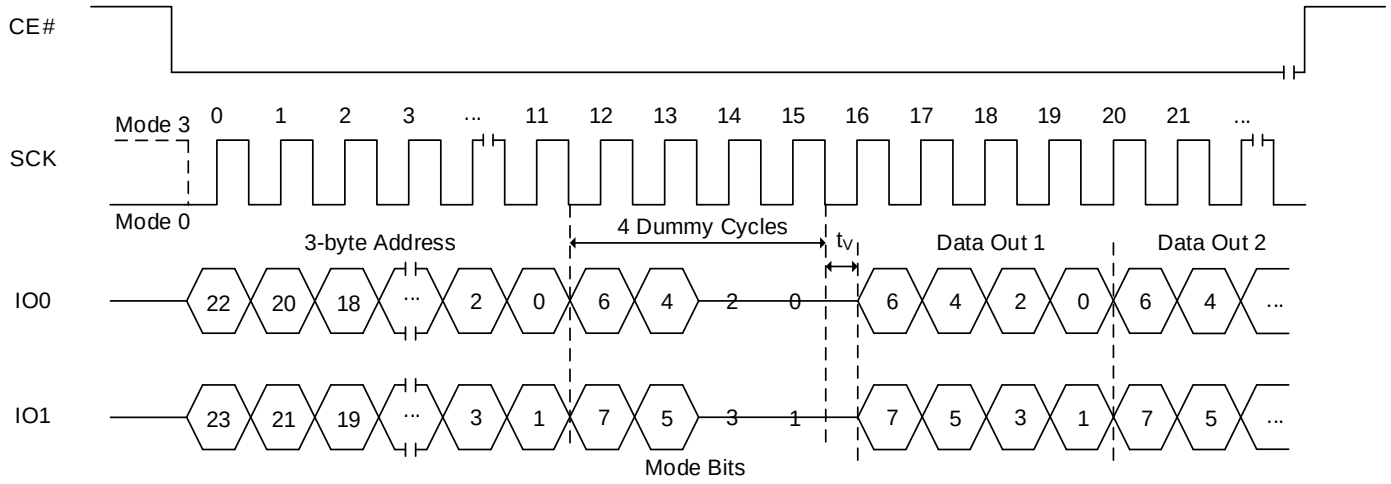
**Figure 8.8 Fast Read Dual I/O Sequence (BBh [EXTADD=1] or BCh, 4-byte address)**




**Notes:**

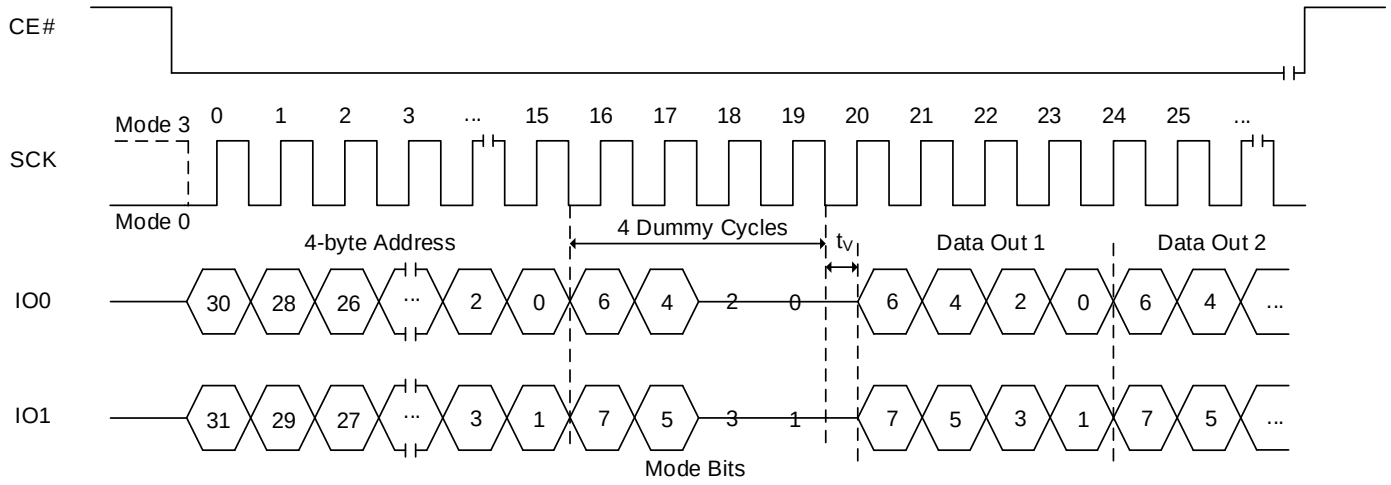
1. **If the mode bits=AXh (where X is don't care), it can execute the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

**Figure 8.9 Fast Read Dual I/O AX Read Sequence (BBh [EXTADD=0], 3-byte address)**




**Notes:**
1. **If the mode bits=AXh (where X is don't care), it will keep executing the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

**Figure 8.10 Fast Read Dual I/O AX Read Sequence (BBh [EXTADD=1] or BCh, 4-byte address)**




**Notes:**
1. **If the mode bits=AXh (where X is don't care), it will keep executing the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

### 8.7 FAST READ DUAL OUTPUT OPERATION (FRDO, 3Bh or 4FRDO, 3Ch)

The FRDO/4FRDO instruction is used to read memory data on two output pins each at up to a 166MHz clock.

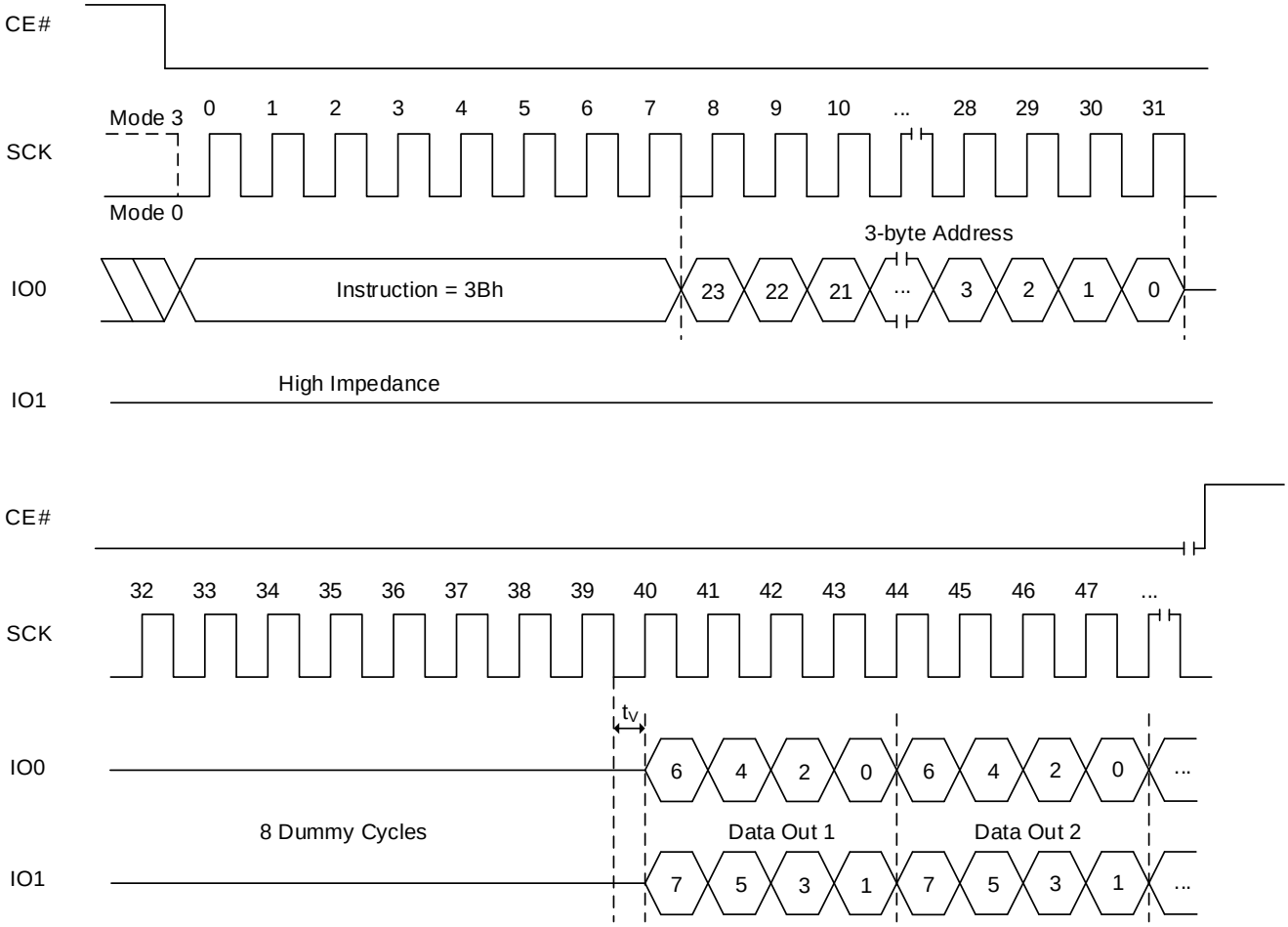
- 3Bh (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- 3Bh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- 3Ch is followed by a 4-byte address (A31-A0)

The FRDO/4FRDO instruction code is followed by three or four address bytes as above and dummy cycles (configurable, default is 8 clocks), transmitted via the IO0 line, with each bit latched-in during the rising edge of SCK. Then the first data byte addressed is shifted out on the IO1 and IO0 lines, with each pair of bits shifted out at a maximum frequency $f_{CT}$, during the falling edge of SCK. The first bit (MSB) is output on IO1. Simultaneously, the second bit is output on IO0.

The first byte addressed can be at any memory location. The address is automatically incremented by one after each byte of data is shifted out. When the highest address is reached, the address counter will roll over to the 000000h address, allowing the entire memory to be read with a single FRDO/4FRDO instruction. The instruction FRDO/4FRDO is terminated by driving CE# high (VIH).

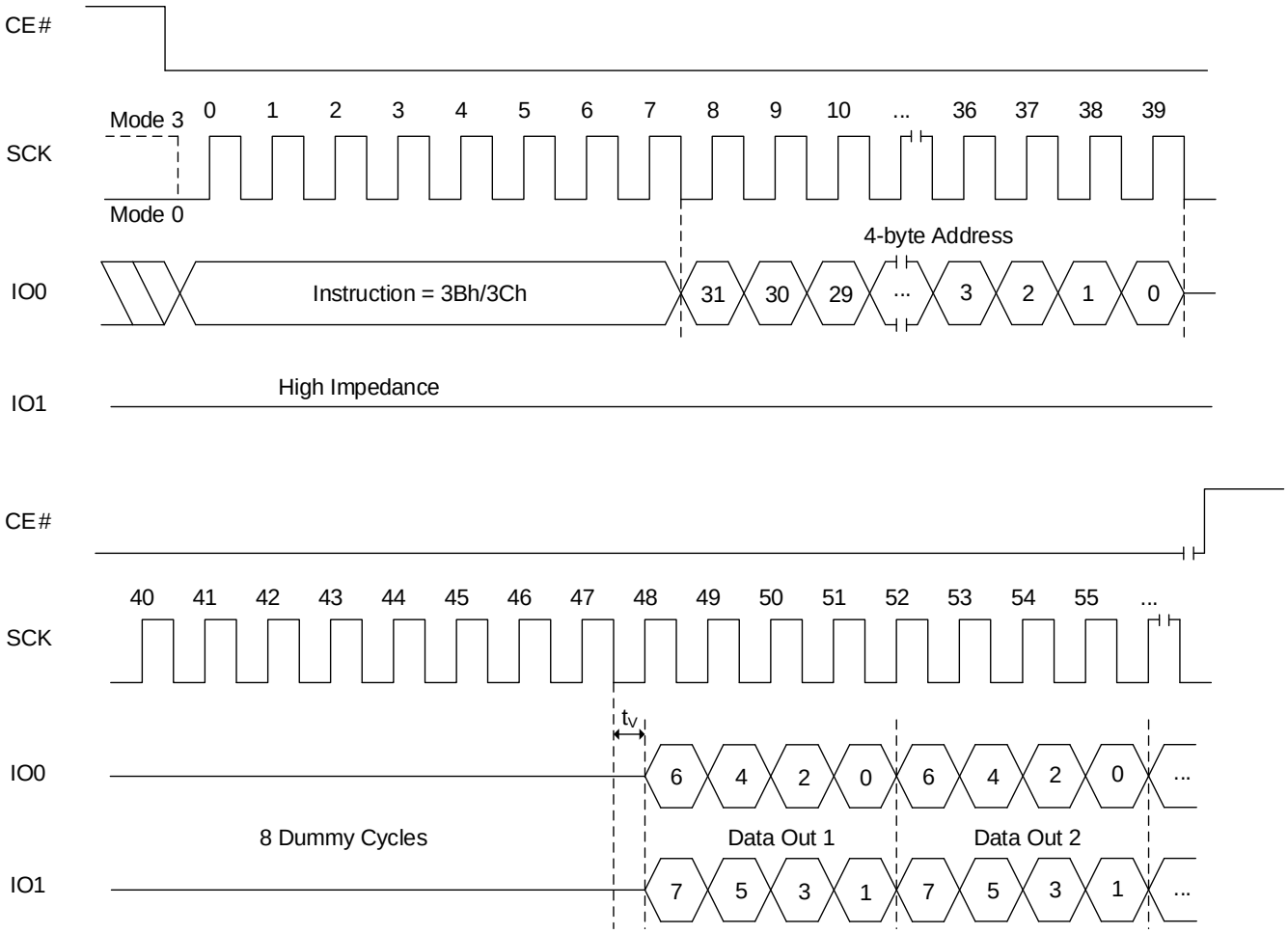
If the FRDO/4FRDO instruction is issued while an Erase, Program or Write cycle is in process (WIP=1) the instruction is ignored and will not have any effects on the current cycle.

**Figure 8.11 Fast Read Dual Output Sequence (3Bh [EXTADD=0], 3-byte address)**




**Note: Dummy cycles depends on Read Parameter setting. Detailed information in Table 6.11 Read Dummy Cycles.**

**Figure 8.12 Fast Read Dual Output Sequence (3Bh [EXTADD=1] or 3Ch, 4-byte address)**




**Note: Dummy cycles depends on Read Parameter setting. Detailed information in Table 6.11 Read Dummy Cycles.**

### 8.8 FAST READ QUAD OUTPUT OPERATION (FRQO, 6Bh or 4FRQO 6Ch)

The FRQO/4FRQO instruction is used to read memory data on four output pins each at up to a 166 MHz clock.

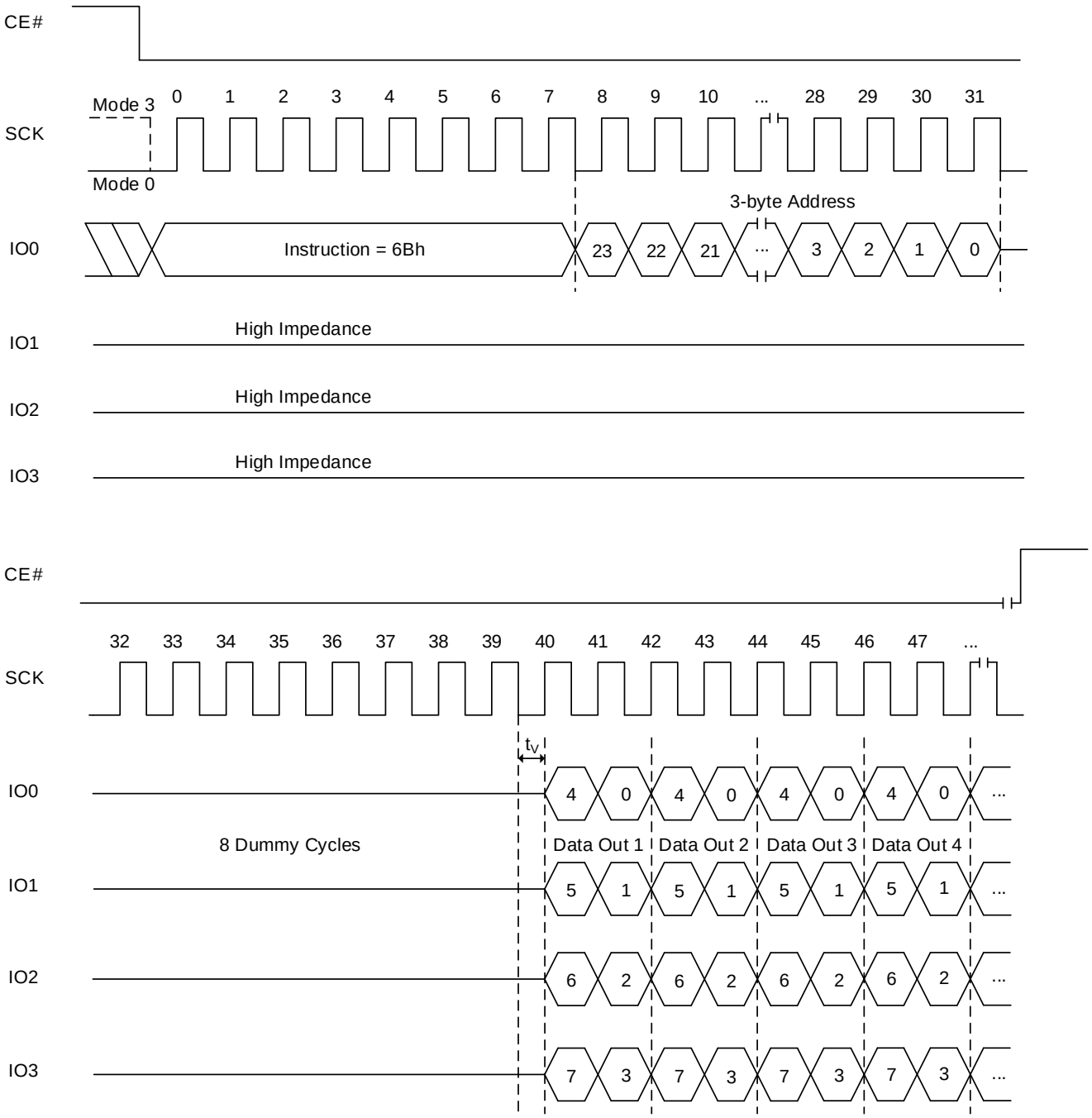
- 6Bh (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- 6Bh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- 6Ch is followed by a 4-byte address (A31-A0)

The FRQO/4FRQO instruction code is followed by three or four address bytes as above and dummy cycles (configurable, default is 8 clocks), transmitted via the IO0 line, with each bit latched-in during the rising edge of SCK. Then the first data byte addressed is shifted out on the IO3, IO2, IO1 and IO0 lines, with each group of four bits shifted out at a maximum frequency $f_{CT}$, during the falling edge of SCK. The first bit (MSB) is output on IO3, while simultaneously the second bit is output on IO2, the third bit is output on IO1, etc.

The first byte addressed can be at any memory location. The address is automatically incremented after each byte of data is shifted out. When the highest address is reached, the address counter will roll over to the 000000h address, allowing the entire memory to be read with a single FRQO/4FRQO instruction. FRQO/4FRQO instruction is terminated by driving CE# high (VIH).

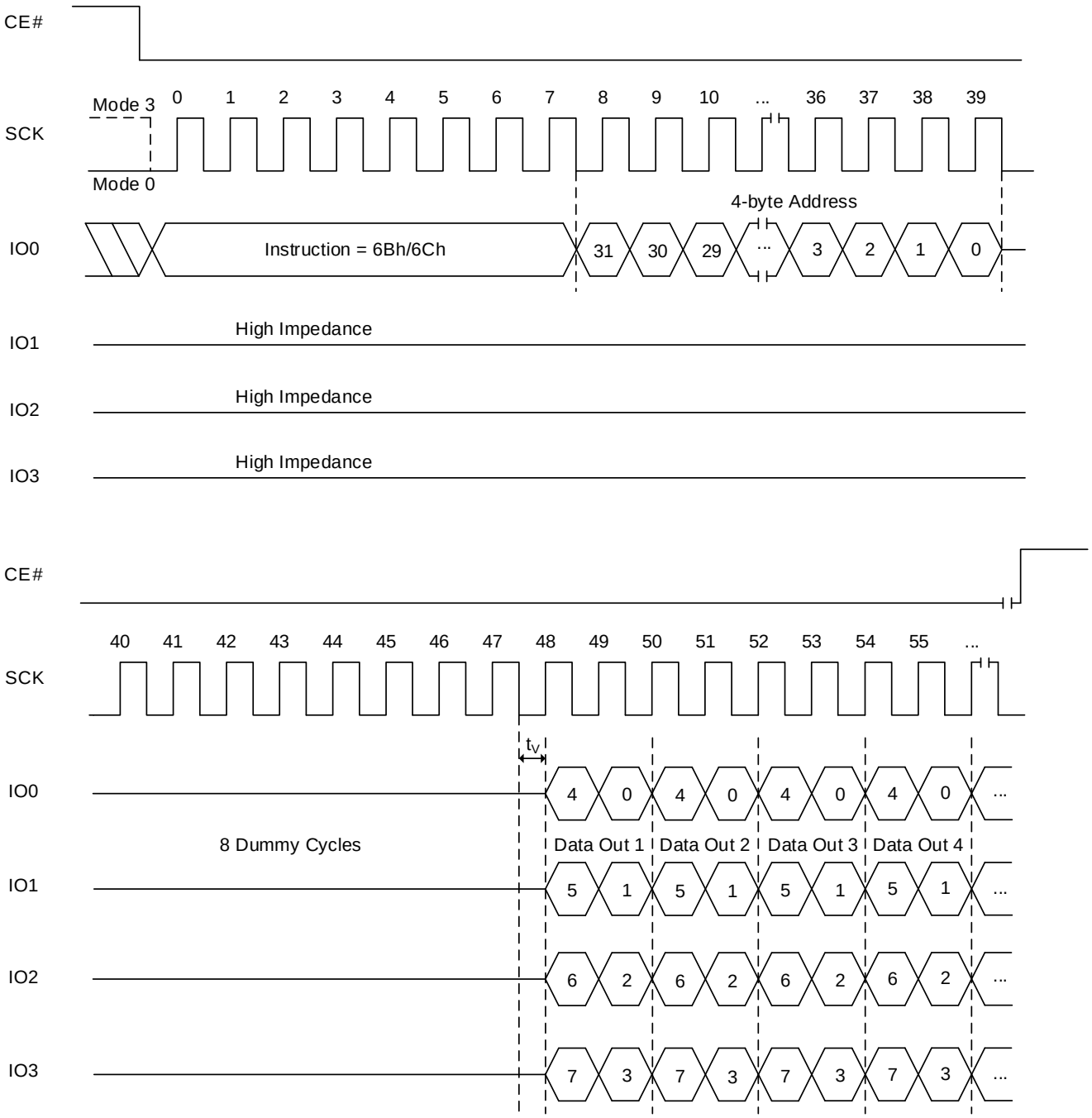
If a FRQO/4FRQO instruction is issued while an Erase, Program or Write cycle is in process (WIP=1) the instruction is ignored and will not have any effects on the current cycle.

**Figure 8.13 Fast Read Quad Output Sequence (6Bh [EXTADD=0], 3-byte address)**




**Note: Dummy cycles depends on Read Parameter setting. Detailed information in Table 6.11 Read Dummy Cycles.**

**Figure 8.14 Fast Read Quad Output Sequence (6Bh [EXTADD=1] or 6Ch, 4-byte address)**




**Note: Dummy cycles depends on Read Parameter setting. Detailed information in Table 6.11 Read Dummy Cycles.**

### 8.9 FAST READ QUAD I/O OPERATION (FRQIO, EBh or 4FRQIO, ECh)

The FRQIO/4FRQIO instruction allows the address bits to be input four bits at a time. This may allow for code to be executed directly from the SPI in some applications.

- EBh (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- EBh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- ECh is followed by a 4-byte address (A31-A0)

The FRQIO/4FRQIO instruction code is followed by three or four address bytes as above and dummy cycles (configurable, default is 6 clocks), transmitted via the IO3, IO2, IO1 and IO0 lines, with each group of four bits latched-in during the rising edge of SCK. The address of MSB inputs on IO3, the next bit on IO2, the next bit on IO1, the next bit on IO0, and continue to shift in alternating on the four. Depending on the usage of AX read operation mode, a mode byte may be located after address input.

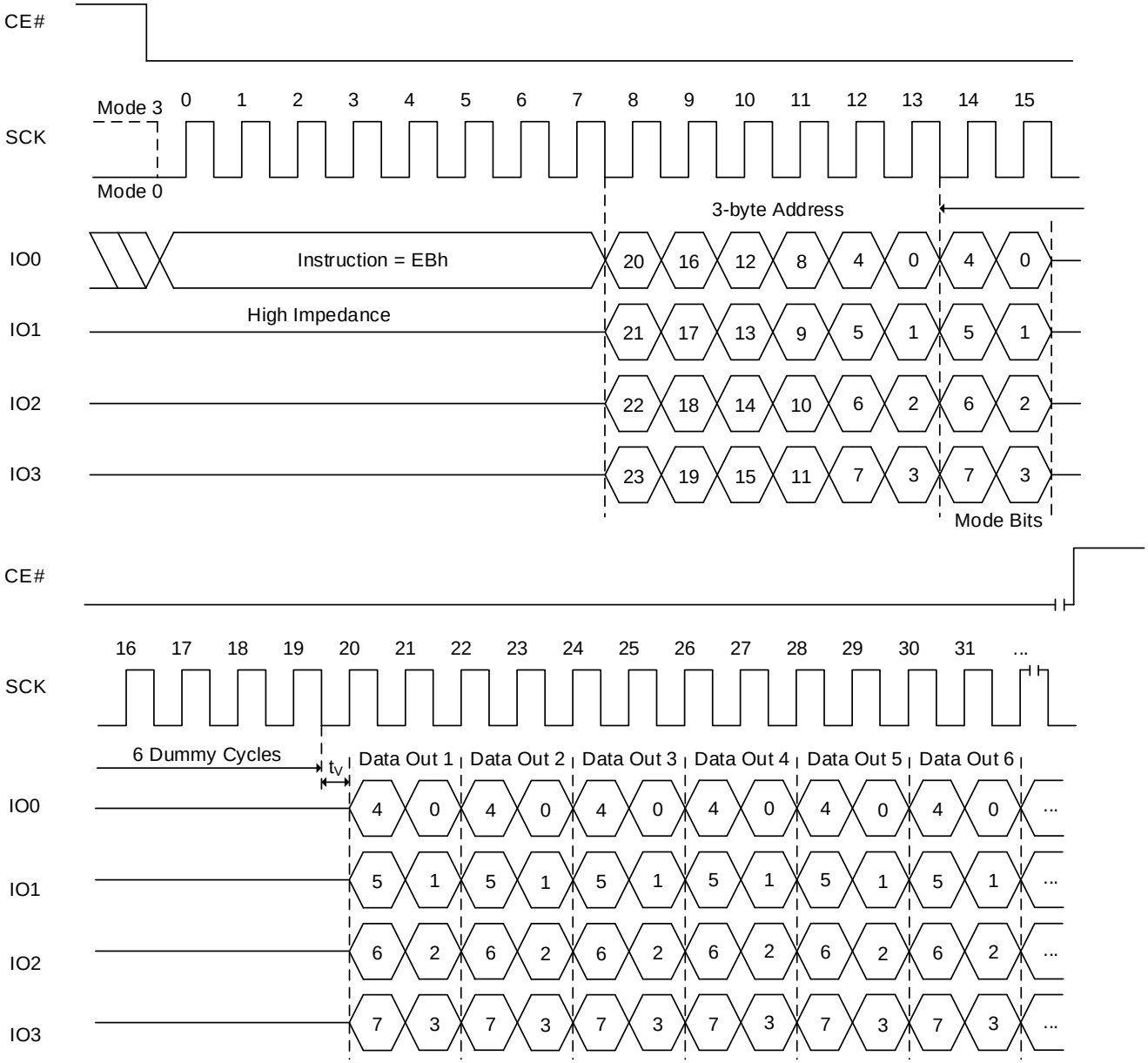
The first data byte addressed is shifted out on the IO3, IO2, IO1 and IO0 lines, with each group of four bits shifted out at a maximum frequency $f_{CT}$, during the falling edge of SCK. The first bit (MSB) is output on IO3, while simultaneously the second bit is output on IO2, the third bit is output on IO1, etc. Figures 8.15 and 8.16 illustrates the timing sequence.

The first byte addressed can be at any memory location. The address is automatically incremented after each byte of data is shifted out. When the highest address is reached, the address counter will roll over to the 000000h address, allowing the entire memory to be read with a single FRQIO/4FRQIO instruction. FRQIO/4FRQIO instruction is terminated by driving CE# high ($V_{IH}$).

The device supports the AX read operation by applying mode bits during dummy period. Mode bits consist of 8 bits, such as M7 to M0. Two cycles after address input are reserved for Mode bits in FRQIO/4FRQIO execution. M7 to M4 are important for enabling this mode. M3 to M0 become don't care for future use. When M[7:4]=1010(Ah), it enables the AX read operation and subsequent FRQIO/4FRQIO execution skips command code. It saves cycles as described in Figures 8.17 and 8.18. When the code is different from AXh (where X is don't care), the device exits the AX read operation. After finishing the read operation, device becomes ready to receive a new command. SPI or QPI mode configuration retains the prior setting. Mode bit must be applied during dummy cycles. Number of dummy cycles in Table 6.11 includes number of mode bit cycles. If dummy cycles are configured as 6 cycles, data output will start right after mode bits and 4 additional dummy cycles are applied.

If the FRQIO/4FRQIO instruction is issued while an Erase, Program or Write cycle is in process (WIP=1) the instruction is ignored and will not have any effects on the current cycle.

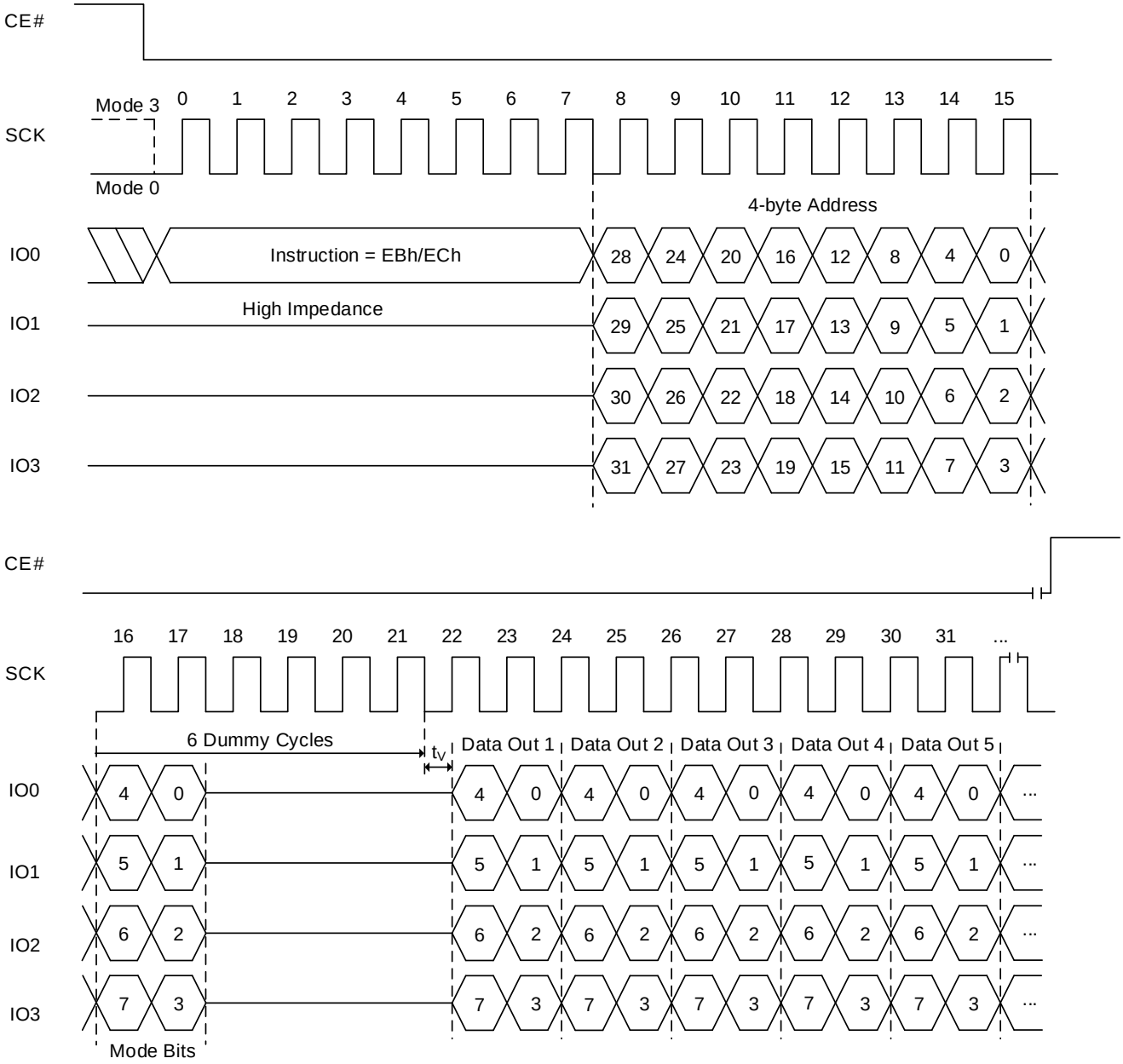
**Figure 8.15 Fast Read Quad I/O Sequence (EBh [EXTADD=0], 3-byte address)**




**Notes:**

1. **If the mode bits=AXh (where X is don't care), it can execute the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

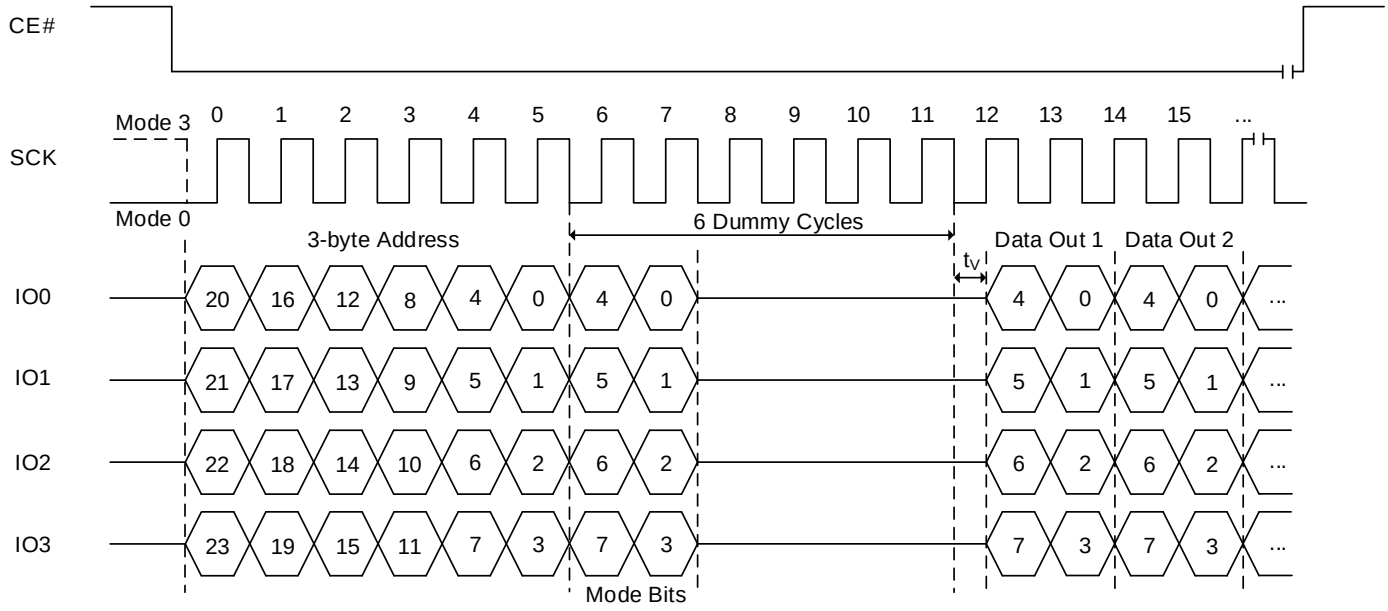
**Figure 8.16 Fast Read Quad I/O Sequence (EBh [EXTADD=1] or ECh, 4-byte address)**




**Notes:**

1. **If the mode bits=AXh (where X is don't care), it can execute the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

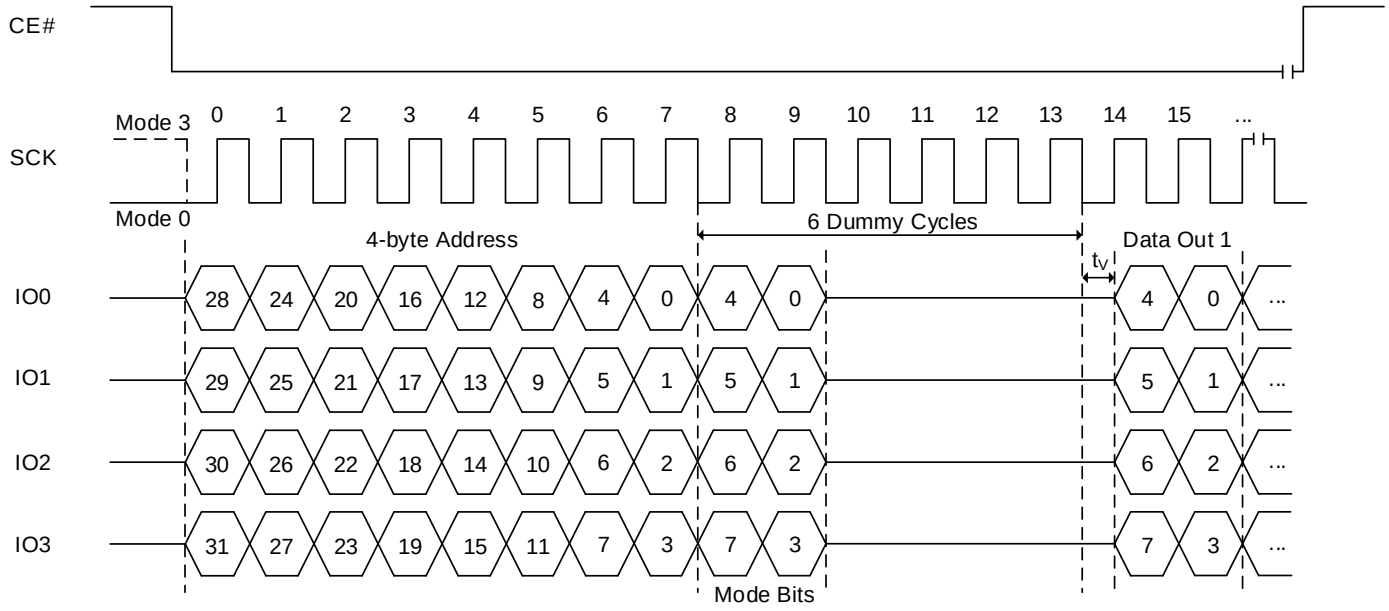
**Figure 8.17 Fast Read Quad I/O AX Read Sequence (EBh [EXTADD=0], 3-byte address)**




**Notes:**

1. **If the mode bits=AXh (where X is don't care), it will keep executing the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

**Figure 8.18 Fast Read Quad I/O AX Read Sequence (EBh [EXTADD=1] or ECh, 4-byte address)**




**Notes:**

1. **If the mode bits=AXh (where X is don't care), it will keep executing the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

**FAST READ QUAD I/O OPERATION IN QPI MODE (FRQIO, EBh or 4FRQIO, ECh)**

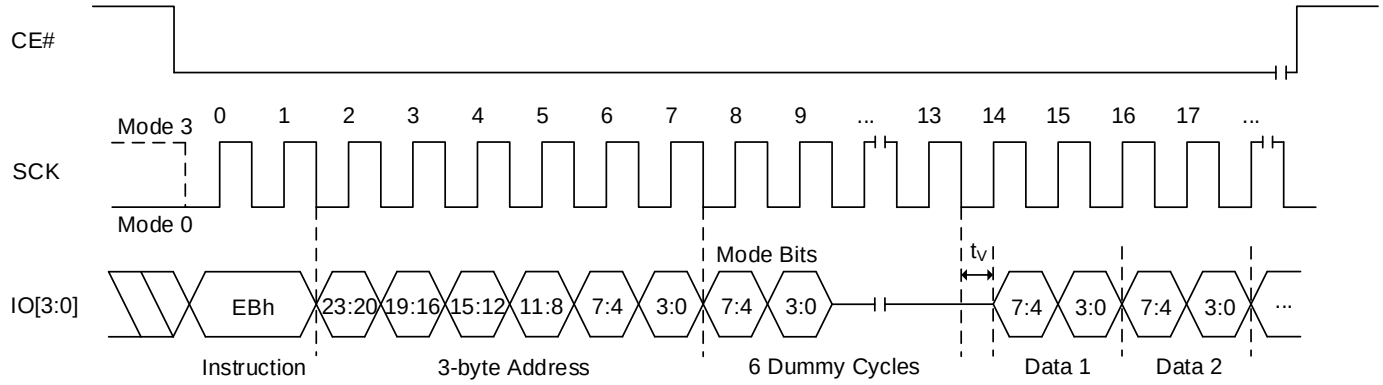
The FRQIO/4FRQIO instruction in QPI mode is used to read memory data at up to a 200MHz clock.

The FRQIO/4FRQIO instruction in QPI mode utilizes all four IO lines to input the instruction code so that only two clocks are required, while the FRQIO/4FRQIO instruction requires that the byte-long instruction code is shifted into the device only via IO0 line in eight clocks. As a result, 6 command cycles will be reduced by the FRQIO/4FRQIO QPI instruction. In addition, subsequent address and data out are shifted in/out via all four IO lines like the FRQIO/4FRQIO instruction. In fact, except for the command cycle, the FRQIO/4FRQIO operation in QPI mode is exactly same as the FRQIO/4FRQIO operation in SPI mode.

The device supports the AX read operation by applying mode bits during dummy period. Mode bits consist of 8 bits, such as M7 to M0. Two cycles after address input are reserved for Mode bits in FRQIO/4FRQIO execution. M7 to M4 are important for enabling this mode. M3 to M0 become don't care for future use. When M[7:4]=1010(Ah), it enables the AX read operation and subsequent FRQIO/4FRQIO execution skips command code. It saves cycles as described in Figures 8.17 and 8.18. When the code is different from AXh (where X is don't care), the device exits the AX read operation. After finishing the read operation, device becomes ready to receive a new command. SPI or QPI mode configuration retains the prior setting. Mode bit must be applied during dummy cycles. Number of dummy cycles in Table 6.11 includes number of mode bit cycles. If dummy cycles are configured as 6 cycles, data output will start right after mode bits and 4 additional dummy cycles are applied.

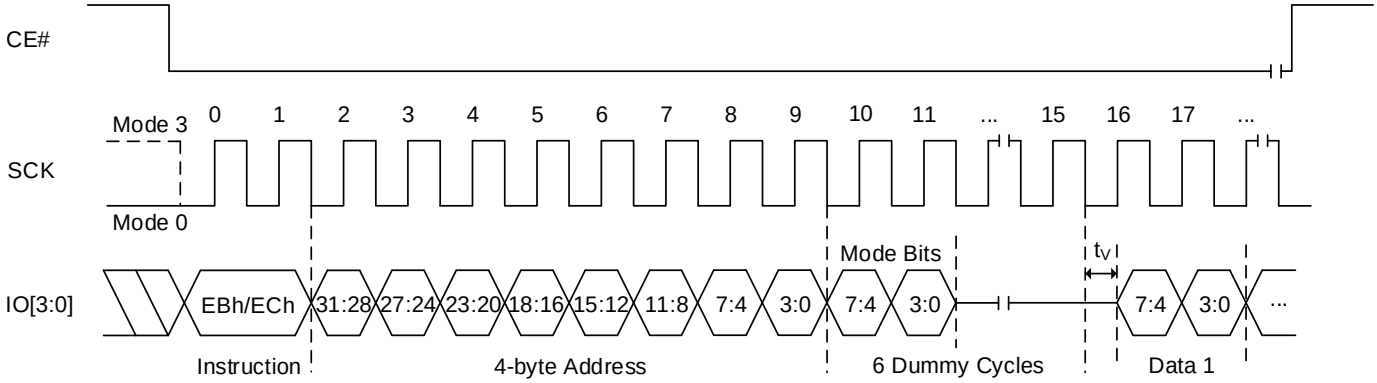
If the FRQIO/4FRQIO instruction in QPI mode is issued while an Erase, Program or Write cycle is in process (WIP=1) the instruction is ignored and will not have any effects on the current cycle.

**Figure 8.19 Fast Read Quad I/O Sequence In QPI Mode (EBh [EXTADD=0], 3-byte address)**




**Notes:**
1. **If the mode bits=AXh (where X is don't care), it can execute the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on Read Parameter setting. Detailed information in Table 6.11 Read Dummy Cycles.**

**Figure 8.20 Fast Read Quad I/O Sequence In QPI Mode (EBh [EXTADD=1] or ECh, 4-byte address)**




**Notes:**

1. **If the mode bits=AXh (where X is don't care), it can execute the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on Read Parameter setting. Detailed information in Table 6.11 Read Dummy Cycles.**

### 8.10 PAGE PROGRAM OPERATION (PP, 02h or 4PP, 12h)

The Page Program (PP/4PP) instruction allows up to 256 bytes data to be programmed into memory in a single operation. The destination of the memory to be programmed must be outside the protected memory area set by the Block Protection bits (BP3, BP2, BP1, BP0) or ASP. A PP/4PP instruction which attempts to program into a page that is write-protected will be ignored. Before the execution of PP/4PP instruction, the Write Enable Latch (WEL) must be enabled through a Write Enable (WREN) instruction.

- 02h (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- 02h (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- 12h is followed by a 4-byte address (A31-A0)

The PP/4PP instruction code, three or four address bytes as above and program data (1 to 256 bytes) are input via the SI line. Program operation will start immediately after the CE# is brought high, otherwise the PP/4PP instruction will not be executed. The internal control logic automatically handles the programming voltages and timing. The progress or completion of the program operation can be determined by reading the WIP bit. If the WIP bit is “1”, the program operation is still in progress. If WIP bit is “0”, the program operation has completed.

If more than 256 bytes data are sent to a device, the address counter rolls over within the same page, the previously latched data are discarded, and the last 256 bytes are kept to be programmed into the page. The starting byte can be anywhere within the page. When the end of the page is reached, the address will wrap around to the beginning of the same page. If the data to be programmed are less than a full page, the data of all other bytes on the same page will remain unchanged.

**Note: A program operation can alter “1”s into “0”s. The same byte location or page may be programmed more than once, to incrementally change “1”s to “0”s. An erase operation is required to change “0”s to “1”s.**

**Figure 8.21 Page Program Sequence (02h [EXTADD=0], 3-byte address)**

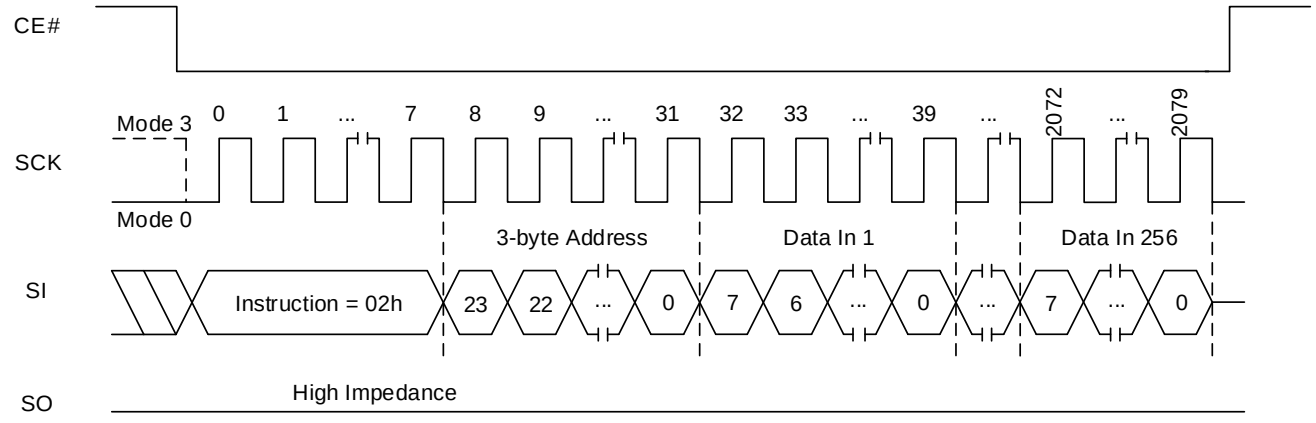



**Figure 8.22 Page Program QPI Sequence (02h [EXTADD=0], 3-byte address)**

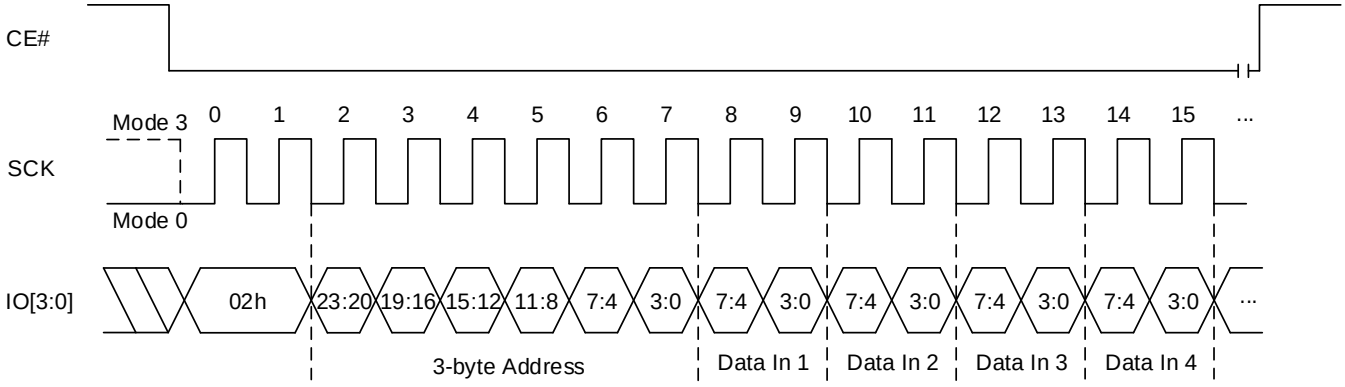


**Figure 8.23 Page Program Sequence In SPI Mode (02h [EXTADD=1] or 12h, 4-byte address)**

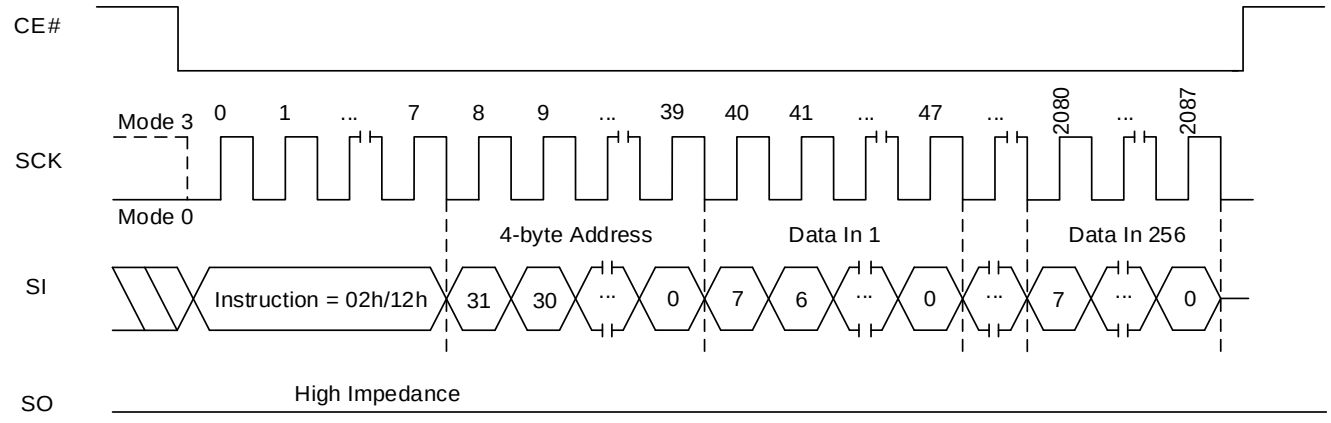
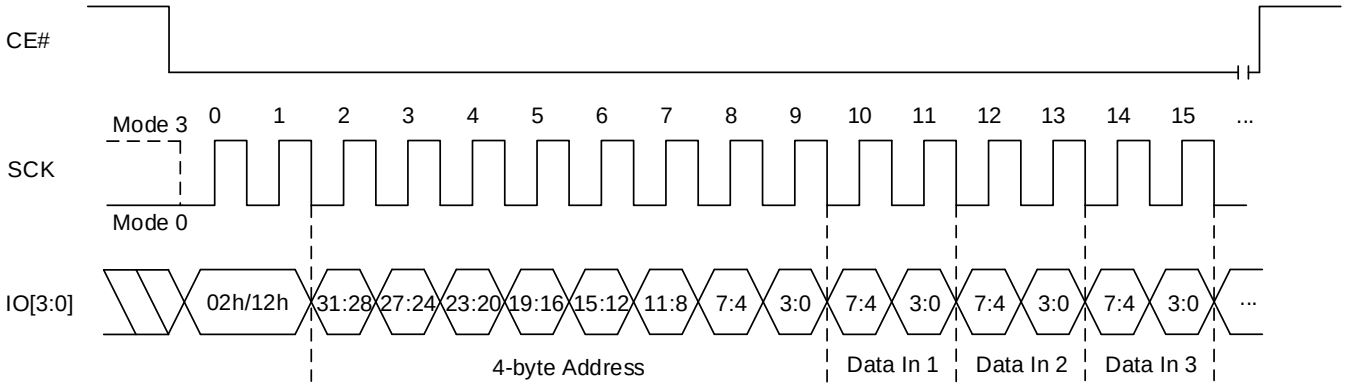



**Figure 8.24 Page Program Sequence In QPI Mode (02h [EXTADD=1] or 12h, 4-byte address)**



### 8.11 QUAD INPUT PAGE PROGRAM OPERATION (PPQ, 32h/38h or 4PPQ, 34h/3Eh)

The Quad Input Page Program instruction allows up to 256 bytes data to be programmed into memory in a single operation with four pins (IO0, IO1, IO2 and IO3). The destination of the memory to be programmed must be outside the protected memory area set by the Block Protection (BP3, BP2, BP1, BP0) bits or ASP. A Quad Input Page Program instruction which attempts to program into a page that is write-protected will be ignored. Before the execution of Quad Input Page Program instruction, the QE bit in the Status Register must be set to "1" and the Write Enable Latch (WEL) must be enabled through a Write Enable (WREN) instruction.

- 32h/38h (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- 32h/38h (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- 34h/3Eh is followed by a 4-byte address (A31-A0)

The Quad Input Page Program instruction code, three or four address bytes as above and program data (1 to 256 bytes) are input via the four pins (IO0, IO1, IO2 and IO3). Program operation will start immediately after the CE# is brought high, otherwise the Quad Input Page Program instruction will not be executed. The internal control logic automatically handles the programming voltages and timing. The progress or completion of the program operation can be determined by reading the WIP bit. If the WIP bit is "1", the program operation is still in progress. If WIP bit is "0", the program operation has completed.

If more than 256 bytes data are sent to a device, the address counter rolls over within the same page, the previously latched data are discarded, and the last 256 bytes data are kept to be programmed into the page. The starting byte can be anywhere within the page. When the end of the page is reached, the address will wrap around to the beginning of the same page. If the data to be programmed are less than a full page, the data of all other bytes on the same page will remain unchanged.

**Note: A program operation can alter "1"s into "0"s. The same byte location or page may be programmed more than once, to incrementally change "1"s to "0"s. An erase operation is required to change "0"s to "1"s.**

**Figure 8.25 Quad Input Page Program operation (32h/38h [EXTADD=0], 3-byte address)**

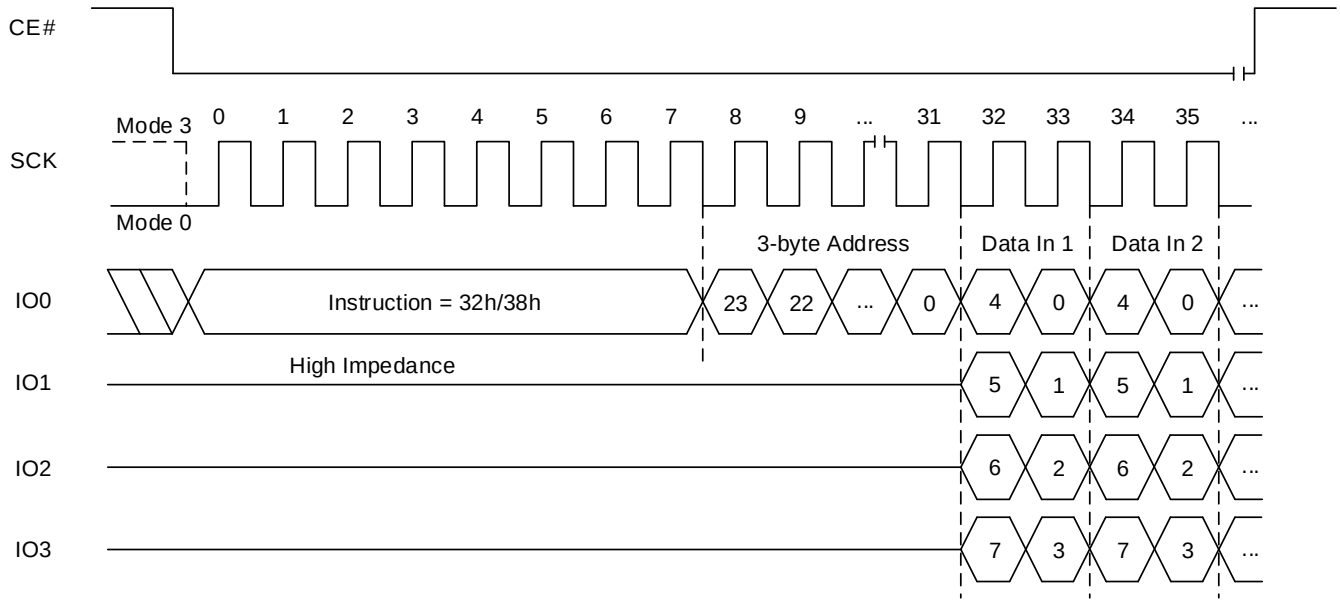
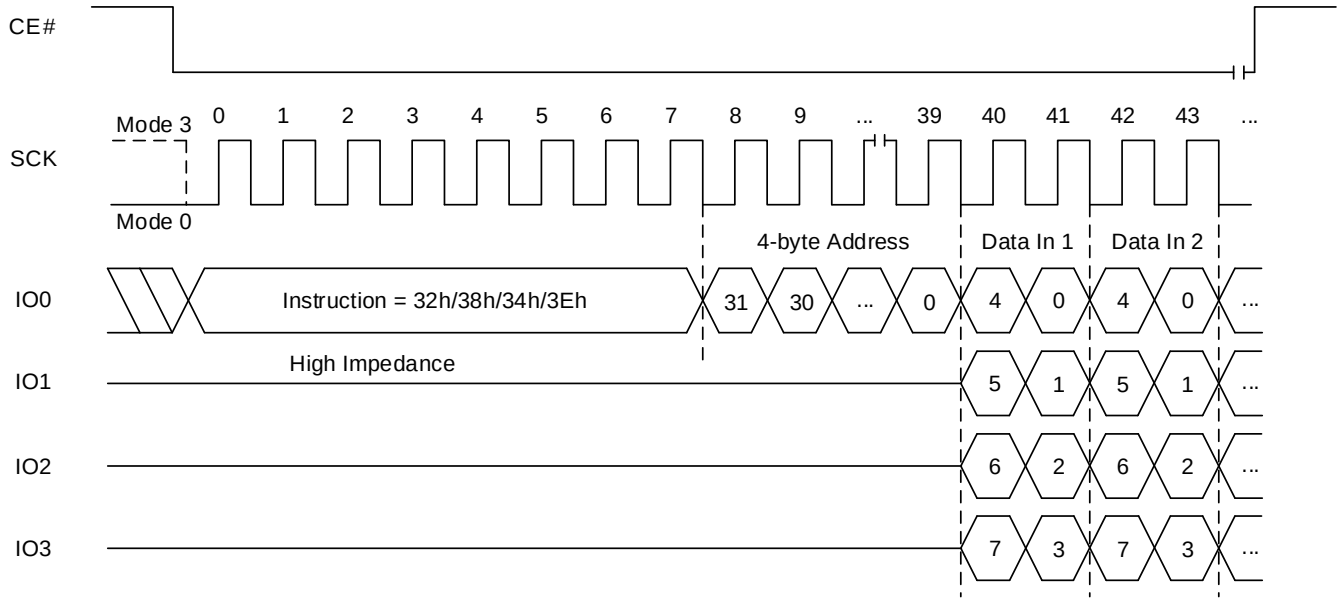


**Figure 8.26 Quad Input Page Program operation (32h/38h [EXTADD=1] or 34h/3Eh, 4-byte address)**




## 8.12 ERASE OPERATION

The Erase command sets all bits in the addressed sector or block to “1”s.

The memory array of the device is organized into uniform 4 Kbyte sectors or 32/64 Kbyte uniform blocks (a block consists of eight/sixteen adjacent sectors respectively).

Before a byte is reprogrammed, the sector or block that contains the byte must be erased (erasing sets bits to “1”). In order to erase the device, there are three erase instructions available: Sector Erase (SER), Block Erase (BER), and Chip Erase (CER). A sector erase operation allows any individual sector to be erased without affecting the data in other sectors. A block erase operation erases any individual block. A chip erase operation erases the whole memory array of a device. A sector erase, block erase, or chip erase operation can be executed prior to any programming operation.

### 8.13 SECTOR ERASE OPERATION (SER, D7h/20h or 4SER, 21h)

A Sector Erase (SER/4SER) instruction erases a 4 Kbyte sector before the execution of a SER/4SER instruction, the Write Enable Latch (WEL) must be set via a Write Enable (WREN) instruction. The WEL bit is automatically reset after the completion of Sector Erase operation.

- D7h/20h (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- D7h/20h (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- 21h is followed by a 4-byte address (A31-A0)

A SER/4SER instruction is entered, after CE# is pulled low to select the device and stays low during the entire instruction sequence The SER/4SER instruction code, and three or four address bytes as above are input via SI. Erase operation will start immediately after CE# is pulled high. The internal control logic automatically handles the erase voltage and timing.

The progress or completion of the erase operation can be determined by reading the WIP bit. If the WIP bit is “1”, the erase operation is still in progress. If the WIP bit is “0”, the erase operation has been completed.

**Figure 8.27 Sector Erase Sequence (D7h/20h [EXTADD=0], 3-byte address)**

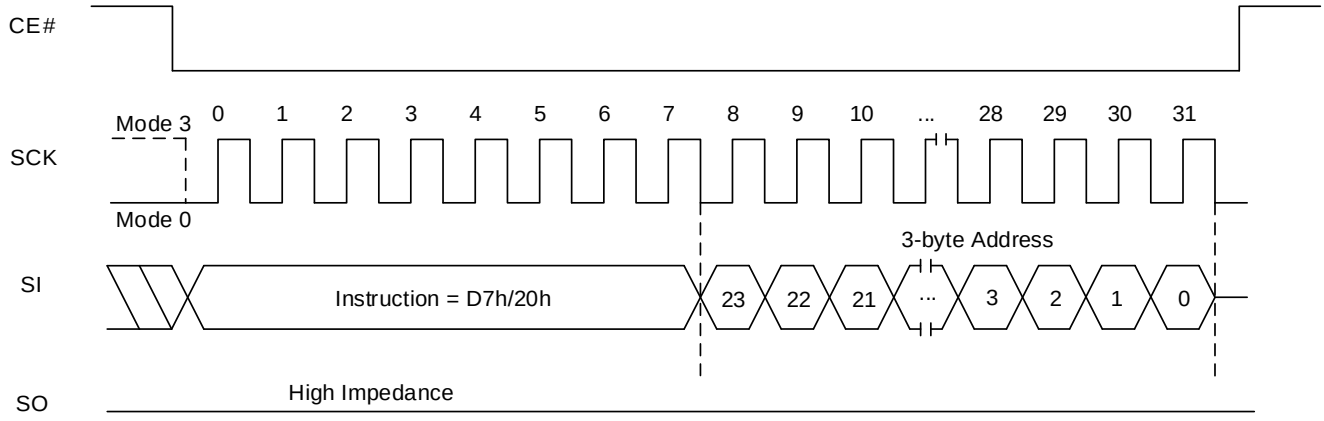


**Figure 8.28 Sector Erase Sequence (D7h/20h [EXTADD=1] or 21h, 4-byte address)**

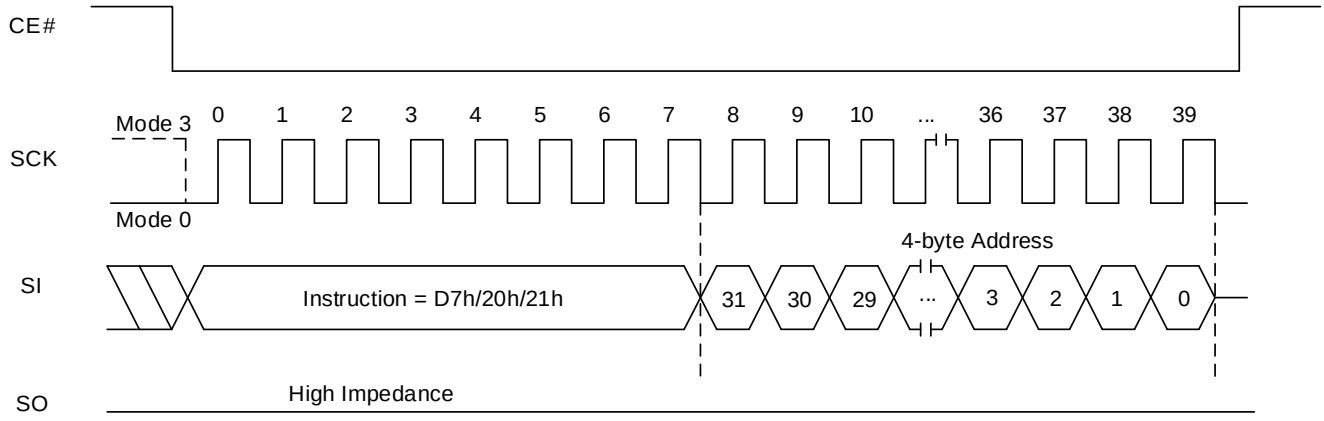



**Figure 8.29 Sector Erase Sequence In QPI Mode (D7h/20h [EXTADD=0], 3-byte address)**

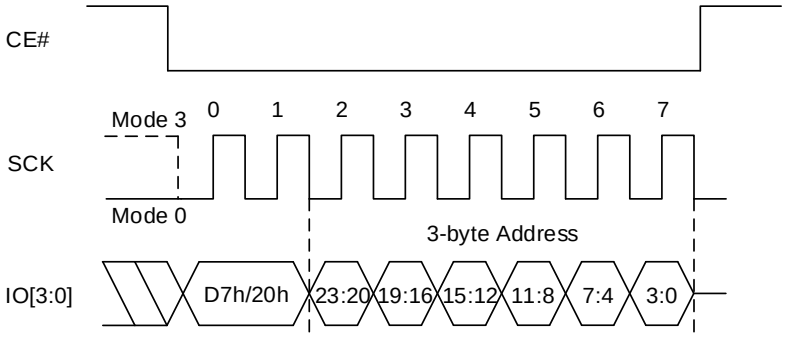
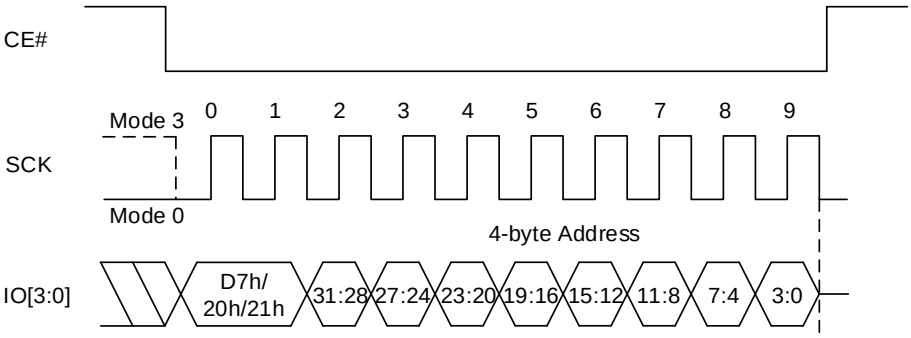



**Figure 8.30 Sector Erase Sequence In QPI Mode (D7h/20h [EXTADD=1] or 21h, 4-byte address)**



### 8.14 BLOCK ERASE OPERATION (BER32K:52h or 4BER32K:5Ch, BER64K:D8h or 4BER64K:DCh)

A Block Erase (BER) instruction erases a 32/64 Kbyte block. Before the execution of a BER instruction, the Write Enable Latch (WEL) must be set via a Write Enable (WREN) instruction. The WEL is reset automatically after the completion of a block erase operation.

- 52h/D8h (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- 52h/D8h (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- 5Ch/DCh is followed by a 4-byte address (A31-A0)

The BER instruction code and three or four address bytes as above are input via SI. Erase operation will start immediately after the CE# is pulled high, otherwise the BER instruction will not be executed. The internal control logic automatically handles the erase voltage and timing.

**Figure 8.31 Block Erase (64K) Sequence (D8h [EXTADD=0], 3-byte address)**

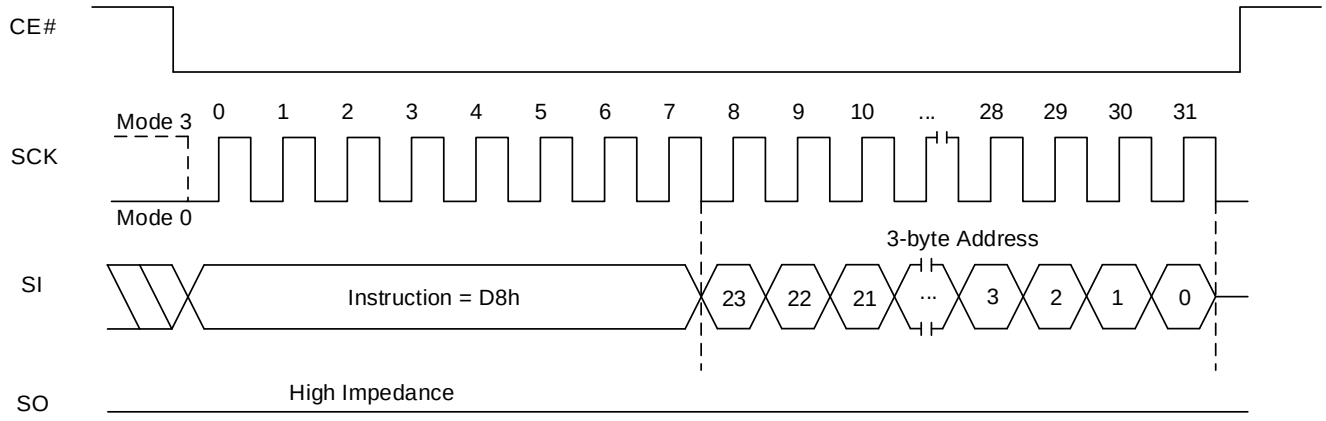



**Figure 8.32 Block Erase (64K) Sequence (D8h [EXTADD=1] or DCh, 4-byte address)**

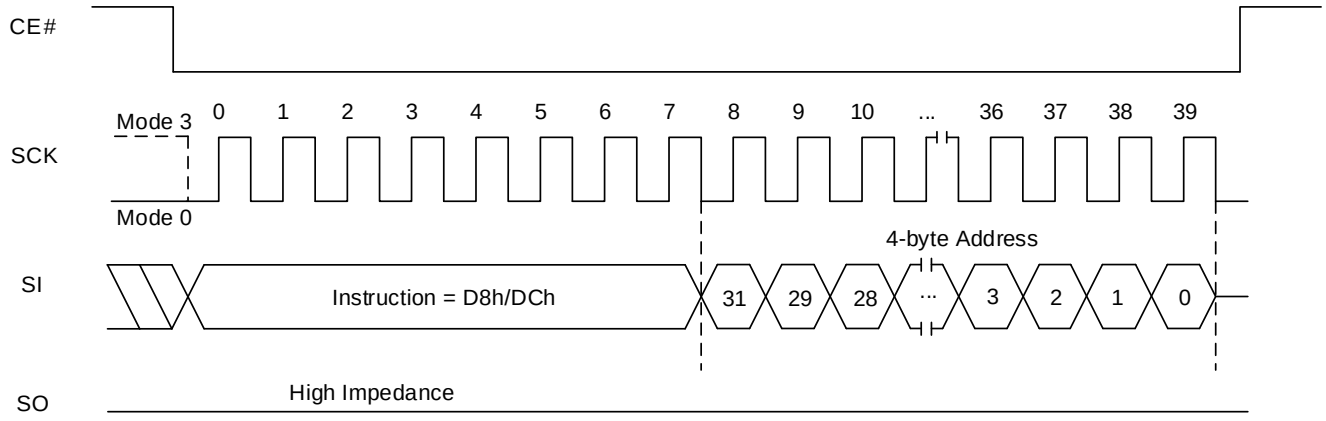


**Figure 8.33 Block Erase (64K) Sequence In QPI Mode (D8h [EXTADD=0], 3-byte address)**

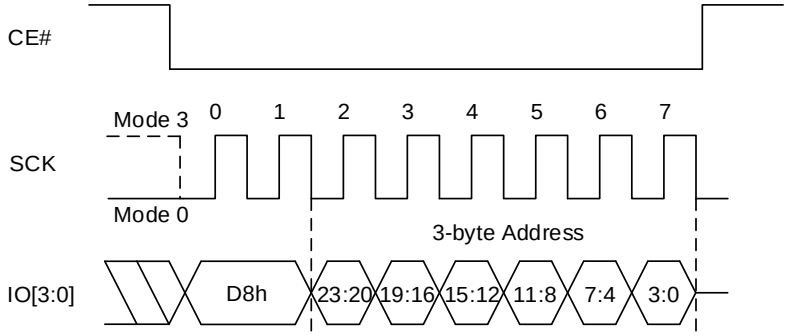



**Figure 8.34 Block Erase (64K) Sequence In QPI Mode (D8h [EXTADD=1] or DCh, 4-byte address)**

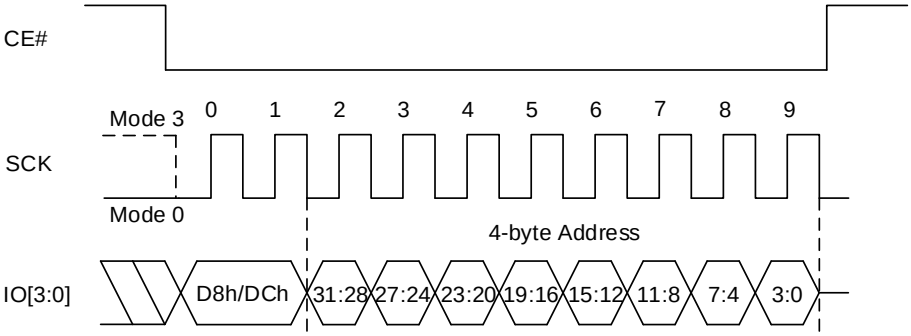



**Figure 8.35 Block Erase (32K) Sequence (52h [EXTADD=0], 3-byte address)**

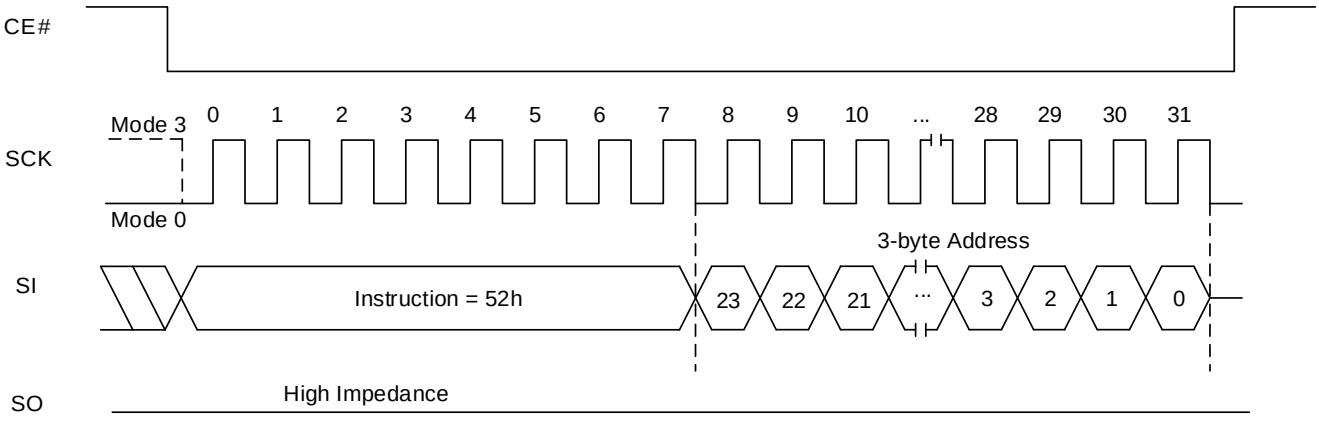


**Figure 8.36 Block Erase (32K) Sequence (52h [EXTADD=1] or 5Ch, 4-byte address)**

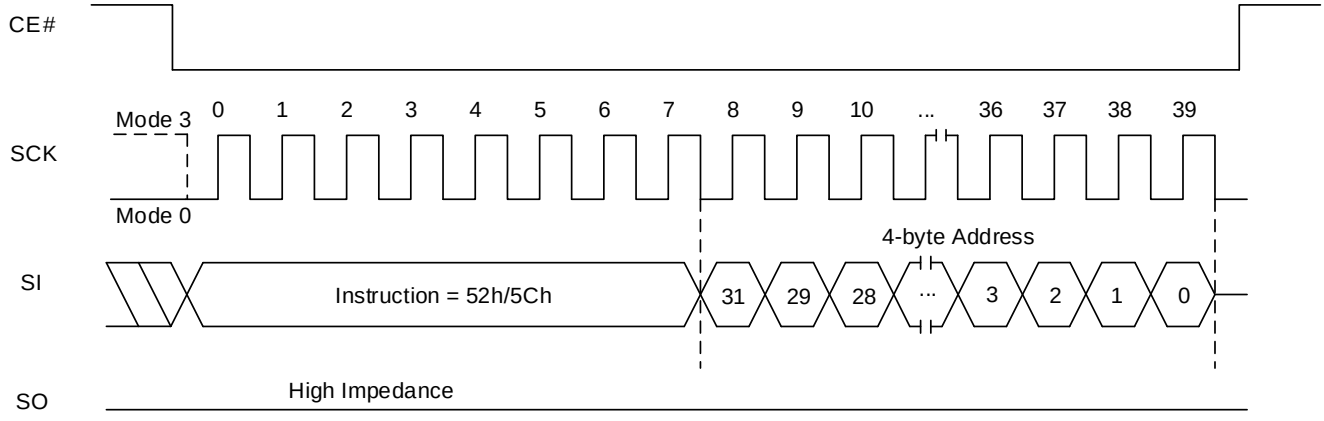



**Figure 8.37 Block Erase (32K) Sequence In QPI Mode (52h [EXTADD=0], 3-byte address)**

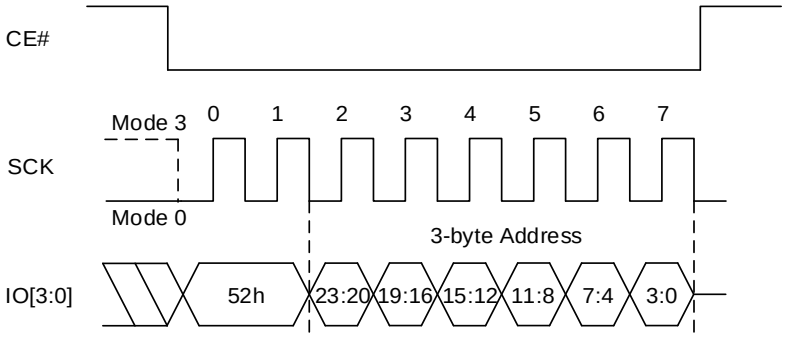
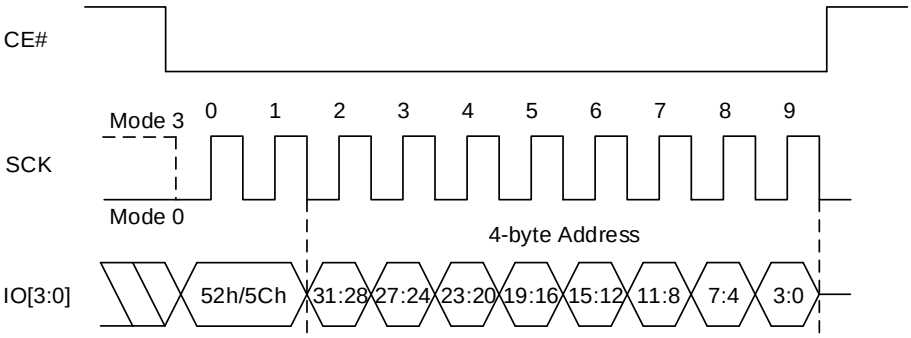



**Figure 8.38 Block Erase (32K) Sequence In QPI Mode (52h [EXTADD=1] or 5Ch, 4-byte address)**



### 8.15 CHIP ERASE OPERATION (CER, C7h/60h)

A Chip Erase (CER) instruction erases the entire memory array. Before the execution of CER instruction, the Write Enable Latch (WEL) must be set via a Write Enable (WREN) instruction. The WEL is automatically reset after completion of a chip erase operation.

The CER instruction code is input via the SI. Erase operation will start immediately after CE# is pulled high, otherwise the CER instruction will not be executed. The internal control logic automatically handles the erase voltage and timing.

Chip Erase (CER) instruction can be executed only when Block Protection (BP3~BP0) bits are set to 0s. If the BP bits are not 0, the CER command is not executed and E_ERR and PROT_E are set.

Chip Erase (CER) instruction will skip sectors/blocks protected by ASP (DYB bits or PPB bits) and will **not** set E_ERR and PROT_E if sectors/blocks are protected by ASP only.

**Figure 8.39 Chip Erase Sequence In SPI Mode**

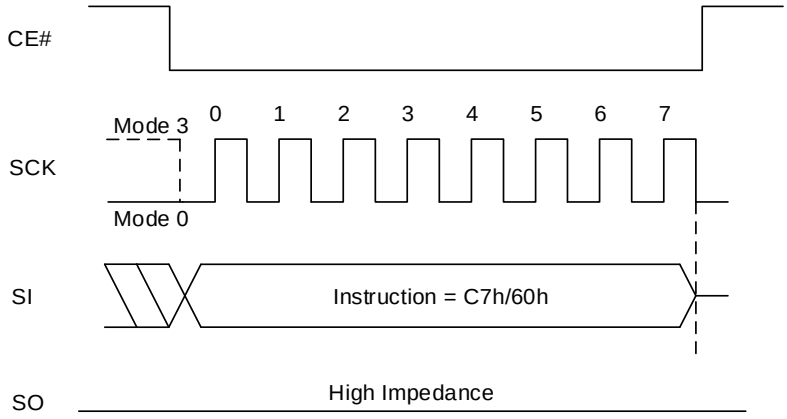
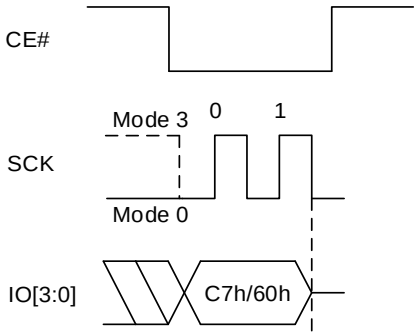



**Figure 8.40 Chip Erase Sequence In QPI Mode**



### 8.16 WRITE ENABLE OPERATION (WREN, 06h)

The Write Enable (WREN) instruction is used to set the Write Enable Latch (WEL) bit. The WEL bit is reset to the write-protected state after power-up. The WEL bit must be write enabled before any write operation, including Sector Erase, Block Erase, Chip Erase, Page Program, Program Information Row, Write Status Register, Write Function Register, Set Non-Volatile Read Register, Set Non-Volatile Extended Read Register, Write Autoboot Register operations, Set Volatile Read Register and Set Volatile Extended Read Register. The WEL bit will be reset to the write-protected state automatically upon completion of a write operation. The WREN instruction is required before any above operation is executed.

**Figure 8.41 Write Enable Sequence In SPI Mode**

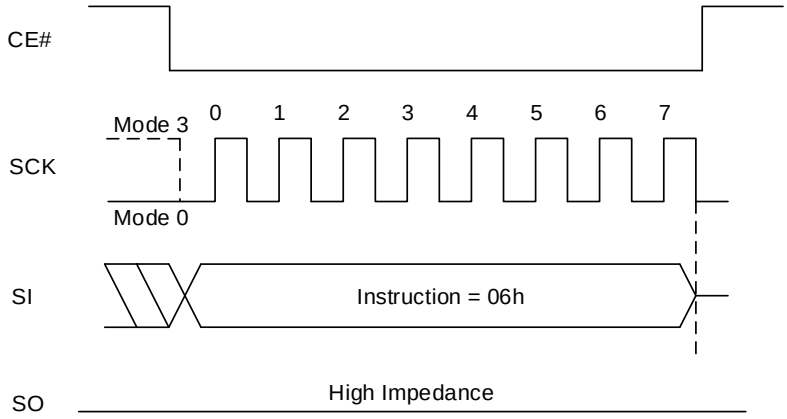
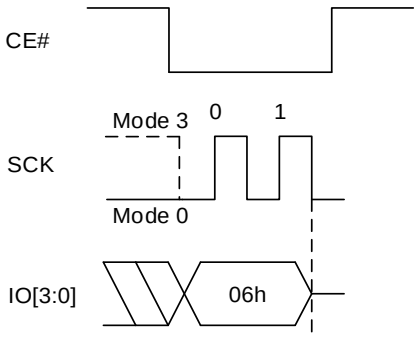



**Figure 8.42 Write Enable Sequence In QPI Mode**



### 8.17 WRITE DISABLE OPERATION (WRDI, 04h)

The Write Disable (WRDI) instruction resets the WEL bit and disables all write instructions. The WRDI instruction is not required after the execution of a write instruction, since the WEL bit is automatically reset.

**Figure 8.43 Write Disable Sequence In SPI Mode**

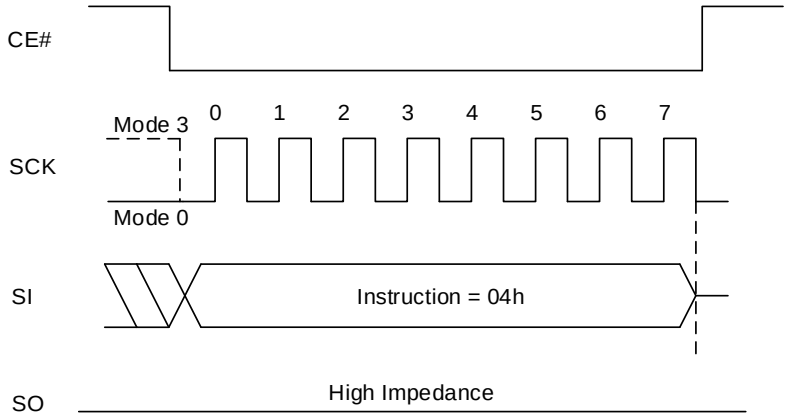
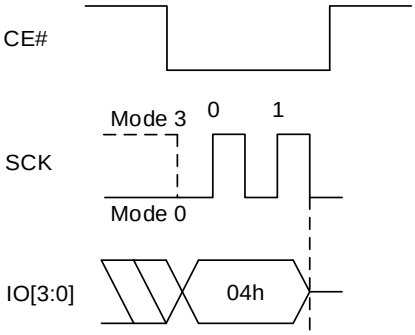



**Figure 8.44 Write Disable Sequence In QPI Mode**



### 8.18 READ STATUS REGISTER OPERATION (RDSR, 05h)

The Read Status Register (RDSR) instruction provides access to Status Register.
During the execution of a program, erase or Write Status Register operation, the RDSR instruction will be executed, which can be used to check the progress or completion of an operation by reading the WIP bit.

**Figure 8.45 Read Status Register Sequence In SPI Mode**

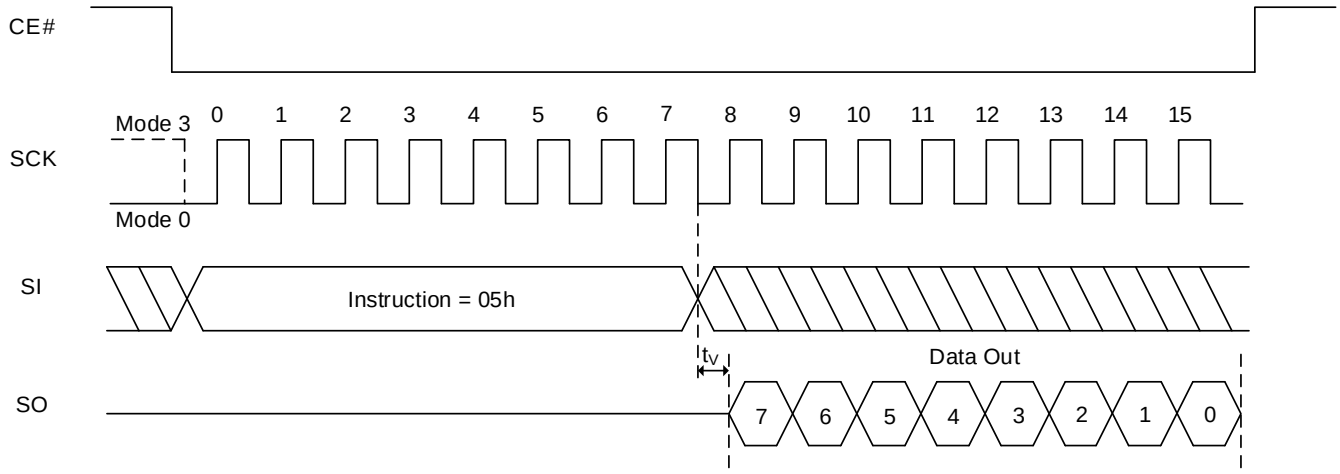
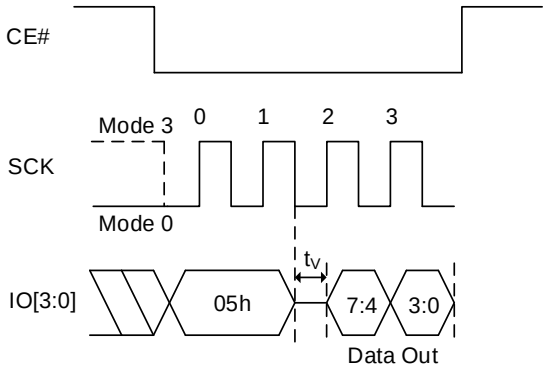



**Figure 8.46 Read Status Register Sequence In QPI Mode**



### 8.19 WRITE STATUS REGISTER OPERATION (WRSR, 01h)

The Write Status Register (WRSR) instruction allows the user to enable or disable the block protection and Status Register write protection features by writing “0”s or “1”s into BP3, BP2, BP1, BP0, and SRWD bits. Also WRSR instruction allows the user to disable or enable quad operation by writing “0” or “1” into QE bit.
To write Status Register bits, a standard Write Enable (06h) instruction must previously have been executed for the device to accept Write Status Register (01h) instruction (Status Register bit WEL must equal 1).

**Figure 8.47 Write Status Register Sequence In SPI Mode**

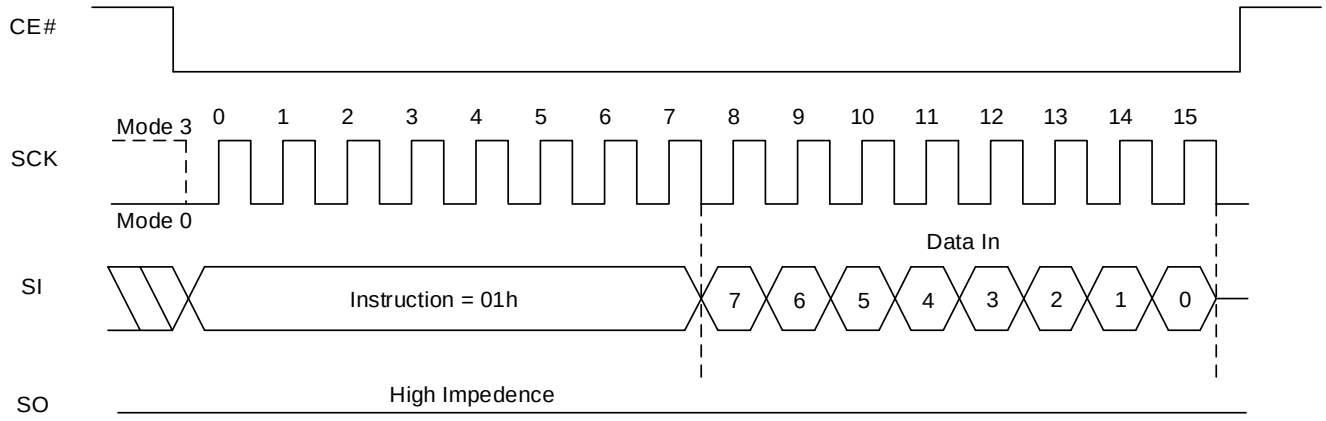
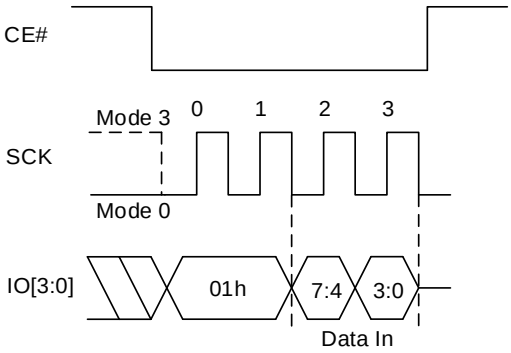



**Figure 8.48 Write Status Register Sequence In QPI Mode**



### 8.20 READ FUNCTION REGISTER OPERATION (RDFR, 48h)

The Read Function Register (RDFR) instruction provides access to the Function Register. Refer to Table 6.6 Function Register Bit Definition for more detail.

**Figure 8.49 Read Function Register Sequence In SPI Mode**

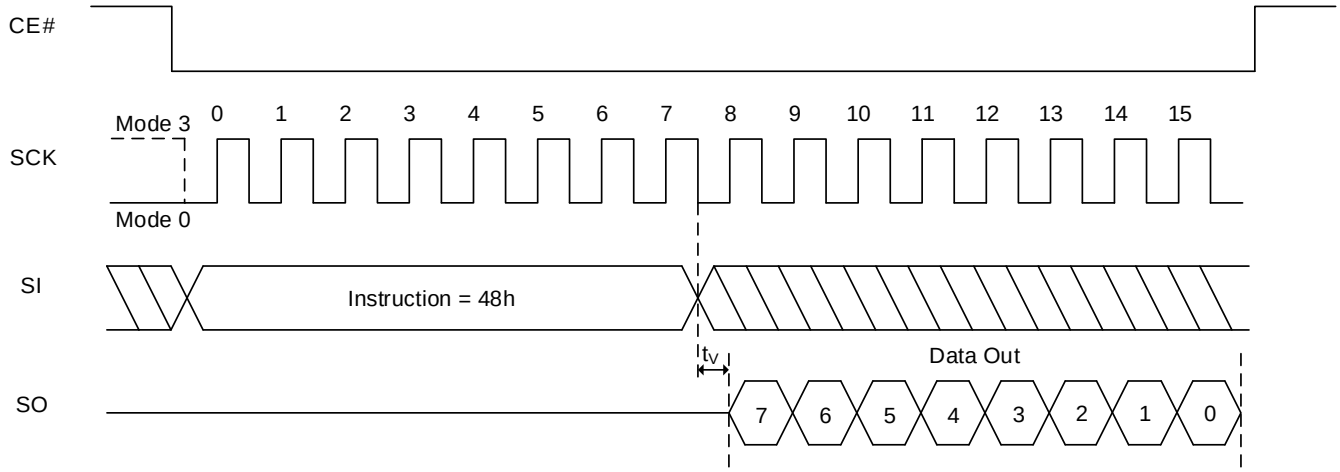
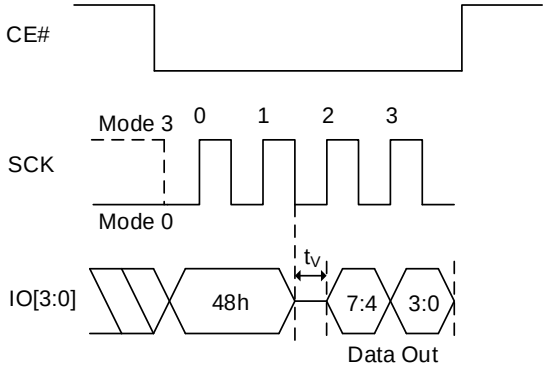



**Figure 8.50 Read Function Register Sequence In QPI Mode**



### 8.21 WRITE FUNCTION REGISTER OPERATION (WRFR, 42h)

The Write Function Register (WRFR) instruction allows the user to disable dedicated RESET# pin or ball on 16-pin SOIC or 24 ball TFBGA by setting Dedicated RESET# Disable bit to "1". Also Information Row Lock bits (IRL3~IRL0) can be set to "1" individually by WRFR instruction in order to lock Information Row.
Since Dedicated RESET# Disable bit and IRL bits are OTP, once they are set to "1", they cannot be set back to "0" again

**Figure 8.51 Write Function Register Sequence In SPI Mode**

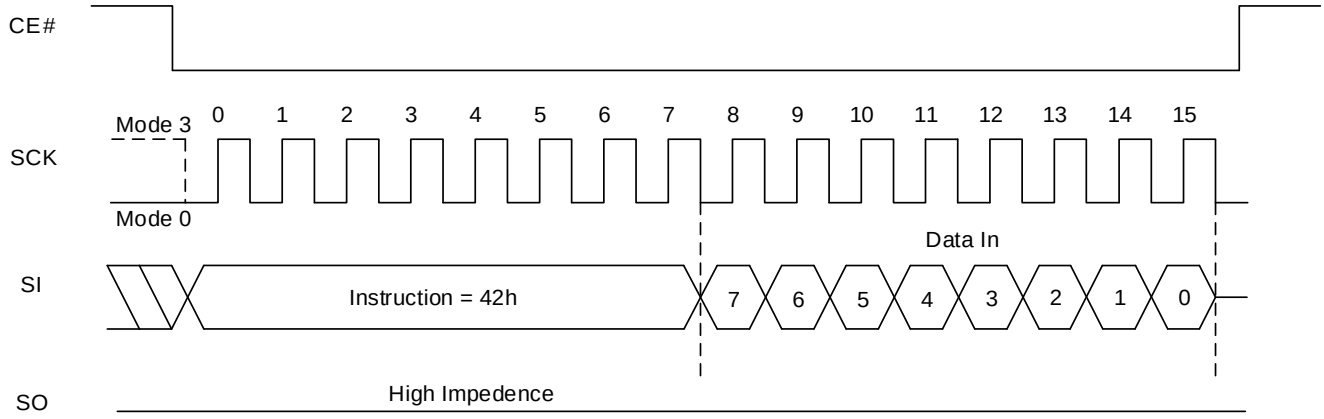
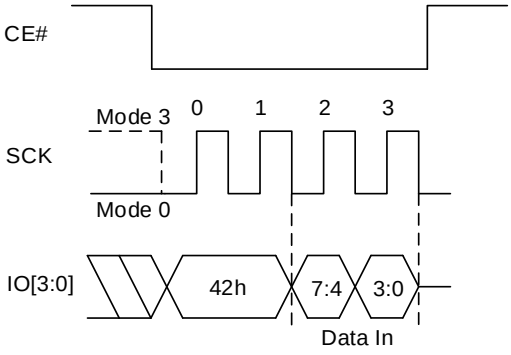



**Figure 8.52 Write Function Register Sequence In QPI Mode**



### 8.22 ENTER QUAD PERIPHERAL INTERFACE (QPI) MODE OPERATION (QPIEN, 35h; QPIDI,F5h)

The Enter QPI (QPIEN) instruction, 35h, enables the Flash device for QPI bus operation. Upon completion of the instruction, all instructions thereafter will be 4-bit multiplexed input/output until a power cycle or an Exit QPI instruction is sent to device.

The Exit QPI instruction, F5h, resets the device to 1-bit SPI protocol operation. To execute an Exit QPI operation, the host drives CE# low, sends the Exit QPI command cycle, then drives CE# high. The device just accepts QPI (2 clocks) command cycles.

**Figure 8.53 Enter Quad Peripheral Interface (QPI) Mode Sequence**

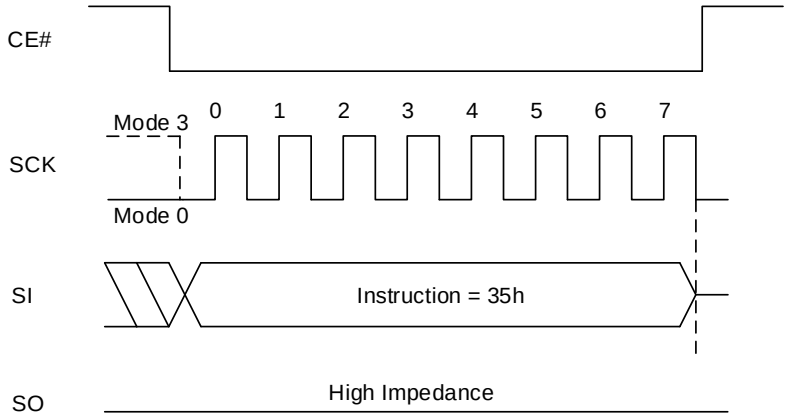
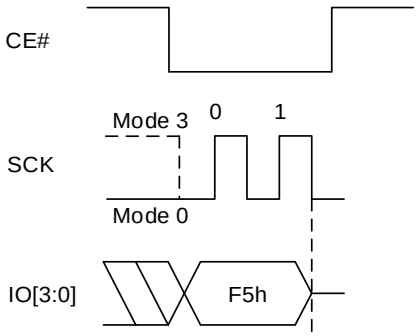



**Figure 8.54 Exit Quad Peripheral Interface (QPI) Mode Sequence**



### 8.23 PROGRAM/ERASE SUSPEND & RESUME

The device allows the interruption of Sector Erase, Block Erase, or Page Program operations to conduct other operations. 75h/B0h command for suspend and 7Ah/30h for resume will be used. (SPI/QPI all acceptable) Function Register bit2 (PSUS) and bit3 (ESUS) are used to check whether or not the device is in suspend mode.

Suspend to read ready timing ($t_{SUS}$): 100µs (TYP)
Resume to another suspend timing ($t_{RS}$): 400µs (TYP)

**SUSPEND DURING SECTOR-ERASE OR BLOCK-ERASE (PERSUS 75h/B0h)**
The Suspend command allows the interruption of Sector Erase and Block Erase operations. But Suspend command will be ignored during Chip Erase operation. After the Suspend command, other commands include array read operation can be accepted.

But Write Status Register command (01h) and Erase instructions are not allowed during Erase Suspend. Also, array read for being erased sector/block is not allowed.

To execute Erase Suspend operation, the host drives CE# low, sends the Suspend command cycle (75h/B0h), then drives CE# high. The Function Register indicates that the Erase has been suspended by setting the ESUS bit from "0" to "1", but the device will not accept another command until it is ready. To determine when the device will accept a new command, poll the WIP bit or wait the specified time $t_{SUS}$. When ESUS bit is set to "1", the Write Enable Latch (WEL) bit clears to "0".

**SUSPEND DURING PAGE PROGRAMMING (PERSUS 75h/B0h)**
The Suspend command also allows the interruption of all array Program operations. After the Suspend command, other commands include array read operation can be accepted can be accepted.

But Write Status Register instruction (01h) and Program instructions are not allowed during Program Suspend. Also, array read for being programmed page is not allowed.

To execute the Program Suspend operation, the host drives CE# low, sends the Suspend command cycle (75h/B0h), then drives CE# high. The Function Register indicates that the programming has been suspended by setting the PSUS bit from "0" to "1", but the device will not accept another command until it is ready. To determine when the device will accept a new command, poll the WIP bit or wait the specified time $t_{SUS}$. When PSUS bit is set to "1", the Write Enable Latch (WEL) bit clears to "0".

**PROGRAM/ERASE RESUME (PERRSM 7Ah/30h)**
The Program/Erase Resume restarts the Program or Erase command that was suspended, and clears the suspend status bit in the Function Register (ESUS or PSUS bits) to "0". To execute the Program/Erase Resume operation, the host drives CE# low, sends the Program/Erase Resume command cycle (7Ah/30h), then drives CE# high. A cycle is two nibbles long, most significant nibble first. To issue another Erase Suspend operation after Erase Resume operation, Erase Resume to another Erase Suspend delay (400us) is required, but it could require longer Erase time to complete Erase operation.

To determine if the internal, self-timed Write operation completed, poll the WIP bit.

**Table 8.6 Instructions accepted during Suspend**

| Operation Suspended | Instruction Allowed | | |
|---|---|---|---|
| | Name | Hex Code | Operation |
| Program or Erase | NORD | 03h | Normal Read Mode |
| Program or Erase | 4NORD | 13h | 4-byte Address Normal Read Mode |
| Program or Erase | FRD | 0Bh | Fast Read Mode |
| Program or Erase | 4FRD | 0Ch | 4-byte Address Fast Read Mode |
| Program or Erase | FRDIO | BBh | Fast Read Dual I/O |
| Program or Erase | 4FRDIO | BCh | 4-byte Address Fast Read Dual I/O |
| Program or Erase | FRDO | 3Bh | Fast Read Dual Output |
| Program or Erase | 4FRDO | 3Ch | 4-byte Address Fast Read Dual Output |
| Program or Erase | FRQIO | EBh | Fast Read Quad I/O |
| Program or Erase | 4FRQIO | ECh | 4-byte Address Fast Read Quad I/O |
| Program or Erase | FRQO | 6Bh | Fast Read Quad Output |
| Program or Erase | 4FRQO | 6Ch | 4-byte Address Fast Read Quad Output |
| Program or Erase | FRDTR | 0Dh | Fast Read DTR Mode |
| Program or Erase | 4FRDTR | 0Eh | 4-byte Address Fast Read DTR Mode |
| Program or Erase | FRDDTR | BDh | Fast Read Dual I/O DTR |
| Program or Erase | 4FRDDTR | BEh | 4-byte Address Fast Read Dual I/O DTR |
| Program or Erase | FRQDTR | EDh | Fast Read Quad I/O DTR |
| Program or Erase | 4FRQDTR | EEh | 4-byte Address Fast Read Quad I/O DTR |
| Program or Erase | WREN | 06h | Write Enable |
| Program or Erase | WRDI | 04hh | Write Disable |
| Program or Erase | RDSR | 05h | Read Status Register |
| Program or Erase | RDFR | 48h | Read Function Register |
| Program or Erase | RDBR | 16h/C8h | Read Bank Address Register |
| Program or Erase | RDRP | 61h | Read Read Parameters (Volatile) |
| Program or Erase | RDERP | 81h | Read Extended Read Parameters (Volatile) |
| Program or Erase | RDID | ABh | Read Manufacturer and Product ID |
| Program or Erase | RDJDID | 9Fh | Read Manufacturer and Product ID by JEDEC ID Command |
| Program or Erase | RDMDID | 90h | Read Manufacturer and Device ID |
| Program or Erase | RDJDIDQ | AFh | Read JEDEC ID QPI mode |
| Program or Erase | RDUID | 4Bh | Read Unique ID Number |
| Program or Erase | RDSFDP | 5Ah | SFDP Read |
| Program or Erase | CLERP | 82h | Clear Extended Read Register |

| Operation Suspended | Instruction Allowed | | |
|---|---|---|---|
| | Name | Hex Code | Operation |
| Program or Erase | PERRSM | 7Ah/30h | Program/Erase Resume |
| Program or Erase | SRPV | C0/63h | Set Read Parameters (Volatile) |
| Program or Erase | SERPV | 83h | Set Extended Read Parameters (Volatile) |
| Program or Erase | WRBRV | 17h/C5 | Write Bank Address Register (Volatile) |
| Program or Erase | EN4B | B7h | Enter 4-byte Address Mode |
| Program or Erase | EX4B | 29h | Exit 4-byte Address Mode |
| Program or Erase | RDPPB | FCh | Read PPB |
| Program or Erase | 4RDPPB | F2h | 4-byte Address Read PPB |
| Program or Erase | RDDYB | FAh | Read DYB |
| Program or Erase | 4RDDYB | E0h | 4-byte Address Read DYB |
| Program or Erase | RDPWD | E7h | Read Password |
| Program or Erase | RDPLB | A7h | Read PPB Lock Bit |
| Program or Erase | RDASP | 2Bh | Read ASP |
| Erase | SECLOCK | 24h | Sector Lock |
| Erase | SECUNLOCK | 26h | Sector Unlock |
| Erase | 4SECUNLOCK | 25h | 4-byte Address Sector Unlock |
| Erase | PERSUS | 75h/B0h | Program/Erase Suspend |
| Erase | PP | 02h | Serial Input Page Program |
| Erase | 4PP | 12h | 4-byte Address Serial Input Page Program |
| Erase | PPQ | 32h/38h | Quad Input Page Program |
| Erase | 4PPQ | 34h/3Eh | 4-byte Address Quad Input Page Program |
| Erase | WRDYB | FBh | Write DYB |
| Erase | 4WRDYB | E0h | 4-byte Address Write DYB |

### 8.24 ENTER DEEP POWER DOWN (DP, B9h)

The Deep Power-down (DP) instruction is for setting the device on the minimizing the power consumption (enter into Power-down mode). During this mode, standby current is reduced from $I_{sb1}$ to $I_{sb2}$. While in the Power-down mode, the device is not active and all Write/Program/Erase instructions are ignored. The instruction is initiated by driving the CE# pin low and shifting the instruction code into the device. The CE# pin must be driven high after the instruction has been latched, or Power-down mode will not engage. Once CE# pin driven high, the Power-down mode will be entered within the time duration of $t_{DP}$. While in the Power-down mode only the Release from Power-down/RDID instruction, which restores the device to normal operation, will be recognized. All other instructions are ignored, including the Read Status Register instruction which is always available during normal operation. Ignoring all but one instruction makes the Power Down state a useful condition for securing maximum write protection. It is available in both SPI and QPI mode.

**Figure 8.55 Enter Deep Power Down Mode Sequence**

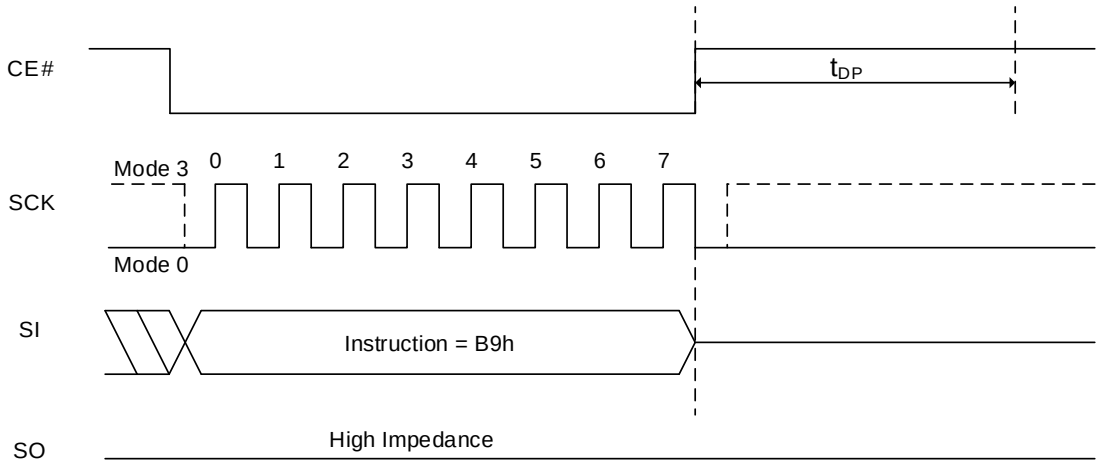
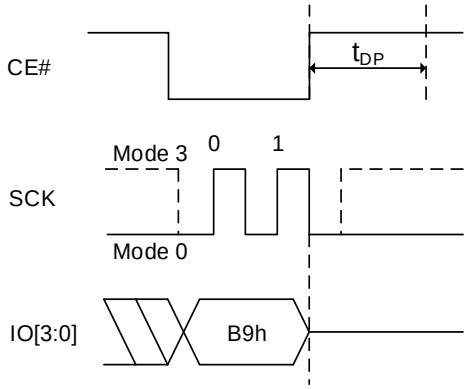



**Figure 8.56 Enter Deep Power Down Mode QPI Sequence**



### 8.25 RELEASE DEEP POWER DOWN (RDPD, ABh)

The Release Deep Power-down/Read Device ID instruction is a multi-purpose command. To release the device from the deep power-down mode, the instruction is issued by driving the CE# pin low, shifting the instruction code into the device and driving CE# high.

Releasing the device from Power-down mode will take the time duration of $t_{RES1}$ before normal operation is restored and other instructions are accepted. The CE# pin must remain high during the $t_{RES1}$ time duration. If the Release Deep Power-down/RDID instruction is issued while an Erase, Program or Write cycle is in progress (WIP=1) the instruction is ignored and will not have any effects on the current cycle.

**Figure 8.57 Release Power Down Mode Sequence In SPI Mode**

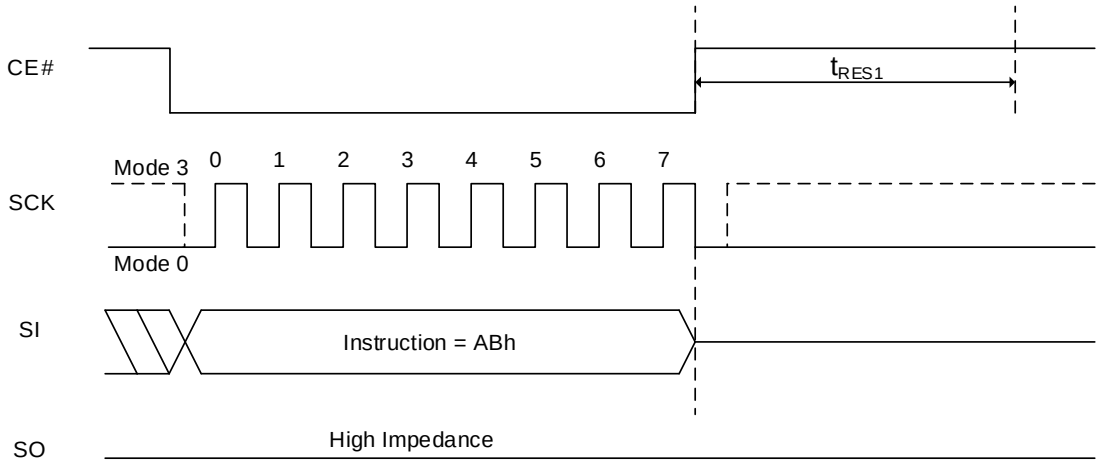
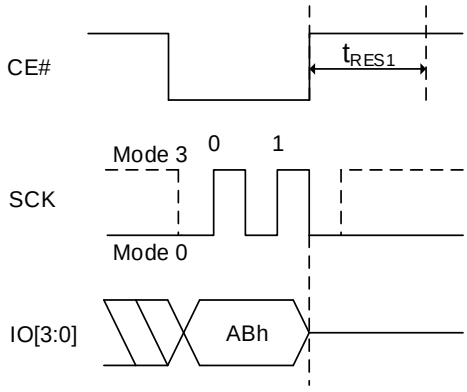



**Figure 8.58 Release Power Down Mode Sequence In QPI Mode**



## 8.26 SET READ PARAMETERS OPERATION (SRPNV: 65h, SRPV: C0h/63h)

### Set Read Parameter Bits

This device supports configurable burst length and dummy cycles in both SPI and QPI mode by setting three bits (P2, P1, P0) and four bits (P6, P5, P4, P3) within the Read Register, respectively. To set those bits the SRPNV and SRPV operation instruction are used. Details regarding burst length and dummy cycles can be found in Table 6.9, Table 6.10, and Table 6.11. HOLD#/RESET# function selection (P7) bit in the Read Register can be set with the SRPNV and SRPV operation as well, in order to select HOLD#/RESET# pin as RESET# or HOLD#.
For the device with dedicated RESET# pin (or ball), RESET# pin (or ball) will be a separate pin (or ball) and it is independent of the P7 bit setting in Read Register.
SRPNV is used to set the non-volatile Read Register, while SRPV is used to set the volatile Read Register.

To write non-volatile Read Parameter bits, a standard Write Enable (06h) instruction must previously have been executed for the device to accept SRPNV(65h) instruction (Status Register bit WEL must equal “1”).

To write volatile Read Parameter bits (SRPV), 63h or C0h command can be used.
When using 63h instruction, a standard Write Enable (06h) instruction must previously have been executed for the device to accept SRPV (63h) instruction (Status Register bit WEL must equal “1”).
But C0h instruction does not require a standard Write Enable (06h) operation. (Status Register bit WEL remains “0”).

**Note: When SRPNV is executed, the volatile Read Register is set as well as the non-volatile Read Register.**

**Figure 8.59 Set Read Parameters Sequence In SPI Mode**

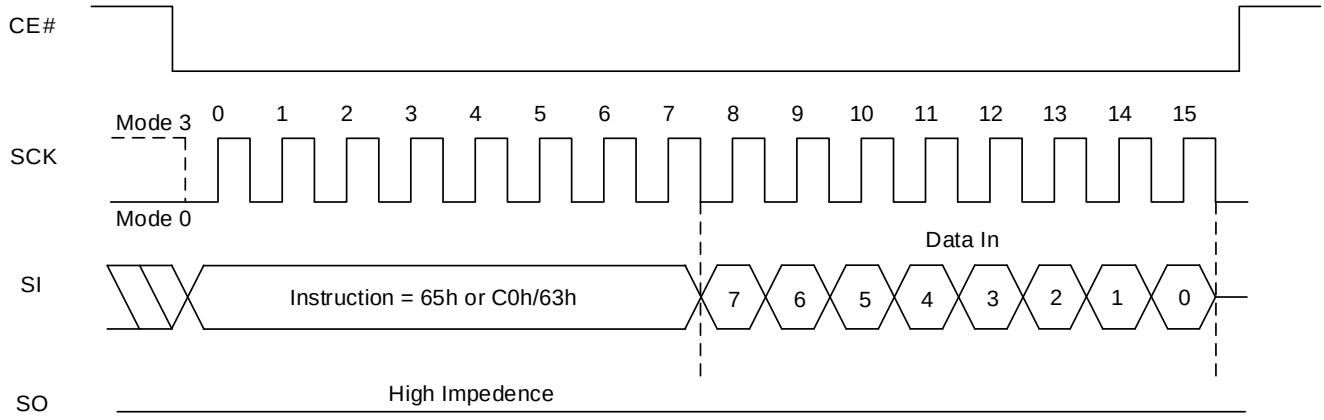
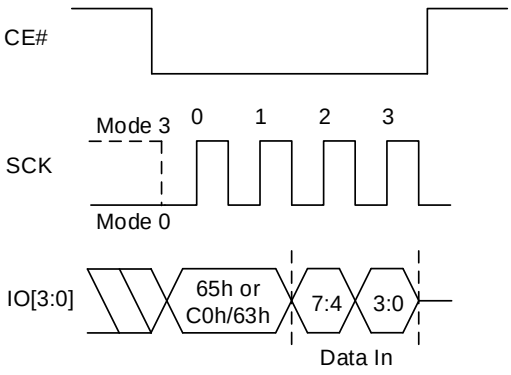



**Figure 8.60 Set Read Parameters Sequence In QPI Mode**



**Read with "8/16/32/64-Byte Wrap Around"**

The device is capable of burst read with wrap around in both SPI and QPI mode. The size of burst length is configurable by using P0, P1, and P2 bits in Read Register. P2 bit (Wrap enable) enables the burst mode feature. P0 and P1 define the size of burst. Burst lengths of 8, 16, 32, and 64 bytes are supported. By default, address increases by one up through the entire array. By setting the burst length, the data being accessed can be limited to the length of burst boundary within a 256 byte page. The first output will be the data at the initial address which is specified in the instruction. Following data will come out from the next address within the burst boundary. Once the address reaches the end of boundary, it will automatically move to the first address of the boundary. CE# high will terminate the command.

For example, if burst length of 8 and initial address being applied is 0h, following byte output will be from address 00h and continue to 01h,..,07h, 00h, 01h… until CE# terminates the operation. If burst length of 8 and initial address being applied is FEh(254d), following byte output will be from address FEh and continue to FFh, F8h, F9h, FAh, FBh, FCh, FDh, and repeat from FEh until CE# terminates the operation.

The commands, "SRPV (65h) or SRPNV (C0h or 63h)", are used to configure the burst length. If the following data input is one of "00h","01h","02h", and "03h", the device will be in default operation mode. It will be continuous burst read of the whole array. If the following data input is one of "04h","05h","06h", and "07h", the device will set the burst length as 8,16,32 and 64, respectively.

To exit the burst mode, another "C0h or 63h" command is necessary to set P2 to 0. Otherwise, the burst mode will be retained until either power down or reset operation. To change burst length, another "C0h or 63h" command should be executed to set P0 and P1 (Detailed information in Table 6.9 Burst Length Data). All read commands will operate in burst mode once the Read Register is set to enable burst mode.

Refer to Figure 8.59 and Figure 8.60 for instruction sequence.

## 8.27 SET EXTENDED READ PARAMETERS OPERATION (SERPNV: 85h, SERPV: 83h)

### Set Read Operational Driver Strength

This device supports configurable Operational Driver Strength in both SPI and QPI modes by setting three bits (ODS0, ODS1, ODS2) within the Extended Read Register. To set the ODS bits the SERPNV and SERPV operation instructions are required. The device's driver strength can be reduced as low as 12.50% of full drive strength. Details regarding the driver strength can be found in Table 6.14.

SERPNV is used to set the non-volatile Extended Read register, while SERPV is used to set the volatile Extended Read register.

**Notes:**
1. **The default driver strength is set to 50%.**
2. **When SERPNV is executed, the volatile Read Extended Register is set as well as the non-volatile Read Extended Register.**

**Figure 8.61 Set Extended Read Parameters Sequence In SPI Mode**

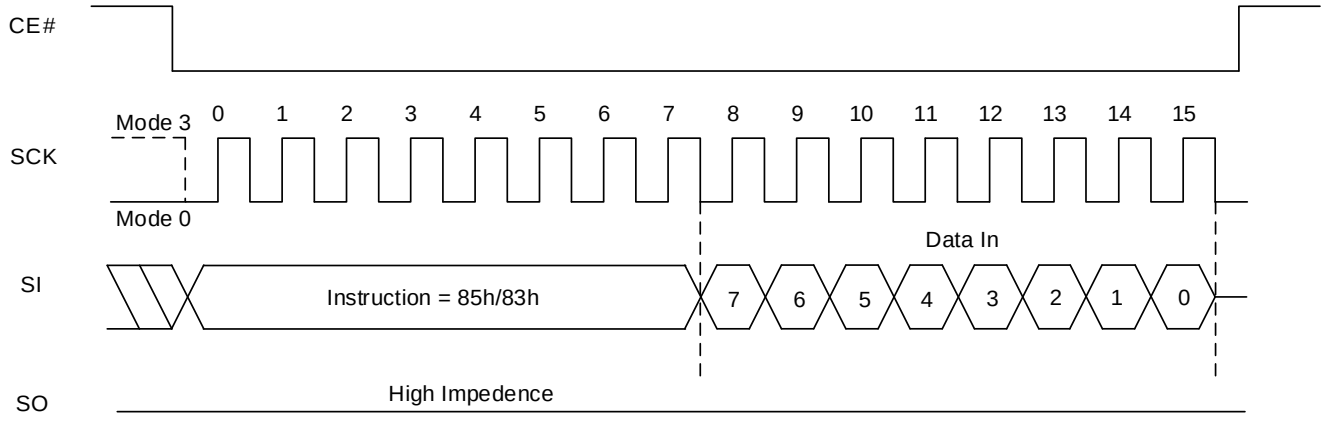
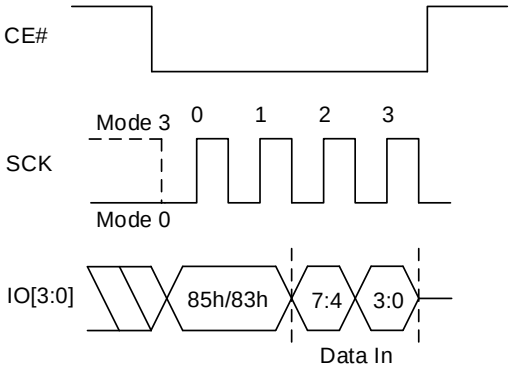



**Figure 8.62 Set Extended Read Parameters Sequence In QPI Mode**



### 8.28 READ READ PARAMETERS OPERATION (RDRP, 61h)

Prior to, or after setting Read Register, the data of the Read Register can be confirmed by the RDRP command. The instruction is only applicable for the volatile Read Register, not for the non-volatile Read Register.

**Figure 8.63 Read Read Parameters Sequence In SPI Mode**

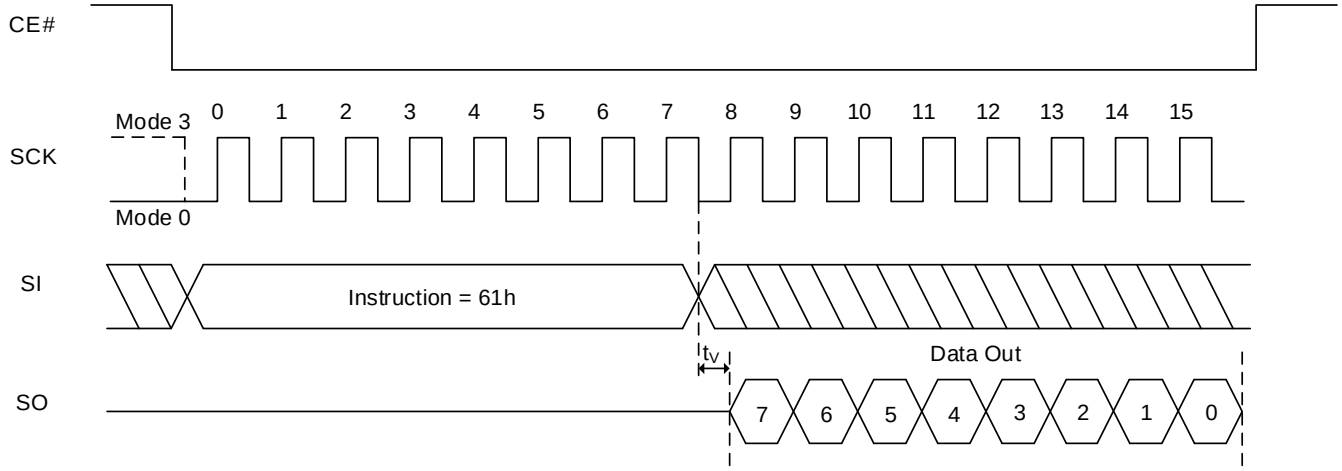
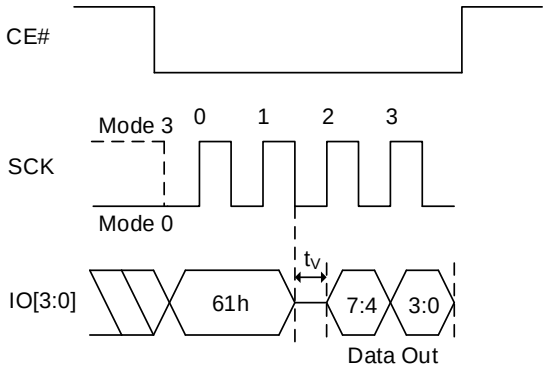



**Figure 8.64 Read Read Parameters Sequence In QPI Mode**



### 8.29 READ EXTENDED READ PARAMETERS OPERATION (RDERP, 81h)

Prior to, or after setting Extended Read Register, the data of the Extended Read Register can be confirmed by the RDERP command. The instruction is only applicable for the volatile Extended Read Register, not for the non-volatile Extended Read Register.

During the execution of a Program, Erase or Write Non-Volatile Register operation, the RDERP instruction will be executed, which can be used to check the progress or completion of an operation by reading the WIP bit.

**Figure 8.65 Read Extended Read Parameters Sequence In SPI Mode**

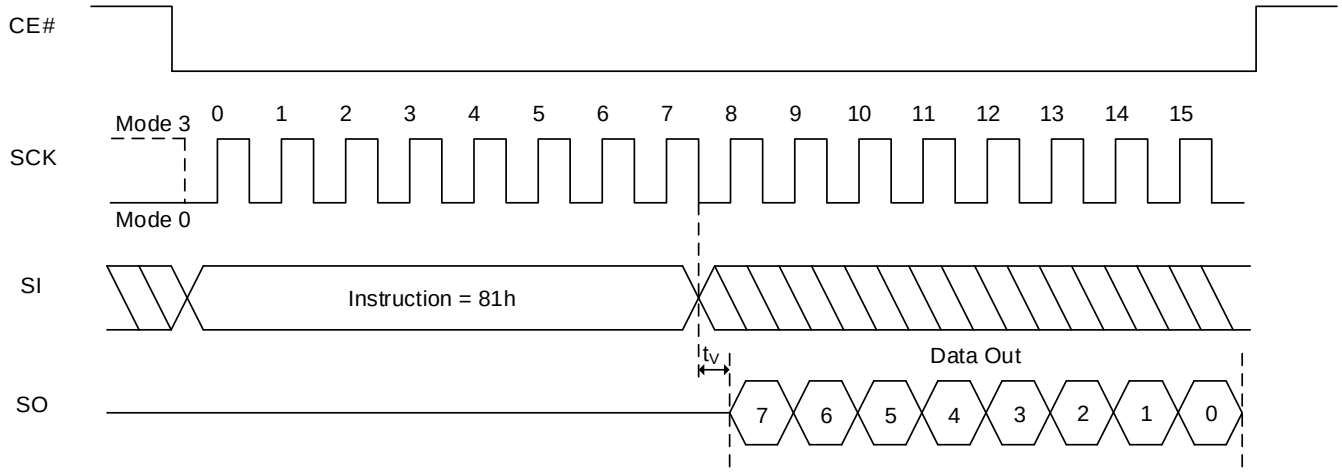
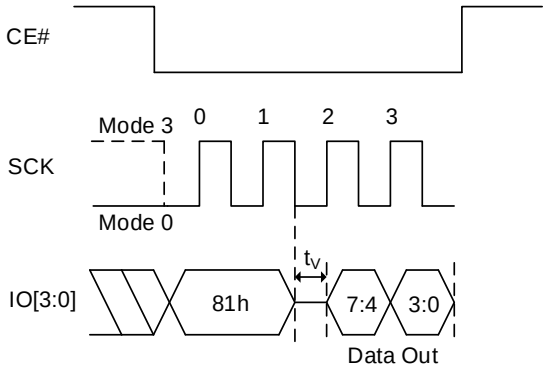



**Figure 8.66 Read Extended Read Parameters Sequence In QPI Mode**



### 8.30 CLEAR EXTENDED READ REGISTER OPERATION (CLERP, 82h)

A Clear Extended Read Register (CLERP) instruction clears PROT_E, P_ERR, and E_ERR error bits in the Extended Read Register to “0” when the error bits are set to “1”. Once the error bits are set to “1”, they remains set to “1” until they are cleared to “0” with a CLERP command.

**Figure 8.67 Clear Extended Read Register Sequence In SPI Mode**

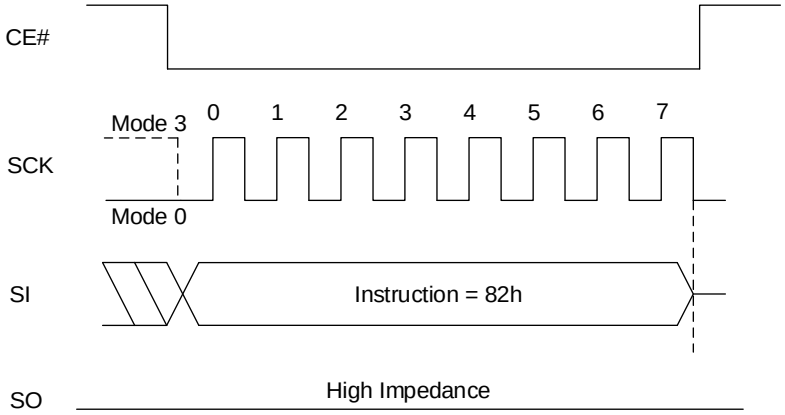
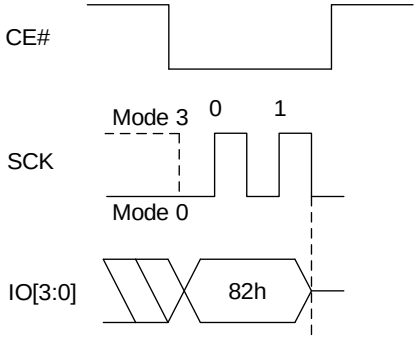



**Figure 8.68 Clear Extended Read Register Sequence In QPI Mode**



### 8.31 READ PRODUCT IDENTIFICATION (RDID, ABh)

The Release from Power-down/Read Device ID instruction is a multi-purpose instruction. It can support both SPI and QPI modes. The Read Product Identification (RDID) instruction is for reading out the old style of 8-bit Electronic Signature, whose values are shown as the table of Product Identification.

The RDID instruction code is followed by three dummy bytes, each bit being latched-in on SI during the rising SCK edge. Then the Device ID is shifted out on SO with the MSB first, each bit been shifted out during the falling edge of SCK. The RDID instruction is ended by driving CE# high. The Device ID (ID7-ID0) outputs repeatedly if additional clock cycles are continuously sent to SCK while CE# is at low.

**Table 8.7 Product Identification**

| **Manufacturer ID** | | **(MF7-MF0)** | |
|---|---|---|---|
| ISSI Serial Flash | | 9Dh | |
| **Instruction** | **ABh** | **90h** | **9Fh** |
| Part Number | Device ID (ID7-ID0) | | Memory Type + Capacity (ID15-ID0) |
| IS25LP128F | 17h | | 6018h |
| IS25WP128F | 17h | | 7018h |

**Figure 8.69 Read Product Identification Sequence**

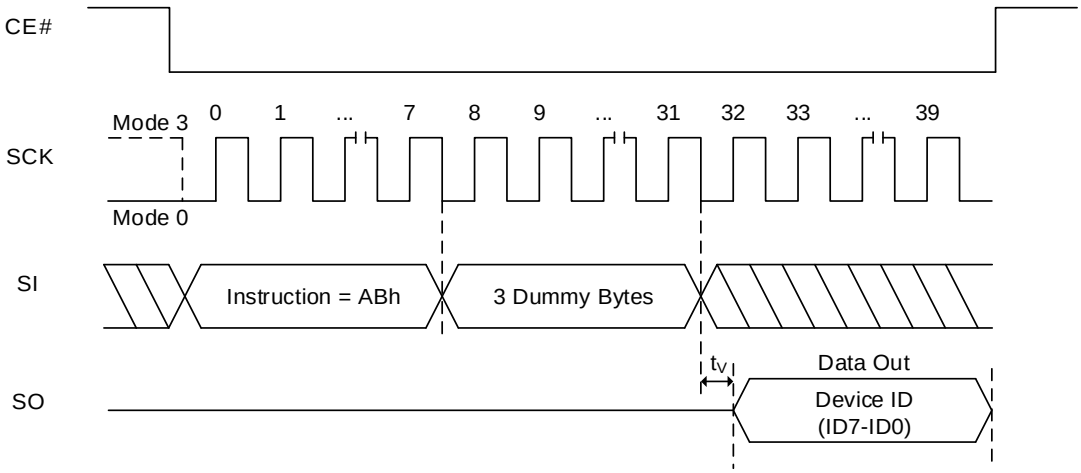
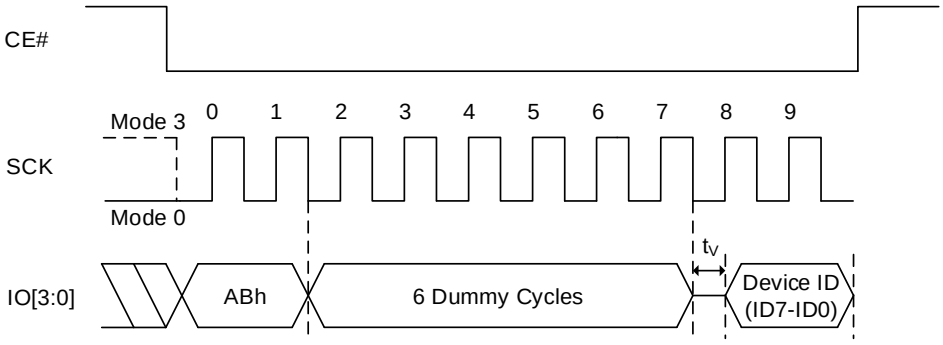


**Figure 8.70 Read Product Identification Sequence In QPI Mode**



### 8.32 READ PRODUCT IDENTIFICATION BY JEDEC ID OPERATION (RDJDID, 9Fh; RDJDIDQ, AFh)

The JEDEC ID READ instruction allows the user to read the manufacturer and product ID of devices. Refer to Table 8.7 Product Identification for Manufacturer ID and Device ID. After the JEDEC ID READ command (9Fh in SPI mode, AFh in QPI mode) is input, the Manufacturer ID is shifted out MSB first followed by the 2-byte electronic ID (ID15-ID0) that indicates Memory Type and Capacity, one bit at a time. Each bit is shifted out during the falling edge of SCK. If CE# stays low after the last bit of the 2-byte electronic ID, the Manufacturer ID and 2-byte electronic ID will loop until CE# is pulled high.

**Figure 8.71 Read Product Identification by JEDEC ID Read Sequence In SPI Mode**

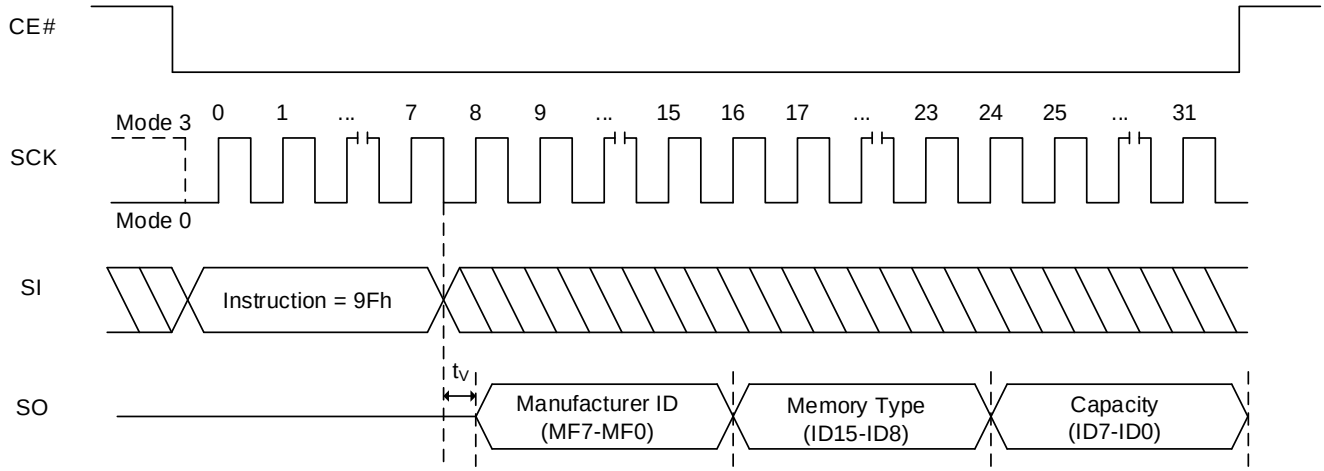
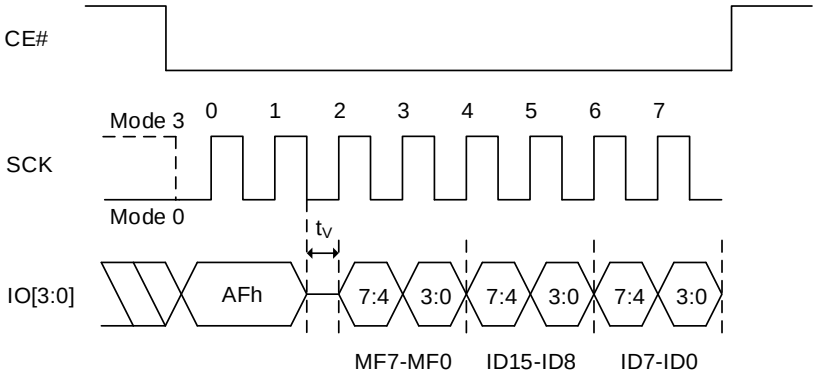


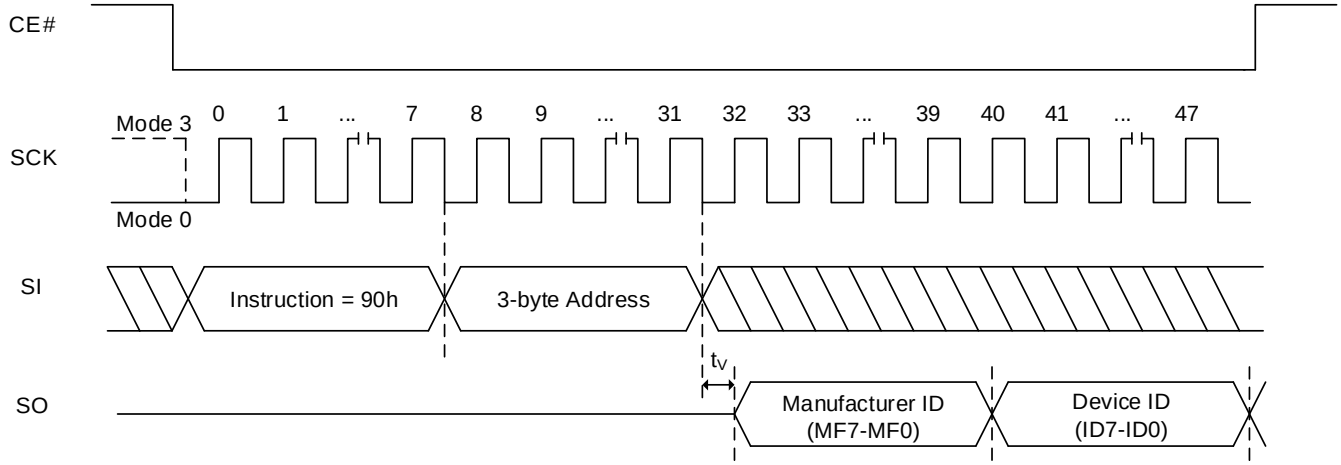

**Figure 8.72 RDJDID and RDJDIDQ (Read JEDEC ID) Sequence In QPI MOde**



### 8.33 READ DEVICE MANUFACTURER AND DEVICE ID OPERATION (RDMDID, 90h)

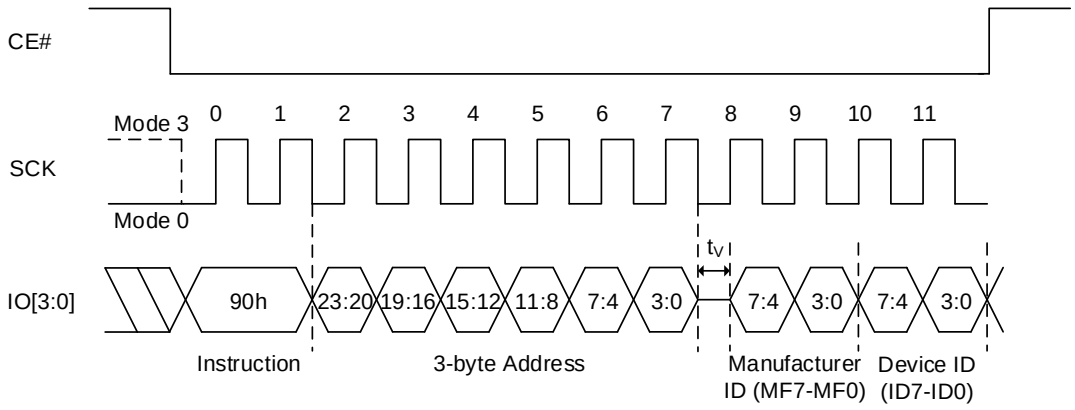
The Read Device Manufacturer and Device ID (RDMDID) instruction allows the user to read the Manufacturer and product ID of devices. Refer to Table 8.7 Product Identification for Manufacturer ID and Device ID. The RDMDID instruction code is followed by two dummy bytes and one byte address (A7~A0), each bit being latched-in on SI during the rising edge of SCK. If one byte address is initially set as A0 = 0, then the Manufacturer ID is shifted out on SO with the MSB first followed by the device ID (ID7- ID0). Each bit is shifted out during the falling edge of SCK. If one byte address is initially set as A0 = 1, then Device ID7-ID0 will be read first followed by the Manufacturer ID. The Manufacturer and Device ID can be read continuously alternating between the two until CE# is driven high.

**Figure 8.73 Read Product Identification by RDMDID Sequence In SPI Mode**




**Notes:**
1. **ADDRESS A0 = 0, will output the 1-byte Manufacturer ID (MF7-MF0) → 1-byte Device ID (ID7-ID0)**
   **ADDRESS A0 = 1, will output the 1-byte Device ID (ID7-ID0) → 1-byte Manufacturer ID (MF7-MF0)**
2. **The Manufacturer and Device ID can be read continuously and will alternate from one to the other until CE# pin is pulled high.**

**Figure 8.74 Read Product Identification by RDMDID Sequence In QPI Mode**




**Notes:**
1. **ADDRESS A0 = 0, will output the 1-byte Manufacturer ID (MF7-MF0) → 1-byte Device ID (ID7-ID0)**
   **ADDRESS A0 = 1, will output the 1-byte Device ID (ID7-ID0) → 1-byte Manufacturer ID (MF7-MF0)**
2. **The Manufacturer and Device ID can be read continuously and will alternate from one to the other until CE# pin is pulled high.**

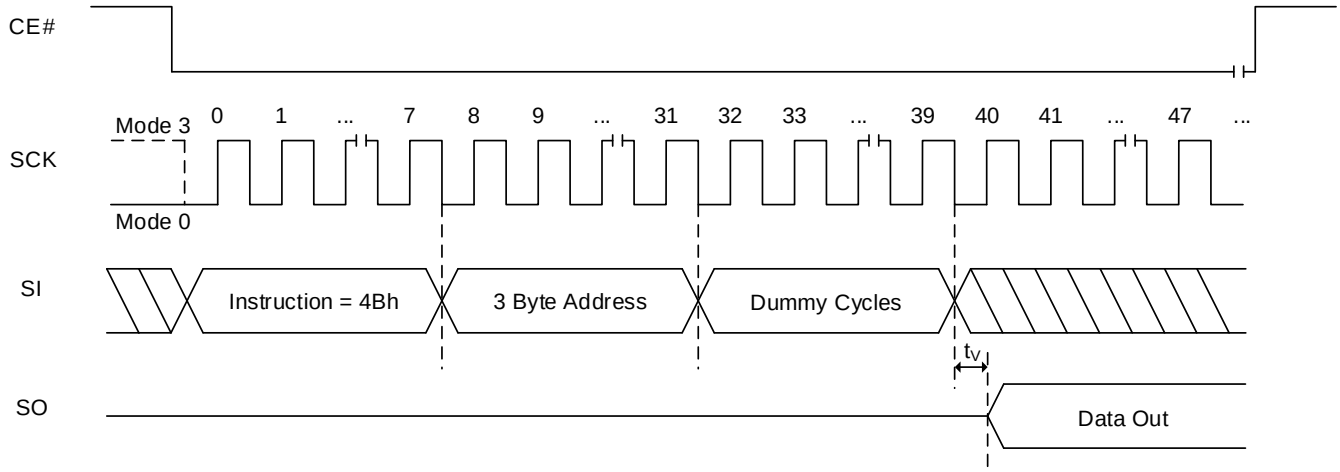
### 8.34 READ UNIQUE ID NUMBER (RDUID, 4Bh)

The Read Unique ID Number (RDUID) instruction accesses a factory-set read-only 16-byte number that is unique to the device. The ID number can be used in conjunction with user software methods to help prevent copying or cloning of a system. The RDUID instruction is instated by driving the CE# pin low and shifting the instruction code (4Bh) followed by 3 address bytes and dummy cycles (configurable, default is 8 clocks). After which, the 16-byte ID is shifted out on the falling edge of SCK as shown below.

As a result, the sequence of RDUID instruction is same as FAST READ. RDUID sequence in QPI mode is also same as FAST READ sequence in QPI mode except for the instruction code. Refer to the FAST READ operation in QPI mode.

**Note: 16 bytes of data will repeat as long as CE# is low and SCK is toggling.**

**Figure 8.75 RDUID Sequence In SPI Mode**




**Note: Dummy cycles depends on Read Parameter setting. Detailed information in Table 6.11 Read Dummy Cycles.**

**Table 8.8 Unique ID Addressing**

| A[23:16] | A[15:9] | A[8:4] | A[3:0] |
|---|---|---|---|
| XXh | XXh | 00h | 0h Byte address |
| XXh | XXh | 00h | 1h Byte address |
| XXh | XXh | 00h | 2h Byte address |
| XXh | XXh | 00h | ⋮ |
| XXh | XXh | 00h | Fh Byte address |

**Note: XX means "don't care".**

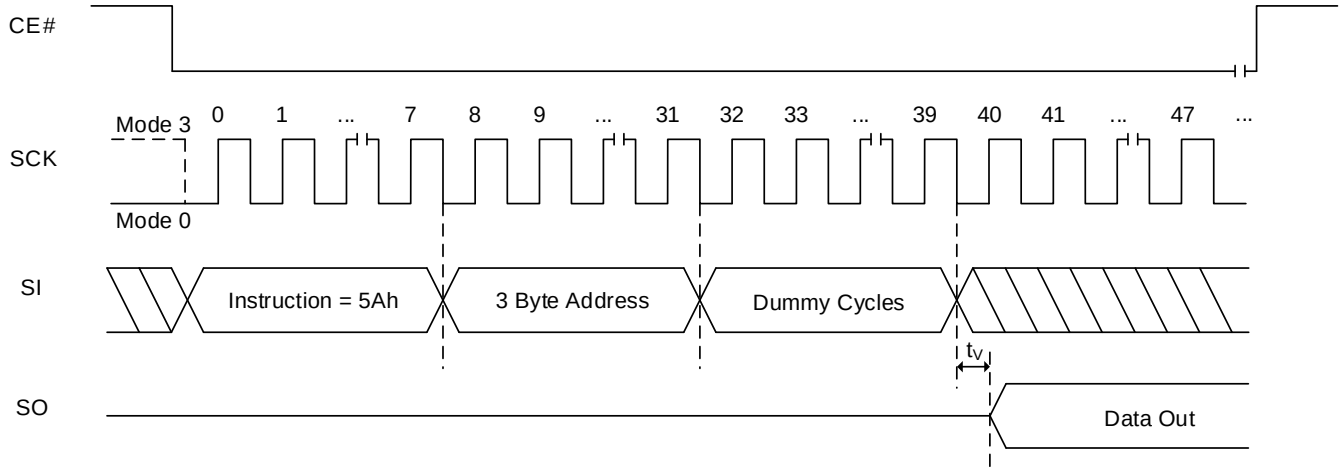
### 8.35 READ SFDP OPERATION (RDSFDP, 5Ah)

The Serial Flash Discoverable Parameters (SFDP) standard provides a consistent method of describing the functions and features of serial Flash devices in a standard set of internal parameter tables. These parameters can be interrogated by host system software to enable adjustments needed to accommodate divergent features from multiple vendors. For more details please refer to the JEDEC Standard JESD216 (Serial Flash Discoverable Parameters).

The sequence of issuing RDSFDP instruction in SPI mode is:

CE# goes low → Send RDSFDP instruction (5Ah) → Send 3 address bytes on SI pin → Read SFDP code on SO after dummy cycles (default 8 cycles) → End RDSFDP operation by driving CE# high at any time during data out.

**Figure 8.76 RDSFDP (Read SFDP) Sequence**




### 8.36 NO OPERATION (NOP, 00h)

The No Operation command solely cancels a Reset Enable command and has no impact on any other commands. It is available in both SPI and QPI modes. To execute a NOP, the host drives CE# low, sends the NOP command cycle (00H), then drives CE# high.

### 8.37 SOFTWARE RESET (RESET-ENABLE (RSTEN, 66h) AND RESET (RST, 99h)) AND HARDWARE RESET

The Software Reset operation is used as a system reset that puts the device in normal operating mode. During the Reset operation, the value of volatile registers will default back to the value in the corresponding non-volatile register. However, **the volatile FREEZE bit and the volatile PPB Lock bit in the PPB Lock Register are not changed by Software Reset**. This operation consists of two commands: Reset-Enable (RSTEN) and Reset (RST). The operation requires the Reset-Enable command followed by the Reset command. Any command other than the Reset command after the Reset-Enable command will disable the Reset-Enable.

Execute the CE# pin low → sends the Reset-Enable command (66h), and drives CE# high. Next, the host drives CE# low again, sends the Reset command (99h), and pulls CE# high.

Only if the RESET# pin is enabled, Hardware Reset function is available.
For the device with HOLD#/RESET#, the RESET# pin will be solely applicable in SPI mode and when the QE bit = "0". For the device with dedicated RESET# (Dedicated RESET**#** Disable bit is "0" in Function Register), the RESET**#** pin is always applicable regardless of the QE bit value in Status Register and HOLD#/RESET# selection bit (P7) in Read Register in SPI/QPI mode.

In order to activate Hardware Reset, the RESET# pin (or ball) must be driven low for a minimum period of $t_{RESET}$ (100ns). Drive RESET# low for a minimum period of $t_{RESET}$ will interrupt any on-going internal and external operations, release the device from deep power down mode[1]**,** disable all input signals, force the output pin enter a state of high impedance, and reset all the read parameters.
The required wait time after activating a HW Reset before the device will accept another instruction is $t_{HWRST}$ of 35us.

The Software/Hardware Reset during an active Program or Erase operation aborts the operation, which can result in corrupting or losing the data of the targeted address range. Depending on the prior operation, the reset timing may vary. Recovery from a Write operation will require more latency than recovery from other operations.

**Note1: The Status and Function Registers remain unaffected.**

**Figure 8.77 Software Reset Enable and Software Reset Sequence (RSTEN, 66h + RST, 99h)**

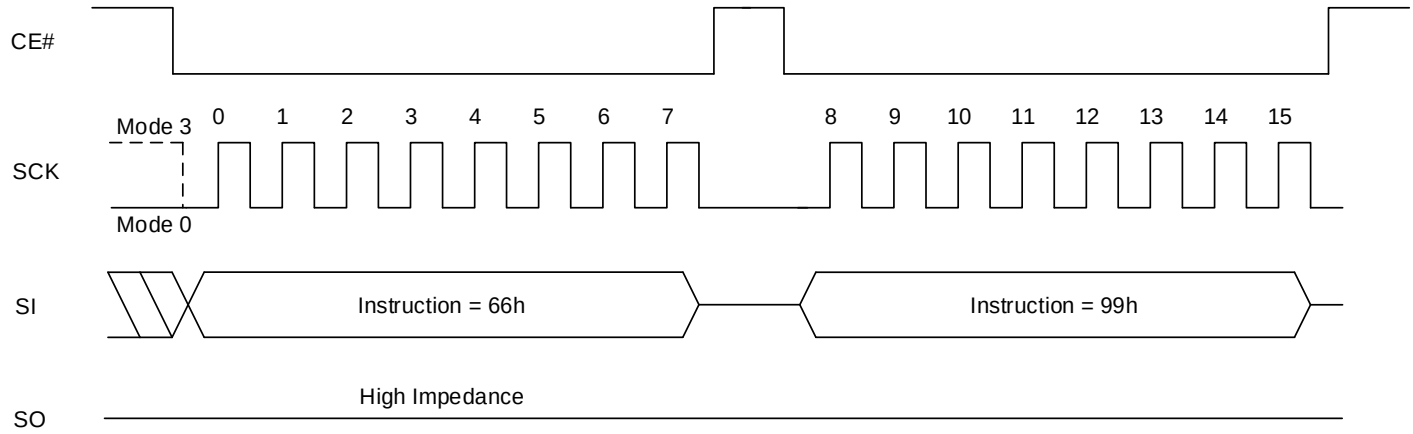
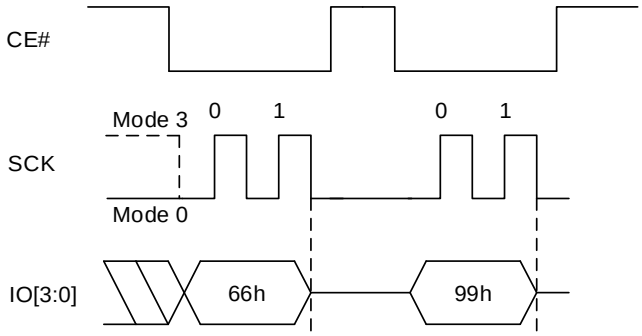


**Figure 8.78 Software Reset Enable and Software Reset QPI Sequence (RSTEN, 66h + RST, 99h)**




## 8.38 SECURITY INFORMATION ROW

The security Information Row is comprised of an additional 4 x 256 bytes of programmable information. The security bits can be reprogrammed by the user. Any program security instruction issued while an erase, program or write cycle is in progress is rejected without having any effect on the cycle that is in progress.

**Table 8.9 Information Row Valid Address Range**

| Address Assignment | A[23:16] | A[15:8] | A[7:0] |
|---|---|---|---|
| IRL0 (Information Row Lock0) | 00h | 00h | Byte address |
| IRL1 | 00h | 10h | Byte address |
| IRL2 | 00h | 20h | Byte address |
| IRL3 | 00h | 30h | Byte address |

Bit 7~4 of the Function Register is used to permanently lock the programmable memory array.

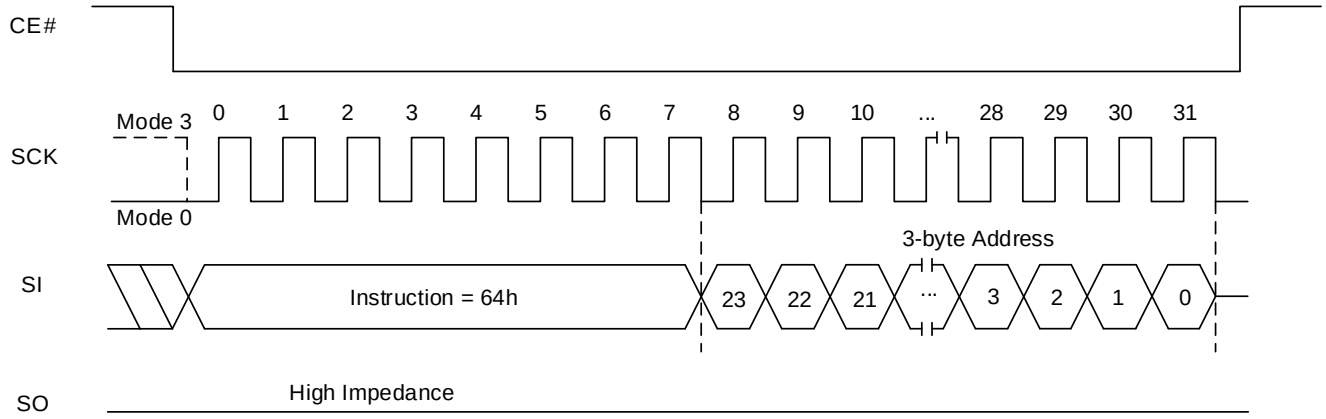
When Function Register bit IRLx = “0”, the 256 bytes of the programmable memory array can be programmed.
When Function Register bit IRLx = “1”, the 256 bytes of the programmable memory array function as read only.

### 8.39 INFORMATION ROW ERASE OPERATION (IRER, 64h)

Information Row Erase (IRER) instruction erases the data in the Information Row x (x: 0~3) array. Prior to the operation, the Write Enable Latch (WEL) must be set via a Write Enable (WREN) instruction. The WEL bit is automatically reset after the completion of the operation.

The sequence of IRER operation: Pull CE# low to select the device → Send IRER instruction code → Send three address bytes → Pull CE# high. CE# should remain low during the entire instruction sequence. Once CE# is pulled high, Erase operation will begin immediately. The internal control logic automatically handles the erase voltage and timing.

**Figure 8.79 IRER (Information Row Erase) Sequence**



### 8.40 INFORMATION ROW PROGRAM OPERATION (IRP, 62h)

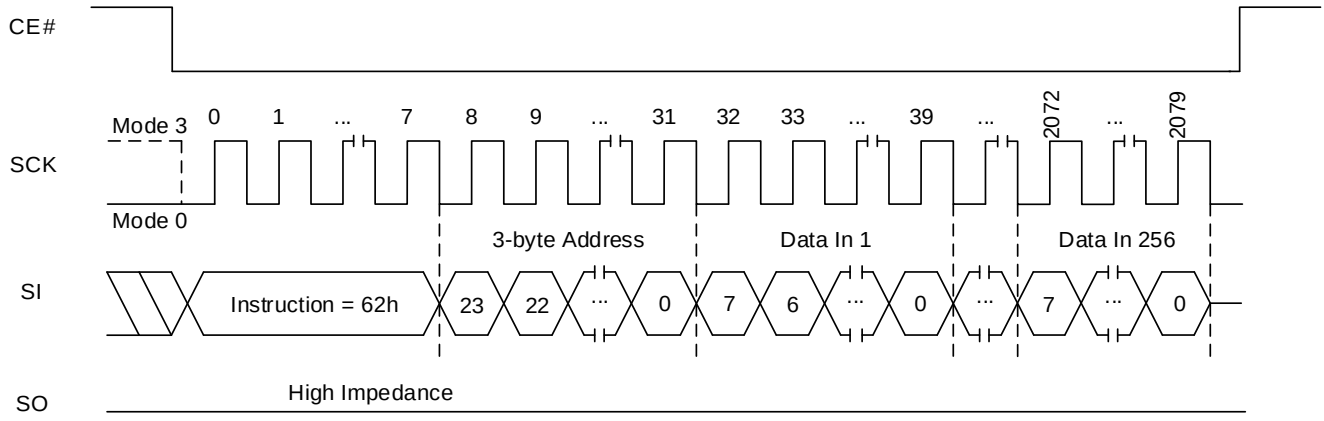
The Information Row Program (IRP) instruction allows up to 256 bytes data to be programmed into the memory in a single operation. Before the execution of IRP instruction, the Write Enable Latch (WEL) must be enabled through a Write Enable (WREN) instruction.

The IRP instruction code, three address bytes and program data (1 to 256 bytes) should be sequentially input. Three address bytes has to be input as specified in the Table 8.9 Information Row Valid Address Range. Program operation will start once the CE# goes high, otherwise the IRP instruction will not be executed. The internal control logic automatically handles the programming voltages and timing. During a program operation, all instructions will be ignored except the RDSR instruction. The progress or completion of the program operation can be determined by reading the WIP bit. If the WIP bit is "1", the program operation is still in progress. If WIP bit is "0", the program operation has completed.

If more than 256 bytes data are sent to a device, the address counter rolls over within the same page. The previously latched data are discarded and the last 256 bytes data are kept to be programmed into the page. The starting byte can be anywhere within the page. When the end of the page is reached, the address will wrap around to the beginning of the same page. If the data to be programmed are less than a full page, the data of all other bytes on the same page will remain unchanged.

**Note: A program operation can alter "1"s into "0"s, but an erase operation is required to change "0"s back to "1"s. A byte cannot be reprogrammed without first erasing the corresponding Information Row array which is one of IR0~3.**

**Figure 8.80 IRP (Information Row Program) Sequence**



### 8.41 INFORMATION ROW READ OPERATION (IRRD, 68h)

The IRRD instruction is used to read memory data at up to a 166MHz clock.

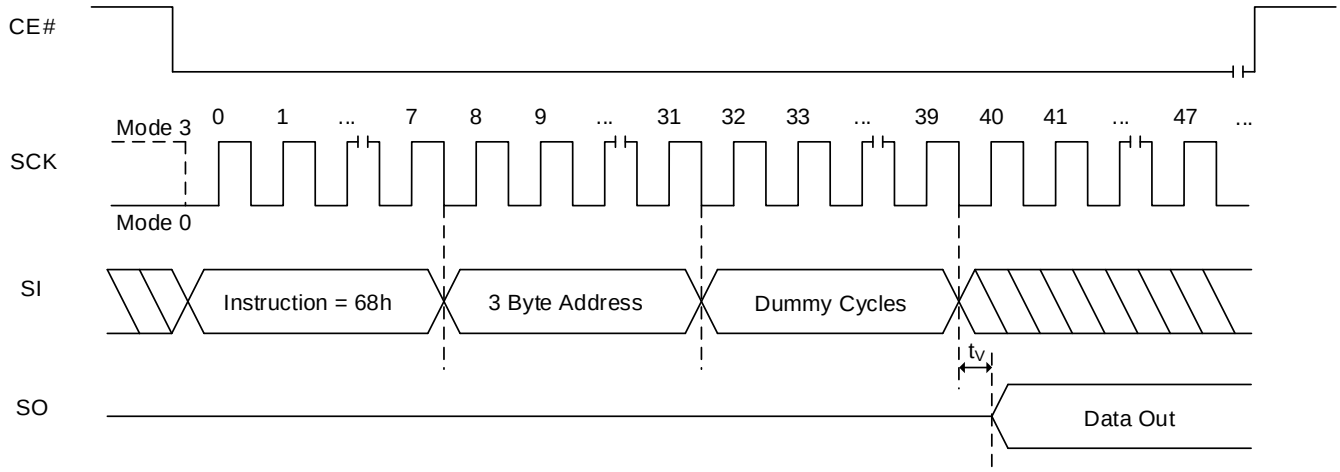
The IRRD instruction code is followed by three address bytes (A23 - A0) and dummy cycles (configurable, default is 8 clocks), transmitted via the SI line, with each bit latched-in during the rising edge of SCK. Then the first data byte addressed is shifted out on the SO line, with each bit shifted out at a maximum frequency $f_{CT}$, during the falling edge of SCK.

The address is automatically incremented by one after each byte of data is shifted out. Once the address reaches the last address of each 256 byte Information Row, the next address will not be valid and the data of the address will be garbage data. It is recommended to repeat four times IRRD operation that reads 256 byte with a valid starting address of each Information Row in order to read all data in the 4 x 256 byte Information Row array. The IRRD instruction is terminated by driving CE# high (VIH).

If an IRRD instruction is issued while an Erase, Program or Write cycle is in process (WIP=1) the instruction is ignored and will not have any effects on the current cycle

The sequence of IRRD instruction is same as Fast Read except for the instruction code. IRRD QPI sequence is same as Fast Read QPI except for the instruction code. Refer to the Fast Read QPI operation.

**Figure 8.81 IRRD (Information Row Read) Sequence**




**Note: Dummy cycles depends on Read Parameter setting. Detailed information in Table 6.11 Read Dummy Cycles.**

### 8.42 FAST READ DTR MODE OPERATION (FRDTR, 0Dh or 4FRDTR, 0Eh)

The FRDTR/4FRDTR instruction is for doubling the data in and out. Signals are triggered on both rising and falling edge of clock. The address is latched on both rising and falling edge of SCK, and data of each bit shifts out on both rising and falling edge of SCK. The 2-bit address can be latched-in at one clock, and 2-bit data can be read out at one clock, which means one bit at the rising edge of clock, the other bit at the falling edge of clock.

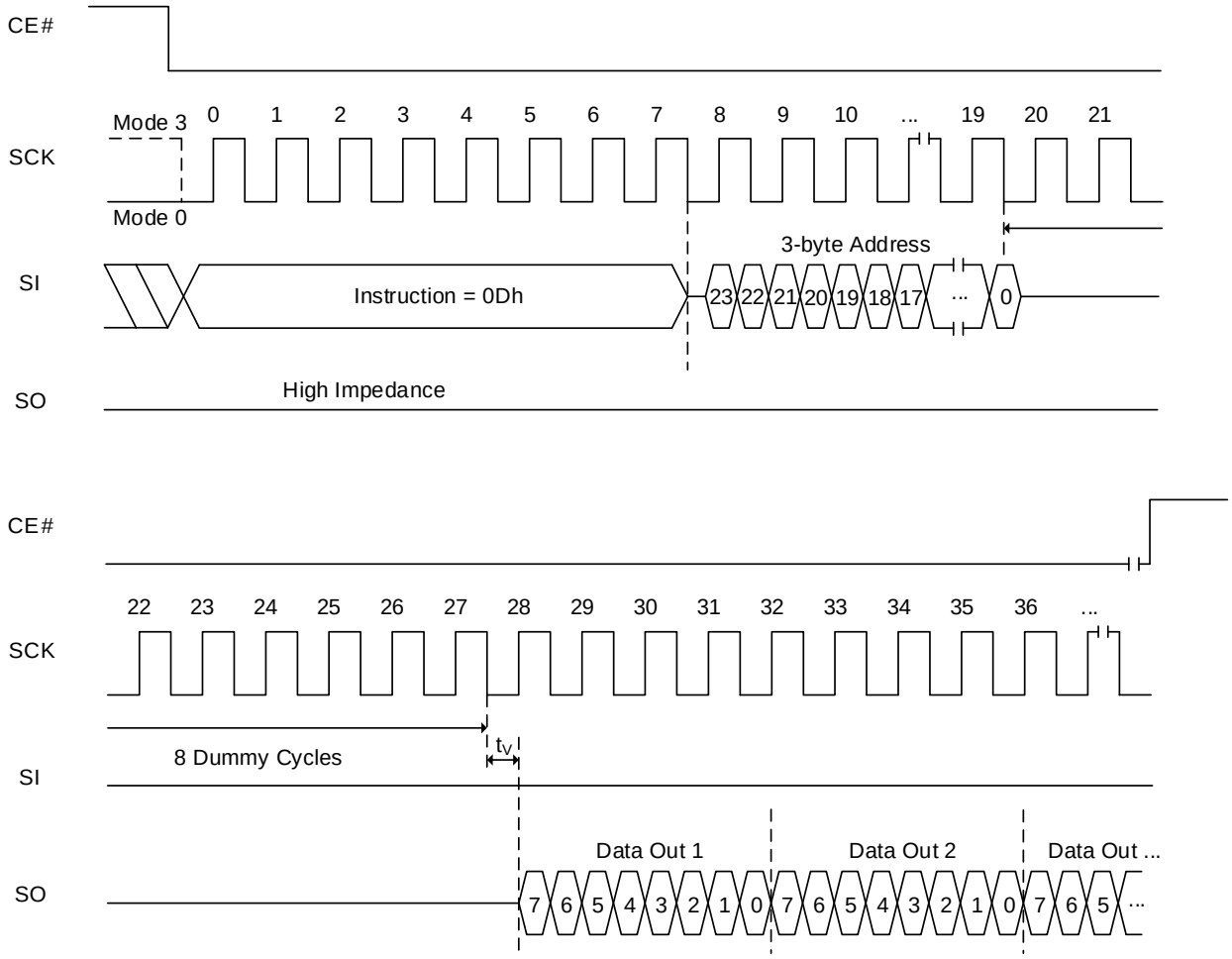
The first address byte can be at any location. The address is automatically increased to the next higher address after each byte of data is shifted out, so the whole memory can be read out in a single FRDTR/4FRDTR instruction. The address counter rolls over to 0 when the highest address is reached.

- 0Dh (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- 0Dh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- 0Eh is followed by a 4-byte address (A31-A0)

The sequence of issuing FRDTR/4FRDTR instruction is: CE# goes low → Sending FRDTR/4FRDTR instruction code (1bit per clock) → 3-byte or 4-byte address on SI (2-bit per clock) as above → 8 dummy clocks (configurable, default is 8 clocks) on SI → Data out on SO (2-bit per clock) → End FRDTR/4FRDTR operation via driving CE# high at any time during data out.

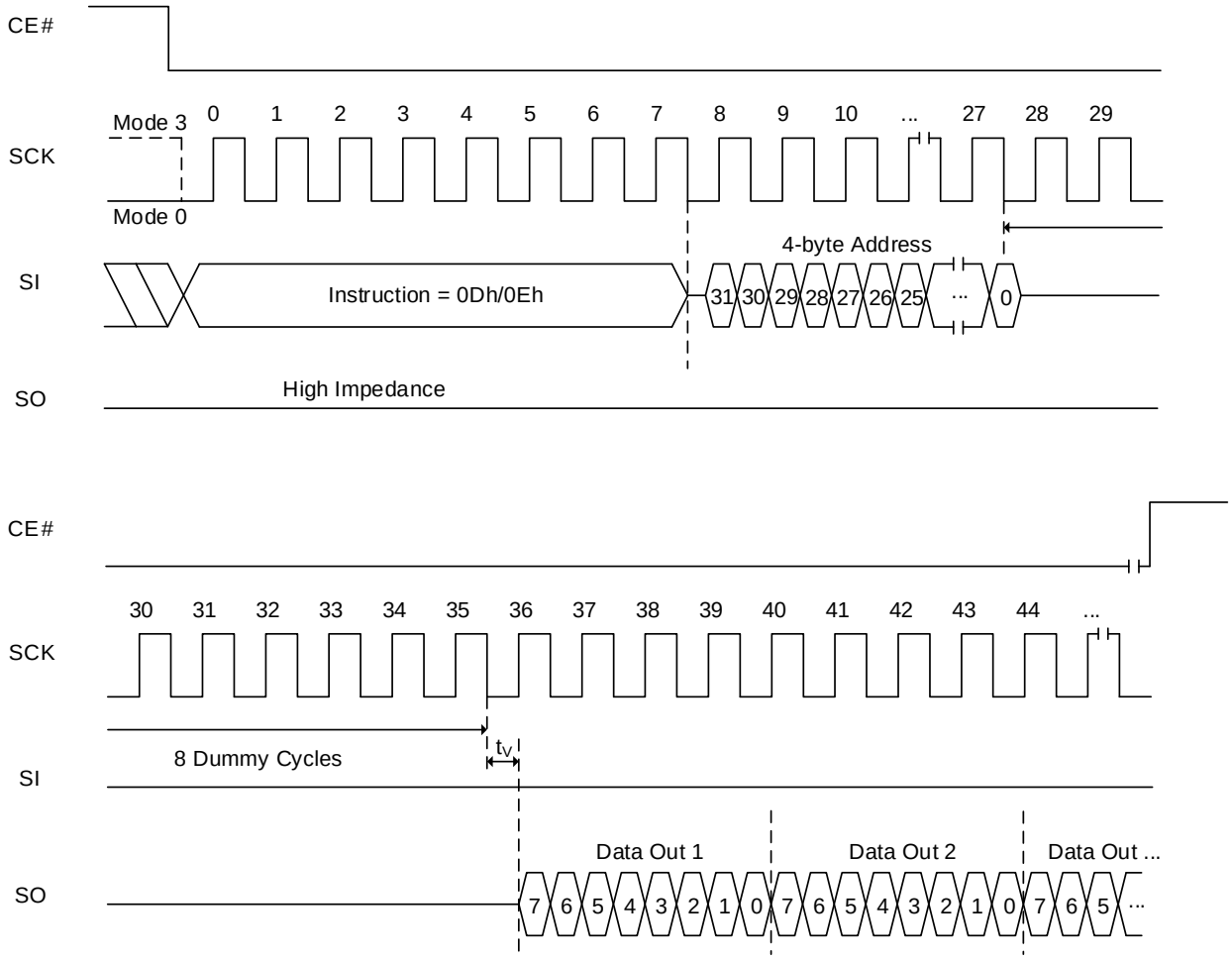
While a Program/Erase/Write Status Register cycle is in progress, FRDTR/4FRDTR instruction will be rejected without any effect on the current cycle.

**Figure 8.82 FRDTR Sequence (0Dh [EXTADD=0], 3-byte address)**




**Note: Dummy cycles depends on Read Parameter setting. Detailed information in Table 6.11 Read Dummy Cycles.**

**Figure 8.83 FRDTR Sequence (0Dh [EXTADD=1] or 0Eh, 4-byte address)**




**Note: Dummy cycles depends on Read Parameter setting. Detailed information in Table 6.11 Read Dummy Cycles.**

**FAST READ DTR MODE OPERATION IN QPI MODE (FRDTR, 0Dh or 4FRDTR, 0Eh)**

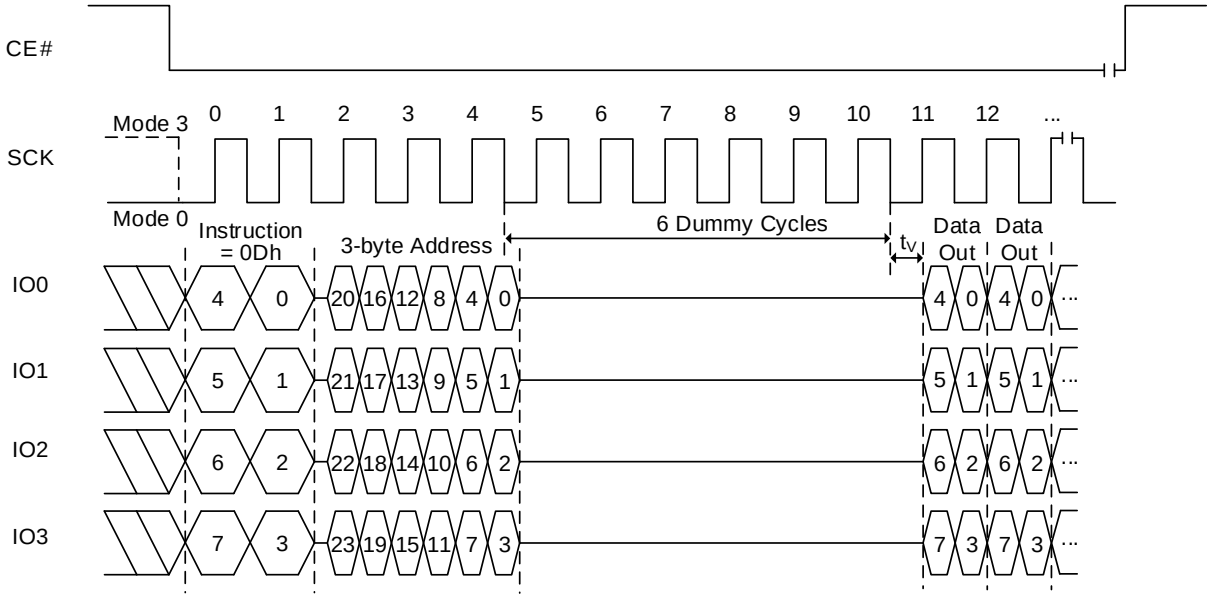
The FRDTR/4FRDTR instruction in QPI mode utilizes all four IO lines to input the instruction code so that only two clocks are required, while the FRDTR/4FRDTR instruction in SPI mode requires that the byte-long instruction code is shifted into the device only via IO0 (SI) line in eight clocks. In addition, subsequent address and data out are shifted in/out via all four IO lines unlike the FRDTR/4FRDTR instruction. Eventually this operation is same as the FRQDTR/4FRQDTR in QPI mode, but the only different thing is that AX mode is not available in the FRDTR/4FRDTR operation in QPI mode.

- 0Dh (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- 0Dh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- 0Eh is followed by a 4-byte address (A31-A0)

The sequence of issuing FRDTR/4FRDTR QPI instruction is: CE# goes low → Sending FRDTR/4FRDTR QPI instruction (4-bit per clock) → 24-bit or 32-bit address interleave on IO3, IO2, IO1 & IO0 (8-bit per clock) as above → 6 dummy clocks (configurable, default is 6 clocks) → Data out interleave on IO3, IO2, IO1 & IO0 (8-bit per clock) → End FRDTR/4FRDTR QPI operation by driving CE# high at any time during data out.

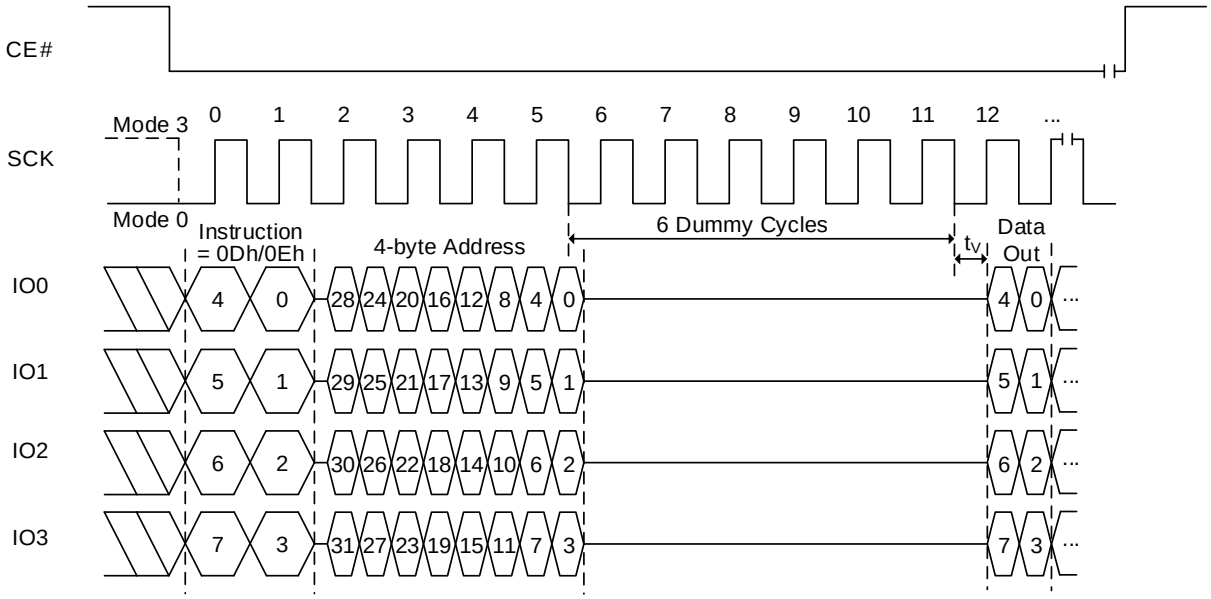
If the FRDTR/4FRDTR instruction in QPI mode is issued while an Erase, Program or Write cycle is in process is in progress (WIP=1), the instruction will be rejected without any effect on the current cycle.

**Figure 8.84 FRDTR Sequence In QPI Mode ( (0Dh [EXTADD=0], 3-byte address)**




**Notes:**
1. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
2. **Sufficient dummy cycles are required to avoid I/O contention.**

**Figure 8.85 FRDTR Sequence In QPI Mode (0Dh [EXTADD=1] or 0Eh, 4-byte address)**




**Notes:**
1. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
2. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

### 8.43 FAST READ DUAL IO DTR MODE OPERATION (FRDDTR, BDh or 4FRDDTR, BEh)

The FRDDTR/4FRDDTR instruction enables Double Transfer Rate throughput on dual I/O of the device in read mode. The address (interleave on dual I/O pins) is latched on both rising and falling edge of SCK, and the data (interleave on dual I/O pins) shift out on both rising and falling edge of SCK. The 4-bit address can be latched-in at one clock, and 4-bit data can be read out at one clock, which means two bits at the rising edge of clock, the other two bits at the falling edge of clock.

The first address byte can be at any location. The address is automatically increased to the next higher address after each byte of data is shifted out, so the whole memory can be read out with a single FRDDTR/4FRDDTR instruction. The address counter rolls over to 0 when the highest address is reached. Once writing FRDDTR/4FRDDTR instruction, the following address/dummy/data out will perform as 4-bit instead of previous 1-bit.

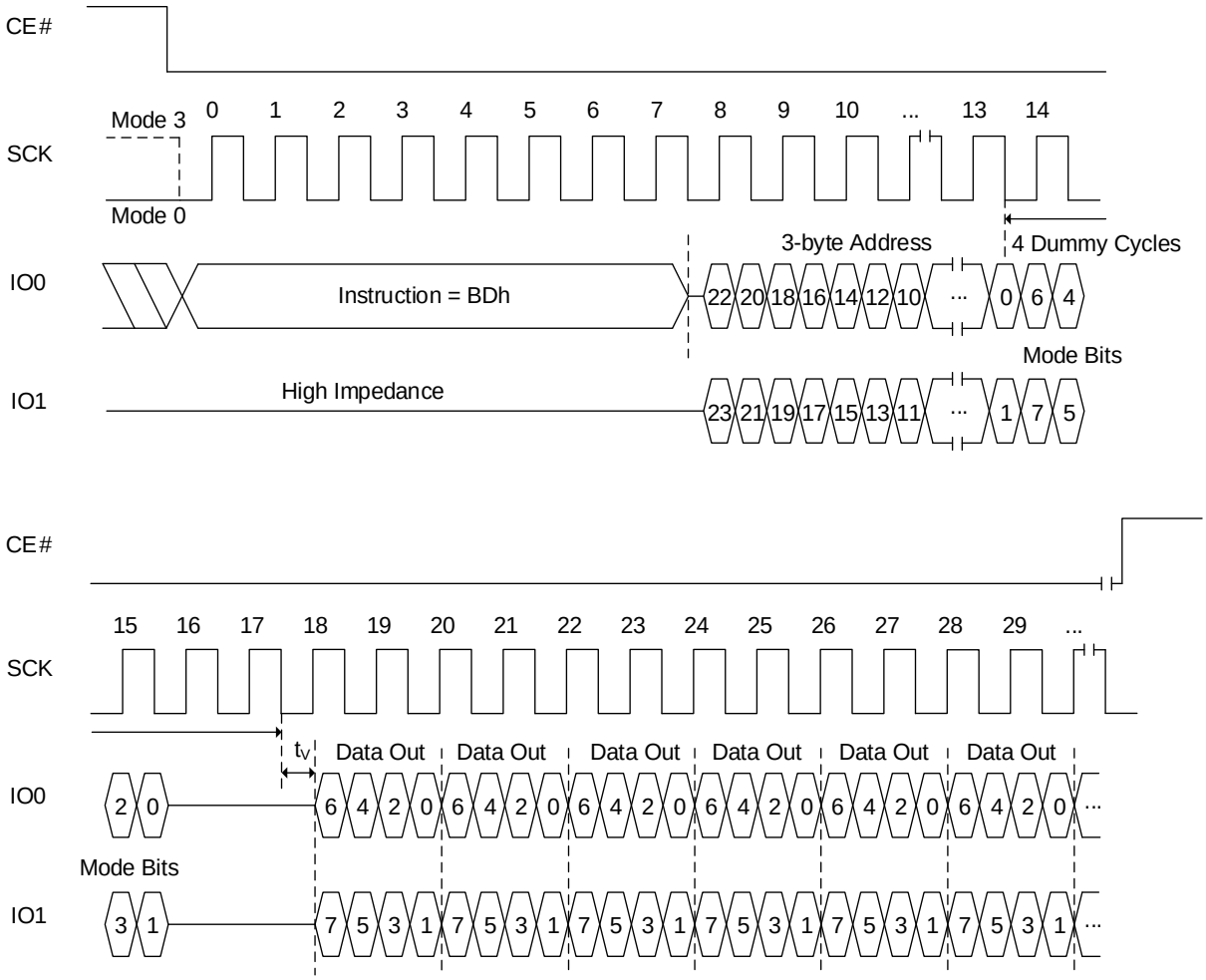
- BDh (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- BDh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- BEh is followed by a 4-byte address (A31-A0)

The sequence of issuing FRDDTR/4FRDDTR instruction is: CE# goes low → Sending FRDDTR/4FRDDTR instruction (1-bit per clock) → 24-bit or 32-bit address interleave on IO1 & IO0 (4-bit per clock) as above → 4 dummy clocks (configurable, default is 4 clocks) on IO1 & IO0 → Data out interleave on IO1 & IO0 (4-bit per clock) → End FRDDTR/4FRDDTR operation via pulling CE# high at any time during data out (Please refer to Figures 8.86 and 8.87 for 2 x I/O Double Transfer Rate Read Mode Timing Waveform).

If AXh (where X is don't care) is input for the mode bits during dummy cycles, the device will enter AX read operation mode which enables subsequent FRDDTR/4FRDDTR execution skips command code. It saves cycles as described in Figures 8.88 and 8.89. When the code is different from AXh (where X is don't care), the device exits the AX read operation. After finishing the read operation, device becomes ready to receive a new command.

If the FRDDTR/4FRDDTR instruction is issued while an Erase, Program or Write cycle is in process is in progress (WIP=1), the instruction will be rejected without any effect on the current cycle.

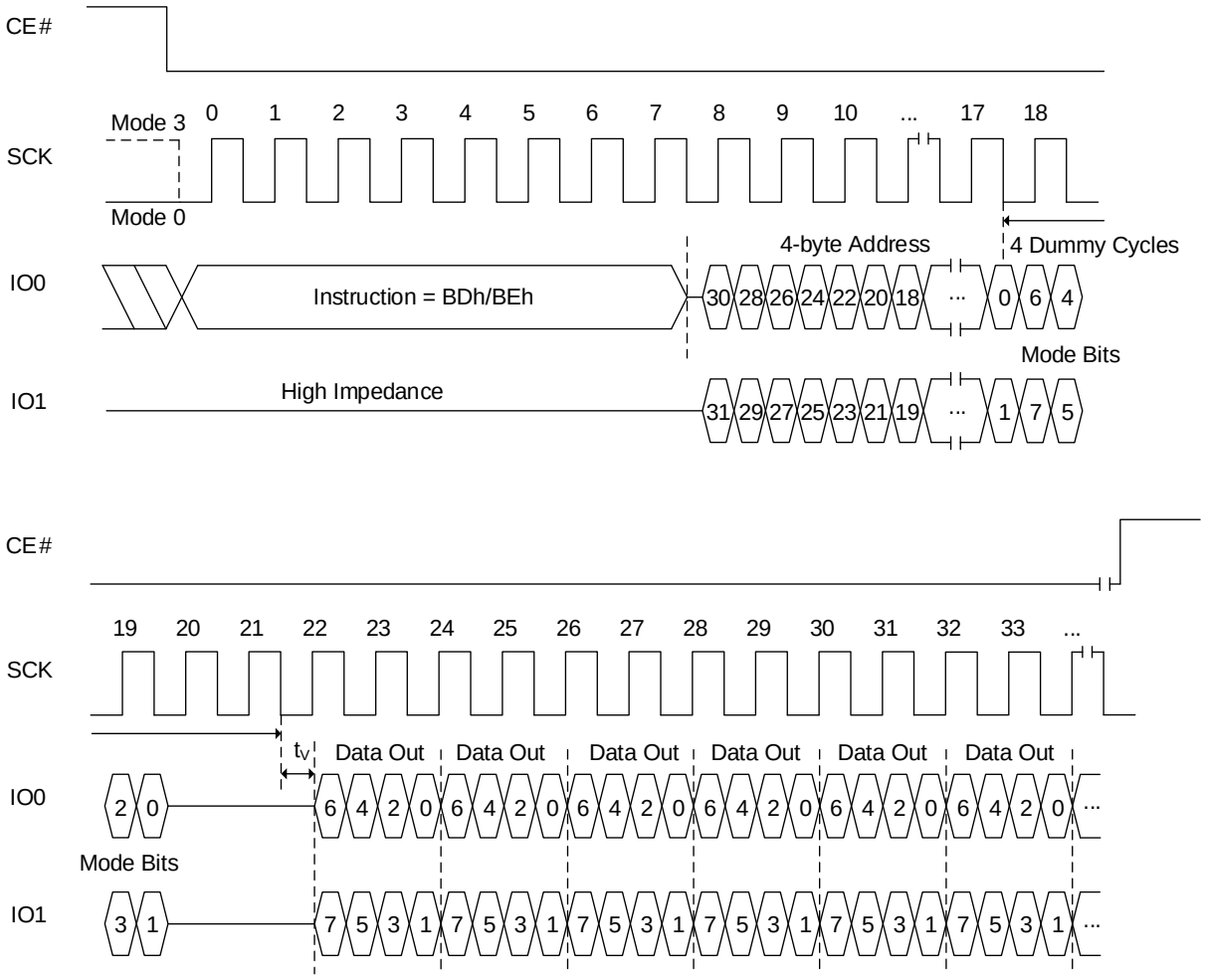
**Figure 8.86 FRDDTR Sequence (BDh [EXTADD=0], 3-byte address)**




**Notes:**

1. **If the mode bits=AXh (where X is don't care), it can execute the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

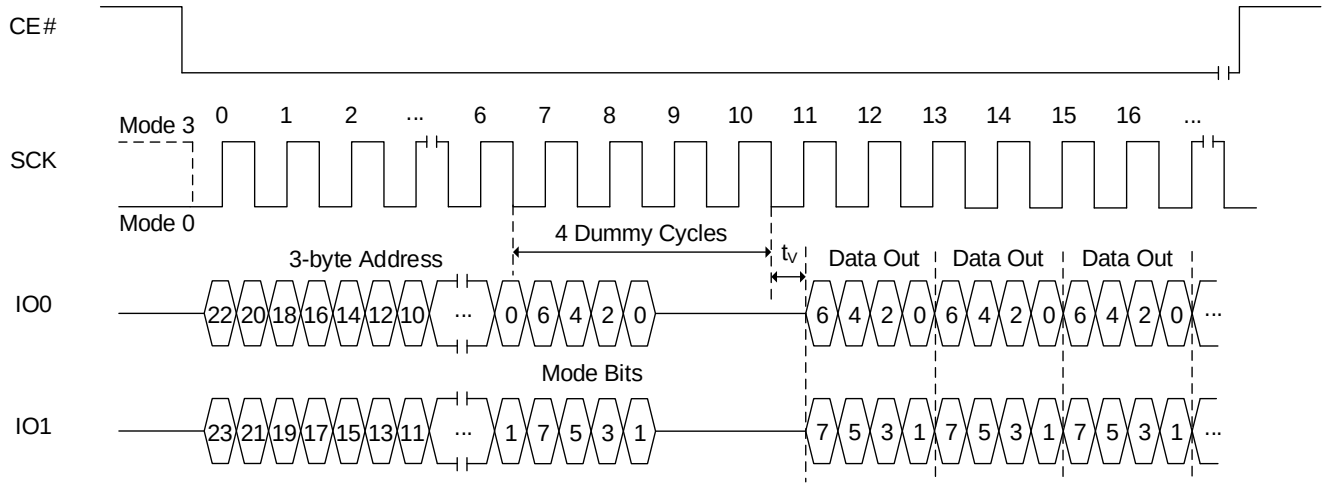
**Figure 8.87 FRDDTR Sequence (BDh [EXTADD=1] or BEh, 4-byte address)**




**Notes:**

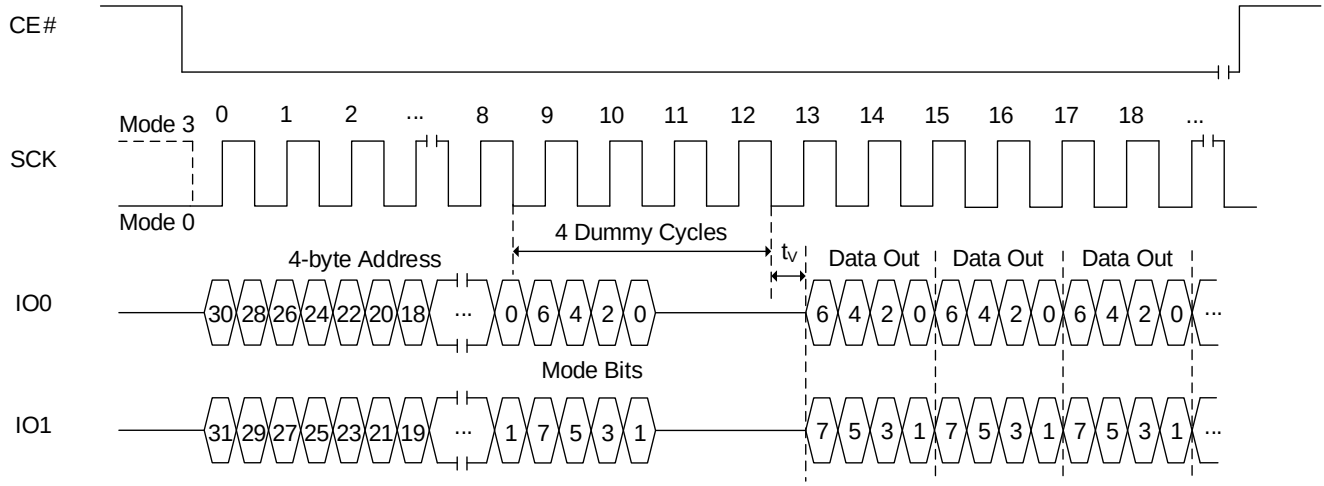
1. **If the mode bits=AXh (where X is don't care), it can execute the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

**Figure 8.88 FRDDTR AX Read Sequence (BDh [EXTADD=0], 3-byte address)**




**Notes:**
1. **If the mode bits=AXh (where X is don't care), it will keep executing the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

**Figure 8.89 FRDDTR AX Read Sequence (BDh [EXTADD=1] or BEh, 4-byte address)**




**Notes:**
1. **If the mode bits=AXh (where X is don't care), it will keep executing the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

### 8.44 FAST READ QUAD IO DTR MODE OPERATION IN SPI MODE (FRQDTR, EDh or 4FRQDTR, EEh)

The FRQDTR/4FRQDTR instruction enables Double Transfer Rate throughput on quad I/O of the device in read mode. The address (interleave on 4 I/O pins) is latched on both rising and falling edge of SCK, and data (interleave on 4 I/O pins) shift out on both rising and falling edge of SCK. The 8-bit address can be latched-in at one clock, and 8-bit data can be read out at one clock, which means four bits at the rising edge of clock, the other four bits at the falling edge of clock.

The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out with a single FRQDTR/4FRQDTR instruction. The address counter rolls over to 0 when the highest address is reached. Once writing FRQDTR/4FRQDTR instruction, the following address/dummy/data out will perform as 8-bit instead of previous 1-bit.

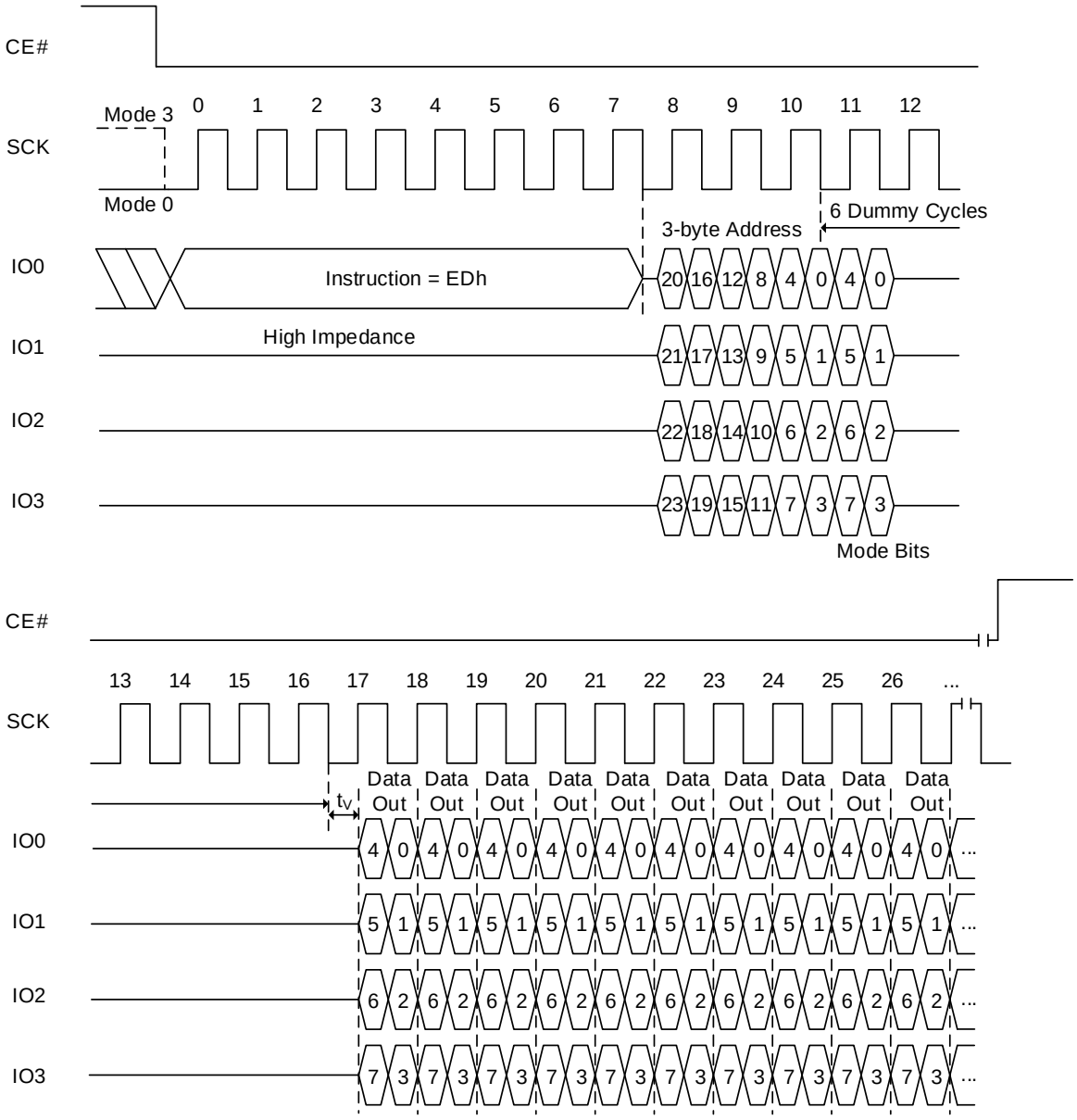
- EDh (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- EDh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- EEh is followed by a 4-byte address (A31-A0)

The sequence of issuing FRQDTR/4FRQDTR instruction is: CE# goes low → Sending FRQDTR/4FRQDTR instruction (1-bit per clock) → 24-bit or 32-bit address interleave on IO3, IO2, IO1 & IO0 (8-bit per clock) as above → 6 dummy clocks (configurable, default is 6 clocks) → Data out interleave on IO3, IO2, IO1 & IO0 (8-bit per clock) → End FRQDTR/4FRQDTR operation by driving CE# high at any time during data out.

If AXh (where X is don't care) is input for the mode bits during dummy cycles, the device will enter AX read operation mode which enables subsequent FRQDTR/4FRQDTR execution skips command code. It saves cycles as described in Figures 8.92 and 8.93. When the code is different from AXh (where X is don't care), the device exits the AX read operation. After finishing the read operation, device becomes ready to receive a new command.

If the FRQDTR/4FRQDTR instruction is issued while an Erase, Program or Write cycle is in process is in progress (WIP=1), the instruction will be rejected without any effect on the current cycle.

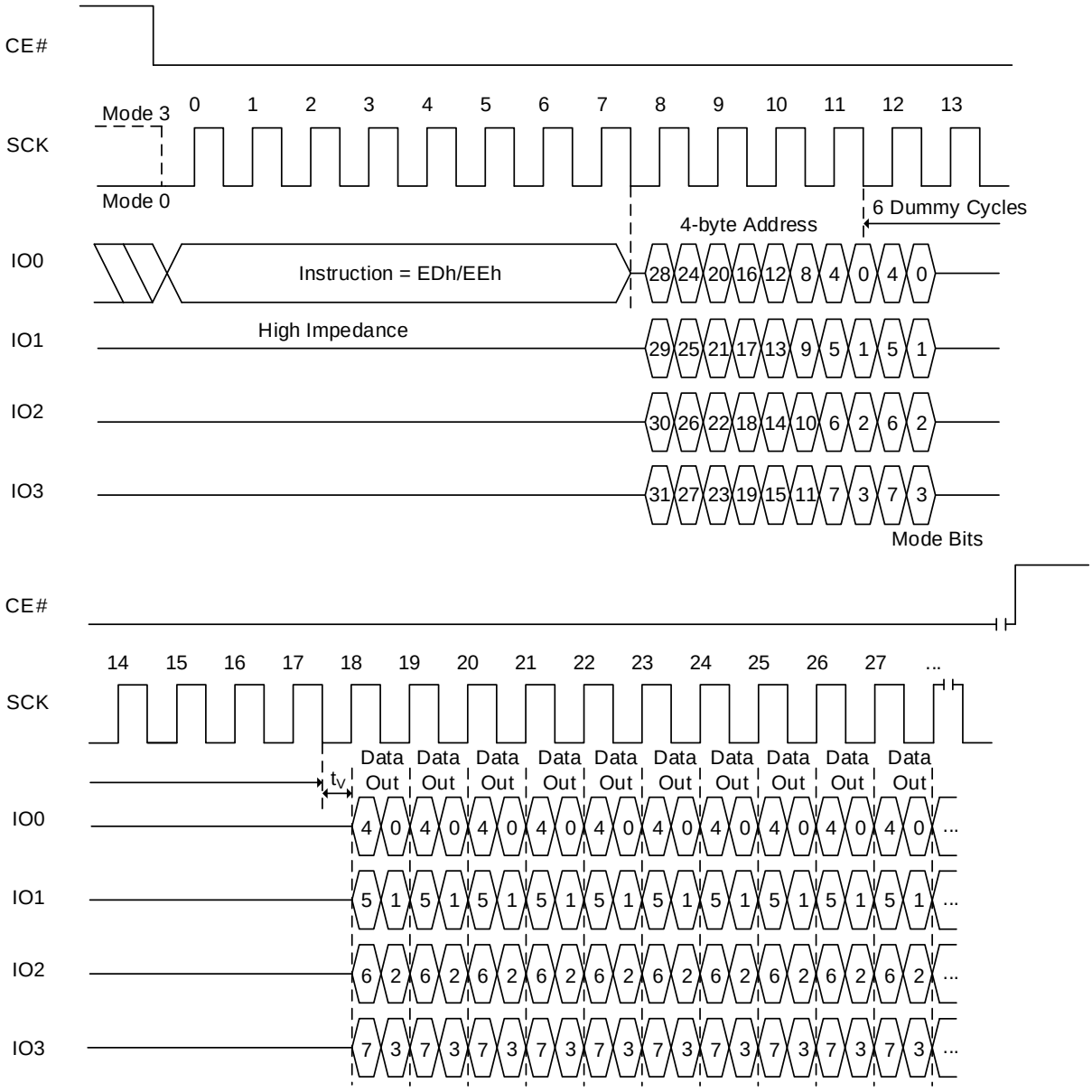
**Figure 8.90 FRQDTR Sequence In SPI Mode (EDh [EXTADD=0], 3-byte address)**




**Notes:**

1. **If the mode bits=AXh (where X is don't care), it can execute the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

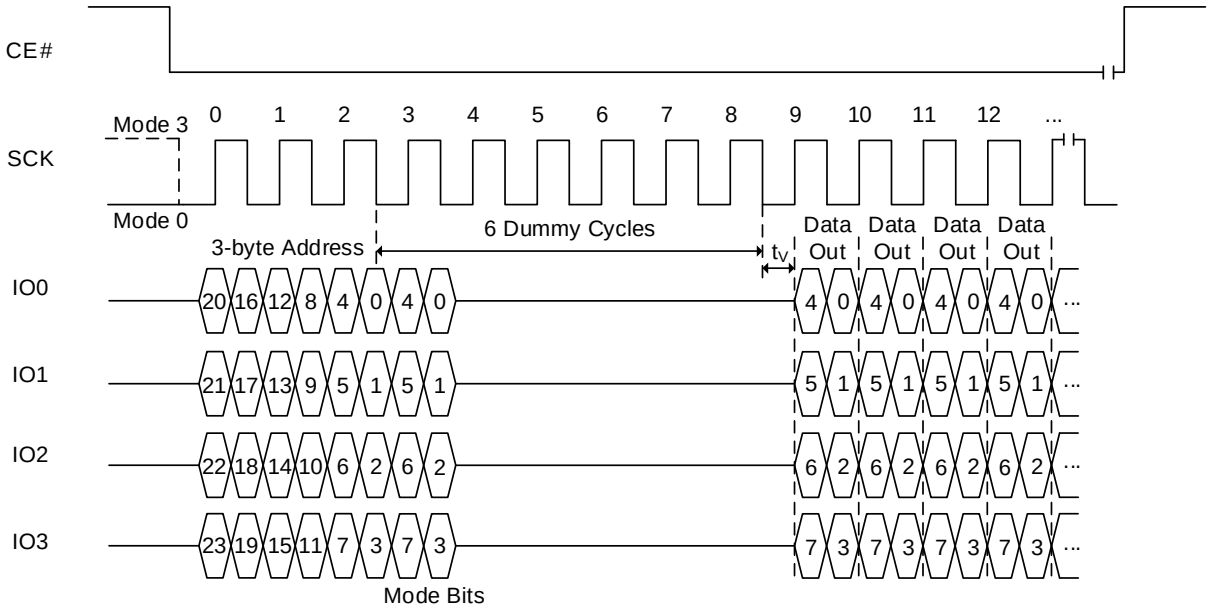
**Figure 8.91 FRQDTR Sequence In SPI Mode (EDh [EXTADD=1] or EEh, 4-byte address)**




**Notes:**

1. **If the mode bits=AXh (where X is don't care), it can execute the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

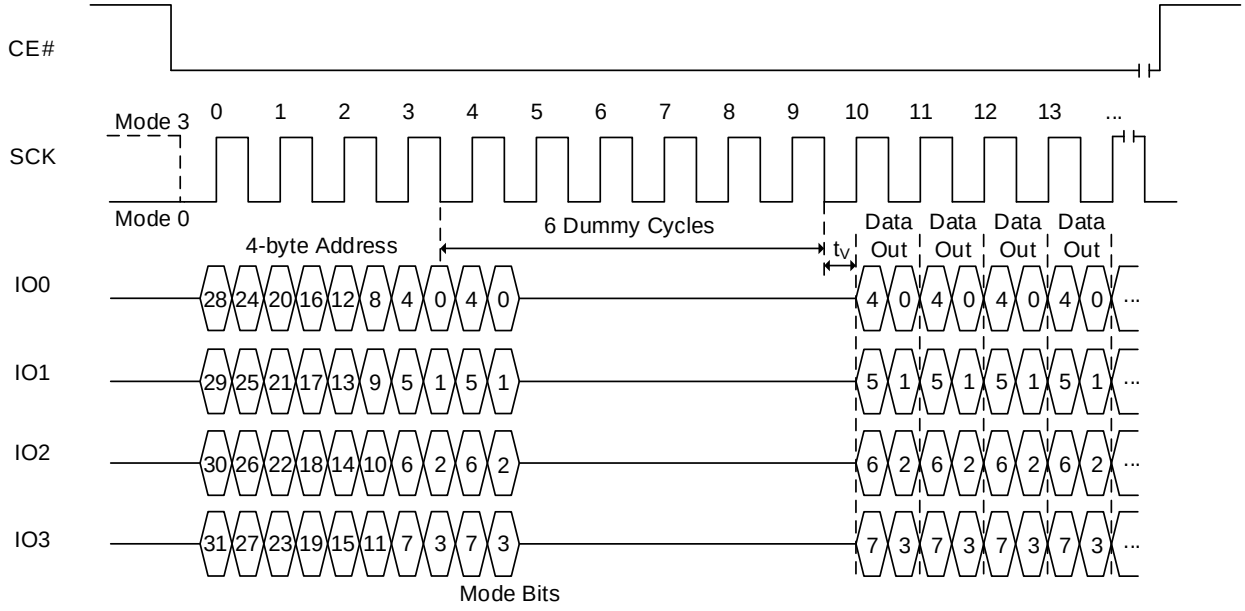
**Figure 8.92 FRQDTR AX Read Sequence (EDh [EXTADD=0], 3-byte address)**




**Notes:**

1. **If the mode bits=AXh (where X is don't care), it will keep executing the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

**Figure 8.93 FRQDTR AX Read Sequence (EDh [EXTADD=1] or EEh, 4-byte address)**




**Notes:**

1. **If the mode bits=AXh (where X is don't care), it will keep executing the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

**FAST READ QUAD IO DTR OPERATION IN QPI MODE (FRQDTR, EDh OR 4FRQDTR, EEh)**

The FRQDTR/4FRQDTR instruction in QPI mode utilizes all four IO lines to input the instruction code so that only two clocks are required, while the FRQDTR/4FRQDTR instruction in SPI mode requires that the byte-long instruction code is shifted into the device only via IO0 line in eight clocks. As a result, 6 command cycles will be reduced by the FRQDTR/4FRQDTR instruction in QPI mode. In addition, subsequent address and data out are shifted in/out via all four IO lines like the FRQDTR/4FRQDTR instruction. In fact, except for the command cycle, the FRQDTR/4FRQDTR operation in QPI mode is exactly same as the FRQDTR/4FRQDTR operation in SPI mode.

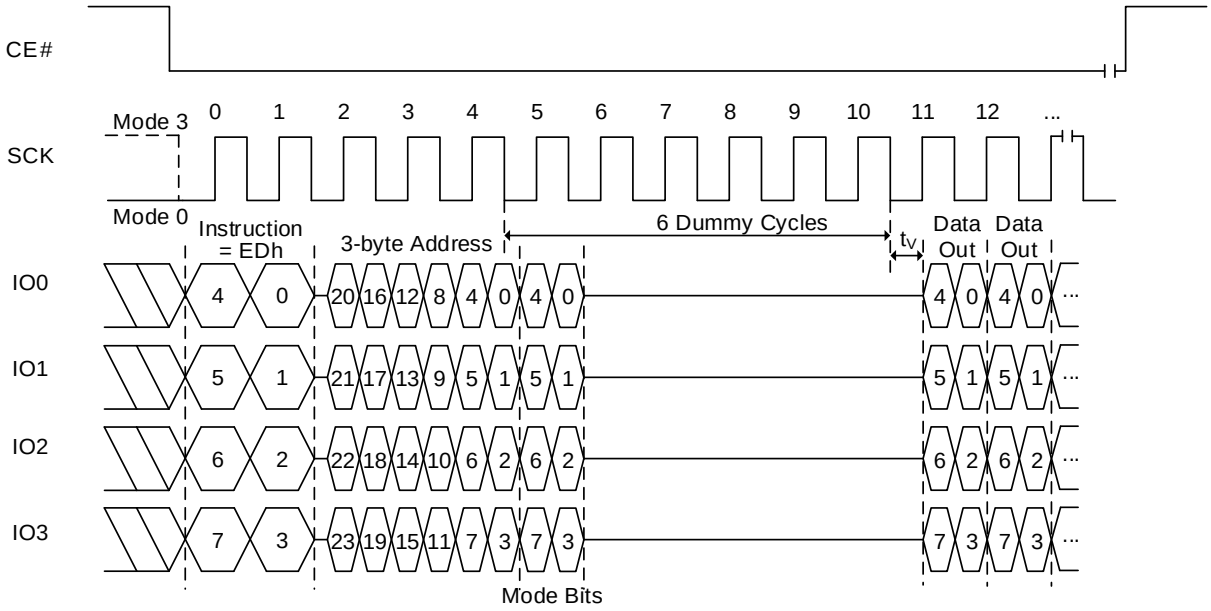
- EDh (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- EDh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- EEh is followed by a 4-byte address (A31-A0)

The sequence of issuing FRQDTR/4FRQDTR instruction is: CE# goes low → Sending FRQDTR/4FRQDTR instruction (4-bit per clock) → 24-bit or 32-bit address interleave on IO3, IO2, IO1 & IO0 (8-bit per clock) as above → 6 dummy clocks (configurable, default is 6 clocks) → Data out interleave on IO3, IO2, IO1 & IO0 (8-bit per clock) → End FRQDTR/4FRQDTR operation by driving CE# high at any time during data out.

If AXh (where X is don't care) is input for the mode bits during dummy cycles, the device will enter AX read operation mode which enables subsequent FRQDTR/4FRQDTR in QPI mode execution skips command code. It saves cycles as described in Figures 8.92 and 8.93. When the code is different from AXh (where X is don't care), the device exits the AX read operation. After finishing the read operation, device becomes ready to receive a new command.

If the FRQDTR/4FRQDTR instruction in QPI mode is issued while an Erase, Program or Write cycle is in process is in progress (WIP=1), the instruction will be rejected without any effect on the current cycle.

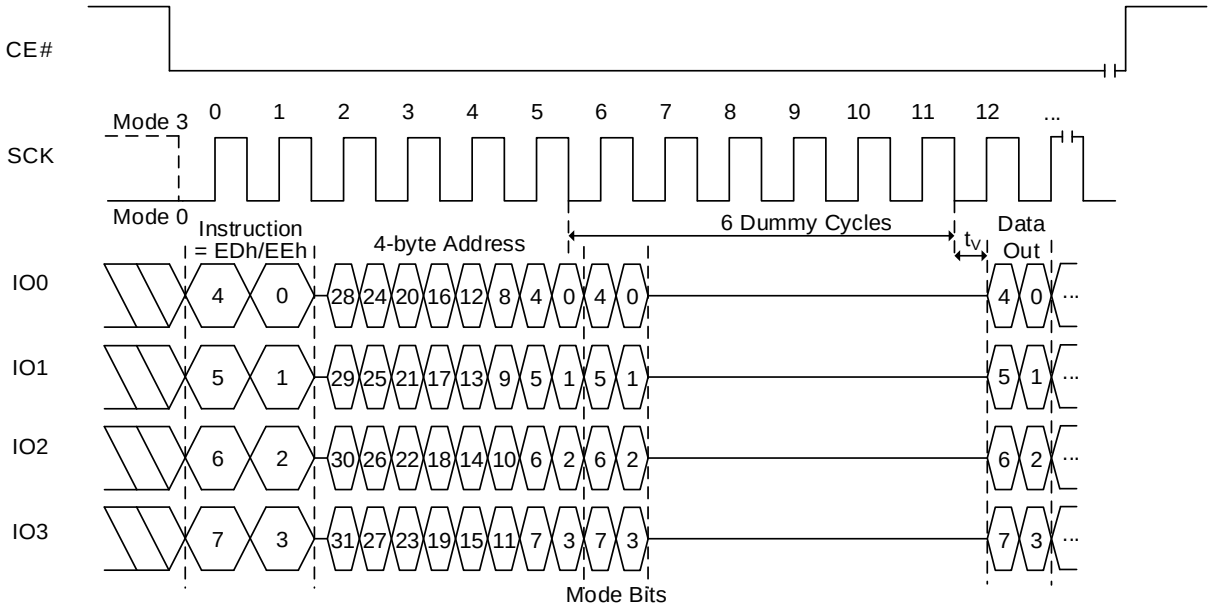
**Figure 8.94 FRQDTR Sequence In QPI Mode (EDh [EXTADD=0], 3-byte address)**




**Notes:**

1. **If the mode bits=AXh (where X is don't care), it can execute the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

**Figure 8.95 FRQDTR Sequence In QPI Mode (EDh [EXTADD=1] or EEh, 4-byte address)**




**Notes:**

1. **If the mode bits=AXh (where X is don't care), it can execute the AX read mode (without command). When the mode bits are different from AXh, the device exits the AX read operation.**
2. **Number of dummy cycles depends on clock speed. Detailed information in Table 6.11 Read Dummy Cycles.**
3. **Sufficient dummy cycles are required to avoid I/O contention. If the number of dummy cycles and AX bits cycles are same, then X should be Hi-Z.**

## 8.45 SECTOR LOCK/UNLOCK FUNCTIONS

### SECTOR UNLOCK OPERATION (SECUNLOCK, 26h or 4SECUNLOCK, 25h)

The Sector Unlock command allows the user to select a specific sector to allow program and erase operations. This instruction is effective when the blocks are designated as write-protected through the BP0-BP3 bits in the Status Register and TBS bit in the Function Register. Only one sector can be enabled at any time. To enable a different sector, a previously enabled sector must be disabled by executing a Sector Lock command.

- 26h (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- 26h (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- 25h is followed by a 4-byte address (A31-A0)

The instruction code is followed by a 24-bit or 32-bit address specifying the target sector as above, but A0 through A11 are not decoded. The remaining sectors within the same block remain as read-only.

**Figure 8.96 Sector Unlock Sequence In SPI Mode (26h [EXTADD=0], 3-byte address)**

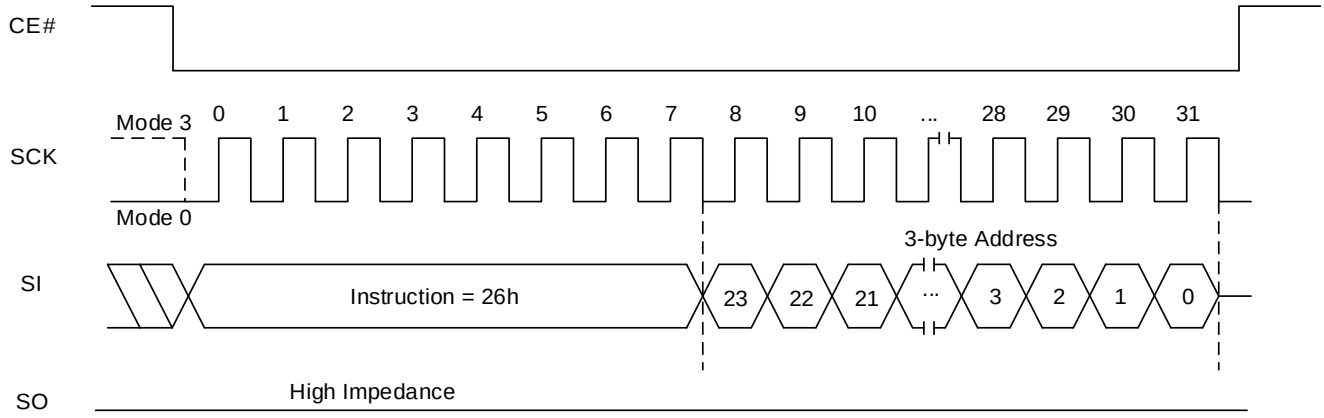



**Figure 8.97 Sector Unlock Sequence In SPI Mode (26h [EXTADD=1] or 25h, 4-byte address)**

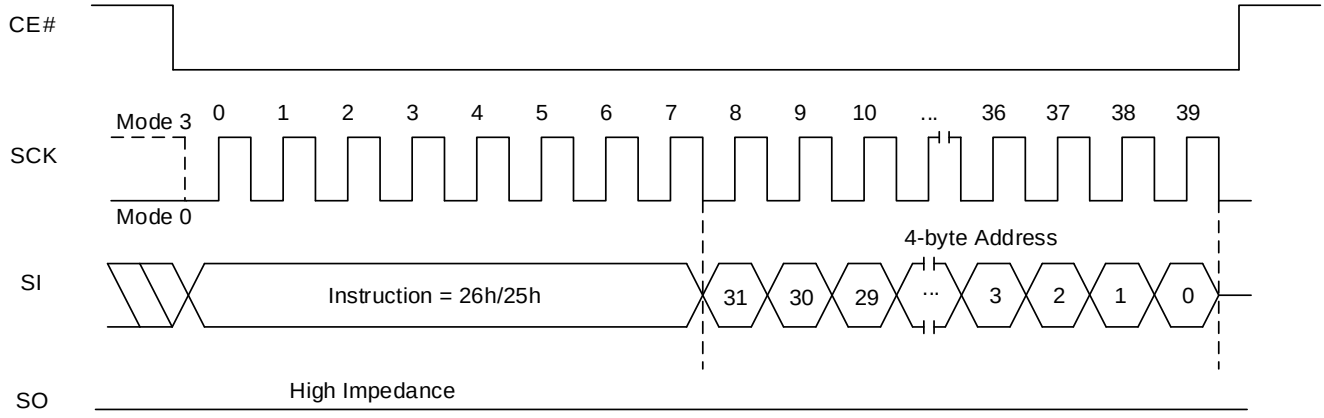


**Figure 8.98 Sector Unlock Sequence In QPI Mode (26h [EXTADD=0], 3-byte address)**

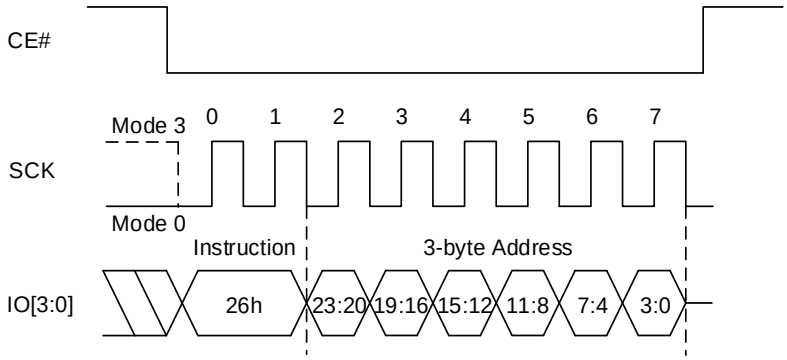
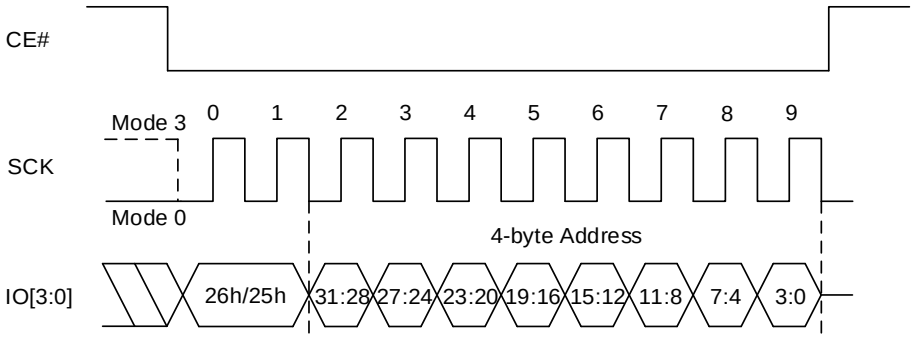



**Figure 8.99 Sector Unlock Sequence In QPI Mode (26h [EXTADD=1] or 25h, 4-byte address)**



## SECTOR LOCK OPERATION (SECLOCK, 24h)

The Sector Lock command relocks a sector that was previously unlocked by the Sector Unlock command. The instruction code does not require an address to be specified, as only one sector can be enabled at a time. The remaining sectors within the same block remain in read-only mode.

**Figure 8.100 Sector Lock Sequence In SPI Mode**

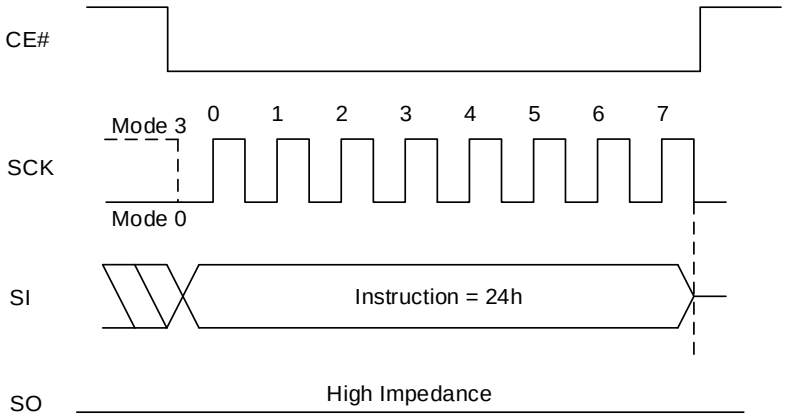
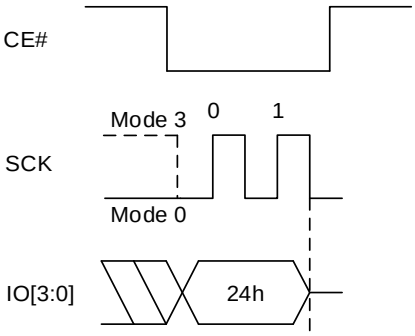



**Figure 8.101 Sector Lock Sequence In QPI Mode**



### 8.46 AUTOBOOT

SPI devices normally require 32 or more cycles of command and address shifting to initiate a read command. And, in order to read boot code from an SPI device, the host memory controller or processor must supply the read command from a hardwired state machine or from some host processor internal ROM code.
Parallel NOR devices need only an initial address, supplied in parallel in a single cycle, and initial access time to start reading boot code.
The AutoBoot feature allows the host memory controller to take boot code from the device immediately after the end of reset, without having to send a read command. This saves 32 or more cycles and simplifies the logic needed to initiate the reading of boot code.

- As part of the Power-up Reset, Hardware Reset, or Software Reset process the AutoBoot feature automatically starts a read access from a pre-specified address. At the time the reset process is completed, the device is ready to deliver code from the starting address. The host memory controller only needs to drive CE# signal from high to low and begin toggling the SCK signal. The device will delay code output for a pre-specified number of clock cycles before code streams out.

  – The Auto Boot Start Delay (ABSD) field of the AutoBoot register specifies the initial delay if any is needed by the host.
  – The host cannot send commands during this time.
  – If QE bit (Bit 6) in the Status Register is set to “1”, Fast Read Quad I/O operation will be selected and initial delay is the same as dummy cycles of Fast Read Quad I/O Read operation. If it is set to “0”, Fast Read operation will be applied and initial delay is the same as dummy cycles of Fast Read operation.

- The starting address of the boot code is selected by the value programmed into the AutoBoot Start Address (ABSA) field of the AutoBoot Register.

  – Data will continuously shift out until CE# returns high.

- At any point after the first data byte is transferred, when CE# returns high, the SPI device will reset to standard SPI mode; able to accept normal command operations.

  – A minimum of one byte must be transferred.
  – AutoBoot mode will not initiate again until another power cycle or a reset occurs.

- An AutoBoot Enable bit (ABE) is set to enable the AutoBoot feature.

The AutoBoot register bits are non-volatile and provide:
- The starting address set by the AutoBoot Start Address (ABSA).
- The number of initial delay cycles, set by the AutoBoot Start Delay (ABSD) 4-bit count value.

**Figure 8.102 AutoBoot Sequence (QE = 0)**

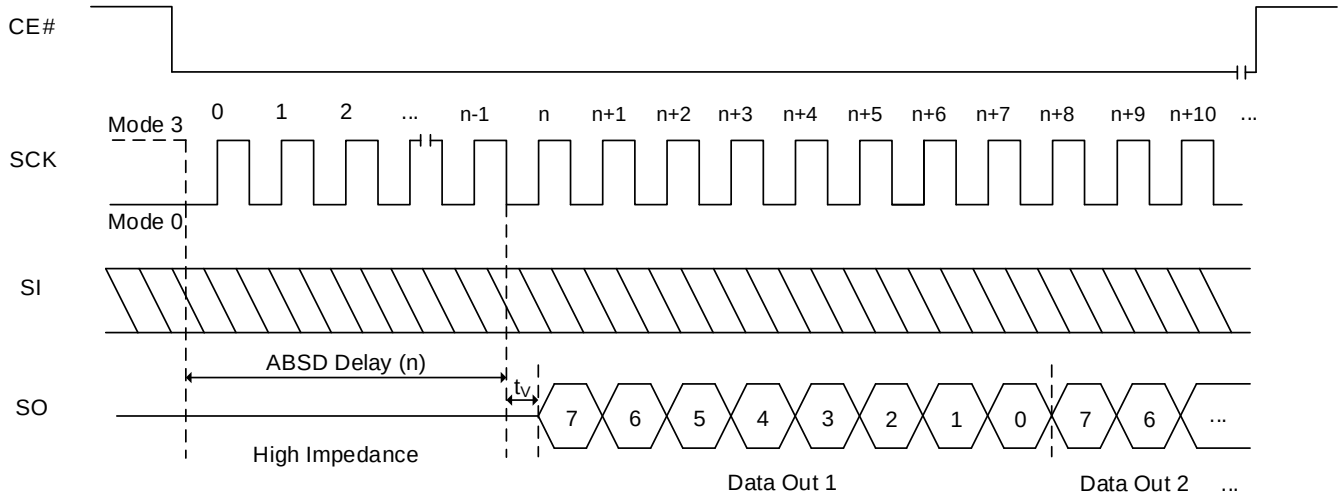
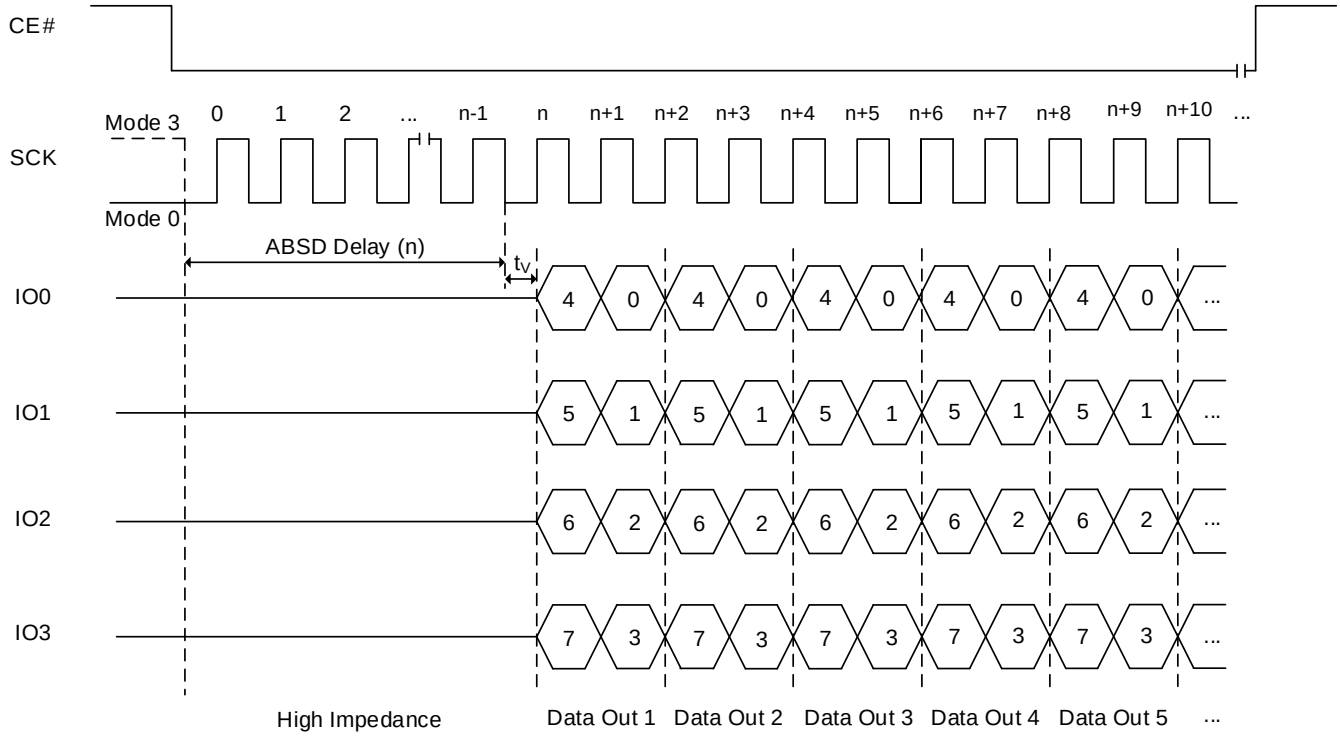



**Figure 8.103 AutoBoot Sequence (QE = 1)**

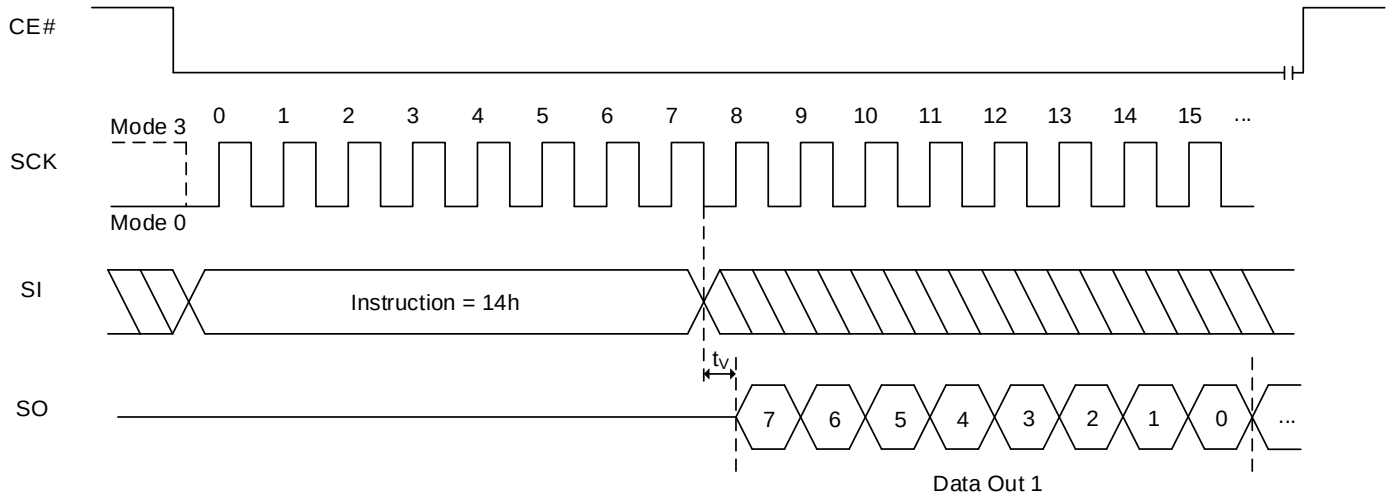


### AUTOBOOT REGISTER READ OPERATION (RDABR, 14h)

The AutoBoot Register Read command is shifted in. Then the 32bit AutoBoot Register is shifted out, least significant byte first, most significant bit of each byte first. It is possible to read the AutoBoot Register continuously by providing multiples of 32bits.

RDABR operation is valid only at SPI mode only.

**Figure 8.104 RDABR Sequence In SPI Mode**



**AUTOBOOT REGISTER WRITE OPERATION (WRABR, 15h)**

Before the WRABR command can be accepted, a Write Enable (WREN) command must be issued and decoded by the device, which sets the Write Enable Latch (WEL) in the Status Register to enable any write operations.

The WRABR command is entered by shifting the instruction and the data bytes, least significant byte first, most significant bit of each byte first. The WRABR data is 32bits in length.

CE# must be driven high after the 32nd bit of data has been latched. If not, the WRABR command is not executed. As soon as CE# is driven high, the WRABR operation is initiated. While the WRABR operation is in progress, Status Register or Extended Read Register may be read to check the value of the Write In Progress (WIP) bit. The WIP bit is "1" during the WRABR operation, and is "0" when it is completed. When the WRABR cycle is completed, the WEL is set to "0".

**Figure 8.105 WRABR Sequence In SPI Mode**

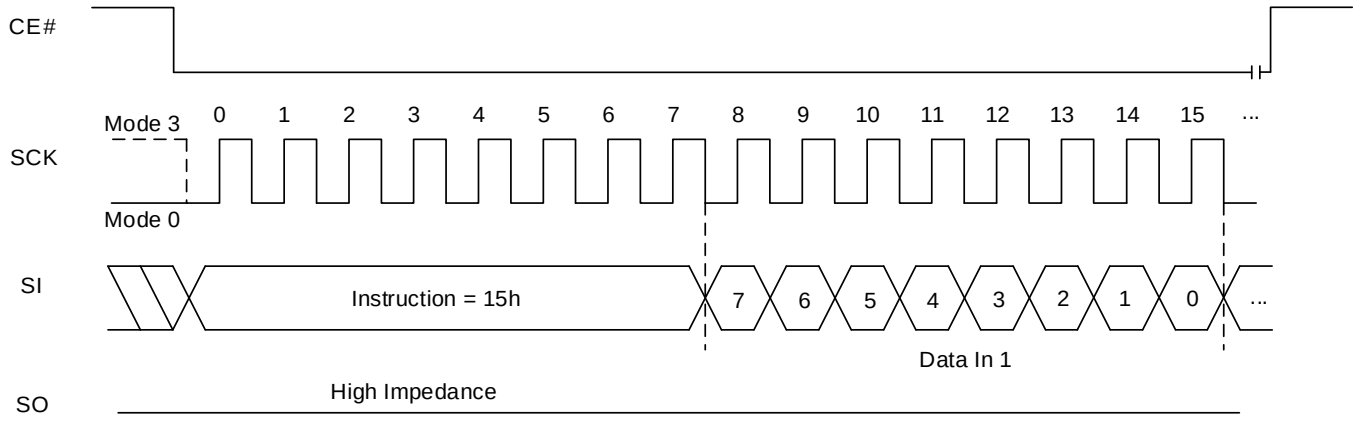
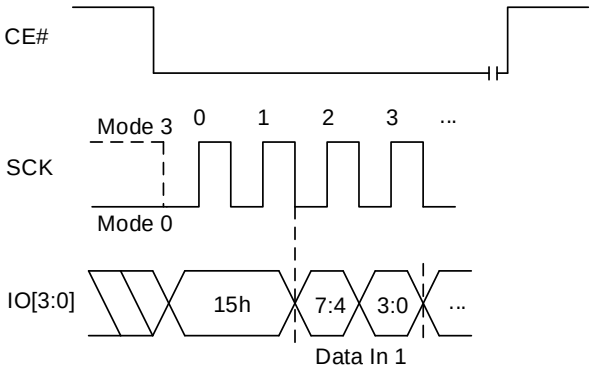



**Figure 8.106 WRABR Sequence In QPI Mode**



### 8.47 READ BANK ADDRESS REGISTER OPERATION (RDBR: 16h/C8h)

The Read Bank Address Register (RDBR) instruction allows the Bank Address Register contents to be read. RDBR is used to read only a volatile Bank Address Register.

The instruction code is first shifted in. Then the 8-bit Bank Register is shifted out. It is possible to read the Bank Address Register continuously by providing multiples of eight bits.

Data is shifted in from SI and data is shifted out from SO in SPI sequence whereas data in and out is via four pins (IO0-IO3) in QPI sequence.

**Figure 8.107 Read Bank Address Register Sequence In SPI Mode**

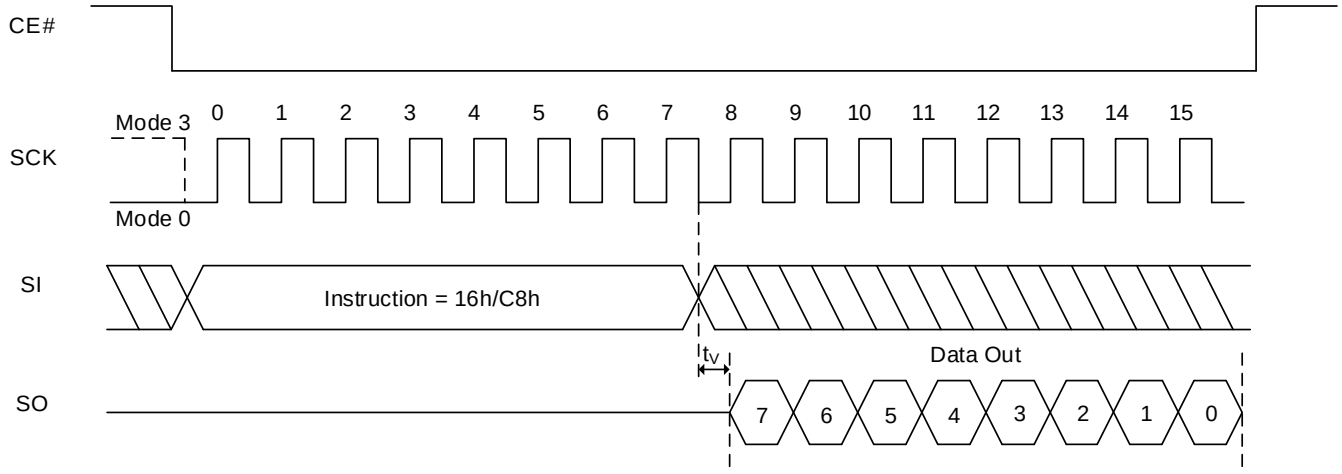
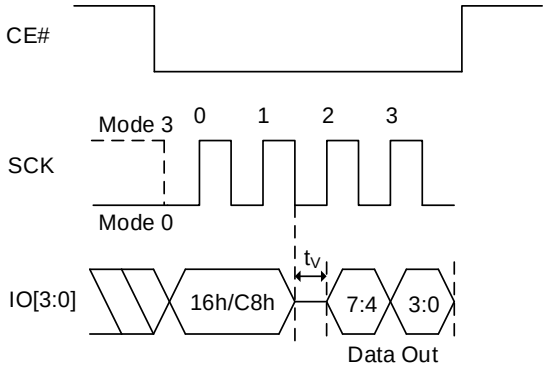



**Figure 8.108 Read Bank Address Register Sequence In QPI Mode**



### 8.48 WRITE BANK ADDRESS REGISTER OPERATION (WRBRNV: 18h, WRBRV: 17h/C5h)

The Write Bank Address Register (WRBRNV and WRBRV) instruction is used to write address bits above A23, into the Bank Address Register (BAR). WRBRNV is used to write the non-volatile Bank Address Register and WRBRV is used to write the volatile Bank Address Register. The instruction is also used to write the Extended Address Control bit (EXTADD) that is also in BAR[7]. BAR provides the high order addresses needed by devices having more than 128Mbits (16Mbytes), when using 3-byte address commands without extended addressing enabled (BAR[7] EXTADD = 0).

To write non-volatile Bank Address Register, a standard Write Enable (06h) instruction must previously have been executed for the device to accept WRBRNV(18h) instruction (Status Register bit WEL must equal "1").

To write volatile Bank Address Register, C5h or 17h command can be used.
When using C5h instruction, a standard Write Enable (06h) instruction must previously have been executed for the device to accept C5h instruction (Status Register bit WEL must equal "1").
But 17h instruction does not require a standard Write Enable (06h) operation. (Status Register bit WEL remains "0").

The WRBRNV/WRBRV instructions are followed by the data byte. The Bank Address Register is one data byte in length. The Write In Progress (WIP) bit is "1" during WRBRNV/WRBRV operation, and is "0" when it is completed. Any bank address bit reserved for the future should always be written as "0". Data is shifted in from SI and in SPI whereas data is shifted in via four pins (IO0-IO3) in QPI.

Bit 7 (EXTADD) of volatile Bank Address Register is also writable with EN4B (B7h)/EX4B (29h) instruction.
But B7h/29h instruction does not require a standard Write Enable (06h) (Status Register bit WEL remains 0).

**Note: When WRBRNV is executed, the volatile Bank Address Register is set as well as the non-volatile Bank Address Register.**

**Figure 8.109 Write Bank Address Register Sequence In SPI Mode**

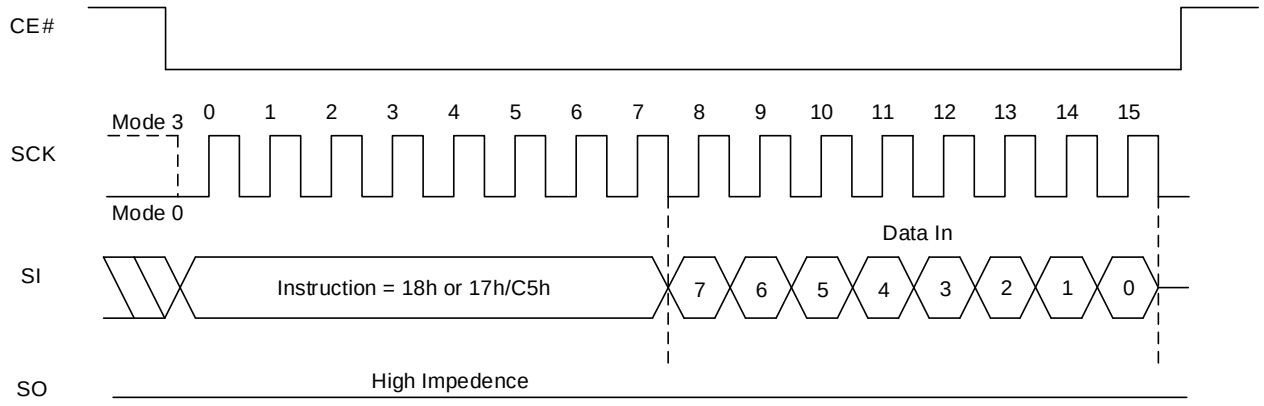
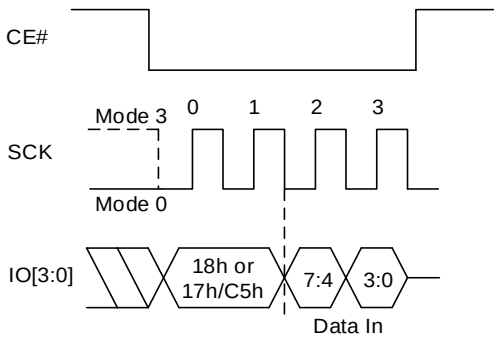



**Figure 8.110 Write Bank Address Register Sequence In QPI Mode**



### 8.49 ENTER 4-BYTE ADDRESS MODE OPERATION (EN4B, B7h)

The Enter 4-byte Address Mode instruction allows 32bit address (A31-A0) to be used to access the memory array beyond 128Mb. To execute EN4B operation, the host drives CE# low, sends the instruction code and then drives CE# high. The Exit 4-byte Address Mode instruction can be used to exit the 4-byte address mode.

A Write Enable (WREN, 06h) command is not required prior to EN4B (B7h) command.

**Note: The EN4B instruction will set the Bit 7 (EXTADD) of the volatile Bank Address Register to "1", but will not change the non-volatile Bank Address Register.**

**Figure 8.111 Enter 4-byte Address Mode Sequence In SPI Mode**

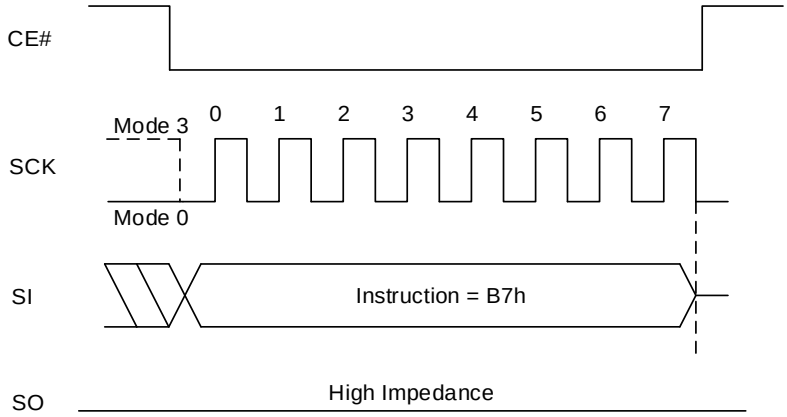
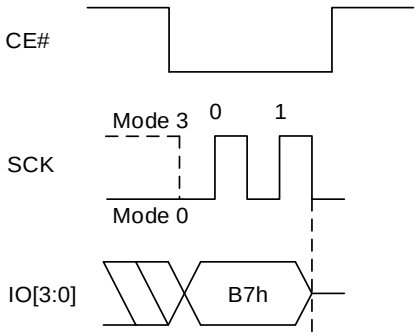



**Figure 8.112 Enter 4-byte Address Mode Sequence In QPI Mode**



### 8.50 EXIT 4-BYTE ADDRESS MODE OPERATION (EX4B, 29h)

In order to be backward compatible, the Exit 4-byte Address Mode instruction allows 24bit address (A23-A0) to be used to access the memory array up to 128Mb. The Bank Address Register must be used to access the memory array beyond 128Mb. To execute EX4B operation, the host drives CE# low, sends the instruction code and then drives CE# high.

A Write Enable (WREN, 06h) command is not required prior to EX4B (29h) command.

**Note: The EX4B instruction will reset the Bit 7 (EXTADD) of the volatile Bank Address Register to "0" ", but will not change the non-volatile Bank Address Register.**

**Figure 8.113 Exit 4-byte Address Mode Sequence In SPI Mode**

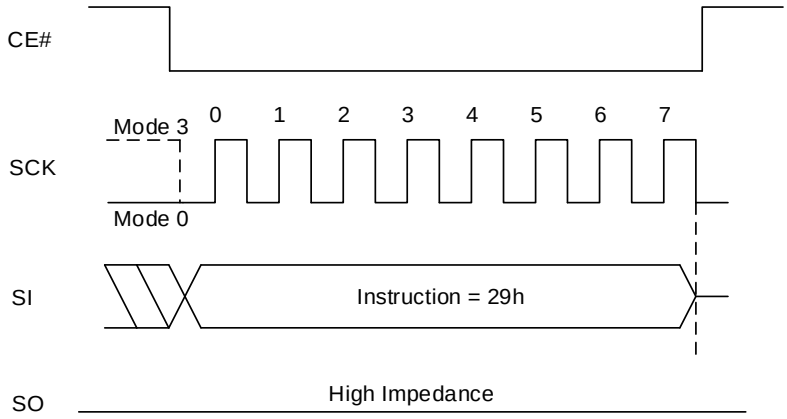
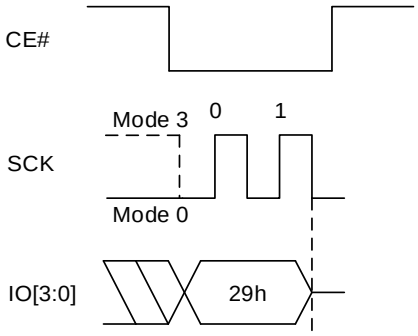



**Figure 8.114 Exit 4-byte Address Mode Sequence In QPI Mode**



### 8.51 READ DYB OPERATION (RDDYB, FAh or 4RDDYB, E0h)

FAh (EXTADD=0) is followed by a 3-byte address (A23-A0) or

- FAh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- E0h is followed by a 4-byte address (A31-A0)

The instruction is used to read Dynamic Protection Bit (DYB) status of the given sector/block. The instruction code is entered first, followed by the 24-bit or 32-bit address selecting location zero within the desired sector/block as above. Then the 8-bit DYB access register contents are shifted out. Each bit (SPI) or four bits (QPI) are shifted out at the SCK frequency by the falling edge of the SCK signal. It is possible to read the same DYB access register continuously by providing multiples of eight bits. The address of the DYB register does not increment so this is not a means to read the entire DYB array. Each location must be read with a separate Read DYB instruction.

**Note: Data must be either 00h (protected) or FFh (unprotected).**

**Figure 8.115 Read DYB Sequence In SPI Mode (FAh [EXTADD=0], 3-byte address)**

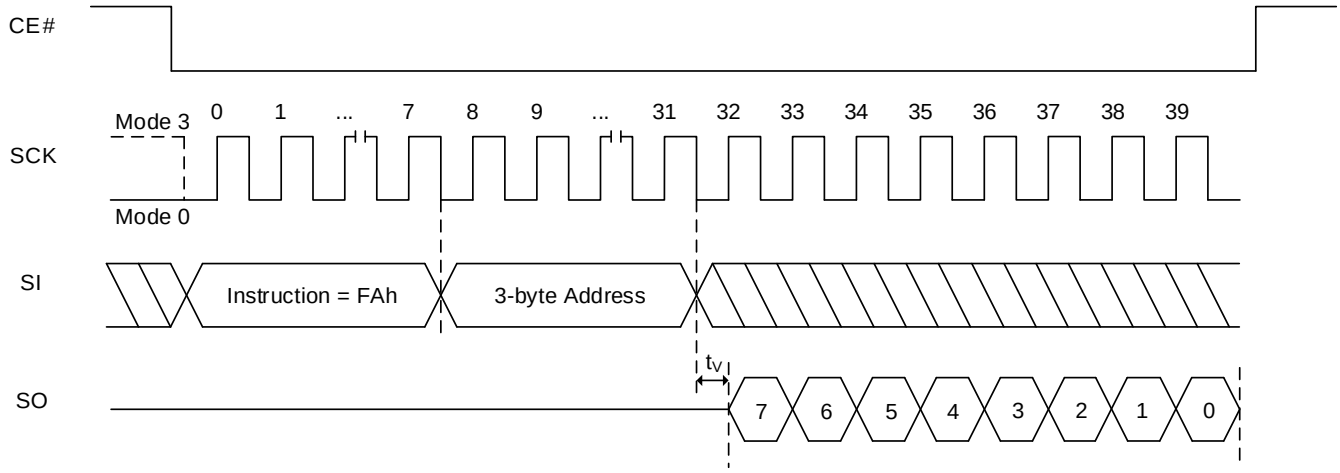


**Figure 8.116 Read DYB Sequence In SPI Mode (FAh [EXTADD=1] or E0h, 4-byte address)**

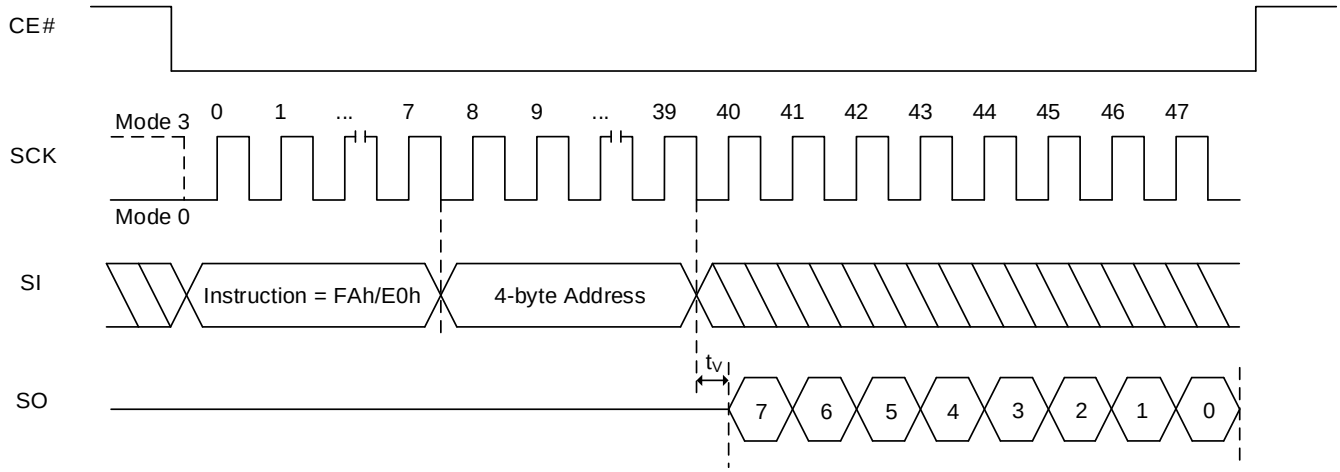



**Figure 8.117 Read DYB Sequence In QPI Mode (FAh [EXTADD=0], 3-byte address)**

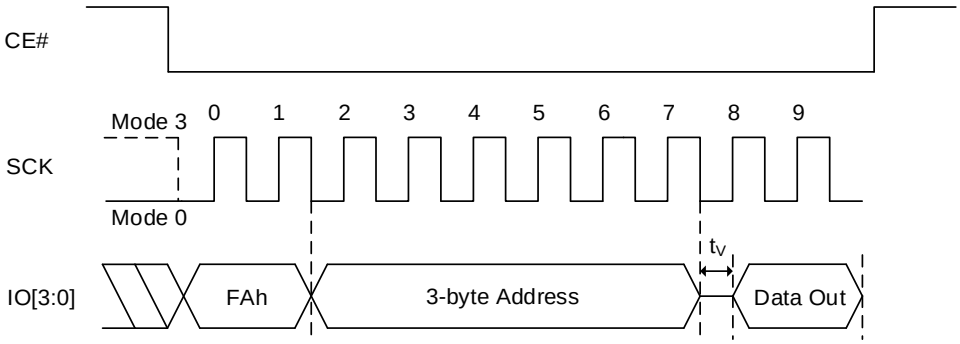
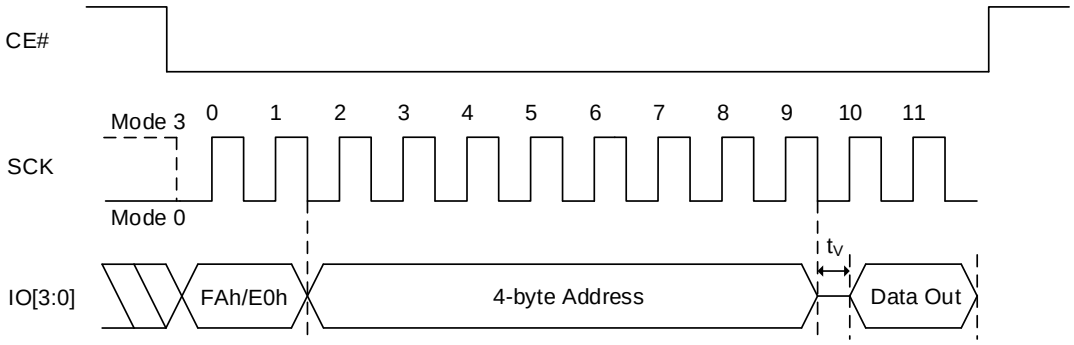



**Figure 8.118 Read DYB Sequence In QPI Mode (FAh [EXTADD=0] or E0h, 4-byte address)**



### 8.52 WRITE DYB OPERATION (WRDYB, FBh or 4WRDYB, E1h)

Before the WRDYB/4WRDYB command can be accepted by the device, a standard Write Enable (06h) instruction must previously have been executed for the device to accept Write DYB instruction (Status Register bit WEL must equal 1).

- FBh (EXTADD=0) is followed by a 3-byte address (A23-A0) or
- FBh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
- E1h is followed by a 4-byte address (A31-A0)

The WRDYB/4WRDYB command is entered by driving CE# low, followed by the instruction code, the 24-bit or 32-bit address selecting location zero within the desired sector/block as above, then the data byte. The DYB Access Register is one data byte in length.

CE# must be driven high after the eighth bit of data has been latched in. As soon as CE# is driven high, the WRDYB/4WRDYB operation is initiated.

**Note: Data must be either 00h (protected) or FFh (unprotected).**

**Figure 8.119 Write DYB Sequence In SPI Mode (FBh [EXTADD=0], 3-byte address)**

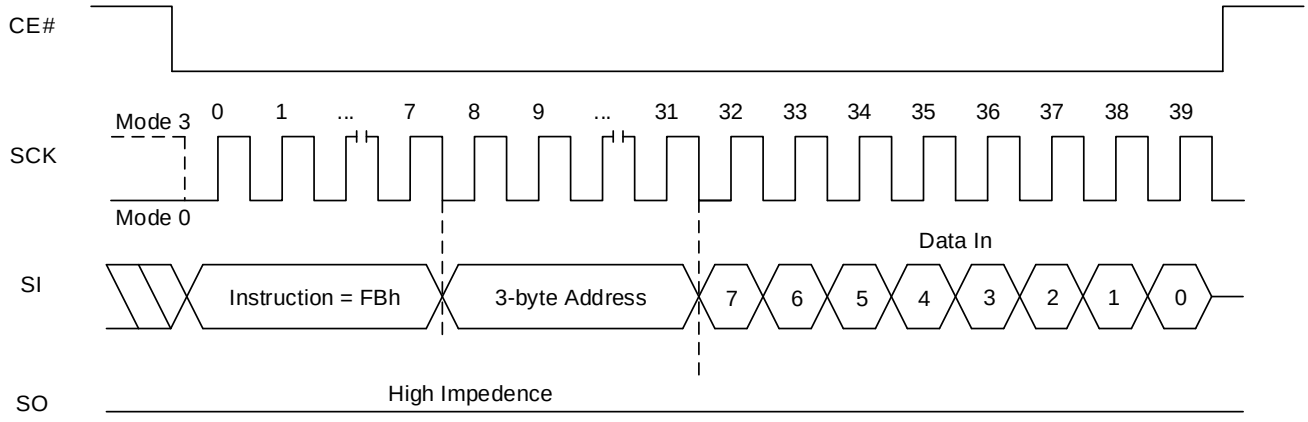


**Figure 8.120 Write DYB Sequence In SPI Mode (FBh [EXTADD=1] or E1h, 4-byte address)**

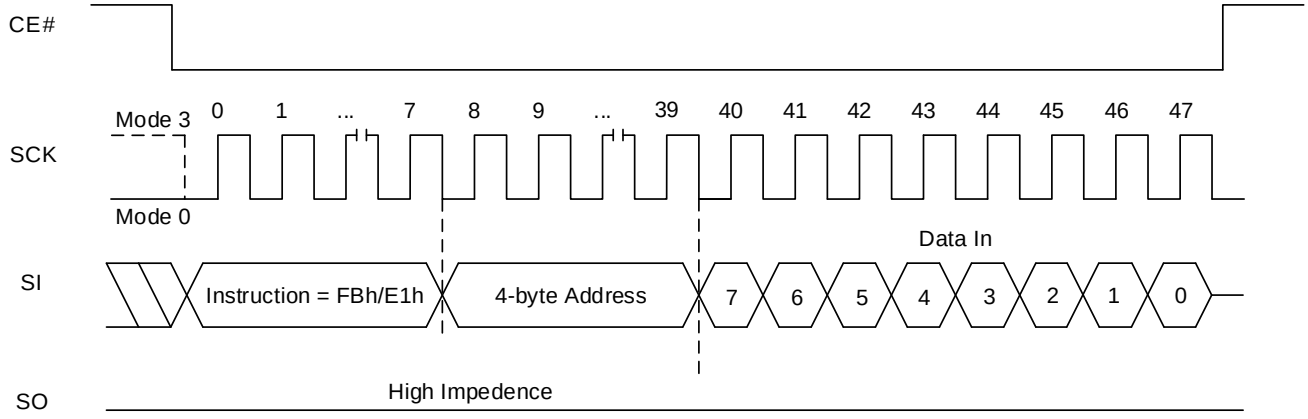



**Figure 8.121 Write DYB Sequence In QPI Mode (FBh [EXTADD=0], 3-byte address)**

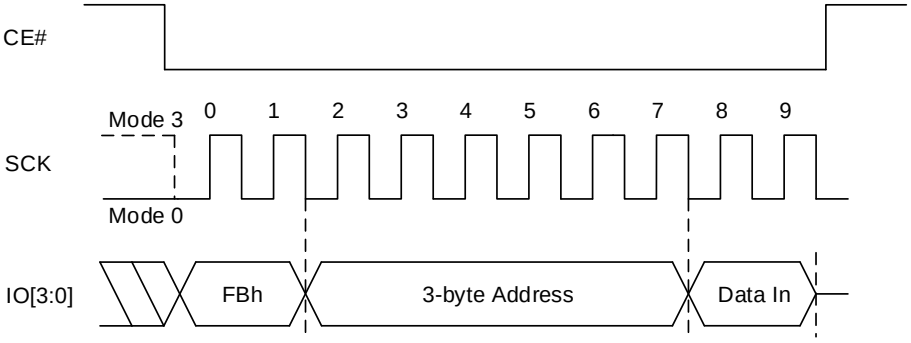
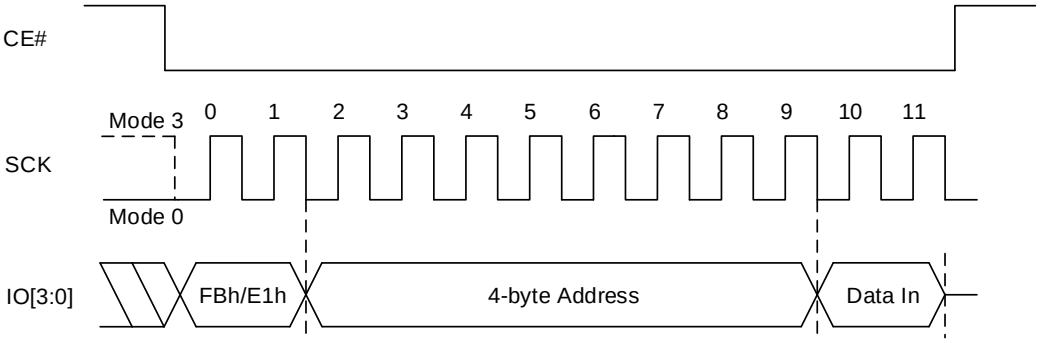



**Figure 8.122 Write DYB Sequence In QPI Mode (FBh [EXTADD=1] or E1h, 4-byte address)**



### 8.53 READ PPB OPERATION (RDPPB, FCh or 4RDPPB, E2h)

FCh (EXTADD=0) is followed by a 3-byte address (A23-A0) or
FCh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
E2h is followed by a 4-byte address (A31-A0)

The instruction code is shifted into SI by the rising edges of the SCK signal, followed by the 24-bit or 32-bit address selecting location zero within the desired sector/block as above. Then the 8-bit PPB Access Register contents are shifted out on SO. The RDPPB/4RDPPB is supporting only SPI, not supporting QPI.

It is possible to read the same PPB Access Register continuously by providing multiples of eight bits. The address of the PPB Access Register does not increment so this is not a means to read the entire PPB array. Each location must be read with a separate Read PPB command.

**Note: Data must be either 00h (protected) or FFh (unprotected).**

**Figure 8.123 Read PPB Sequence (FCh [EXTADD=0], 3-byte address)**

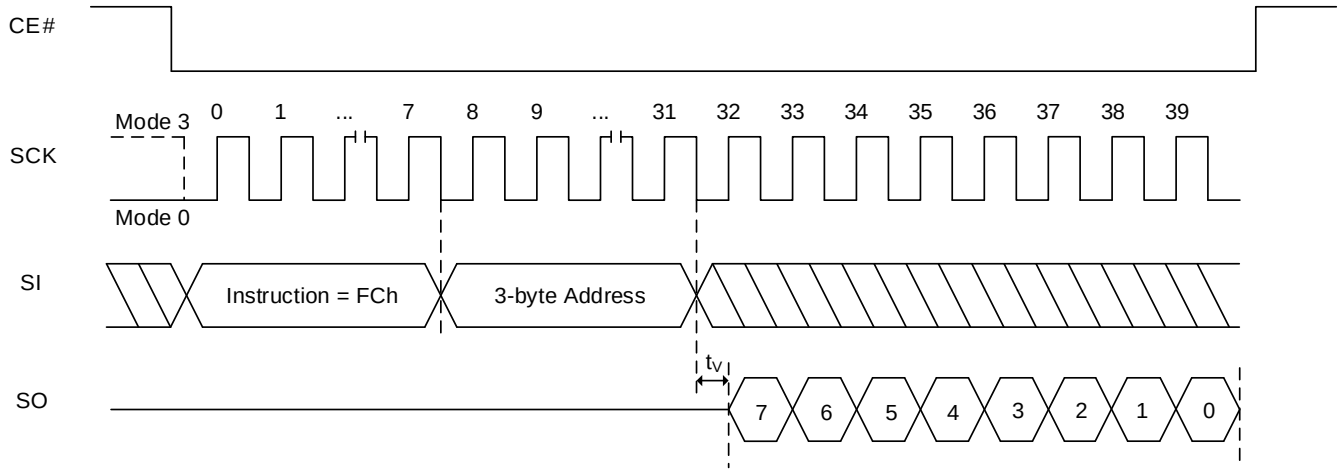
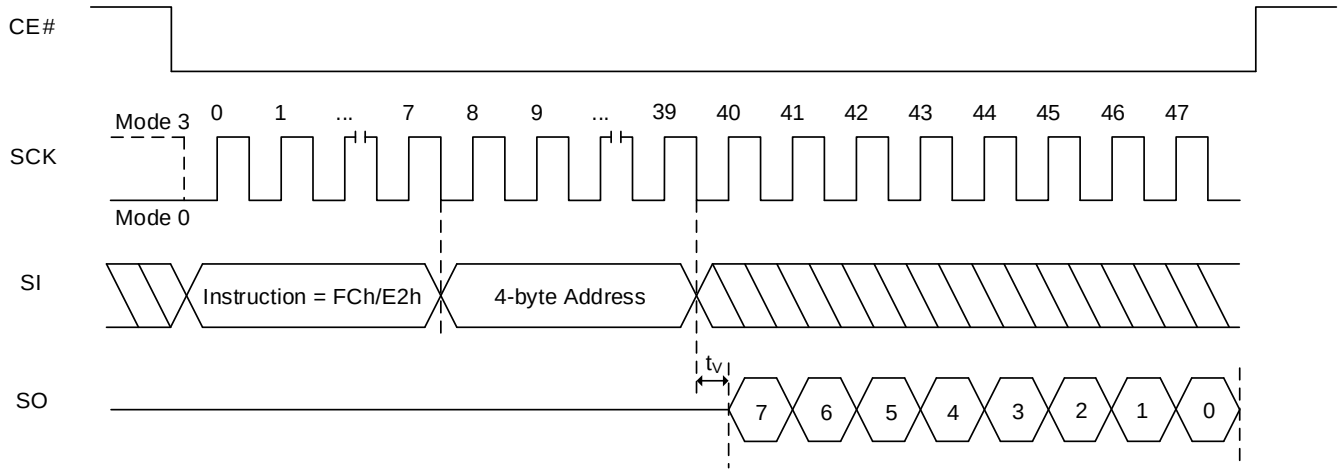



**Figure 8.124 Read PPB Sequence (FCh [EXTADD=1] or E2h, 4-byte address)**



### 8.54 PROGRAM PPB OPERATION (PGPPB, FDh or 4PGPPB, E3h)

Before the Program PPB (PGPPB/4PGPPB) command is sent, a Write Enable (WREN) command must be issued. After the WREN command has been decoded, the device will set the Write Enable Latch (WEL) in the Status Register.

FDh (EXTADD=0) is followed by a 3-byte address (A23-A0) or
FDh (EXTADD=1) is followed by a 4-byte address (A31-A0) or
E3h is followed by a 4-byte address (A31-A0)

The PGPPB/4PGPPB command is entered by driving CE# low, followed by the instruction code, followed by the 24-bit or 32-bit address selecting location zero within the desired sector/block as above.

The PGPPB/4PGPPB command affects the WIP bit in the same manner as any other programming operation. CE# must be driven high after the last bit of address has been latched in. As soon as CE# is driven high, the PGPPB/4PGPPB operation is initiated. While the PGPPB/4PGPPB operation is in progress, the Status Register or Extended Read Register may be read to check the value of the Write In Progress (WIP) bit. The WIP bit is "1" during the PGPPB/4PGPPB operation, and is "0" when it is completed. When the PGPPB/4PGPPB operation is completed, the WEL is set to "0".

**Note: Data must be either 00h (protected) or FFh (unprotected).**

**Figure 8.125 Program PPB Sequence In SPI Mode (FDh [EXTADD=0], 3-byte address)**

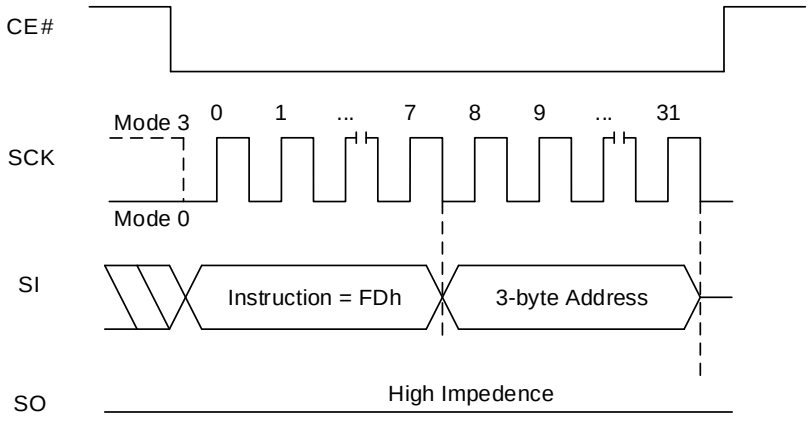



**Figure 8.126 Program PPB Sequence In SPI Mode (FDh [EXTADD=1] or E3h, 4-byte address)**

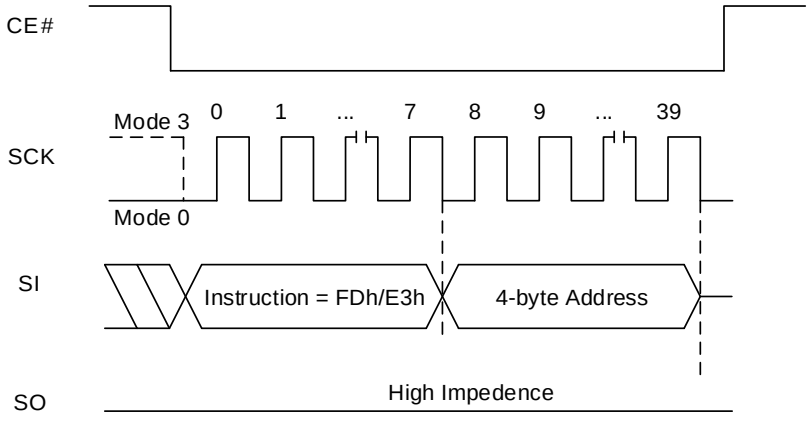


**Figure 8.127 Program PPB Sequence In QPI Mode (FDh [EXTADD=0], 3-byte address)**

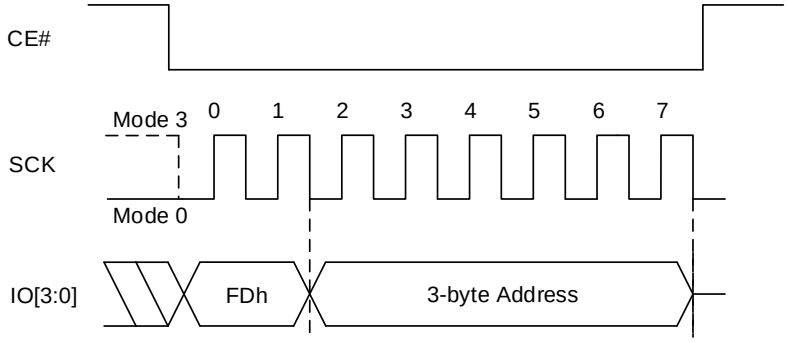
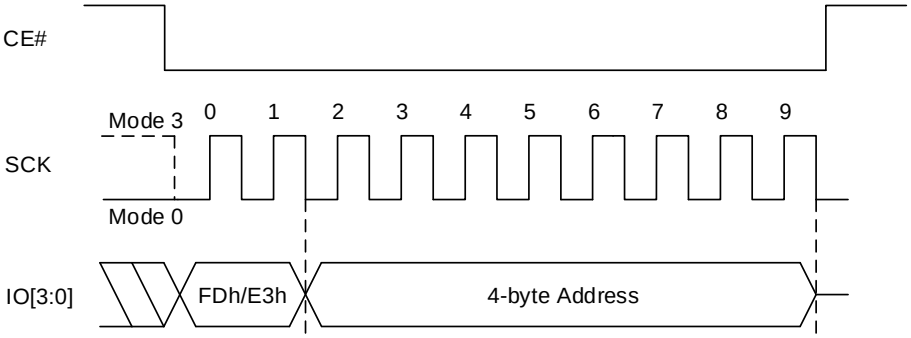



**Figure 8.128 Program PPB Sequence In QPI Mode (FDh [EXTADD=1] or E3h, 4-byte address)**



### 8.55 ERASE PPB OPERATION (ERPPB, E4h)

The Erase PPB (ERPPB) command sets all PPB bits to “1”. Before the ERPPB command can be accepted by the device, a Write Enable (WREN) command must be issued and decoded by the device, which sets the Write Enable Latch (WEL) in the Status Register to enable any write operations.

The instruction code is shifted in by the rising edges of the SCK signal. CE# must be driven high after the eighth bit of the instruction byte has been latched in. This will initiate the beginning of internal erase cycle, which involves the pre-programming and erase of the entire PPB memory array. Without CE# being driven high after the eighth bit of the instruction, the PPB erase operation will not be executed.

With the internal erase cycle in progress, the user can read the value of the Write In Progress (WIP) bit to check if the operation has been completed. The WIP bit will indicate “1” when the erase cycle is in progress and “0” when the erase cycle has been completed. When the ERPPB operation is completed, the WEL is set to “0”. Erase suspend is not allowed during PPB Erase.

**Figure 8.129 Erase PPB Sequence In SPI Mode**

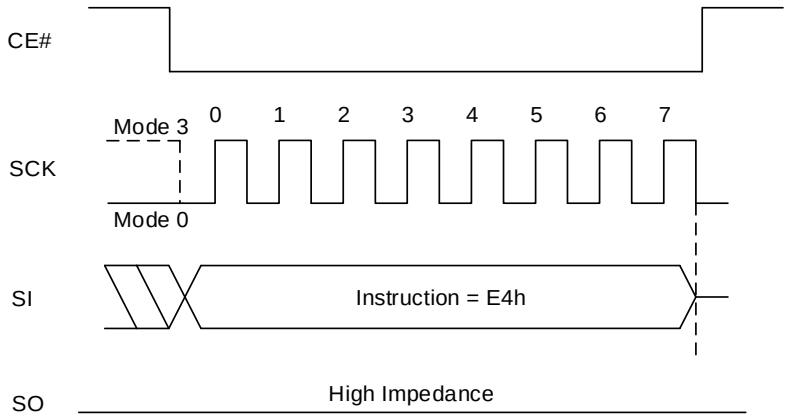
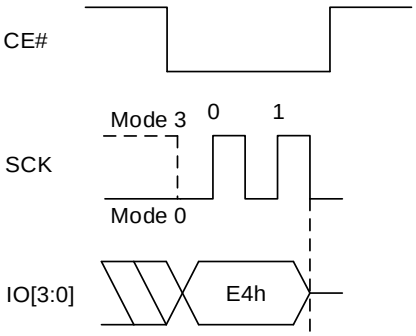



**Figure 8.130 Erase PPB Sequence In QPI Mode**



### 8.56 READ ASP OPERATION (RDASP, 2Bh)

The RDASP instruction code is shifted in by the rising edge of the SCK signal. Then the 16-bit ASP register contents is shifted out, least significant byte first, most significant bit of each byte first. Each bit is shifted out at the SCK frequency by the falling edge of the SCK signal. It is possible to read the ASP register continuously by providing multiples of 16 bits.

**Figure 8.131 Read ASP Sequence In SPI Mode**

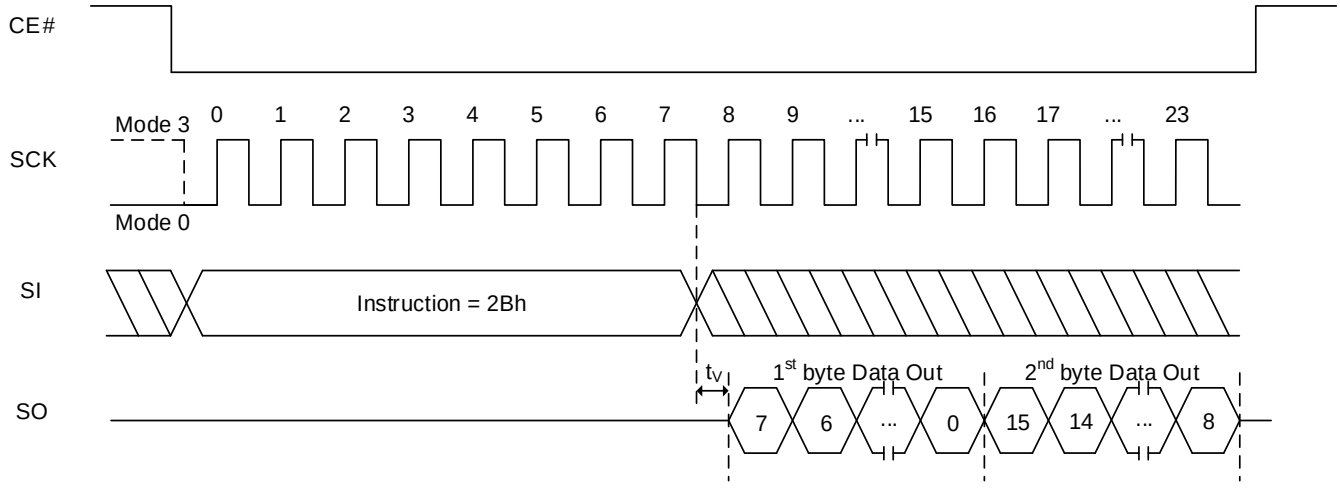
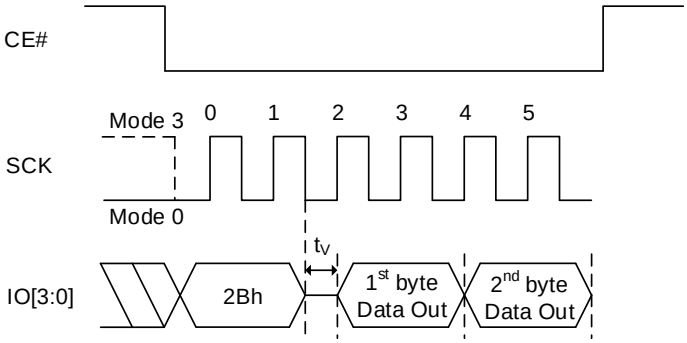



**Figure 8.132 Read ASP Sequence In QPI Mode**



### 8.57 PROGRAM ASP OPERATION (PGASP, 2Fh)

Before the Program ASP (PGASP) command can be accepted by the device, a Write Enable (WREN) command must be issued. After the WREN command has been decoded, the device will set the Write Enable Latch (WEL) in the Status Register to enable any write operations.

The PGASP command is entered by driving CE# low, followed by the instruction code and two data bytes, least significant byte first, most significant bit of each byte first. The ASP Register is two data bytes in length. The PGASP command affects the Write In Progress (WIP) bit in the same manner as any other programming operation.

CE# input must be driven high after the sixteenth bit of data has been latched in. If not, the PGASP command is not executed. As soon as CE# is driven high, the PGASP operation is initiated. While the PGASP operation is in progress, the Status Register or the Extended Read Register may be read to check the value of WIP bit. The WIP bit is "1" during the PGASP operation, and is "0" when it is completed. When the PGASP operation is completed, the WEL is set to "0".

**Figure 8.133 Program ASP Sequence In SPI Mode**

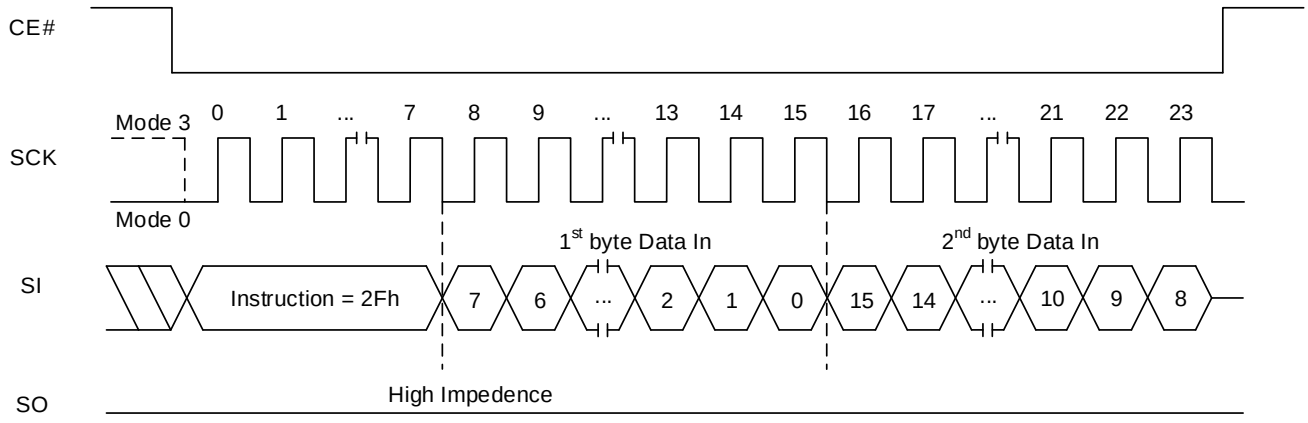
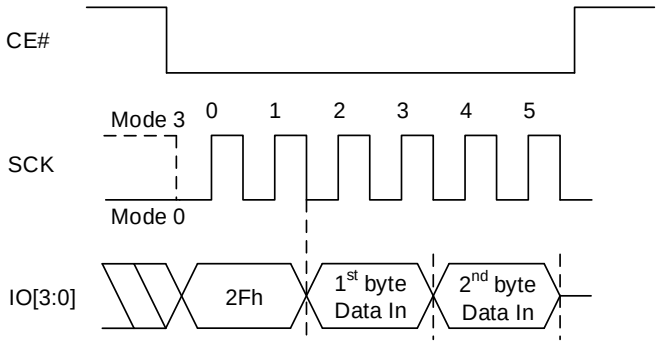



**Figure 8.134 Program ASP Sequence In QPI Mode**

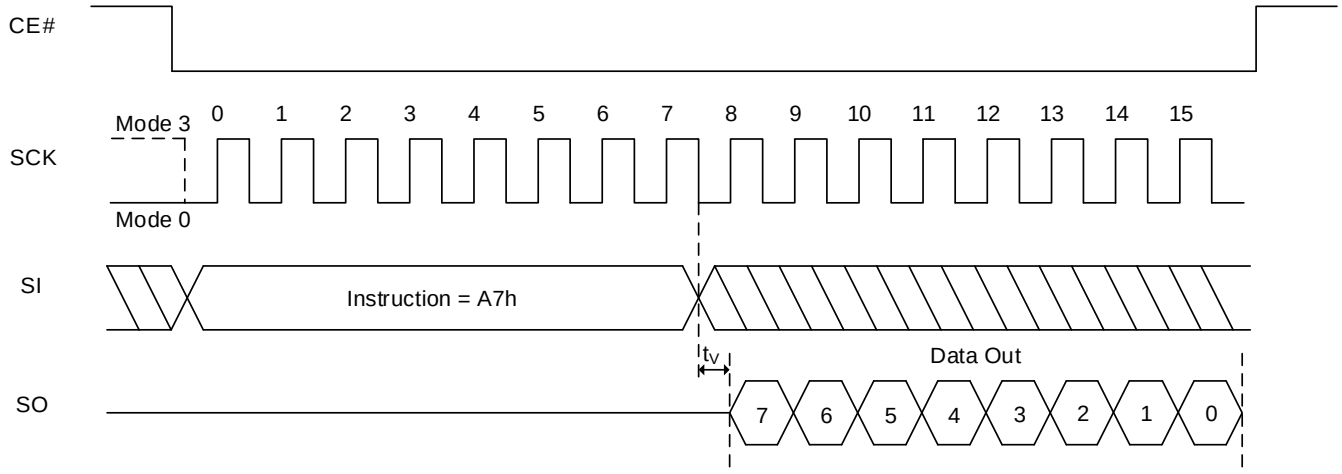


### 8.58 READ PPB LOCK BIT OPERATION (RDPLB, A7h)

The Read PPB Lock Bit (RDPLB) command allows the PPB Lock Register contents to be read. It is possible to read the PPB Lock Register continuously by providing multiples of eight bits. The PPB Lock Register contents may only be read when the device is in standby state with no other operation in progress. It is recommended to check the Write In Progress (WIP) bit before issuing a new command to the device.

RDPLB operation is valid only at SPI mode only.

**Figure 8.135 Read PPB Lock Bit Sequence In SPI Mode**



### 8.59 WRITE PPB LOCK BIT OPERATION (WRPLB, A6h)

The Write PPB Lock Bit (WRPLB) command only clears the PPB Lock (PPBLK) bit to "0" in the Persistent Protection mode. Before the WRPLB command can be accepted by the device, a Write Enable (WREN) command must be issued and decoded by the device, which sets the Write Enable Latch (WEL) in the Status Register to enable any write operations.

The WRPLB command is entered by driving CE# low, followed by the instruction code. CE# must be driven high after the eighth bit of instruction has been latched in. If not, the WRPLB command is not executed. As soon as CE# is driven high, the WRPLB operation is initiated. While the WRPLB operation is in progress, the Status Register or Extended Read Register may still be read to check the value of the Write In Progress (WIP) bit. The WIP bit is "1" during the WRPLB operation, and is "0" when it is completed. When the WRPLB operation is completed, the WEL is set to "0".

**Figure 8.136 Write PPB Lock Bit Sequence In SPI Mode**

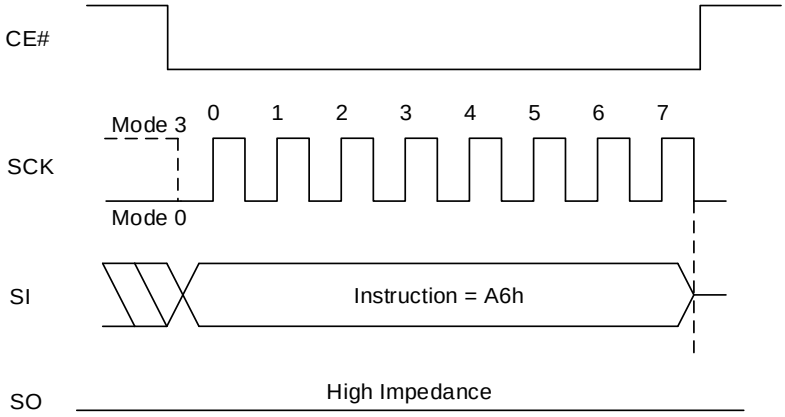
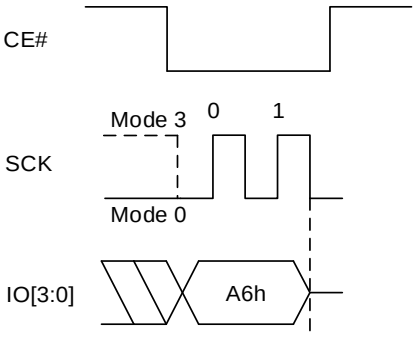



**Figure 8.137 Write PPB Lock Bit Sequence In QPI Mode**



### 8.60 SET FREEZE BIT OPERATION (SFRZ, 91h)

The Set FREEZE Bit (SFRZ) command only sets FREEZE (PPB Lock Register bit7) to “1”. Please refer to the section 6.6.3 PPB Lock Register for more detail. Before the SFRZ command can be accepted by the device, a Write Enable (WREN) command must be issued and decoded by the device, which sets the Write Enable Latch (WEL) in the Status Register to enable any write operations.

The SFRZ command is entered by driving CE# low, followed by the instruction code. CE# must be driven high after the eighth bit of instruction has been latched in. If not, the SFRZ command is not executed. As soon as CE# is driven high, the SFRZ operation is initiated. While the SFRZ operation is in progress, the Status Register or Extended Read Register may still be read to check the value of the Write In Progress (WIP) bit. The WIP bit is “1” during the SFRZ operation, and is “0” when it is completed. When the SFRZ operation is completed, the WEL is set to “0”.

**Figure 8.138 Set FREEZE Bit Sequence In SPI Mode**

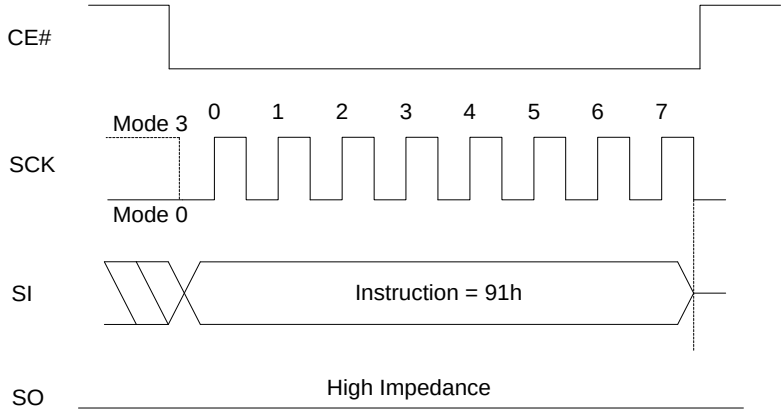
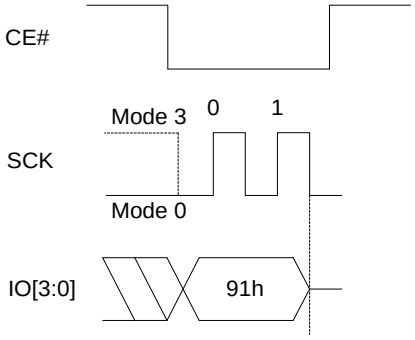



**Figure 8.139 Set FREEZE Bit Sequence In QPI Mode**



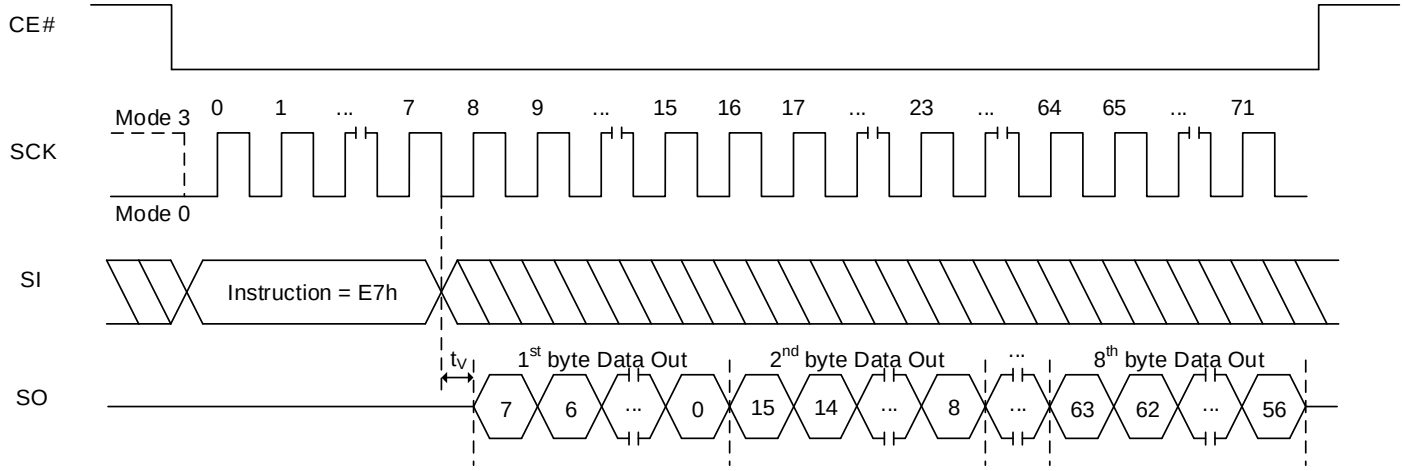
### 8.61 READ PASSWORD OPERATION (RDPWD, E7h)

The correct password value may be read only after it is programmed and before the Password Mode has been selected by programming the Password Protection Mode bit to "0" in the ASP Register (ASP [2]). After the Password Protection Mode is selected the RDPWD command is ignored.

The RDPWD command is shifted in. Then the 64-bit Password is shifted out, least significant byte first, most significant bit of each byte first. Each bit is shifted out at the SCK frequency by the falling edge of the SCK signal. It is possible to read the Password continuously by providing multiples of 64bits.

RDPWD operation is valid only at SPI mode only.

**Figure 8.140 Read password Sequence In SPI Mode**



### 8.62 PROGRAM PASSWORD OPERATION (PGPWD, E8h)

Before the Program Password (PGPWD) command can be accepted by the device, a Write Enable (WREN) command must be issued and decoded by the device which sets the Write Enable Latch (WEL) to enable the PGPWD operation. The password can only be programmed before the Password Mode is selected by programming the Password Protection Mode bit to "0" in the ASP Register (ASP [2]). After the Password Protection Mode is selected the PGPWD command is ignored.

The PGPWD command is entered by driving CE# low, followed by the instruction code and the password data bytes, least significant byte first, most significant bit of each byte first. The password is 64bits in length.

CE# must be driven high after the 64th bit of data has been latched. If not, the PGPWD command is not executed. As soon as CE# is driven high, the PGPWD operation is initiated. While the PGPWD operation is in progress, the Status Register or Extended Read Register may be read to check the value of the Write In Progress (WIP) bit. The WIP bit is "1" during the PGPWD operation, and is "0" when it is completed. When the PGPWD operation is completed, the Write Enable Latch (WEL) is set to "0".

**Figure 8.141 Program Password Sequence In SPI Mode**

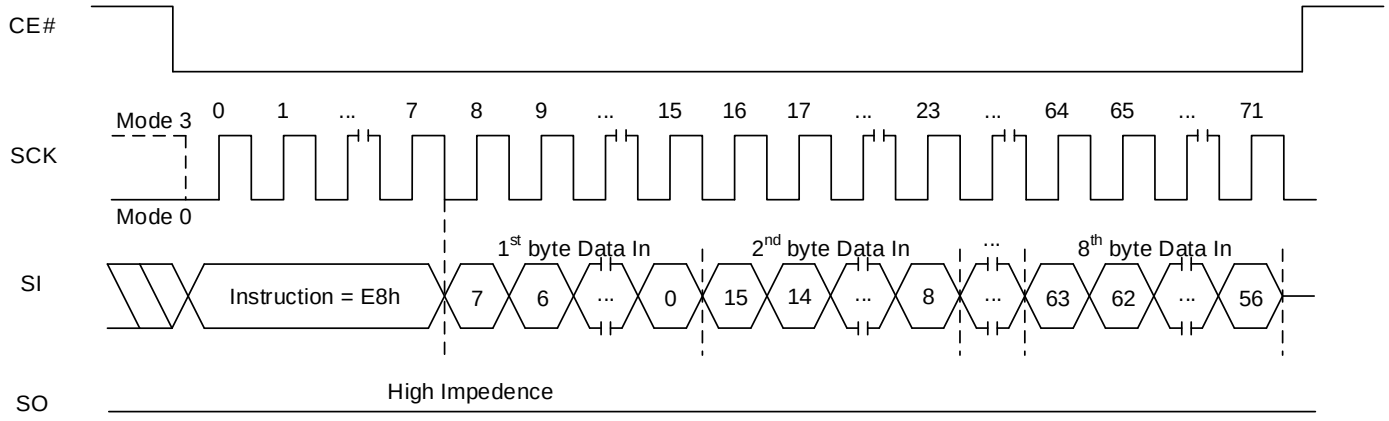
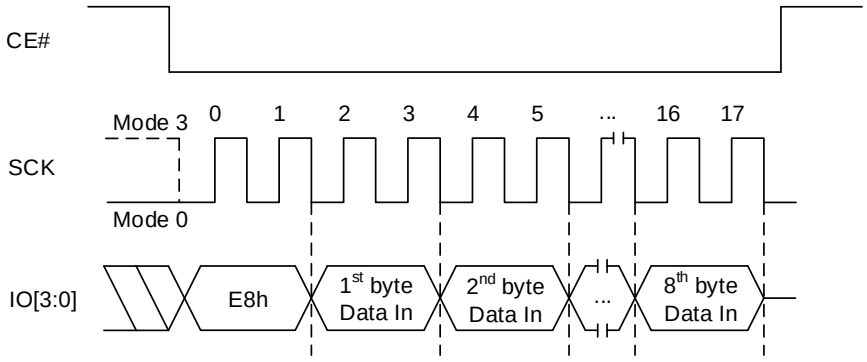



**Figure 8.142 Program Password Sequence In QPI Mode**



### 8.63 UNLOCK PASSWORD OPERATION (UNPWD, E9h)

In the Password Protection mode, the PPB Lock bit is cleared to "0" during POR or Hardware Reset. The PPB Lock bit can only be set to 1 by the Unlock Password command.

A Write Enable (WREN) command is not required prior to UNPWD command
The UNPWD command is entered by driving CE# low, followed by the instruction code and the password data bytes, least significant byte first, most significant bit of each byte first. The password is 64bits in length.

CE# must be driven high after the 64th bit of data has been latched. If not, the UNPWD command is not executed. As soon as CE# is driven high, the UNPWD operation is initiated. While the UNPWD operation is in progress, the Status Register or Extended Read Register may be read to check the value of the Write In Progress (WIP) bit. The WIP bit is "1" during the UNPWD operation, and is "0" when it is completed.

If the UNPWD command supplied password does not match the hidden password in the Password Register, the UNPWD command is ignored. This returns the device to standby state, ready for a new command such as a retry of the UNPWD command. If the password does match, the PPB Lock bit is set to "1".

**Figure 8.143 Unlock Password Sequence In SPI Mode**

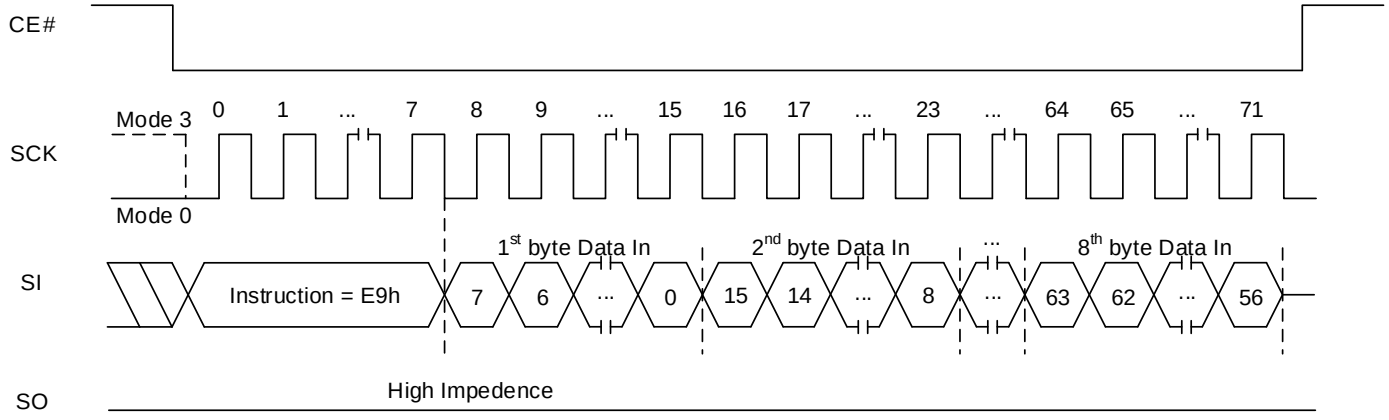
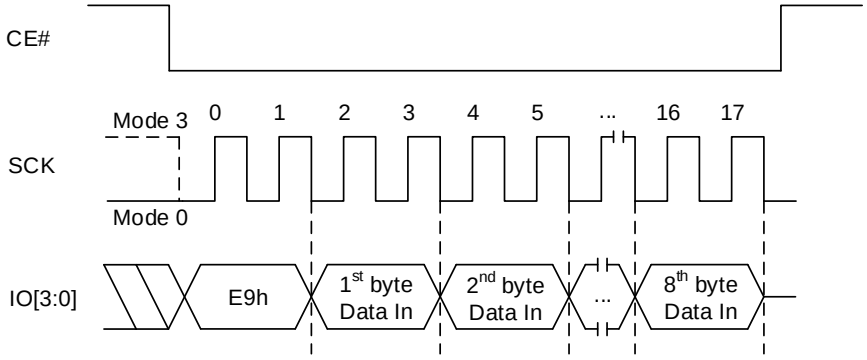



**Figure 8.144 Unlock Password Sequence In SPI Mode**



### 8.64 GANG SECTOR/BLOCK LOCK OPERATION (GBLK, 7Eh)

The Gang Sector/Block Lock (GBLK) instruction provides a quick method to set all DYB (Dynamic Protection Bit) bits to “0” at once.

Before the GBLK (7Eh) command can be accepted by the device, a Write Enable (WREN) command must be issued and decoded by the device, which sets the Write Enable Latch (WEL) in the Status Register to enable any write operations.

The sequence of issuing GBLK instruction is: drive CE# low → send GBLK instruction code → drive CE# high. The instruction code will be shifted into the device on the rising edge of SCK.

The GBLK command is accepted in both SPI and QPI mode. The CE# must go high exactly at the byte boundary, otherwise, the instruction will be ignored. While the GBLK operation is in progress, the Status Register or Extended Read Register may be read to check the value of the Write In Progress (WIP) bit. The WIP bit is “1” during the GBLK operation, and is “0” when it is completed.

**Figure 8.145 Gang Sector/Block Lock Sequence In SPI Mode**

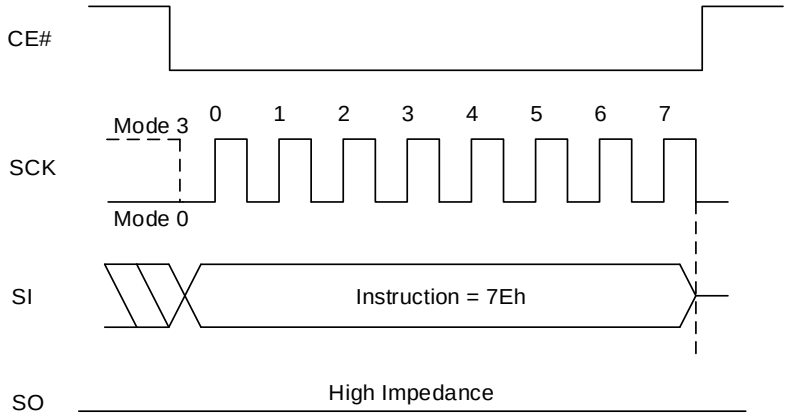
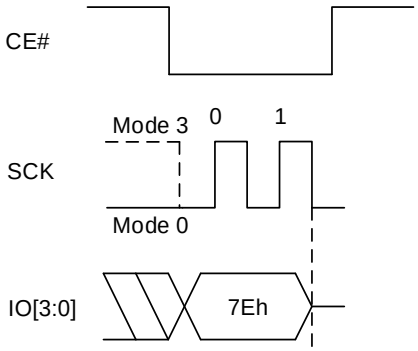



**Figure 8.146 Gang Sector/Block Lock Sequence In QPI Mode**



### 8.65 GANG SECTOR/BLOCK UNLOCK OPERATION (GBUN, 98h)

The Gang Sector/Block Unlock (GBUN) instruction provides a quick method to clear all DYB (Dynamic Protection Bit) bits to "1" at once.

Before the GBUN (98h) command can be accepted by the device, a Write Enable (WREN) command must be issued and decoded by the device, which sets the Write Enable Latch (WEL) in the Status Register to enable any write operations.

The sequence of issuing GBUN instruction is: drive CE# low → send GBUN instruction code → drive CE# high. The instruction code will be shifted into the device on the rising edge of SCK.

The GBUN command is accepted in both SPI and QPI mode. The CE# must go high exactly at the byte boundary, otherwise, the instruction will be ignored and not be executed. While the GBUN operation is in progress, the Status Register or Extended Read Register may be read to check the value of the Write In Progress (WIP) bit. The WIP bit is "1" during the GBUN operation, and is "0" when it is completed.

**Figure 8.147 Gang Sector/Block Unlock Sequence In SPI Mode**

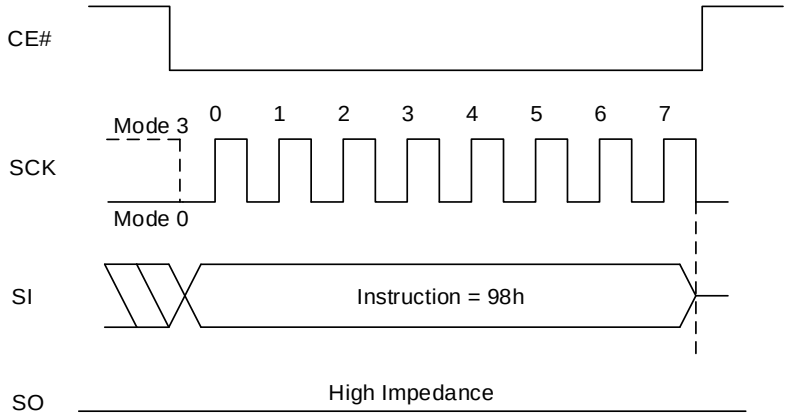
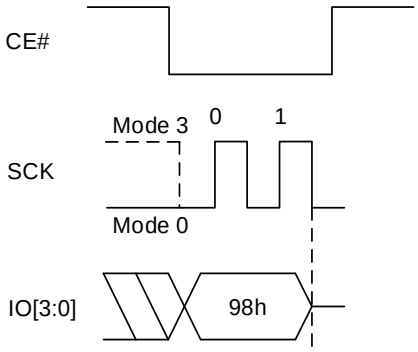



**Figure 8.148 Gang Sector/Block Unlock Sequence In QPI Mode**



# 9. ELECTRICAL CHARACTERISTICS

## 9.1 ABSOLUTE MAXIMUM RATINGS (1)

| | | |
|---|---|---|
| Storage Temperature | | -65°C to +150°C |
| Surface Mount Lead Soldering Temperature | Standard Package | 240°C 3 Seconds |
| | Lead-free Package | 260°C 3 Seconds |
| Input Voltage with Respect to Ground on All Pins | | -0.5V to $V_{CC}$ + 0.5V |
| All Output Voltage with Respect to Ground | | -0.5V to $V_{CC}$ + 0.5V |
| $V_{CC}$ | IS25LP | -0.5V to +6.0V |
| | IS25WP | -0.5V to +2.5V |

**Notes:**
1. **Applied conditions greater than those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.**
2. **ANSI/ESDA/JEDEC JS-001**

## 9.2 OPERATING RANGE

| | | |
|---|---|---|
| Operating Temperature | Extended Grade E | -40°C to 105°C |
| | Automotive Grade A3 | -40°C to 125°C |
| $V_{CC}$ Power Supply | IS25LP | 2.3V (VMIN) – 3.6V (VMAX); 3.0V (Typ) |
| | IS25WP | 1.65V (VMIN) –1.95V (VMAX); 1.8V (Typ) |

## 9.3 DC CHARACTERISTICS

(-40°C to 125°C, 2.3V – 3.6V for 3.0V device & 1.65V– 1.95V for 1.8V device)

| Symbol | Parameter | | Condition | | Min | Typ(2) | Max | Units |
|---|---|---|---|---|---|---|---|---|
| $I_{CC1}$ | $V_{CC}$ Active Read current(3) | | NORD at 80MHz | | | 8 | 9 | mA |
| | | | FRD Single at 166MHz | | | 9 | 11 | |
| | | | FRD Dual at 166MHz | | | 11 | 12 | |
| | | | FRD Quad at 166MHz | | | 14 | 15 | |
| | | | FRD Single at 133MHz | | | 9 | 10.5 | |
| | | | FRD Dual at 133MHz | | | 10 | 11 | |
| | | | FRD Quad at 133MHz | | | 12.5 | 13.5 | |
| | | | FRD Quad at 83MHz | | | 10 | 11 | |
| | | | FRD Quad at 104MHz | | | 11 | 12 | |
| | | | FRD Single DTR at 80MHz | | | 8.5 | 9.5 | |
| | | | FRD Dual DTR at 80MHz | | | 10 | 11 | |
| | | | FRD Quad DTR at 80MHz | | | 11 | 12 | |
| $I_{CC2}$ | $V_{CC}$ Program Current | | CE# = $V_{CC}$ | 85°C | | 25 | 30 (6) | mA |
| | | | | 105°C | | | 30 (6) | |
| | | | | 125°C | | | 30 | |
| $I_{CC3}$ | $V_{CC}$ WRSR Current | | CE# = $V_{CC}$ | 85°C | | 25 | 30 (6) | |
| | | | | 105°C | | | 30 (6) | |
| | | | | 125°C | | | 30 | |
| $I_{CC4}$ | $V_{CC}$ Erase Current (SER/4SER/BER32/4BER32/ BER64/4BER64) | | CE# = $V_{CC}$ | 85°C | | 25 | 30 (6) | |
| | | | | 105°C | | | 30 (6) | |
| | | | | 125°C | | | 30 | |
| $I_{CC5}$ | $V_{CC}$ Erase Current (CE) | | CE# = $V_{CC}$ | 85°C | | 25 | 30 (6) | |
| | | | | 105°C | | | 30 (6) | |
| | | | | 125°C | | | 30 | |
| $I_{SB1}$ | $V_{CC}$ Standby Current CMOS | IS25LP | CE# = $V_{CC}$, $V_{IN}$ = GND or $V_{CC}$ (4) | 85°C | | 8 | 30 (6) | µA |
| | | | | 105°C | | | 45 (6) | |
| | | | | 125°C | | | 70 | |
| | | IS25WP | | 85°C | | 8 | 35 (6) | |
| | | | | 105°C | | | 45 (6) | |
| | | | | 125°C | | | 75 | |
| $I_{SB2}$ | Deep power down current | IS25LP | CE# = $V_{CC}$, $V_{IN}$ = GND or $V_{CC}$ (4) | 85°C | | 5 | 15 (6) | µA |
| | | | | 105°C | | | 20 (6) | |
| | | | | 125°C | | | 35 | |
| | | IS25WP | | 85°C | | 1 | 10 (6) | |
| | | | | 105°C | | | 15 (6) | |
| | | | | 125°C | | | 25 | |
| $I_{LI}$ | Input Leakage Current | | $V_{IN}$ = 0V to $V_{CC}$ | | | | ±1(5) | µA |
| $I_{LO}$ | Output Leakage Current | | $V_{IN}$ = 0V to $V_{CC}$ | | | | ±1(5) | µA |
| $V_{IL}$(1) | Input Low Voltage | | | | -0.5 | | 0.3$V_{CC}$ | V |
| $V_{IH}$(1) | Input High Voltage | | | | 0.7$V_{CC}$ | | $V_{CC}$ + 0.3 | V |
| $V_{OL}$ | Output Low Voltage | | $I_{OL}$ = 100 µA | | | | 0.2 | V |
| $V_{OH}$ | Output High Voltage | | $I_{OH}$ = -100 µA | | $V_{CC}$ - 0.2 | | | V |

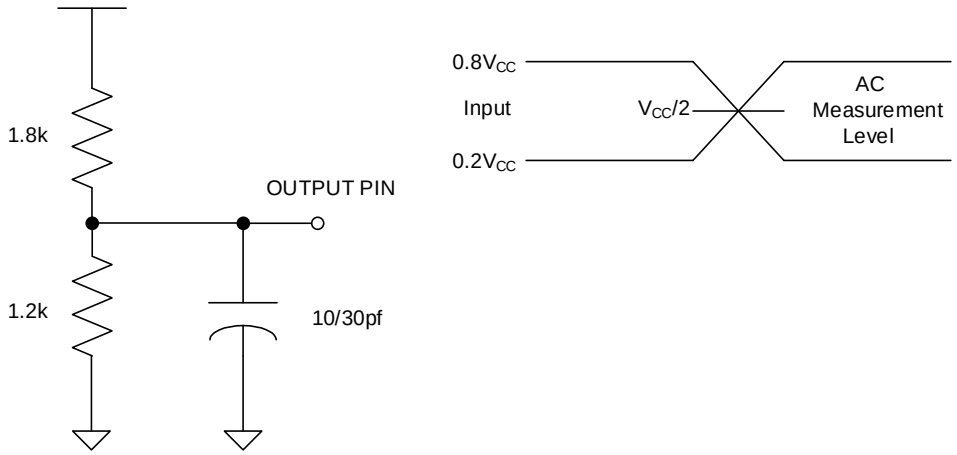
**Notes:**

1. **Maximum DC voltage on input or I/O pins is VCC + 0.5V. During voltage transitions, input or I/O pins may overshoot VCC by +2.0V for a period of time not to exceed 20ns. Minimum DC voltage on input or I/O pins is -0.5V. During voltage transitions, input or I/O pins may undershoot GND by -2.0V for a period of time not to exceed 20ns.**
2. **Typical values are included for reference only and are not guaranteed or tested. Typical values are measured at $V_{CC}$ = $V_{CC}$ (Typ), TA=25°C.**
3. **Outputs are unconnected during reading data so that output switching current is not included.**
4. **$V_{IN}$ = Vcc for the dedicated RESET# pin (or ball).**
5. **The Max of $I_{LI}$ and $I_{LO}$ for the dedicated RESET# pin (or ball) is ±2 µA.**
6. **These parameters are characterized and are not 100% tested.**

### 9.4 AC MEASUREMENT CONDITIONS

| Symbol | Parameter | Min | Max | Units |
|---|---|---|---|---|
| CL | Load Capacitance | | 30 | pF |
| | Load Capacitance | | 10 | pF |
| TR,TF | Input Rise and Fall Times | | 5 | ns |
| VIN | Input Pulse Voltages | $0.2V_{CC}$ to $0.8V_{CC}$ | | V |
| VREFI | Input Timing Reference Voltages | $0.3V_{CC}$ to $0.7V_{CC}$ | | V |
| VREFO | Output Timing Reference Voltages | $0.5V_{CC}$ | | V |

**Figure 9.1 Output test load & AC measurement I/O Waveform**




### 9.5 PIN CAPACITANCE

(TA = 25°C, VCC=3V for IS25LP, VCC=1.8V for IS25WP, 1MHz)

| Symbol | Parameter | Test Condition | IS25LP | | IS25WP | | Units |
|---|---|---|---|---|---|---|---|
| | | | Min | Max | Min | Max | |
| $C_{IN}$ | Input Capacitance (CE#, SCK) | $V_{IN}$ = 0V | - | 6 | - | 6 | pF |
| $C_{IN/OUT}$ | Input/Output Capacitance (other pins) | $V_{IN/OUT}$ = 0V | - | 8 | - | 10 | pF |

## 9.6 AC CHARACTERISTICS

(-40°C to 125°C, 2.3V – 3.6V for 3.0V device & 1.65V– 1.95V for 1.8V device)

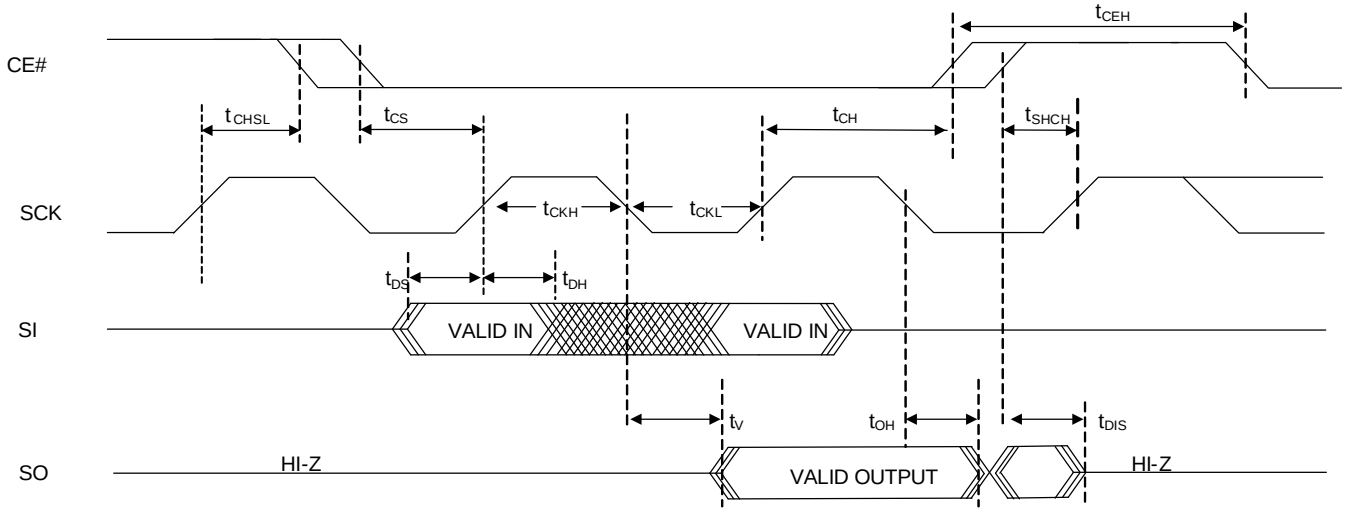
| Symbol | Parameter | | | | Min | Typ[2] | Max | Units |
|---|---|---|---|---|---|---|---|---|
| $f_{CT}$ | Clock Frequency except for fast read DTR and read (03h) | | IS25LP | VCC = 2.7V to 3.6V | 0 | | 166 | MHz |
| | | | | VCC = 2.3V to 3.6V | 0 | | 133 | MHz |
| | | | IS25WP | VCC = 1.7V to 1.95V | 0 | | 166[4, 5, 6] | MHz |
| | | | | VCC = 1.65V to 1.95V | 0 | | 133 | MHz |
| | Clock Frequency for fast read DTR: SPI DTR, Dual DTR, Dual I/O DTR, Quad I/O DTR, and QPI DTR. | | | | 0 | | 80 | MHz |
| $f_C$ | Clock Frequency for read (03h) | | | | 0 | | 80 | MHz |
| $t_{CLCH}$[1] | SCK Rise Time (peak to peak) | | | | 0.1 | | | V/ns |
| $t_{CHCL}$[1] | SCK Fall Time ( peak to peak) | | | | 0.1 | | | V/ns |
| $t_{CKH}$ | SCK High Time | | | For read (03h) | 0.45 x 1/$f_{Cmax}$ | | | ns |
| | | | | For others | 0.45 x 1/$f_{CTmax}$ | | | |
| $t_{CKL}$ | SCK Low Time | | | For read (03h) | 0.45 x 1/$f_{Cmax}$ | | | ns |
| | | | | For others | 0.45 x 1/$f_{CTmax}$ | | | |
| $t_{CEH}$ | CE# High Time | | | For read mode | 7 | | | ns |
| | | | | For write mode | 20 | | | ns |
| $t_{CS}$ | CE# Setup Time | | | | 3 | | | ns |
| $t_{CH}$ | CE# Hold Time | | | | 3 | | | ns |
| $t_{CHSL}$ | CE# Not Active Hold Time | | | | 3 | | | ns |
| $t_{SHCH}$ | CE# Not Active Setup Time | | | | 3 | | | ns |
| $t_{DS}$ | Data In Setup Time | | | STR | 2 | | | ns |
| | | | | DTR | 1.5 | | | |
| $t_{DH}$ | Data in Hold Time | | | STR | 2 | | | ns |
| | | | | DTR | 1.5 | | | |
| $t_V$ | Output Valid | IS25LP | 2.7~3.6V, -40°C to 85°C | @10pF | | | 5.5[4] | ns |
| | | | | @30pF | | | 7.0[4] | |
| | | | 2.3~3.6V, -40°C to 125°C | @10pF | | | 6.5 | |
| | | | | @30pF | | | 8.0 | |
| | | IS25WP | 1.65~1.95V, -40°C to 125°C | @10pF | | | 5.5 | |
| | | | | @30pF | | | 7.0 | |
| $t_{OH}$ | Output Hold Time | | | | 2 | | | ns |
| $t_{DIS}$[1] | Output Disable Time | | | | | | 8 | ns |
| $t_{WHSL}$[3] | Write Protect Setup Time | | | | 20 | | | ns |
| $t_{SHWL}$[3] | Write Protect Hold Time | | | | 100 | | | ns |

| Symbol | Parameter | | Min | Typ(2) | Max | Units |
|---|---|---|---|---|---|---|
| $t_{HLCH}$ | HOLD Active Setup Time relative to SCK | | 2 | | | ns |
| $t_{CHHH}$ | HOLD Active Hold Time relative to SCK | | 2 | | | ns |
| $t_{HHCH}$ | HOLD Not Active Setup Time relative to SCK | | 2 | | | ns |
| $t_{CHHL}$ | HOLD Not Active Hold Time relative to SCK | | 2 | | | ns |
| $t_{LZ}$(1) | HOLD to Output Low Z | | | | 8 | ns |
| $t_{HZ}$(1) | HOLD to Output High Z | | | | 8 | ns |
| $t_{EC}$ | Sector Erase Time (4Kbyte) | | | 100 | 300 | ms |
| | Block Erase Time (32Kbyte) | | | 0.14 | 0.5 | s |
| | Block Erase time (64Kbyte) | | | 0.17 | 1.0 | s |
| | Chip Erase Time | | | 35 | 90 | s |
| $t_{PP}$ | Page Program Time | | | 0.2 | 0.8 | ms |
| $t_{RES1}$(1) | Release deep power down | IS25LP | | | 3 | µs |
| | | IS25WP | | | 5 | |
| $t_{DP}$(1) | Deep power down | | | | 3 | µs |
| $t_W$ | Write Status Register time | | | 2 | 15 | ms |
| $t_{SUS}$(1) | Suspend to read ready | | | 100 | - | µs |
| $T_{RS}$(1) | Resume to next suspend | | | 400 | - | µs |
| $t_{SRST}$(1) | Software Reset recovery time | | | | 35 | µs |
| $t_{RESET}$(1) | RESET# pin low pulse width | | 100 | | | ns |
| $t_{HWRST}$(1) | Hardware Reset recovery time | | | | 35 | µs |

**Notes:**
1. **These parameters are characterized and not 100% tested.**
2. **Typical values are for reference purpose only and are not guaranteed nor tested. Typical values are measured at $V_{CC}$ = $V_{CC}$ (Typ), TA=25°C.**
3. **Only applicable as a constraint for a WRITE STATUS REGISTER command when SRWD is set at 1**
4. **Values are guaranteed by characterization and not 100% tested in production.**
5. **166MHz at - 40°C to 105°C**
6. **Max. Frequency for RDDYB (FAh) or 4RDDYB (E0h) in QPI mode is 133MHz.**

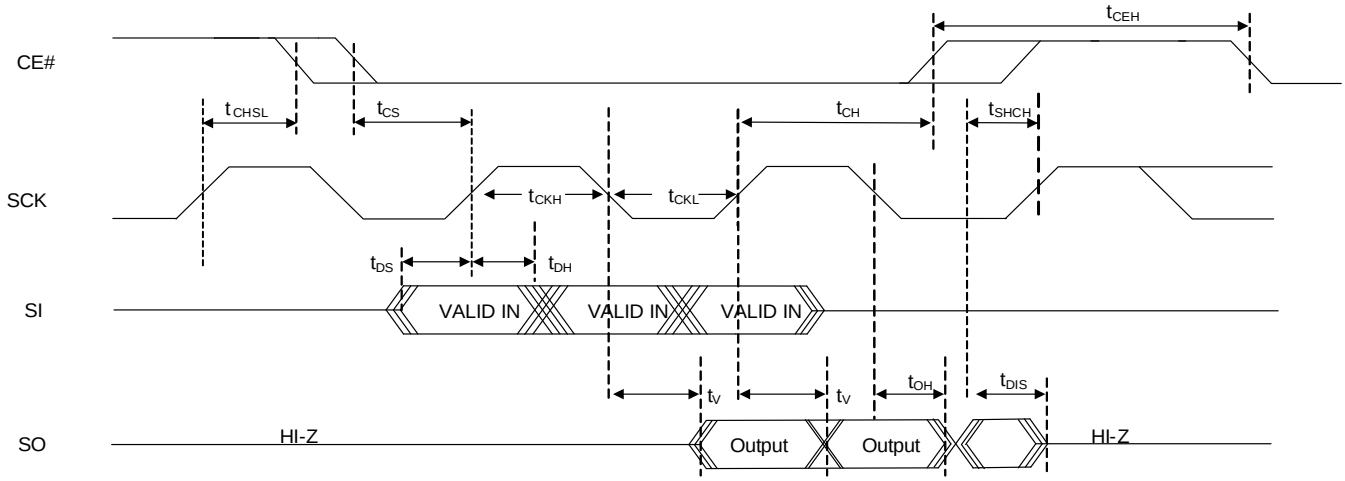
## 9.7 SERIAL INPUT/OUTPUT TIMING

**Figure 9.2 SERIAL INPUT/OUTPUT TIMING (Normal Mode)** (1)




**Note1: For SPI Mode 0 (0,0)**

**Figure 9.3 SERIAL INPUT/OUTPUT TIMING (DTR Mode)** (1)




**Note1: For SPI Mode 0 (0,0)**

**Figure 9.4 HOLD TIMING**

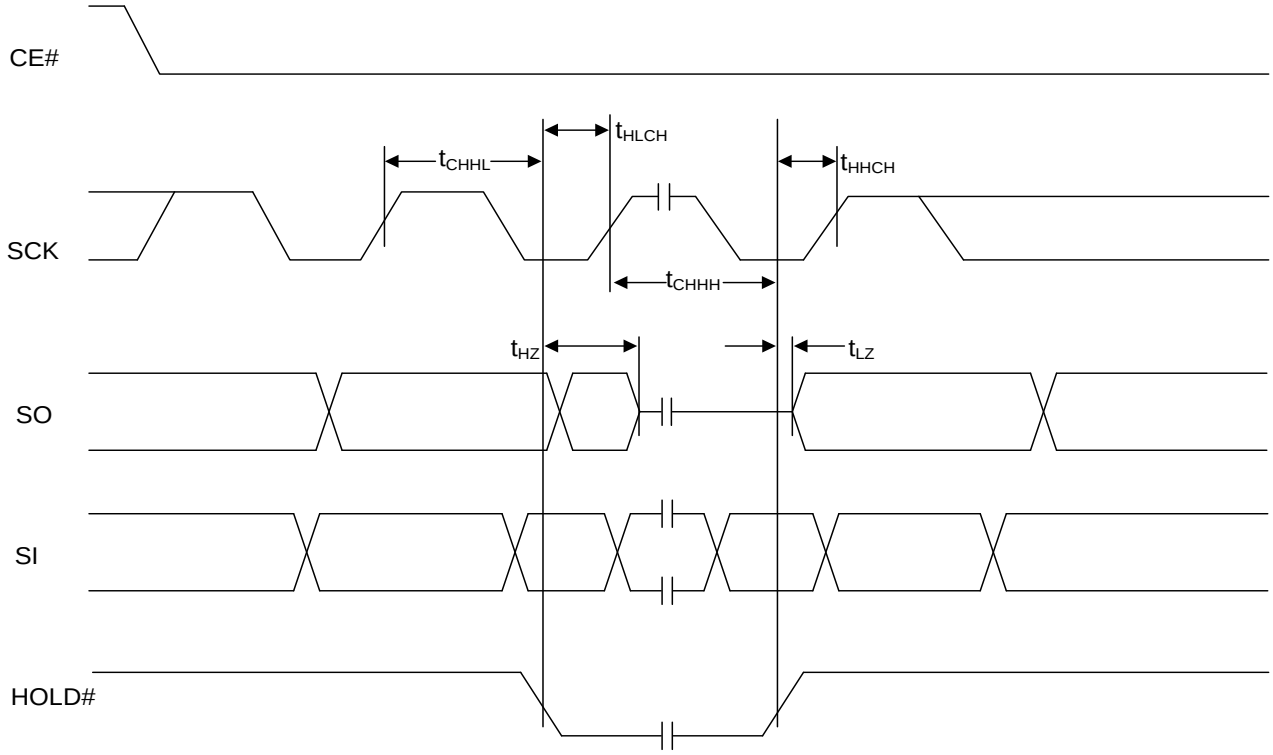
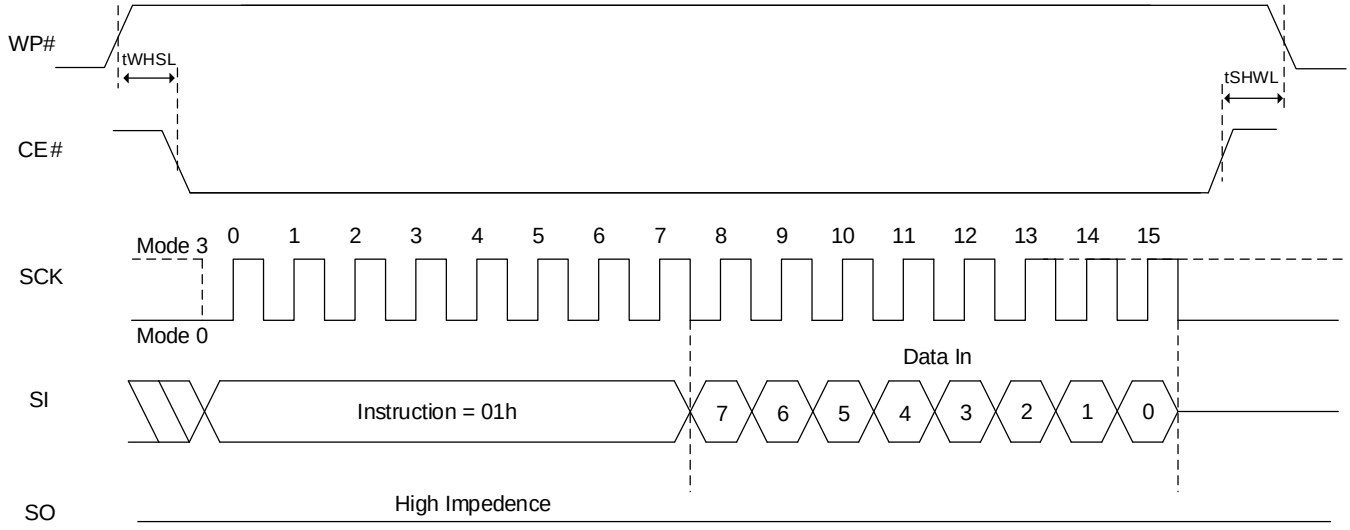



**Figure 9.5 WRITE PROTECT SETUP AND HOLD TIMIMNG DURING WRITE STATUS REGISTER (SRWD=1)**

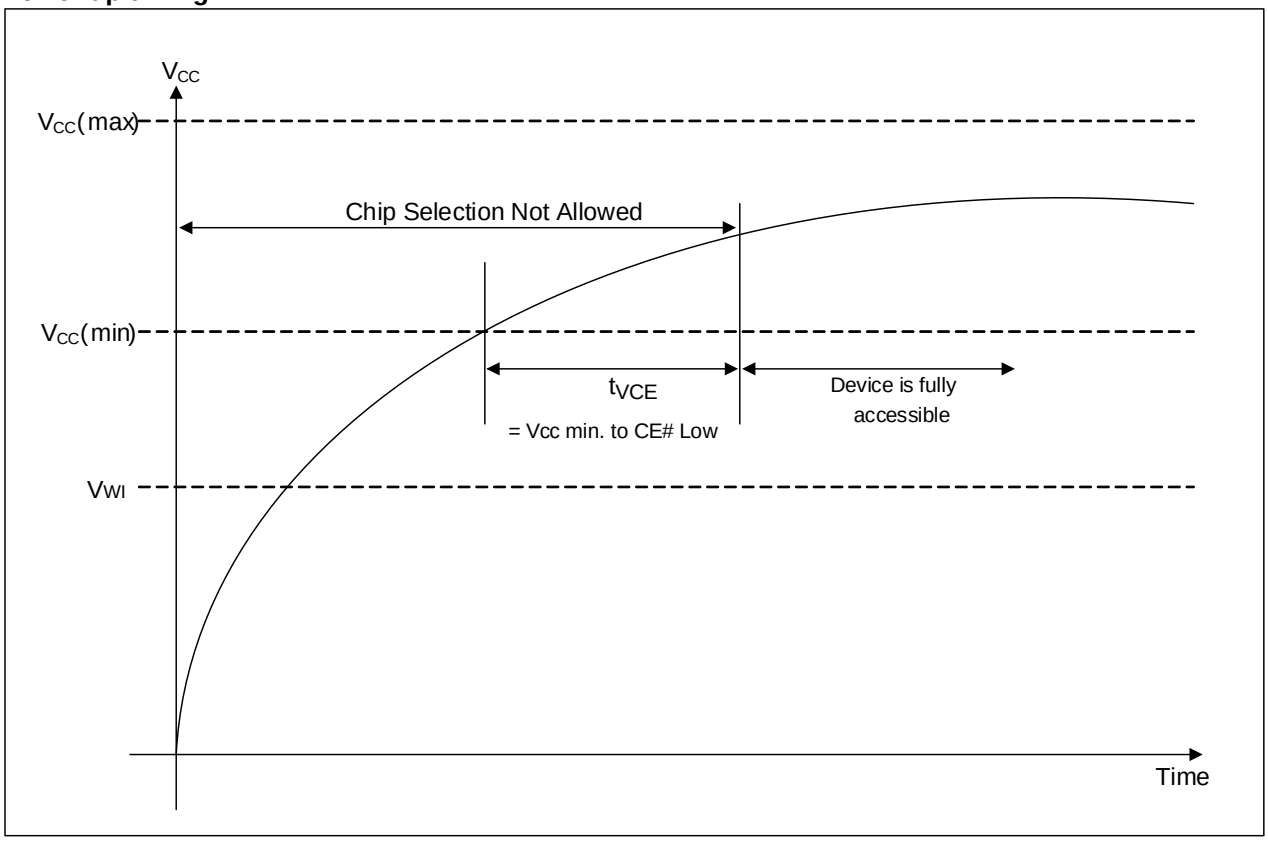



**Note: WP# must be kept high until the embedded operation finish.**

### 9.8 POWER-UP AND POWER-DOWN

At Power-up and Power-down, the device must be NOT SELECTED until Vcc reaches at the right level. (Adding a simple pull-up resistor on CE# is recommended.)

**Power up timing**




| Symbol | Parameter | | Min. | Max | Unit |
|---|---|---|---|---|---|
| tVCE(1) | Vcc(min) to CE# Low | | 300 | | us |
| VWI(1) | Write Inhibit Voltage | IS25LP | | 2.1 | V |
| | | IS25WP | | 1.4 | |

**Note: These parameters are characterized and not 100% tested.**

### 9.9 PROGRAM/ERASE PERFORMANCE

| Parameter | Typ | Max | Unit |
|---|---|---|---|
| Sector Erase Time (4Kbyte) | 100 | 300 | ms |
| Block Erase Time (32Kbyte) | 0.14 | 0.5 | s |
| Block Erase Time (64Kbyte) | 0.17 | 1.0 | s |
| Chip Erase Time | 35 | 90 | s |
| Page Programming Time | 0.2 | 0.8 | ms |
| Byte Program | 8 | 40 | µs |

**Note: These parameters are characterized and not 100% tested.**

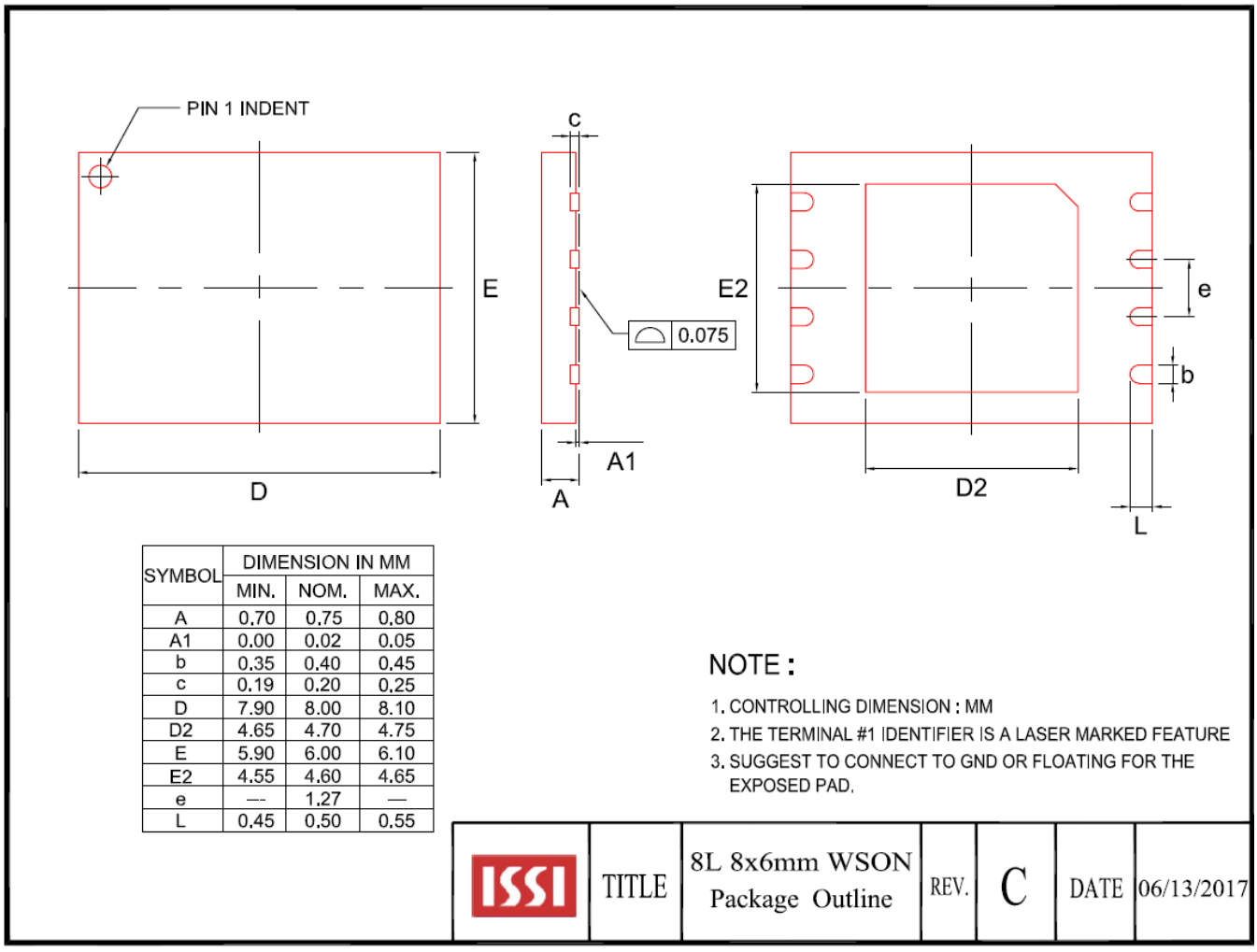
### 9.10 RELIABILITY CHARACTERISTICS

| Parameter | Min | Max | Unit | Test Method |
|---|---|---|---|---|
| Endurance | 100,000 | - | Cycles | JEDEC Standard A117 |
| Data Retention | 20 | - | Years | JEDEC Standard A117 |
| Latch-Up | -100 | +100 | mA | JEDEC Standard 78 |

**Note: These parameters are characterized and not 100% tested.**

# 10. PACKAGE TYPE INFORMATION

## 10.1 8-CONTACT ULTRA-THIN SMALL OUTLINE NO-LEAD (WSON) PACKAGE 8X6MM (L)



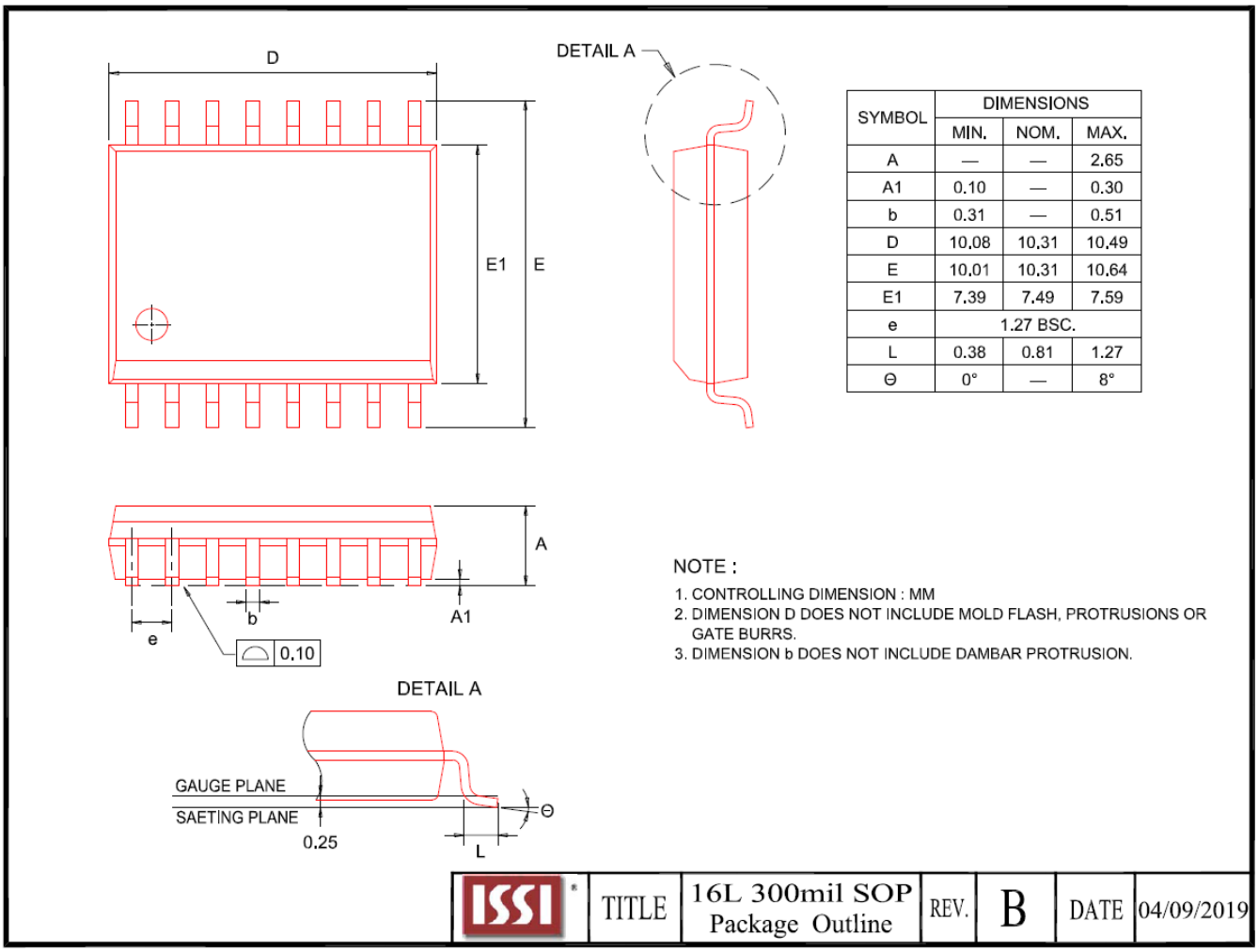

| SYMBOL | DIMENSION IN MM | | |
|---|---|---|---|
| | MIN. | NOM. | MAX. |
| A | 0.70 | 0.75 | 0.80 |
| A1 | 0.00 | 0.02 | 0.05 |
| b | 0.35 | 0.40 | 0.45 |
| c | 0.19 | 0.20 | 0.25 |
| D | 7.90 | 8.00 | 8.10 |
| D2 | 4.65 | 4.70 | 4.75 |
| E | 5.90 | 6.00 | 6.10 |
| E2 | 4.55 | 4.60 | 4.65 |
| e | --- | 1.27 | --- |
| L | 0.45 | 0.50 | 0.55 |

NOTE :

1. CONTROLLING DIMENSION : MM
2. THE TERMINAL #1 IDENTIFIER IS A LASER MARKED FEATURE
3. SUGGEST TO CONNECT TO GND OR FLOATING FOR THE EXPOSED PAD.

| | TITLE | 8L 8x6mm WSON Package Outline | REV. | C | DATE | 06/13/2017 |
|---|---|---|---|---|---|---|

## 10.2 16-LEAD PLASTIC SMALL OUTLINE PACKAGE (300 MILS BODY WIDTH) (M)

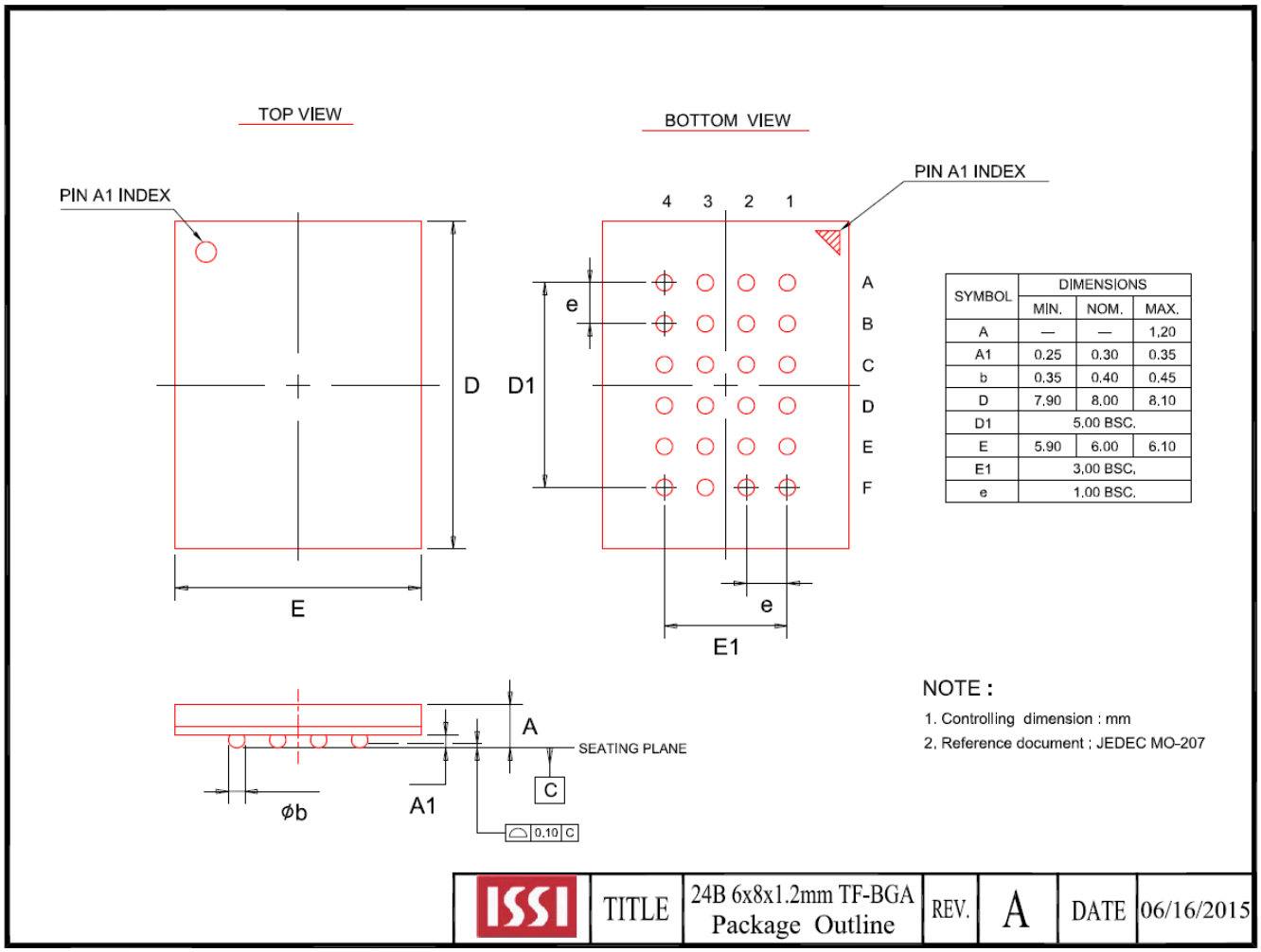



| SYMBOL | DIMENSIONS | | |
|---|---|---|---|
| | MIN. | NOM. | MAX. |
| A | — | — | 2.65 |
| A1 | 0.10 | — | 0.30 |
| b | 0.31 | — | 0.51 |
| D | 10.08 | 10.31 | 10.49 |
| E | 10.01 | 10.31 | 10.64 |
| E1 | 7.39 | 7.49 | 7.59 |
| e | 1.27 BSC. | | |
| L | 0.38 | 0.81 | 1.27 |
| Θ | 0° | — | 8° |

NOTE :
1. CONTROLLING DIMENSION : MM
2. DIMENSION D DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION.

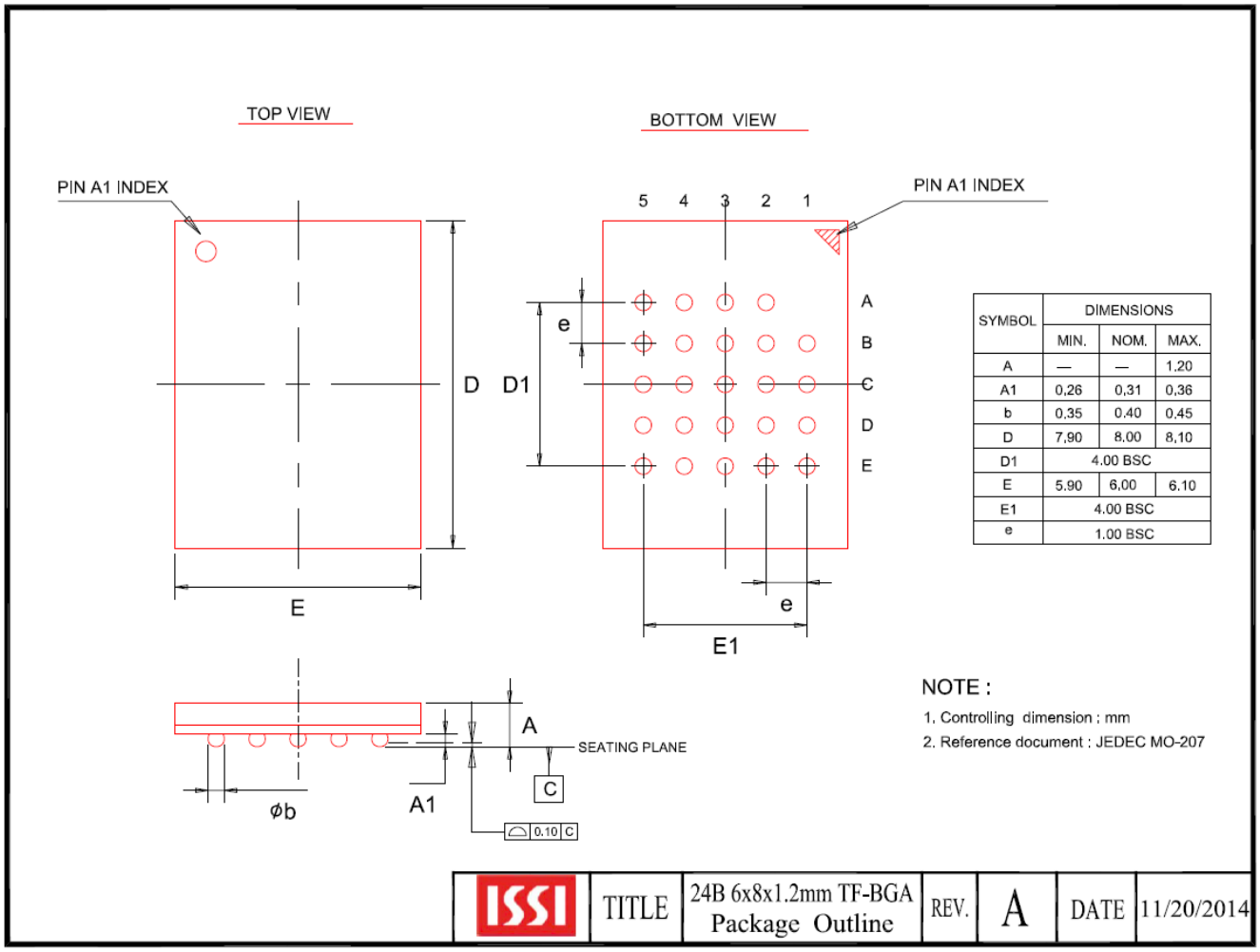
| | | | | | | | |
|---|---|---|---|---|---|---|---|
| ISSI | TITLE | 16L 300mil SOP Package Outline | REV. | B | DATE | 04/09/2019 |

## 10.3 24-BALL THIN PROFILE FINE PITCH BGA 6X8MM 4X6 BALL ARRAY (G)



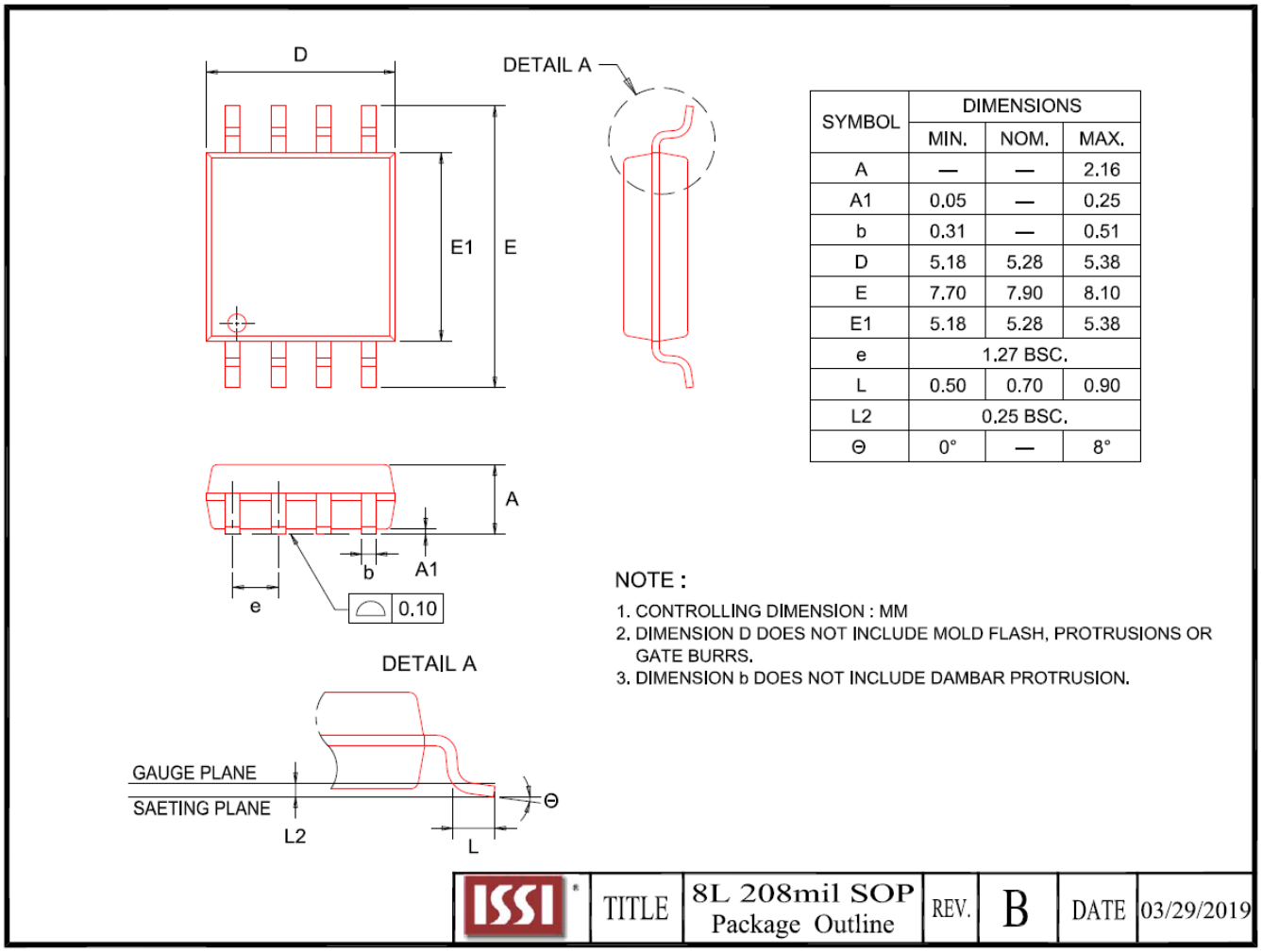

| SYMBOL | DIMENSIONS | | |
|---|---|---|---|
| | MIN. | NOM. | MAX. |
| A | — | — | 1.20 |
| A1 | 0.25 | 0.30 | 0.35 |
| b | 0.35 | 0.40 | 0.45 |
| D | 7.90 | 8.00 | 8.10 |
| D1 | | 5.00 BSC. | |
| E | 5.90 | 6.00 | 6.10 |
| E1 | | 3.00 BSC. | |
| e | | 1.00 BSC. | |

## 10.4 24-BALL THIN PROFILE FINE PITCH BGA 6X8MM 5X5 BALL ARRAY (H)




| SYMBOL | DIMENSIONS | | |
|---|---|---|---|
| | MIN. | NOM. | MAX. |
| A | — | — | 1.20 |
| A1 | 0.26 | 0.31 | 0.36 |
| b | 0.35 | 0.40 | 0.45 |
| D | 7.90 | 8.00 | 8.10 |
| D1 | | 4.00 BSC | |
| E | 5.90 | 6.00 | 6.10 |
| E1 | | 4.00 BSC | |
| e | | 1.00 BSC | |

## 10.5 8-PIN JEDEC 208MIL BROAD SMALL OUTLINE INTEGRATED CIRCUIT (SOIC) PACKAGE (B)



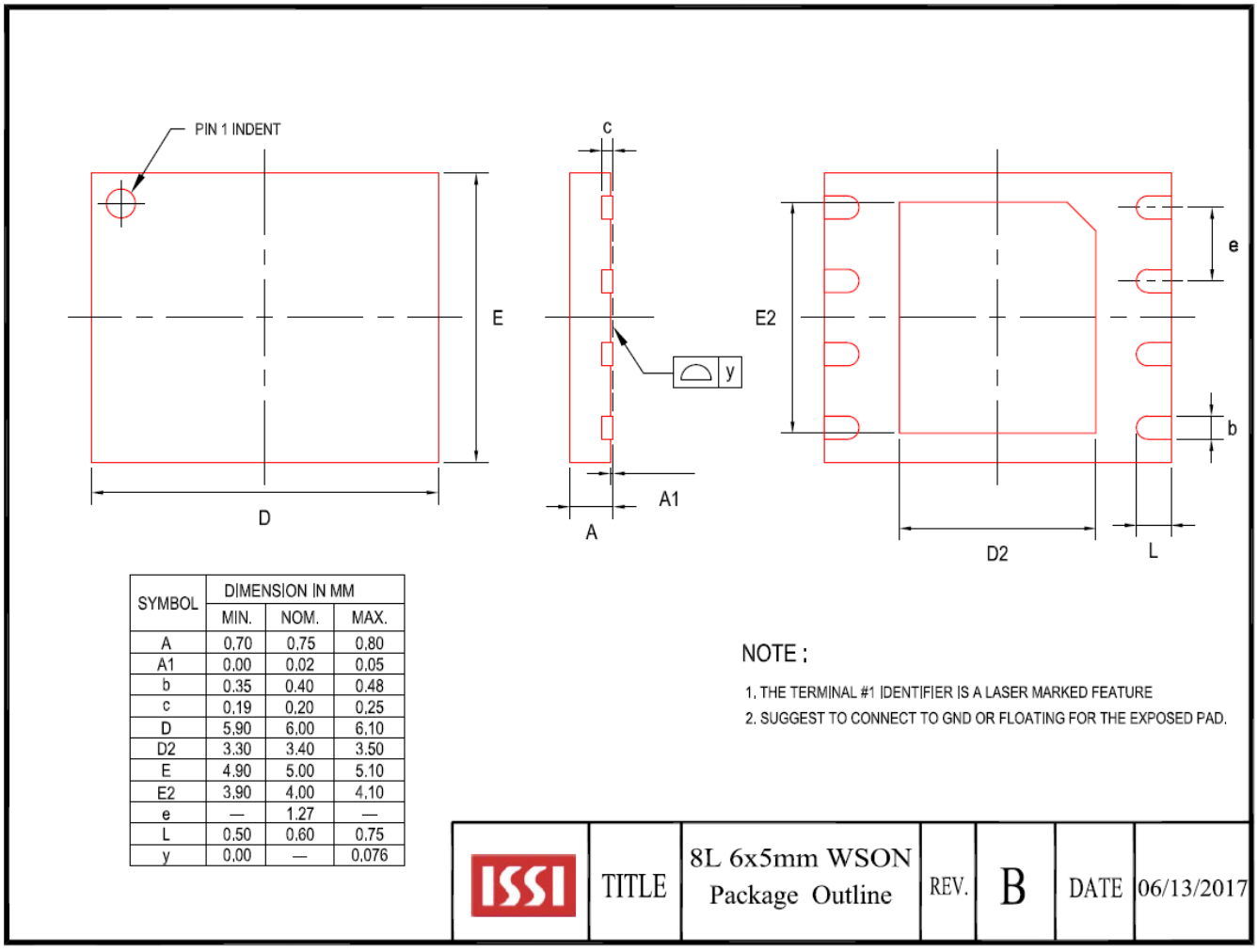

| SYMBOL | DIMENSIONS | | |
|---|---|---|---|
| | MIN. | NOM. | MAX. |
| A | — | — | 2.16 |
| A1 | 0.05 | — | 0.25 |
| b | 0.31 | — | 0.51 |
| D | 5.18 | 5.28 | 5.38 |
| E | 7.70 | 7.90 | 8.10 |
| E1 | 5.18 | 5.28 | 5.38 |
| e | 1.27 BSC. | | |
| L | 0.50 | 0.70 | 0.90 |
| L2 | 0.25 BSC. | | |
| Θ | 0° | — | 8° |

NOTE :

1. CONTROLLING DIMENSION : MM
2. DIMENSION D DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION.

| | | | | | | | |
|---|---|---|---|---|---|---|---|
| ISSI | TITLE | 8L 208mil SOP Package Outline | REV. | B | DATE | 03/29/2019 |

## 10.6 8 CONTACT ULTRA-THIN SMALL OUTLINE NO-LEAD (WSON) PACKAGE 6X5MM (K)



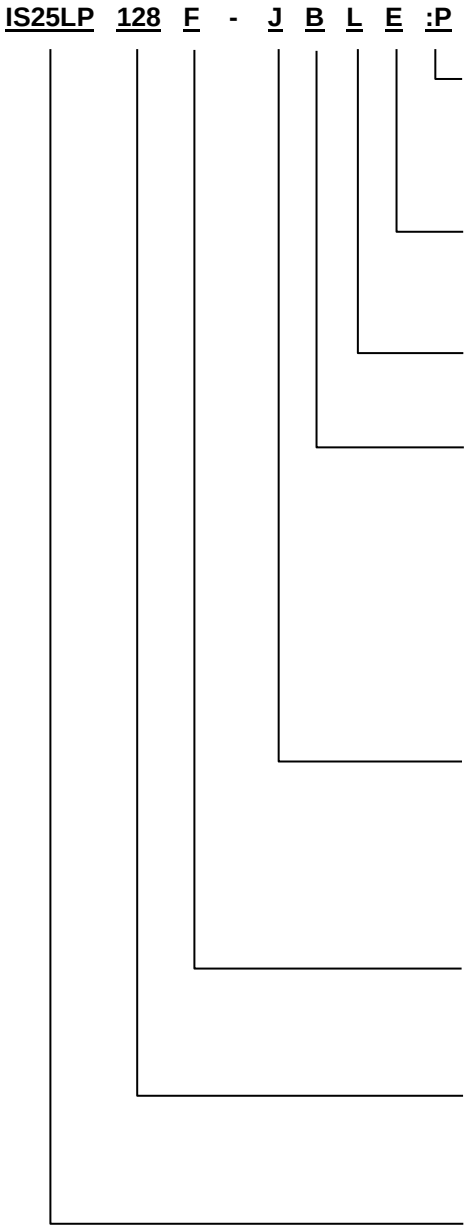

| SYMBOL | DIMENSION IN MM | | |
|---|---|---|---|
| | MIN. | NOM. | MAX. |
| A | 0.70 | 0.75 | 0.80 |
| A1 | 0.00 | 0.02 | 0.05 |
| b | 0.35 | 0.40 | 0.48 |
| c | 0.19 | 0.20 | 0.25 |
| D | 5.90 | 6.00 | 6.10 |
| D2 | 3.30 | 3.40 | 3.50 |
| E | 4.90 | 5.00 | 5.10 |
| E2 | 3.90 | 4.00 | 4.10 |
| e | — | 1.27 | — |
| L | 0.50 | 0.60 | 0.75 |
| y | 0.00 | — | 0.076 |

NOTE :

1. THE TERMINAL #1 IDENTIFIER IS A LASER MARKED FEATURE
2. SUGGEST TO CONNECT TO GND OR FLOATING FOR THE EXPOSED PAD.

| | TITLE | 8L 6x5mm WSON Package Outline | REV. | B | DATE | 06/13/2017 |
|---|---|---|---|---|---|---|

## 11. ORDERING INFORMATION – Valid Part Numbers




**PBO (Polybenzoxazole) LAYER**
:P = Die Overcoat process-PBO layer (Call Factory)
Blank = Without Die Overcoat process-PBO layer

**TEMPERATURE RANGE**
E = Extended (-40°C to +105°C)
A3 = Automotive Grade (-40°C to +125°C)

**PACKAGING CONTENT**
L = **RoHS compliant**

**PACKAGE Type**
B = 8-pin SOIC 208mil
K = 8-contact WSON 6x5mm
L = 8-contact WSON (8x6mm)
M = 16-pin SOIC 300mil
G = 24-ball TFBGA 4x6 ball array
H = 24-ball TFBGA 5x5 ball array
W = KGD (Call Factory)

**Option**
J = Standard
R = Dedicated RESET# for 16-pin SOIC/24-ball BGA
B = Optional BP Table
Q = QE bit set to 1

**Die Revision**
F = Revision F

**Density**
128 = 128 Megabit

**BASE PART NUMBER**
**IS = Integrated Silicon Solution Inc.**
25LP = FLASH, 2.30V ~ 3.60V, QPI
25WP = FLASH, 1.65V ~ 1.95V, QPI

| Density, Voltage | Frequency (MHz) | Order Part Number | | Package |
|---|---|---|---|---|
| | | **E-Temp.** (-40°C to +105°C) | **Auto A3-Temp.**[(1)] (-40°C to +125°C) | |
| 128M, 3V | STR 166, DTR 80 | IS25LP128F-JBLE | IS25LP128F-JBLA3 | 8-pin SOIC 208mil |
| | | IS25LP128F-JKLE | IS25LP128F-JKLA3 | 8-contact WSON 6x5mm |
| | | IS25LP128F-JLLE | IS25LP128F-JLLA3 | 8-contact WSON 8x6mm |
| | | IS25LP128F-JMLE | IS25LP128F-JMLA3 | 16-pin SOIC 300mil |
| | | IS25LP128F-JGLE | IS25LP128F-JGLA3 | 24-ball TFBGA 6x8mm 4x6 ball array |
| | | IS25LP128F-JHLE | IS25LP128F-JHLA3 | 24-ball TFBGA 6x8mm 5x5 ball array |
| | | IS25LP128F-RMLE | IS25LP128F-RMLA3 | 16-pin SOIC 300mil |
| | | IS25LP128F-RGLE | IS25LP128F-RGLA3 | 24-ball TFBGA 6x8mm 4x6 ball array |
| | | IS25LP128F-RHLE | IS25LP128F-RHLA3 | 24-ball TFBGA 6x8mm 5x5 ball array |
| | | IS25LP128F-QBLE | IS25LP128F-QBLA3 | 8-pin SOIC 208mil |
| | | IS25LP128F-QKLE | IS25LP128F-QKLA3 | 8-contact WSON 6x5mm |
| | | IS25LP128F-QLLE | IS25LP128F-QLLA3 | 8-contact WSON 8x6mm |
| | | IS25LP128F-QMLE | IS25LP128F-QMLA3 | 16-pin SOIC 300mil |
| | | IS25LP128F-QGLE | IS25LP128F-QGLA3 | 24-ball TFBGA 6x8mm 4x6 ball array |
| | | IS25LP128F-QHLE | IS25LP128F-QHLA3 | 24-ball TFBGA 6x8mm 5x5 ball array |
| | | IS25LP128F-BBLE | IS25LP128F-BBLA3 | 8-pin SOIC 208mil |
| | | IS25LP128F-BKLE | IS25LP128F-BKLA3 | 8-contact WSON 6x5mm |
| | | IS25LP128F-BLLE | IS25LP128F-BLLA3 | 8-contact WSON 8x6mm |
| | | IS25LP128F-BMLE | IS25LP128F-BMLA3 | 16-pin SOIC 300mil |
| | | IS25LP128F-BGLE | IS25LP128F-BGLA3 | 24-ball TFBGA 6x8mm 4x6 ball array |
| | | IS25LP128F-BHLE | IS25LP128F-BHLA3 | 24-ball TFBGA 6x8mm 5x5 ball array |

| Density, Voltage | Frequency (MHz) | Order Part Number | | Package |
|---|---|---|---|---|
| | | E-Temp. (-40°C to +105°C) | Auto A3-Temp.[1] (-40°C to +125°C) | |
| 128M, 1.8V | STR 166, DTR 80 | IS25WP128F-JBLE | IS25WP128F-JBLA3 | 8-pin SOIC 208mil |
| | | IS25WP128F-JKLE | IS25WP128F-JKLA3 | 8-contact WSON 6x5mm |
| | | IS25WP128F-JLLE | IS25WP128F-JLLA3 | 8-contact WSON 8x6mm |
| | | IS25WP128F-JMLE | IS25WP128F-JMLA3 | 16-pin SOIC 300mil |
| | | IS25WP128F-JGLE | IS25WP128F-JGLA3 | 24-ball TFBGA 6x8mm 4x6 ball array |
| | | IS25WP128F-JHLE | IS25WP128F-JHLA3 | 24-ball TFBGA 6x8mm 5x5 ball array |
| | | IS25WP128F-RMLE | IS25WP128F-RMLA3 | 16-pin SOIC 300mil |
| | | IS25WP128F-RGLE | IS25WP128F-RGLA3 | 24-ball TFBGA 6x8mm 4x6 ball array |
| | | IS25WP128F-RHLE | IS25WP128F-RHLA3 | 24-ball TFBGA 6x8mm 5x5 ball array |
| | | IS25WP128F-QBLE | IS25WP128F-QBLA3 | 8-pin SOIC 208mil |
| | | IS25WP128F-QKLE | IS25WP128F-QKLA3 | 8-contact WSON 6x5mm |
| | | IS25WP128F-QLLE | IS25WP128F-QLLA3 | 8-contact WSON 8x6mm |
| | | IS25WP128F-QMLE | IS25WP128F-QMLA3 | 16-pin SOIC 300mil |
| | | IS25WP128F-QGLE | IS25WP128F-QGLA3 | 24-ball TFBGA 6x8mm 4x6 ball array |
| | | IS25WP128F-QHLE | IS25WP128F-QHLA3 | 24-ball TFBGA 6x8mm 5x5 ball array |
| | | IS25WP128F-BBLE | IS25WP128F-BBLA3 | 8-pin SOIC 208mil |
| | | IS25WP128F-BKLE | IS25WP128F-BKLA3 | 8-contact WSON 6x5mm |
| | | IS25WP128F-BLLE | IS25WP128F-BLLA3 | 8-contact WSON 8x6mm |
| | | IS25WP128F-BMLE | IS25WP128F-BMLA3 | 16-pin SOIC 300mil |
| | | IS25WP128F-BGLE | IS25WP128F-BGLA3 | 24-ball TFBGA 6x8mm 4x6 ball array |
| | | IS25WP128F-BHLE | IS25WP128F-BHLA3 | 24-ball TFBGA 6x8mm 5x5 ball array |

**Notes:**
**1. A3 meets AEC-Q100 requirements with PPAP.**

Стандарт Электрон Связь

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**Наши контакты:**

**Телефон:** +7 812 627 14 35

**Электронная почта:** sales@st-electron.ru

**Адрес:** 198099, Санкт-Петербург,
Промышленная ул, дом № 19, литера Н,
помещение 100-Н Офис 331